

1995

**DATA HANDBOOK SC16** 

PHILIPS

**PHILIPS** 

#### **QUALITY ASSURED**

Our quality system focuses on the continuing high quality of our components and the best possible service for our customers. We have a three-sided quality strategy: we apply a system of total quality control and assurance; we operate customer-oriented dynamic improvement programmes; and we promote a partnering relationship with our customers and suppliers.

#### PRODUCT SAFETY

In striving for state-of-the-art perfection, we continuously improve components and processes with respect to environmental demands. Our components offer no hazard to the environment in normal use when operated or stored within the limits specified in the data sheet.

Some components unavoidably contain substances that, if exposed by accident or misuse, are potentially hazardous to health. Users of these components are informed of the danger by warning notices in the data sheets supporting the components. Where necessary the warning notices also indicate safety precautions to be taken and disposal instructions to be followed. Obviously users of these components, in general the set-making industry, assume responsibility towards the consumer with respect to safety matters and environmental demands.

All used or obsolete components should be disposed of according to the regulations applying at the disposal location. Depending on the location, electronic components are considered to be 'chemical', 'special' or sometimes 'industrial' waste. Disposal as domestic waste is usually not permitted.

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#### **DEFINITIONS**

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
more of the limiting values	accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or may cause permanent damage to the device. These are stress ratings only and hese or at any other conditions above those given in the Characteristics sections of the

#### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

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# **SELECTION GUIDE**

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# Selection guide

#### **CATV AMPLIFIER MODULES**

TYPE NUMBER	FREQUENCY RANGE (MHz)	POWER GAIN at f = 50 MHz (G <sub>p</sub> ) (dB)	SLOPE CABLE EQUIVALENT (SL) (dB)	APPLICATION	PAGE
BGD102	40 to 450	18 to 19	0.5 to 2.5	power doubler	34
BGD104	40 to 450	19.5 to 20.5	0.5 to 2.5	power doubler	34
BGD106	40 to 450	21.5 to 22.5	0 to 2	power doubler	36
BGD108	40 to 450	35 to 37	0.2 to 2.2	power doubler	38
BGD502 (note 1)	40 to 550	18 to 19	0.2 to 2.2	power doubler	40
BGD504 (note 1)	40 to 550	19.5 to 20.5	0.2 to 2.2	power doubler	40
BGD506	40 to 550	21.5 to 22.5	0 to 2	power doubler	44
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BGD601 (note 2)	40 to 600	12 to 13	0.2 to 2.2	power doubler	49
BGD602 (note 2)	40 to 600	18 to 19	0.2 to 2.2	power doubler	53
BGD602D (note 2)	40 to 600	17.5 to 18.5	0.2 to 2.2	p.d., darlington	57
BGD702 (note 5)	40 to 750	18 to 19	0.2 to 2	power doubler	61
BGD704 (note 5)	40 to 750	19.5 to 20.5	0 to 2	power doubler	66
BGD885	40 to 860	16.5 to 17.5	0.2 to 1.6	power doubler	71
BGE85A	40 to 450	17.4 to 19.4	0.3 to 1.5	output amplifier	74
BGE88	40 to 450	33 to 36	0.5 to 2.5	amplifier	76
BGE88/01	40 to 450	33 to 36	0.5 to 2.5	amplifier	76
BGE884	40 to 860	16.5 to17.5	0.2 to 1.4	amplifier	78
BGE885	40 to 860	16.5 to 17.5	0.2 to 1.2	amplifier	80
BGE887	470 to 860			amplifier	83
BGX881	40 to 860	12 to 13	0.2 to 1.4	amplifier	85
BGX885N	40 to 860	16.5 to 17.5	0.2 to 1.4	amplifier	88
BGY61	5 to 200	12.5 to 13.5 (note 4)	-0.2 to +0.5	reverse amplifier	91
BGY65	5 to 200	18 to 19 (note 4)	-0.2 to +0.5	reverse amplifier	93
BGY66B	5 to 120	24.5 to 25.5	-0.2 to +0.5	reverse amplifier	95
BGY67	5 to 200	21.5 to 22.5 (note 4)	-0.2 to +0.5	reverse amplifier	97
BGY67A	5 to 200	23.5 to 24.5 (note 4)	-0.2 to +0.5	reverse amplifier	99
BGY80	40 to 450	12 to 13	0.2 to 1.5	pre-amplifier	101
BGY81	40 to 450	12 to 13	0.2 to 1.5	final amplifier	101
BGY82	40 to 450	13.5 to 14.5	0.2 to 1.5	pre-amplifier	103
BGY83	40 to 450	13.5 to 14.5	0.2 to 1.5	amplifier	103
BGY84	40 to 450	16.5 to 17.5	0.5 to 1.5	pre-amplifier	106
BGY84A	40 to 450	18 to 18.8	0.3 to 1.5	pre-amplifier	109
BGY85	40 to 450	16.5 to 17.5	0.5 to 1.5	final amplifier	106
BGY85A	40 to 450	18 to 18.8	0.3 to 1.5	final amplifier	109
BGY85H/01	40 to 450	14.8 to 16.4		trunk amplifier	112

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# Selection guide

### **CATV AMPLIFIER MODULES (continued)**

TYPE NUMBER	FREQUENCY RANGE (MHz)	POWER GAIN at f = 50 MHz (G <sub>p</sub> ) (dB)	SLOPE CABLE EQUIVALENT (SL) (dB)	APPLICATION	PAGE	
BGY86 40 to 450		21.5 to 22.5	0 to 1.5	pre-amplifier	115	
BGY87	40 to 450	21.5 to 22.5	0 to 1.5	final amplifier	115	
BGY87B	40 to 450	26.2 to 27.8	0.5 to 2.5	amplifier	117	
BGY88	40 to 450	33.5 to 35.5	0.5 to 2.5	line extender	119	
BGY89	40 to 450	37 to 39	0 to 2.5	line extender	121	
BGY580	40 to 550	12 to 13	0.5 to 2	pre-amplifier	123	
BGY581	40 to 550	12 to 13	0.5 to 2	final amplifier	123	
BGY582	40 to 550	13.5 to 14.5	0.2 to 1.5	pre-amplifier	126	
BGY583	40 to 550	13.5 to 14.5	0.2 to 1.5	amplifier	126	
BGY584 (note 1)	40 to 550	16.5 to 17.5	0.5 to 2	pre-amplifier	129	
BGY584A (note 1)	40 to 550	17.7 to 18.7	0.5 to 2	pre-amplifier	132	
BGY585 (note 1)	40 to 550	16.5 to 17.5	0.5 to 2	final amplifier	129	
BGY585A (note 1)	40 to 550	17.7 to 18.7	0.5 to 2	final amplifier	132	
BGY586	40 to 550	21.5 to 22.5	0.2 to 1.5	pre-amplifier	137	
BGY587	40 to 550	21.5 to 22.5	0.2 to 1.5	final amplifier	137	
BGY587B	40 to 550	26.2 to 27.8	0.5 to 2.5	amplifier	139	
BGY588 (note 1)	40 to 550	33.5 to 35.5	0 to 2.5	line extender	141	
BGY681 (note 2)	40 to 600	12 to 13	0.7 to 2.2	amplifier	144	
BGY683 (note 2)	40 to 600	13.5 to 14.5	0.2 to 1.7	amplifier	148	
BGY685 (note 2)	40 to 600	16.5 to 17.5	0.5 to 2.2	amplifier	152	
BGY685A/04 (note 2)	40 to 600	17.7 to 18.7	0.5 to 2.2	amplifier	156	
BGY685AD	40 to 600	18 to 19	0.2 to 2.2	darlington amp.	160	
BGY685AL (note 2)	40 to 600	18 to 19	0.5 to 2	amplifier	162	
BGY687	40 to 600	21 to 22	0.8 to 2.2	amplifier	166	

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#### **CATV AMPLIFIER MODULES (continued)**

TYPE NUMBER	FREQUENCY RANGE (MHz)	POWER GAIN at f = 50 MHz (G <sub>p</sub> ) (dB)	SLOPE CABLE EQUIVALENT (SL) (dB)	APPLICATION	PAGE
BGY687B	40 to 600	26.2 to 27.8	0.8 to 2.8	amplifier	168
BGY785A	40 to 750	18 to 19	0 to 2	amplifier	172
BGY785AD	40 to 750	18 to 19	0 to 1.5	amplifier	174
BGY787	40 to 750	21 to 22	0 to 1.5	amplifier	179
BGY883	40 to 860	14.5 to 15.5	0 to 2	amplifier	184
BGY885A	40 to 860	18 to 19	0 to 2	amplifier	186
BGY885B	40 to 860	19.5 to 20.5	0 to 2	amplifier	192
BGY887B	40 to 860	28.5 to 29.5	0.5 to 2.5	amplifier	194
BGY887BO	40 to 860	-		optical receiver	199
BGY888	40 to 860	33.5 to 34.5	0.5 to 2.5	amplifier	201
BGY1085A	40 to 100	18 to 19	0 to 2	amplifier	206

#### Notes

- 1. Specifications also supplied for 450 MHz bandwidth operation.
- 2. Specifications also supplied for 450 MHz and 550 MHz bandwidth operation.
- 3. Power gain measured at f = 470 MHz.
- 4. Power gain measured at 10 MHz.
- 5. Specifications also supplied for 450 MHz, 550 MHz and 600 MHz bandwidth operation.

# Selection guide

#### **GENERAL PURPOSE HYBRID AMPLIFIER MODULES**

'Low noise' CECC; 12 V supply voltage (note 1)

TYPE	SUPPLY CURRENT	STAGES	GAIN (dB)	NOISE TYP. VALUES (note 2)		MAX. VSWR TYP. VALUES (note 2)		PAGE
	(mA)		(GD)	(dB)	(note 1)	INPUT	OUTPUT	
OM2045	11.5	1	12	3.6	99	2.0	1.4	245
OM2050	18	2	18	5.2	100	1.5	1.9	257
OM2052	42	2	28	4.5	107	2.2	2.1	263
OM2060	56	- 3	23	5.4	107	1.4	1.6	269
OM2063	52	3	29	3.6	105	2.3	1.4	275
OM2064	51	3	28	4.4	107	1.3	1.5	282
OM2070	100	3	28	4.8	112	2.3	1.9	289

### 'High output' CECC; 12 V supply voltage (note 1)

SUPPLY TYPE CURRENT	I STATE I	GAIN FI	NOISE FIGURE	V <sub>O(RMS)</sub> TYP. VALUES	MAX. VSWR TYP. VALUES (note 2)		PAGE	
	(mA)		(dB)	(dB)	(dB/µV) (note 1)	INPUT	ОИТРИТ	
OM2046	82	1	10	10	114	1.5	1.4	251
OM2070B	100	3	30	4.8	112	2.7	1.9	295
OM2081/60	85	1	10	7.5	115	1.5	1.3	301
OM2081/86	65	1	10.5	7.5	115	1.5	1.3	307
OM2082/60	145	2	20	7.5	114	1.5	1.6	313
OM2082/86	145	2	19	7.5	114	1.7	1.4	319
OM2083/60	175	3	29	6.5	114	1.2	1.3	325
OM2083/86	165	3	30	7	112	1.9	1.7	332

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'Satellite band'; 12 V supply voltage (note 1)

TYPE	SUPPLY CURRENT	STAGES	GAIN (dB)	NOISE FIGURE	V <sub>O(RMS)</sub> TYP. VALUES (dB/µV)	TYP.	. VSWR VALUES ote 2)	PAGE
	(mA)		(GD)	(dB)	(note 1)	INPUT	OUTPUT	
OM926	28	2	16	6.5	103	1.8	1.7	225
OM926E	37.5	2	20	6.5	105	2.1	2.0	232
OM956/1	57.5	3	18.5	4.5	112 (note 3)	2.0	1.7	238

#### Notes

- 1. Information on 24 volt versions available on request.
- 2. Measured at -60 dB intermodulation distortion to DIN 45004, para. 6.3: 3-tone.
- 3. The typical maximum VSWR occurring in the frequency range 40 860 MHz, for a sample connected to a 75  $\Omega$  line.
- 4. Measured at -60 dB intermodulation distortion to DIN 45004, para. 6.3: 3-tone.

# **GENERAL**

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### General

#### QUALITY

#### **Total Quality Management**

Philips Semiconductors is a Quality Company, renowned for the high quality of our products and service. We keep alive this tradition by constantly aiming towards one ultimate standard, that of zero defects. This aim is guided by our Total Quality Management (TQM) system, the basis of which is described in the following paragraphs.

#### QUALITY ASSURANCE

Based on ISO 9000 standards, customer standards such as Ford TQE and IBM MDQ. Our factories are certified to ISO 9000 by external inspectorates.

#### PARTNERSHIPS WITH CUSTOMERS

PPM co-operations, design-in agreements, ship-to-stock, just-in-time and self-qualification programmes, and application support.

#### PARTNERSHIPS WITH SUPPLIERS

Ship-to-stock, statistical process control and ISO 9000 audits.

#### QUALITY IMPROVEMENT PROGRAMME

Continuous process and system improvement, design improvement, complete use of statistical process control, realization of our final objective of zero defects, and logistics improvement by ship-to-stock and just-in-time agreements.

#### Advanced quality planning

During the design and development of new products and processes, quality is built-in by advanced quality planning. Through failure-mode-and-effect analysis the critical parameters are detected and measures taken to ensure good performance on these parameters. The capability of process steps is also planned in this phase.

#### Product conformance

The assurance of product conformance is an integral part of our quality assurance (QA) practice. This is achieved by:

- Incoming material management through partnerships with suppliers.
- In-line quality assurance to monitor process reproducibility during manufacture and initiate any necessary corrective action. Critical process steps are 100% under statistical process control.
- Acceptance tests on finished products to verify conformance with the device specification. The test results are used for quality feedback and corrective actions. The inspection and test requirements are detailed in the general quality specifications.
- Periodic inspections to monitor and measure the conformance of products.

#### **Product reliability**

With the increasing complexity of Original Equipment Manufacturer (OEM) equipment, component reliability must be extremely high. Our research laboratories and development departments study the failure mechanisms of semiconductors. Their studies result in design rules and process optimization for the highest built-in product reliability. Highly accelerated tests are applied to the products reliability evaluation. Rejects from reliability tests and from customer complaints are submitted to failure analysis, to result in corrective action.

#### Customer responses

Our quality improvement depends on joint action with our customer. We need our customer's inputs and we invite constructive comments on all aspects of our performance. Please contact our local sales representative.

#### Recognition

The high quality of our products and services is demonstrated by many Quality Awards granted by major customers and international organizations.

General

#### PRO ELECTRON TYPE NUMBERING SYSTEM

#### Basic type number

This type designation code applies to discrete semiconductor devices (not integrated circuits), multiples of such devices, semiconductor chips and darlington transistors.

#### FIRST LETTER

The first letter gives information about the material for the active part of the device.

- A germanium or other material with a band gap of 0.6 to 1 eV
- B silicon or other material with a band gap of 1 to 1.3 eV
- C gallium arsenide (GaAs) or other material with a band gap of 1.3 eV or more
- R compound materials, e.g. cadmium sulphide.

#### SECOND LETTER

The second letter indicates the function for which the device is primarily designed. The same letter can be used for multi-chip devices with similar elements. In the following list low power types are defined by  $R_{th \ imb} >$  15 K/W and power types by  $R_{th \ imb} \leq$  15 K/W.

- A diode; signal, low power
- B diode; variable capacitance
- C transistor; low power, audio frequency
- D transistor; power, audio frequency
- E diode; tunnel
- F transistor; low power, high frequency
- G multiple of dissimilar devices/miscellaneous devices; e.g. oscillators. Also with special third letter, see under 'Serial number'
- H diode; magnetic sensitive
- L transistor; power, high frequency
- N photocoupler
- P radiation detector; e.g. high sensitivity photo-transistor; with special third letter

- Q radiation generator; e.g. LED, laser; with special third letter
- R control and switching device; e.g. thyristor, low power; with special third letter
- S transistor; low power, switching
- T control and switching device; e.g. thyristor, power; with special third letter
- U transistor; power, switching
- W surface acoustic wave device
- X diode; multiplier, e.g. varactor, step recovery
- Y diode; rectifying, booster
- Z diode; voltage reference or regulator, transient suppressor diode; with special third letter.

#### SERIAL NUMBER/SPECIAL THIRD LETTER

The number comprises three figures running from 100 to 999 for devices primarily intended for consumer equipment, or one letter (Z, Y, X, etc.) and two figures running from 10 to 99 for devices primarily intended for industrial or professional equipment.<sup>(1)</sup> The letter has no fixed meaning, except in the following cases:

- A for triacs, after second letter 'R' or 'T'
- F for emitters and receivers in fibre-optic communication, after second letter 'G', 'P' or 'Q'. When the second letter is 'G', the first letter should be defined in accordance with the material of the main optical device.
- L for lasers in non-fibre-optic applications, after second letter 'G' or 'Q'. When the second letter is 'G', the first letter should be defined in accordance with the material of the main optical device.
- O for opto-triacs, after second letter 'R'
- T for 3-state bicolour LEDs, after second letter 'Q'
- W for transient voltage suppressor diodes, after second letter 'Z'.

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<sup>(1)</sup> When the supply of these serial numbers is exhausted, the serial number may be expanded to three figures for industrial types and four figures for consumer types.

General

EXAMPLES OF BASIC TYPE NUMBERS

AA112: germanium, low-power signal diode

(consumer type)

ACY32: germanium, low-power AF transistor (industrial

type)

BD232: silicon, power AF transistor (consumer type)
CQY17: GaAs, light-emitting diode (industrial type)
RPY84: CdS, photo-conductive cell (industrial type).

#### Version letter(s)

One or two letters may be added to the basic type number to indicate minor electrical or mechanical variants of the basic type. The letters never have a fixed meaning, except that the letter 'R' indicates reverse polarity and the letter 'W' indicates a surface mounted device (SMD).

#### Suffix

Sub-classification can be used for devices supplied in a wide range of variants, called associated types. The following sub-coding suffixes are in use:

VOLTAGE REFERENCE AND VOLTAGE REGULATOR DIODES

One letter and one number, preceded by a hyphen (-). The letter, if required, indicates the nominal tolerance of the Zener voltage.

A 1% (in accordance with IEC 63, series E96)

B 2% (in accordance with IEC 63, series E48)

C 5% (in accordance with IEC 63, series E24)

D 10% (in accordance with IEC 63, series E12)

E 20% (in accordance with IEC 63, series E6).

In the case of a 3% tolerance, the letter 'F' is used.

The number denotes the typical operating (Zener) voltage, related to the nominal current rating for the entire range. The letter 'V' is used in place of the decimal point.

Example: BZY74-C6V3 or -C10.

TRANSIENT VOLTAGE SUPPRESSOR DIODES

One number, preceded by a hyphen (-). The number indicates the maximum recommended continuous reversed (stand-off) voltage, V<sub>R</sub>. The letter 'V' is used in place of the decimal point.

Example: BZW70-9V1 or -39.

The letter 'B' may be used immediately after the last number, to indicate a bidirectional suppressor diode.

Example: BZW10-15B.

CONVENTIONAL AND CONTROLLED AVALANCHE RECTIFIER DIODES AND THYRISTORS

One number, preceded by a hyphen (-). The number indicates the rated maximum repetitive peak reverse voltage,  $V_{\text{RRM}}$ , or the rated repetitive peak off-state voltage,  $V_{\text{DRM}}$ , whichever is the lower. Reversed polarity with respect to the case is indicated by the letter 'R' immediately after the number.

Example: BYT-100 or -100R.

RADIATION DETECTORS

One number, preceded by a hyphen (-). The number indicates the depletion layer in micrometres ( $\mu m$ ). The resolution is indicated by a version letter.

Example: BPX10-2A.

ARRAY OF RADIATION DETECTORS AND GENERATORS

One number, preceded by a hyphen (-). The number indicates the number of basic devices assembled into the array.

Examples: BPW50-6, BPW50-9, BPW50-12.

HIGH FREQUENCY POWER TRANSISTORS

One number, preceded by a hyphen (-). The number indicates the supply voltage.

Example: BLU80-24.

#### **RATING SYSTEMS**

The rating systems described are those recommended by the International Electrotechnical Commission (IEC) in its publication number 134.

#### Definitions of terms used

ELECTRONIC DEVICE

An electronic tube or valve, transistor or other semiconductor device. This definition excludes inductors, capacitors, resistors and similar components.

General

#### CHARACTERISTIC

A characteristic is an inherent and measurable property of a device. Such a property may be electrical, mechanical, thermal, hydraulic, electro-magnetic or nuclear, and can be expressed as a value for stated or recognized conditions. A characteristic may also be a set of related values, usually shown in graphical form.

#### BOGEY ELECTRONIC DEVICE

An electronic device whose characteristics have the published nominal values for the type. A bogey electronic device for any particular application can be obtained by considering only those characteristics that are directly related to the application.

#### RATING

A value that establishes either a limiting capability or a limiting condition for an electronic device. It is determined for specified values of environment and operation, and may be stated in any suitable terms. Limiting conditions may be either maxima or minima.

#### RATING SYSTEM

The set of principles upon which ratings are established and which determine their interpretation. The rating system indicates the division of responsibility between the device manufacturer and the circuit designer, with the object of ensuring that the working conditions do not exceed the ratings.

#### Absolute maximum rating system

Absolute maximum ratings are limiting values of operating and environmental conditions applicable to any electronic device of a specified type, as defined by its published data, which should not be exceeded under the worst probable conditions.

These values are chosen by the device manufacturer to provide acceptable serviceability of the device, taking no responsibility for equipment variations, environmental variations, and the effects of changes in operating conditions due to variations in the characteristics of the device under consideration and of all other electronic devices in the equipment.

The equipment manufacturer should design so that, initially and throughout the life of the device, no absolute maximum value for the intended service is exceeded with any device, under the worst probable operating conditions with respect to supply voltage variation,

equipment component variation, equipment control adjustment, load variations, signal variation, environmental conditions, and variations in characteristics of the device under consideration and of all other electronic devices in the equipment.

#### Design maximum rating system

Design maximum ratings are limiting values of operating and environmental conditions applicable to a bogey electronic device of a specified type as defined by its published data, and should not be exceeded under the worst probable conditions.

These values are chosen by the device manufacturer to provide acceptable serviceability of the device, taking responsibility for the effects of changes in operating conditions due to variations in the characteristics of the electronic device under consideration.

The equipment manufacturer should design so that, initially and throughout the life of the device, no design maximum value for the intended service is exceeded with a bogey electronic device, under the worst probable operating conditions with respect to supply voltage variation, equipment component variation, variation in characteristics of all other devices in the equipment, equipment control adjustment, load variation, signal variation and environmental conditions.

#### Design centre rating system

Design centre ratings are limiting values of operating and environmental conditions applicable to a bogey electronic device of a specified type as defined by its published data, and should not be exceeded under normal conditions.

These values are chosen by the device manufacturer to provide acceptable serviceability of the device in average applications, taking responsibility for normal changes in operating conditions due to rated supply voltage variation, equipment component variation, equipment control adjustment, load variation, signal variation, environmental conditions, and variations in the characteristics of all electronic devices.

The equipment manufacturer should design so that, initially, no design centre value for the intended service is exceeded with a bogey electronic device in equipment operating at the stated normal supply voltage.

General

#### **LETTER SYMBOLS**

The letter symbols for transistors and signal diodes detailed in this section are based on IEC publication number 148.

#### Letter symbols for currents, voltages and powers

#### BASIC LETTERS

I, i current
V, v voltage
P, p power.

Upper-case letter symbols are used to represent all values except instantaneous values that vary with time, these are represented by lower-case letters.

anode terminal

#### SUBSCRIPTS

A a

A, a	anode terminal
(AV), (av)	average value
B, b	base terminal (for MOS devices: substrate)
C, c	collector terminal
D, d	drain terminal
E, e	emitter terminal
F, f	forward
G, g	gate terminal
K, k	cathode terminal
M, m	peak value
О, о	as third subscript: the terminal not mentioned is open-circuit
R, r	as first subscript: reverse. As second subscript: repetitive. As third subscript: with a specified resistance between the terminal not mentioned and the reference terminal
(RMS), (rms)	root-mean-square value
S, s	as first or second subscript: source terminal (FETs only). As second subscript: non-repetitive (not FETs). As third subscript: short circuit between the terminal not mentioned and the reference terminal
X, x	specified circuit
Z, z	replaces R to indicate the actual working

No additional subscript is used for DC values.

Upper-case subscripts are used for the indication of:

voltage, current or power of voltage reference and voltage regulator diodes.

- continuous (DC) values (without signal), e.g. I<sub>B</sub>
- instantaneous total values, e.g. in
- average total values, e.g. I<sub>B(AV)</sub>
- peak total values, e.g. I<sub>BM</sub>
- root-mean-square total values, e.g. I<sub>B(RMS)</sub>.

Lower-case subscripts are used for the indication of values applying to the varying component alone:

- instantaneous values, e.g. ib
- root-mean-square values, e.g. Ib(ms)
- peak values, e.g. Ibm
- average values, e.g. I<sub>b(av)</sub>.

If more than one subscript is used, the subscript for which both styles exist are either all upper-case or all lower-case.

#### ADDITIONAL RULES FOR SUBSCRIPTS

#### Transistor currents

If it is necessary to indicate the terminal carrying the current, this should be done by the first subscript (conventional current flow from the external circuit into the terminal is positive).

#### Diode currents

To indicate a forward current (conventional current flow into the anode terminal), the subscript F or f should be used. For a reverse current (conventional current flow out of the anode terminal), the subscript R or r should be used.

#### Transistor voltages

If it is necessary to indicate the points between which a voltage is measured, this should be done by the first two subscripts. The first subscript indicates the terminal at which the voltage is measured and the second the reference terminal or the circuit node. Where there is no possibility of confusion, the second subscript may be omitted.

Examples: 
$$V_{BE}$$
,  $v_{BE}$ ,  $v_{be}$ ,  $V_{bem}$ .

#### General

#### Diode voltages

To indicate a forward voltage (anode positive with respect to cathode), the subscript F or f should be used. For a reverse voltage (anode negative with respect to cathode), the subscript R or r should be used.

Examples: V<sub>F</sub>, V<sub>B</sub>, v<sub>F</sub>, V<sub>m</sub>.

#### Supply voltages or currents

Supply voltages or supply currents are indicated by repeating the appropriate terminal subscript.

Examples: V<sub>CC</sub>, I<sub>EE</sub>.

If it is necessary to indicate a reference terminal, this should be done by a third subscript.

Example: V<sub>CCE</sub>.

Subscripts for devices with more than one terminal of the same kind

If a device has more than one terminal of the same kind, the subscript is formed by the appropriate letter for the terminal, followed by a number. In the case of multiple subscripts, hyphens may be necessary to avoid confusion.

#### Examples:

I<sub>B2</sub> continuous (DC) current flowing into the second base terminal

V<sub>B2-E</sub> continuous (DC) voltage between the terminals of second base and emitter.

#### Subscripts for multiple devices

For multiple unit devices, the subscripts are modified by a number preceding the letter subscript. In the case of multiple subscripts, hyphens may necessary to avoid confusion.

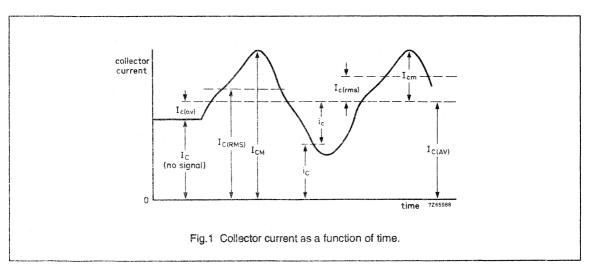
#### Examples:

l<sub>20</sub> continuous (DC) current flowing into the collector terminal of the second unit

V<sub>1C-2C</sub> continuous (DC) voltage between the collector terminals of the first and second units.

#### Application of the rules

Figure 1 represents a transistor collector current as a function of time. It comprises a continuous (DC) current and a varying component.



General

#### Letter symbols for electrical parameters

#### DEFINITION

For the purpose of this publication, the term 'electrical parameter' applies to four-pole matrix parameters, elements of electrical equivalent circuits, electrical impedances and admittances, inductances and capacitances.

#### BASIC LETTERS

The following list comprises the most important basic letters used for electrical parameters of semiconductor devices.

B, b	susceptance (imaginary part of an admittance)
C	capacitance
G, g	conductance (real part of an admittance)
H, h	hybrid parameter
L	inductance
R, r	resistance (real part of an impedance)
X, x	reactance (imaginary part of an impedance)
Y, y	admittance
Z, z	impedance.

Upper-case letters are used for the representation of:

- electrical parameters of external circuits and of circuits in which the device forms only a part
- all inductances and capacitances.

Lower-case letters are used for the representation of electrical parameters inherent in the device, with the exception of inductances and capacitances.

#### SUBSCRIPTS

#### General subscripts

The following list comprises the most important general subscripts used for electrical parameters of semiconductor devices.

F, f	forward (forward transfer)	
l, i (or 1)	input	
L, I	load	
O, o (or 2)	output	

R, r reverse (reverse transfer)

source.

Examples: Z<sub>s</sub>, h<sub>f</sub>, h<sub>F</sub>.

The upper-case variant of a subscript is used for the

designation of static (DC) values.

#### Examples:

h<sub>FE</sub> static value of forward current transfer ratio in common-emitter configuration (DC current gain)

R<sub>F</sub> DC value of the external emitter resistance.

The static value is the slope of the line from the origin to the operating point on the appropriate characteristic curve, i.e. the quotient of the appropriate electrical quantities at the operating point.

The lower-case variant of a subscript is used for the designation of small-signal values.

#### Examples:

h<sub>fe</sub> small-signal value of the short-circuit forward current transfer ratio in common-emitter configuration

 $Z_e = R_e + jX_e$  small-signal value of the external impedance.

If more than one subscript is used, subscripts for which both styles exist are either all upper-case or all lower-case.

Example: hee, yee, hee

Subscripts for four-pole matrix parameters

The first letter subscript (or double numeric subscript) indicates input, output, forward transfer or reverse transfer.

Examples:  $h_i$  (or  $h_{11}$ ),  $h_o$  (or  $h_{22}$ ),  $h_i$  (or  $h_{21}$ ),  $h_r$  (or  $h_{12}$ ).

A further subscript is used for the identification of the circuit configuration. When no confusion is possible, this further subscript may be omitted.

Examples: h<sub>fe</sub> (or h<sub>21e</sub>), h<sub>FE</sub> (or h<sub>21E</sub>).

DISTINCTION BETWEEN REAL AND IMAGINARY PARTS

If it is necessary to distinguish between real and imaginary parts of electrical parameters, no additional subscripts should be used. If basic symbols for the real and imaginary parts exist, these may be used.

Examples:  $Z_i = R_i + jX_i$ ,  $y_{fe} = g_{fe} + jb_{fe}$ .

If such symbols do not exist, or if they are not suitable, the following notation is used:

Examples:

Re (h<sub>ib</sub>) etc. for the real part of h<sub>ib</sub> Im (h<sub>ib</sub>) etc. for the imaginary part of h<sub>ib</sub>.

S. s

#### **CATV PARAMETERS**

#### Gain (G<sub>p</sub>)

#### DEFINITION

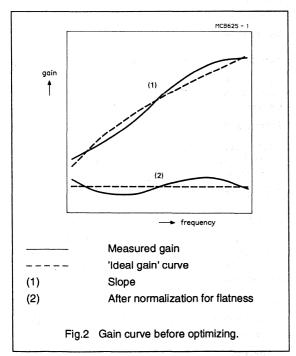
The power gain, expressed in dB, is the ratio of output and input power of a module, operating in a 75  $\Omega$  (Z<sub>o</sub>) system.

#### **MEASUREMENT**

The power gain is measured at several frequencies throughout the band, although the gain performances are mostly given only at the start and stop frequencies. The gain is measured by applying a single tone signal to the module and measuring the output power. The input power is measured before connecting the module using a thru-line and feeding the system with exactly the same signals.

#### EQUIPMENT

Input and output power levels are measured with a power meter.



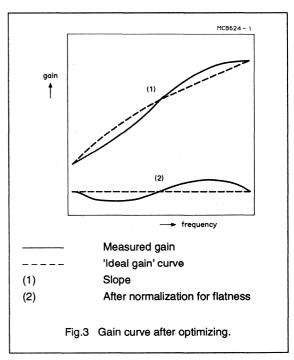
#### Flatness of frequency response (FL)

#### DEFINITION

The flatness of gain of a CATV amplifier module is defined as the maximum deviation from an absolute flat gain over a given frequency range, after the slope of the amplifier over this frequency range has been optimized and equalized by means of a certain cable length to give the best result for flatness (see Figs 2 and 3). This means that an 'ideal gain curve' for the module is calculated and the flatness is the maximum deviation of this 'ideal gain' curve.

#### CALCULATION

To determine the flatness, the measured gain values are compared with an 'ideal gain' curve derived from a mathematical model. The formula used is as follows:



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$$Gain = G + C \sqrt{\frac{f_x}{f_1}}$$

where

G = constant gain (frequency independent)

C = cable constant

f<sub>x</sub> = desired frequency

f<sub>1</sub> = start frequency

The cable constant (C) must be optimized during the flatness determination so that the gain curve best fits the measured gain figures. The start value for C is calculated using the formula:

$$C_{start} = \frac{G_n - G_1}{\sqrt{\frac{f_n}{f}} - 1}$$

where

G<sub>n</sub> = the measured gain at stop frequency

G<sub>1</sub> = the measured gain at start frequency

f<sub>n</sub> = stop frequency

The value of G is chosen so that the maximum positive deviation of the measured gain from the 'ideal gain' curve is the same as the maximum negative deviation. The value of C is adapted by  $\pm$  0.001 until the 'ideal gain' curve best fits the measured curve.

The flatness of the module gain is the maximum deviation in measured gain from the optimized gain formula.

#### Slope (SL)

DEFINITION

The slope of a module is the difference between the 'ideal gain' at the start frequency and the 'ideal gain' at the stop frequency (see 'Flatness').

#### Flatness (S-curve method)

DEFINITION

For some high-slope modules the flatness is calculated according to the 'S-curve' method. The ideal S-curve is defined as:

$$G_t = G_t + \delta G \cdot a \cdot (f - f_1) + \delta G \cdot b \cdot (f - f_1)^2 + \delta G \cdot c \cdot (f - f_1)^3$$

where

$$\delta G = G_t - G_t$$

f<sub>1</sub> = start frequency

f<sub>n</sub> = stop frequency

 $a = 3.1224 \times 10^{-3}$ 

 $b = 1.9932 \times 10^{-6}$ 

 $c = -8.934 \times 10^{-9}$ 

The flatness is the maximum deviation between the measured gain and the 'ideal gain' curve.

#### Delta gain

DEFINITION

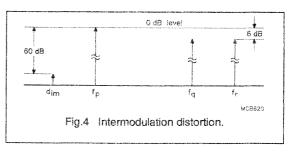
Delta gain is the difference in gain between two given frequencies (mostly the start and stop frequencies).

#### Intermodulation distortion (dim)

In accordance with DIN 45004B 6.3, 3-tone

#### DEFINITION

The intermodulation distortion product is the difference in dB between the peak of the RF signal in the measuring channel and the peak of the distortion signal caused by the influence of a signal in a neighbouring channel (see Fig.4).



To measure 3-tone  $\mathbf{d}_{\mathrm{im}}$  three CW signals are applied to the module:

$$f_p = f$$
 level = 0 dB  
 $f_q = f + 7$  MHz level = -6 dB  
 $f_r = f + 9$  MHz level = -6 dB

The distortion product is measured at f-2 MHz. This distortion product consists of the  $(f_p+f_q-f_r)$  beats and is expressed in dB referred to the 0 dB level (the  $f_p$  signal level).

This 0 dB level should be chosen so that the distortion product  $(d_m)$  is -60 dB. For practical reasons the given output level  $(V_o)$  for 3-tone distortion is defined as the

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0 dB level and the modules are rejected if the distortion level is worse than -60 dB.

#### EQUIPMENT

Spectrum analyzer with settings:

internal attenuator 40 dB resolution bandwidth 3 kHz video bandwidth 100 Hz span 50 kHz.

The three signals are obtained from three different generators (see Appendix A).

# Composite third order distortion: composite triple beat (CTB) in CW carriers

In accordance with National Cable Television Association recommendations.

#### DEFINITION

Composite third order modulation is the amplitude distortion of desired signals, caused by third order curvature of non-linear transfer characteristics in system equipment. It is the ratio, expressed in dB, of the peak level of the RF signal to the peak level of the cluster of distortion components centred around the carrier.

#### **M**EASUREMENT

To measure the CTB, a signal at the measuring frequency is set to the specified V<sub>o</sub> level. This output level is defined as the 0 dB level. During the measurement<sup>(1)</sup> all channels in the band are set to the specified V<sub>o</sub> level, see Appendix E. Now, at the measuring frequency, the distortion product is measured with a spectrum analyzer or distortion analyzer.

The CTB distortion is measured high in the band because here the distortion products have most

amplitude (although the greatest number of beats ( $f_1 \pm f_2$ )  $\pm f_3$  and  $2 \times f_1 \pm f_2$ ) are found in the centre of the band).

#### EQUIPMENT

Spectrum analyzer with settings:

resolution bandwidth 30 kHz video bandwidth 100 kHz span 500 kHz.

A bandpass filter is used to eliminate the distortion products caused by the spectrum analyzer itself. If desired, a distortion analyzer can be used instead of the spectrum analyzer.

The carrier signals are obtained from a multi-channel generator. The frequency deviation of each channel must be less than 5 kHz.

# Composite third order distortion: cross modulation $(X_{mod})$ in modulated carriers

#### DEFINITION

Cross modulation distortion is a form of distortion where modulation of interfering stations appears as a modulation of the desired station, caused by third order curvature of non-linear transfer characteristics in system equipment. It is the ratio, expressed in dB, of the peak level of the modulated RF signal to the peak level of the distortion components centred around the carrier (see Figs 5, 6 and 7).

#### MEASUREMENT

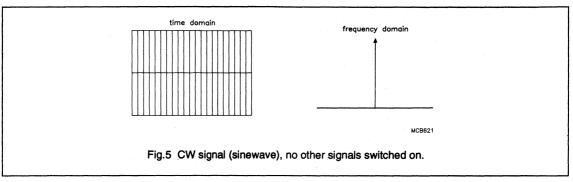
To measure  $X_{mod}$ , the carrier of the desired channel is set to the specified  $V_o$  level. This channel is then 100% modulated with a 15.75 kHz square wave.<sup>(2)</sup> The peak level of this modulation signal (15.75 kHz on the carrier) is defined as the 0 dB level. The distortion product is now measured by setting each individual CW channel to the specified  $V_o$  level and switching them on in modulated

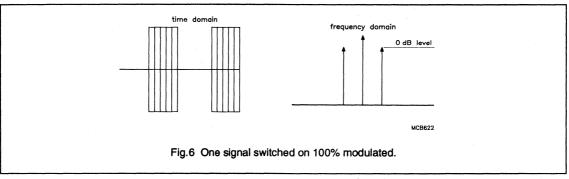
<sup>(1)</sup> In the USA, an equally spaced frequency raster is used with a space of 6 MHz between the channels. In the German frequency distribution the space between the channels is 7 MHz up to 300 MHz, and 8 MHz above 300 MHz. In general, the Philips measurements are made in accordance with the American frequency raster. For the German market, measurements can be made with a set-up which approximates as closely as possible to the German raster. A list of both rasters is given in Appendix D.

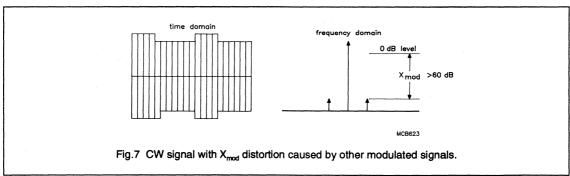
<sup>(2)</sup> The 15.75 kHz square wave modulation signal, used with X<sub>mod</sub> measurements, found its origin in the American broadcasting method. Using the NTSC system, the 15.75 kHz is defined by the 60 Hz mains frequency and the number of 525 TV lines, i.e. (NTSC) = 60 × 525 + 2 = 15.75 kHz.

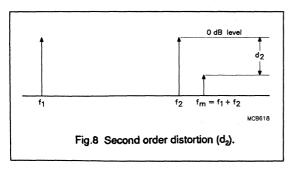
The modulation frequency for PAL (one of the European methods) is 15.625 kHz. This is because in Europe the mains frequency is 50 Hz and the number of TV lines using PAL is 625.

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mode, see Appendix E. Only the carrier in the channel where the  $X_{mod}$  distortion is to be measured, is not modulated. The  $X_{mod}$  distortion peak now appears as 15.75 kHz on the carrier.

The  $X_{\rm mod}$  distortion is most easily measured at the low end of the frequency band.

#### EQUIPMENT

#### Bandpass filter:

tuned to the channel in which the distortion product is to be measured.

Spectrum analyzer with settings (for most types):

resolution bandwidth 300 kHz video bandwidth 30 Hz span 5 kHz.

A multi-channel generator is required for the test signals.

A distortion analyzer will be required if the  $X_{\rm mod}$  is to be measured at a high frequency in the band. This is because phase noise will make spectrum analyzer measurements inaccurate.

#### Second order distortion (d<sub>2</sub>)

In accordance with DIN 45004-A1

#### DEFINITION

The second order distortion product is the difference in dB between the peak level of an RF signal at the measuring frequency, and the peak level of the signal at the measuring frequency caused by two CW signals with their second order modulation product  $(f_1 \pm f_2)$  at the measuring frequency (see Fig.8).

#### MEASUREMENT

Second order modulation is measured at the frequency in the band where the distortion product is found to be worst. In general this will be at the high end of the band.

In most cases the measuring procedure will be as follows:

Signals  $f_1$  and  $f_2$  are chosen so that  $f_1$  is the lowest channel in the band and  $f_2$  is the highest, this means that  $f_1 + f_2$  lays within the band.

The peak levels of  $f_1$  and  $f_2$  are equal and are defined as the 0 dB level. For frequency sets, see Appendix B.

#### EQUIPMENT

Spectrum analyzer with settings:

resolution bandwidth 3 kHz video bandwidth 100 Hz span 50 kHz.

A tunable bandpass filter is used to eliminate the distortion caused by the spectrum analyzer.

#### Composite second order (CSO) distortion

#### DEFINITION

Composite second order distortion is the ratio, expressed in dB, of the peak level, of the RF signal to the peak level of the cluster of distortion components centred around the desired signal. This distortion is caused by a compilation of components of second order intermodulation products of interfering signals with frequencies  $f_1$  and  $f_2$ , so that

 $f_m = f_1 \pm f_2$  or  $f_m = 2 \times f_1$  or  $f_m = 2 \times f_2$ .

#### MEASUREMENT

Measurement is made by setting a signal with the desired frequency to the specified level for  $V_{\rm o}$ . This  $V_{\rm o}$  level is defined as the 0 dB level.

During the measurement, all channels in the band are levelled to the specified  $V_{\rm o}$ . Now at the measurement frequency, the distortion product is measured by use of a spectrum analyzer.

The CSO distortion is measured high in the band because it is here that this distortion product has most influence, see Appendix E.

#### EQUIPMENT

Spectrum analyzer with settings:

resolution bandwidth 30 kHz video bandwidth 100 Hz span 400 kHz.

A bandpass filter is used at the input of the spectrum analyzer.

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#### S-parameters S<sub>11</sub> and S<sub>22</sub> (return losses)

In accordance with IEC 747-7

#### DEFINITION

The return losses or reflection coefficients of a module can be defined as the  $S_{11}$  and the  $S_{22}$  of a two-port network (see Fig.9).

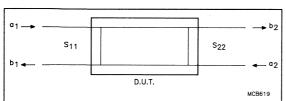


Fig.9 Two-port network with reflection coefficients S<sub>11</sub> and S<sub>22</sub>.

$$b_1 = S_{11} \cdot a_1 + S_{12} \cdot a_2 \tag{1}$$

$$b_2 = S_{21} \cdot a_1 + S_{22} \cdot a_2 \tag{2}$$

whore

$$a_1 = \frac{1}{2 \cdot \sqrt{Z_o}} \cdot (V_1 + Z_o \cdot i_1) = \text{signal into port 1}$$
 (3)

$$a_2 = \frac{1}{2 \cdot \sqrt{Z_0}} \cdot (V_2 + Z_0 \cdot i_2) = \text{signal into port 2}$$
 (4)

$$b_1 = \frac{1}{2 \cdot \sqrt{Z_0}} \cdot (V_1 + Z_0 \cdot i_1) = \text{signal out of port 1}$$

$$b_2 = \frac{1}{2 \cdot \sqrt{Z_o}} \cdot (V_2 + Z_o \cdot i_2) = \text{signal out of port 2}$$

From (1) and (2) formulae for the return losses can be derived:

$$S_{11} = \frac{b_1}{a_1} \mid a_2 = 0 \tag{5}$$

$$S_{22} = \frac{b_2}{a_2} \mid a_1 = 0 \tag{6}$$

In (5),  $a_2 = 0$  means output port terminated with  $Z_o$  (derived from formula (4)).

In (6),  $a_1 = 0$  means input port terminated with  $Z_o$  (derived from formula (3)).

#### MEASUREMENT

The return losses are measured with a network analyzer after calibration, where the influence of the test jig is

eliminated. The necessary termination of the other port with  $Z_0$  is done automatically by the network analyzer.

The network analyzer must have a directivity of at least 40 dB to obtain an accuracy of 0.5 dB when measuring return loss figures of 20 dB. A full two-port correction method can be used to improve the accuracy.

#### Noise figure (F)

In accordance with IEC 747-7

#### DEFINITION

The noise figure is defined as the ratio of the total available noise power output from the module when connected to a noise source to that which is generated solely by the noise source.

#### MEASUREMENT

Noise figure is measured with a noise figure meter at the output of the module, while a noise source is connected to the input of the module. Measurements should be done in an electrically-shielded room to prevent pick-up of unwanted signals.

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APPENDIX A - COMMON FREQUENCY SETS for  $d_{\rm dim}$  MEASUREMENTS

f <sub>m</sub> (MHz)	f <sub>p</sub> (MHz)	f <sub>q</sub> (MHz)	f, (MHz)
33.25	35.25	42.25	44.25
163.25	165.25	172.25	174.25
185.25	187.25	194.25	196.25
285.25	287.25	294.25	296.25
335.25	337.25	344.25	346.25
339.25	341.25	348.25	350.25
385.25	387.25	394.25	396.25
438.25	440.25	447.25	449.25
481.25	483.25	490.25	492.25
538.25	540.25	547.25	549.25
849.25	851.25	858.25	860.25

### APPENDIX B - COMMON FREQUENCY SETS for d<sub>2</sub> MEASUREMENTS

f <sub>p</sub> (MHz)	f <sub>q</sub> (MHz)	f <sub>m</sub> (MHz)
83.25	109.25	192.50
66.00	144.00	210.00
55.25	211.25	266.50
55.25	343.35	398.50
55.25	391.25	446.50
55.25	493.25	548.50
300.00	450.00	750.00

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#### APPENDIX C - DISTORTION RESULTS USING THE CENELEC FREQUENCY RASTER

The CENELEC Frequency Raster is increasingly being used in Europe. This raster has less channels and these are no longer equally spaced as with the USA Frequency Raster. This results generally in much better distortion readings.

The distortion figures of the CATV hybrids are measured using the standard USA Frequency Raster. A different number of channels is used, however, depending on the frequency range.

The following table based on calculations and correlation measurements using several different hybrid types provides a means of converting the standard measured distortion figures (USA Frequency Raster) into CENELEC Frequency Raster readings.

FREQUENCY	CHANNELS		CTB	X <sub>mod</sub>	CSO
RANGE (MHz)	USA	CENELEC	(dB)	(dB)	(dB)
40 - 600	85	29	-11.00	-8.00	-6.00
40 - 750	110	35	-12.00	-9.00	-9.00
40 - 860	49	42	+2.00	-1.00	+1.00

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APPENDIX D - LIST of FREQUENCY RASTERS for USA and GERMANY

USA				
CHANNEL	FREQUENCY (MHz)			
2	55.25			
3	61.25			
4	67.25			
5	77.25			
6	83.25			
A2	109.25			
A1	115.25			
Α	121.25			
В	127.25			
С	133.25			
D	139.25			
E3	145.25			
F	151.25			
G	157.25			
н	163.25			
1.	169.25			
7	175.25			
8	181.25			
9	187.25			
10	193.25			
11	199.25			
12	205.25			
13	211.25			
J	217.25			
к	223.25			
L	229.25			
М	235.25			
N	241.25			
0	247.25			
P	253.25			
Q	259.25			
R	265.25			
S	271.25			
Т	277.25			

USA			
CHANNEL FREQUENCY (MHz)			
U	283.25		
V	289.25		
w	295.25		
X	301.25		
Υ	307.25		
z	313.25		
Н1	319.25		
H2	325.25		
Н3	331.25		
H4	337.25		
H5	343.25		
H6	349.25		
H7	355.25		
Н8	361.25		
H9	367.25		
H10	373.25		
H11	379.25		
H12	385.25		
H13	391.25		
H14	397.25		
H15	403.25		
H16	409.25		
H17	415.25		
H18	421.25		
H19	427.25		
H20	433.25		
H21	439.25		
H22	445.25		
H23	451.25		
H24	457.25		
H25	463.25		
14	469.25		
15	475.25		
16	481.25		

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#### APPENDIX D (continued)

USA		
CHANNEL	FREQUENCY (MHz)	
17	487.25	
18	493.25	
19	499.25	
20	505.25	
21	511.25	
22	517.25	
23	523.25	
24	529.25	
25	535.25	
26	541.25	
27	547.25	
28	553.25	
29	559.25	
30	565.25	
31	571.25	
32	577.25	
33	583.25	
34	589.25	
35	595.25	
36	601.25	
37	607.25	
38	461.25	
39	619.25	
40	625.25	
41	631.25	
42	637.25	
43	643.25	
44	649.25	
45	655.25	
46	661.25	
47	667.25	
48	673.25	
49	679.25	
50	685.25	
51	691.25	

	USA
CHANNEL	FREQUENCY (MHz)
52	697.25
53	703.25
54	709.25
55	715.25
56	721.25
57	727.25
58	733.25
59	739.25
60	745.25
61	751.25
62	757.25
63	763.25
64	769.25
65	775.25
66	781.25
67	787.25
68	793.25
69	799.25
70	805.25
71	811.25
72	817.25
73	823.25
74	829.25
75	835.25
76	841.25
77	847.25
78	853.25
79	859.25
80	865.25
81	871.25
82	877.25
83	883.25
84	889.25
85	895.25

February 1995 30

# General

#### APPENDIX D (continued)

CHANNEL         FREQUENCY (MHz           K2         48.25           K3         55.25
K3 55.25
K4 62.25
- 69.25
- 76.25
S2 112.25
S3 119.25
S4 126.25
S5 133.25
S6 140.25
S7 147.25
S8 154.25
S10 168.25
K5 175.25
K6 182.25
K7 189.25
K8 196.25
K9 203.25
K10 210.25
K11 217.25
K12 224.25
S11 231.25
S12 238.25
S13 245.25
S14 252.25

GERMANY			
CHANNEL	FREQUENCY (MHz)		
S15	259.25		
S16	266.25		
S17	273.25		
S18	280.25		
S19	287.25		
S20	294.25		
S21	303.25		
S22	311.25		
S23	319.25		
S24	327.25		
S25	335.25		
S26	343.25		
S27	351.25		
S28	259.25		
S29	367.25		
S30	375.25		
S31	383.25		
S32	391.25		
S33	399.25		
S34	407.25		
S35	415.25		
S36	423.25		
S37	431.25		
S38	439.25		
S39	445.25		

**APPENDIX E - TEST CHANNELS** 

Channels used during CTB,  $\mathbf{X}_{\mathrm{mod}}$  and CSO measurements

RANGE	NAMES	FREQUENCIES (MHz)	CHANNELS
40 - 300 MHz	2-4	55.25 - 67.25	3 channels
32 channels	5-6	77.25 - 83.25	2 channels
	A-2	109.25	1 channel
	A-F	121.25 - 151.25	6 channels
	H-S	163.25 - 271.25	19 channels
	W	295.25	1 channel
40 - 450 MHz	2-4	55.25 - 67.25	3 channels
52 channels	5-6	77.25 - 83.25	2 channels
	A-2	109.25	1 channel
	A-F	121.25 - 151.25	6 channels
	H-H14	163.25 - 397.25	40 channels
5 - 200 MHz	T7-T13	7.00 - 43.00	7 channels
22 channels	2-4	55.25 - 67.25	3 channels
	5-6	77.25 - 83.25	2 channels
	A-7	121.25 - 175.25	10 channels
40 - 450 MHz	2-4	55.25 - 67.25	3 channels
60 channels	5-6	77.25 - 83.25	2 channels
	A-H22	121.25 - 445.25	55 channels
40 - 550 MHz	2-4	55.25 - 67.25	3 channels
77 channels	5-6	77.25 - 83.25	2 channels
	A-27	121.25 - 547.25	77 channels
40 - 600 MHz	2-4	55.25 - 67.25	3 channels
85 channels	5-6	77.25 - 83.25	2 channels
	A-35	121.25 - 595.25	80 channels
40 - 750 MHz	2-4	55.25 - 67.25	3 channels
110 channels	5-6	77.25 - 83.25	2 channels
	A-60	121.25 - 745.25	105 channels
40 - 860 MHz	2-4	55.25 - 67.25	3 channels
129 channels	5-6	77.25 - 83.25	2 channels
	A-79	121.25 - 859.25	124 channels
40 - 450 MHz	2-3	55.25 - 61.25	2 channels
36 channels	C-F	133.25 - 151.25	4 channels
German raster	н	163.25	1 channel
	7	175.25	1 channel
	9	187.25	1 channel
	12	205.25	1 channel
	J	217.25	1 channel
	L-M	229.25 - 235.25	2 channels

# **CATV AMPLIFIER MODULES**

Device data (in alphanumeric sequence)

# **CATV** power doubler amplifier modules

**BGD102; BGD104** 

#### **FEATURES**

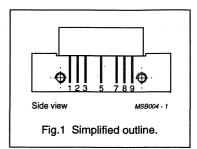
- Excellent linearity
- High output level
- · Silicon nitride passivation
- Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

#### **DESCRIPTION**

Power doubler amplifier modules for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of 24 V (DC).

#### **PINNING - SOT115C**

PIN	DESCRIPTION		
1	input		
2	common		
3	common		
5	+V <sub>B</sub>		
7	common		
8	common		
9	output		



#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz			
	BGD102		18	19	dB
	BGD104		19.5	20.5	dB
-	power gain	f = 450 MHz			
	BGD102		19.2	21.2	dB
	BGD104		20.5	22.5	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	_	435	mA

#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER		MAX.	UNIT
Vi	RF input voltage	_	60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

BGD102; BGD104

### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $V_B = 24 \text{ V}$ ;  $T_{mb} = 35 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz			
	BGD102		18	19	dB
	BGD104		19.5	20.5	dB
	power gain	f = 450 MHz			
	BGD102		19.2	21.2	dB
	BGD104		20.5	22.5	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	2.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	÷	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	-	20	dB
		f = 80 to 160 MHz		19	dB
		f = 160 to 450 MHz	-	18	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	<b> </b> -	20	dB
		f = 80 to 160 MHz	T-	19	dB
		f = 160 to 450 MHz	-	18	dB
S <sub>21</sub>	phase response	f = 50 MHz	+135	+225	deg-
СТВ	composite triple beat	60 channels flat;			
	BGD102	$V_0 = 46 \text{ dBmV};$	-	-65	dB
	BGD104	measured at 445.25 MHz	-	-64	dB
X <sub>mod</sub>	cross modulation	60 channels flat;			
	BGD102	$V_0 = 46 \text{ dBmV};$	-	-67	dB
	BGD104	measured at 55.25 MHz	-	-66	dB
d <sub>2</sub>	second order distortion	note 1	- * *	-73	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2		· [ · .	
	BGD102		65	-	dBmV
	BGD104		64.5	-	dBmV
F	noise figure	f = 40 to 450 MHz	-	7	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	-	435	mA

#### **Notes**

- 1.  $f_p = 55.25 \text{ MHz}$ ;  $V_o = 46 \text{ dBmV}$ ;  $f_q = 343.25 \text{ MHz}; V_q = 46 \text{ dBmV};$ measured at  $f_p + f_q = 398.5$  MHz.
- 2. Measured according to DIN45004B:
  - $f_p = 440.25 \text{ MHz}; V_p = V_o;$  $f_q = 447.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$

 $f_r = 449.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$ 

measured at  $f_p + f_q - f_r = 438.25 \text{ MHz}$ .

3. The modules normally operate at  $V_B = 24 \text{ V}$ , but are able to withstand supply transients up to 30 V.

**BGD106** 

#### **FEATURES**

- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

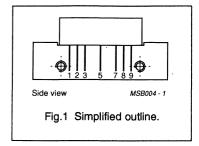
### **DESCRIPTION**

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of +24 V (DC).

#### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output

#### PIN CONFIGURATION



### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	21.5	22.5	dB
		f = 450 MHz	22.1	-	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V	_	435	mA

#### **LIMITING VALUES**

In accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	60	dBmV
T <sub>stg</sub>	storage temperature range	<del>-4</del> 0	+100	°C
T <sub>mb</sub>	mounting base operating temperature range	-20	+100	°C

**BGD106** 

#### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $T_{case}$  = 35 °C;  $Z_{S}$  =  $Z_{L}$  = 75  $\Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	21.5	22.5	dB
1.		f = 450 MHz	22.1	-	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0	2	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	± 0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz;	-	20	dB
		f = 80 to 160 MHz;	- 1	19	dB
		f = 160 to 450 MHz	_	18	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz;	-	20	dB
		f = 80 to 160 MHz;	-	19	dB
		f = 160 to 450 MHz	_	18	dB
СТВ	composite triple beat	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	-	-63	dB
X <sub>mod</sub>	cross modulation	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz		-63	dB
CSO	composite second order distortion	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 446.5 MHz	-	-59	dB
d <sub>2</sub>	second order distortion	V <sub>o</sub> = 46 dBmV note 1	-	-68	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2	66.5	_	dBmV
F	noise figure	f = 450 MHz	-	6.5	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3	_	435	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 391.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 446.5$  MHz
- 2. Measured according to DIN45004B;  $f_p = 440.25 \text{ MHz}; V_p = V_o = 66.5 \text{ dBmV}; f_q = 447.25 \text{ MHz}; V_q = V_o -6 \text{ dB}; f_r = 449.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$
- 3. The module normally operates at  $V_B = +24$  V, but is able to withstand supply transients up to +30 V.

**BGD108** 

### **FEATURES**

- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

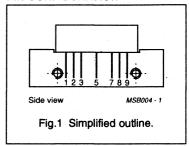
#### **DESCRIPTION**

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of +24 V (DC).

#### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output

### **PIN CONFIGURATION**



### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	35	37	dB
		f = 450 MHz	36.5	-	dB
I <sub>tot</sub>	total current consumption	DC value;	-	625	mA
		$V_B = +24 V$			

#### LIMITING VALUES

In accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage	-	55	dBmV
T <sub>stg</sub>	storage temperature range	-40	+100	°C
T <sub>mb</sub>	mounting base operating temperature range	-20	+100	°C

**BGD108** 

#### **CHARACTERISTICS**

 $T_{case} = 35 \, ^{\circ}C; Z_{S} = Z_{L} = 75 \, \Omega;$  Bandwidth 40 to 450 MHz;  $V_{B} = +24 \, V.$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	35	37	dB
		f = 450 MHz	36.5		dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.2	2.2	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	± 0.4	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz;	20	-	dB
		f = 80 to 160 MHz;	19	-	dB
	and the second second	f = 160 to 450 MHz	18	- / - / - / -	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz;	20	-	dB
		f = 80 to 160 MHz;	19	1 <b>-</b> 1 - 1 - 1 - 1	dB
		f = 160 to 450 MHz	18	-	dB
СТВ	composite triple beat	60 chs flat;	-	-64	dB
		V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz			
X <sub>mod</sub>	cross modulation	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	-	-65	dB
CSO	composite second order distortion	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 446.5 MHz	-	-62	dB
d <sub>2</sub>	second order distortion	note 1	_	-73	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2	67		dBmV
F	noise figure	f = 450 MHz	-	7	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3		625	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 391.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 446.5$  MHz
- 2.  $f_p = 440.25 \text{ MHz}; V_p = V_o;$   $f_q = 447.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$   $f_r = 449.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$  measured at  $f_p + f_q f_r = 438.25 \text{ MHz}.$
- 3. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

# BGD502; BGD504

#### **FEATURES**

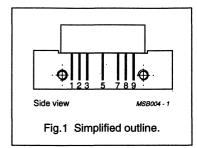
- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

#### **DESCRIPTION**

Hybrid amplifier modules for CATV systems operating over a frequency range of 40 to 550 MHz at a voltage supply of 24 V (DC).

#### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output



#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz			
	BGD502		18	19	dB
·	BGD504		19.5	20.5	dB
	power gain	f = 550 MHz			
	BGD502		18.8	20.8	dB
	BGD504		20.2	22.2	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	-	435	mA

### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

BGD502; BGD504

#### **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $V_B$  = 24 V;  $T_{mb}$  = 35 °C;  $Z_S$  =  $Z_L$  = 75  $\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz				
	BGD502		18		19	dB
	BGD504		19.5	-	20.5	dB
	power gain	f = 550 MHz				
	BGD502		18.8	-	20.8	dB
	BGD504		20.2		22.2	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	<del>-</del>	2.2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	1-	-	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	_	-	dB
		f = 80 to 160 MHz	19	-	_	dB
		f = 160 to 550 MHz	18	-	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	19	1-	-	dB
		f = 160 to 550 MHz	18	-	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	+135	-	+225	deg
СТВ	composite triple beat	77 channels flat;				
	BGD502	$V_0 = 44 \text{ dBmV};$	_		-65	dB
-	BGD504	measured at 547.25 MHz	_	-	-64	dB
X <sub>mod</sub>	cross modulation	77 channels flat;				
-	BGD502	$V_o = 44 \text{ dBmV};$	-	-	-68	dB
	BGD504	measured at 55.25 MHz		_	-67	dB
CSO	composite second order distortion	77 channels flat;				
	BGD502	$V_0 = 44 \text{ dBmV};$	-	- 1112	-62	dB
	BGD504	measured at 548.5 MHz	-	-	-60	dB
d <sub>2</sub>	second order distortion	note 1				
	BGD502			-	-72	dB
	BGD504		-	-	-70	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2				
	BGD502	,	64	-	-	dBmV
	BGD504		63.5	-	-	dBmV
F	noise figure	f = 550 MHz	1-	1-	8	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	1-	415	435	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 493.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 548.5$  MHz.
- 2. Measured according to DIN45004B:  $f_p = 540.25$  MHz;  $V_p = V_o$ ;  $f_q = 547.25$  MHz;  $V_q = V_o$  –6 dB;  $f_r = 549.25$  MHz;  $V_r = V_o$  –6 dB; measured at  $f_p + f_q f_r = 538.25$  MHz.
- 3. The modules normally operate at  $V_B = 24 \text{ V}$ , but are able to withstand supply transients up to 30 V.

BGD502; BGD504

### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $V_B$  = 24 V;  $T_{mb}$  = 35 °C;  $Z_S$  =  $Z_L$  = 75  $\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz				
	BGD502		19	-	20	dB
	BGD504		19.5	_ '	20.5	dB
	power gain	f = 450 MHz				
	BGD502		18.6	_	20.6	dB
	BGD504		20	_	22	dB
SL	slope cable equivalent	f = 40 to 450 MHz				
	BGD502		0.2		1.8	dB
	BGD504		0	1-	1.65	dB
FL	flatness of frequency response	f = 40 to 450 MHz	1-		±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	_	dB
		f = 80 to 160 MHz	19	-	_	dB
-		f = 160 to 450 MHz	18	-	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	_	dB
		f = 80 to 160 MHz	19	_		dB
		f = 160 to 450 MHz	18	-	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	+135	_	+225	deg
СТВ	composite triple beat	60 channels flat;				
	BGD502	$V_0 = 46 \text{ dBmV};$	-	_	-67	dB
	BGD504	measured at 445.25 MHz	_	-	-66	dB
CSO	composite second order distortion	60 channels flat;				
	BGD502	$V_0 = 46 \text{ dBmV};$	-	_	t.b.f.	dB
	BGD504	measured at 548.5 MHz	-	-	t.b.f.	dB
X <sub>mod</sub>	cross modulation	60 channels flat;				
	BGD502	$V_0 = 46 \text{ dBmV};$	-	-	-67	dB
	BGD504	measured at 55.25 MHz	_	_	-66	dB
$d_2$	second order distortion	note 1				
	BGD502		-	_	-75	dB
	BGD504		-	_	-73	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2				
	BGD502		67	_	_	dBmV
	BGD504		66.5	_	_	dBmV
F	noise figure	f = 450 MHz	1-	_	7	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	<b> </b> -	415	435	mA

BGD502; BGD504

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 391.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 446.5$  MHz.
- 2. Measured according to DIN45004B:  $f_p$  = 440.25 MHz;  $V_p$  =  $V_o$ ;  $f_q$  = 447.25 MHz;  $V_q$  =  $V_o$  –6 dB;  $f_r$  = 449.25 MHz;  $V_r$  =  $V_o$  –6 dB; measured at  $f_p$  +  $f_q$   $f_r$  = 438.25 MHz.
- 3. The modules normally operate at  $V_B = 24 \text{ V}$ , but are able to withstand supply transients up to 30 V.

**BGD506** 

#### **FEATURES**

- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

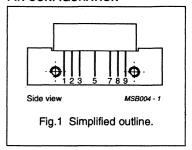
### **DESCRIPTION**

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 550 MHz at a voltage supply of +24 V (DC).

#### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output

#### PIN CONFIGURATION



### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	21.5	22.5	dB
		f = 550 MHz	22.1	-	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V	-	435	mA

### **LIMITING VALUES**

In accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage	-	60	dBmV
T <sub>stg</sub>	storage temperature range	<del>-4</del> 0	+100	°C
T <sub>mb</sub>	mounting base operating temperature range	-20	+100	°C
V <sub>B</sub>	DC supply voltage	_	+28	V

Philips Semiconductors Product specification

# CATV amplifier module

**BGD506** 

#### **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $T_{case}$  = 35 °C;  $Z_{S}$  =  $Z_{L}$  = 75  $\Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	21.5	22.5	dB
		f = 550 MHz	22.1	-	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	± 0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz;	_	20	dB
		f = 80 to 160 MHz;	_	19	dB
		f = 160 to 550 MHz	-	18	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz;	-	20	dB
		f = 80 to 160 MHz;	_	19	dB
		f = 160 to 550 MHz	-	18	dB
СТВ	composite triple beat	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz	<del>-</del>	<b>–62</b>	dB
X <sub>mod</sub>	cross modulation	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-63	dB
CSO	composite second order distortion	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz	-	-55	dB
d <sub>2</sub>	second order distortion	V <sub>o</sub> = 44 dBmV; note 1	-	66	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2	62.5		dBmV
F	noise figure	f = 550 MHz	-	7	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3	-	435	mA

#### Notes

1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 493.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 548.5$  MHz

2. Measured according to DIN45004B;

$$\begin{split} &f_p = 540.25 \text{ MHz; } V_o = V_p; \\ &f_q = 547.25 \text{ MHz; } V_q = V_o -6 \text{ dB;} \\ &f_r = 549.25 \text{ MHz; } V_r = V_o -6 \text{ dB;} \\ &\text{measured at } f_p + f_q - f_r = 538.25 \text{ MHz} \end{split}$$

 $V_0 = 62.5 \text{ dBmV}.$ 

3. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

**BGD508** 

### **FEATURES**

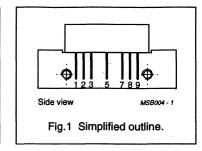
- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

#### DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 550 MHz at a voltage supply of 24 V (DC).

### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output



#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	35	37	dB
2		f = 550 MHz	36.5	-	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	_	625	mA

#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	55	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

**BGD508** 

### **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $V_B = 24$  V;  $T_{mb} = 35$  °C;  $Z_S = Z_L = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	35	37	dB
		f = 550 MHz	36.5	-	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	2.2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	- 1	±0.4	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 550 MHz	18	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	<u> </u> -	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 550 MHz	18	_	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz	_	-62	dB
X <sub>mod</sub>	cross modulation	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-65	dB
CSO	composite second order distortion	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz	-	-60	dB
d <sub>2</sub>	second order distortion	note 1	-	-70	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	63	1-	dBmV
F	noise figure	f = 550 MHz	-	7.5	dB
I <sub>tot</sub>	total current consumption (DC)	note 3		625	mA

#### **Notes**

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 393.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 548.5$  MHz.
- 2. Measured according to DIN45004B:

```
f_p = 440.25 \text{ MHz}; V_p = V_o;

f_q = 447.25 \text{ MHz}; V_q = V_o -6 \text{ dB};

f_r = 449.25 \text{ MHz}; V_r = V_o -6 \text{ dB};

measured at f_p + f_q - f_r = 438.25 \text{ MHz}.
```

3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

**BGD508** 

#### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $V_B = 24$  V;  $T_{mb} = 35$  °C;  $Z_S = Z_L = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	35	37	dB
		f = 450 MHz	36.5	-	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.2	2.2	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	±0.4	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 450 MHz	18	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	<b>1</b> -	dB
·		f = 160 to 450 MHz	18	_	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	_	-64	dB
X <sub>mod</sub>	cross modulation	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	-	-65	dB
CSO	composite second order distortion	60 channels flat; V <sub>o</sub> = 46 dBmV measured at 446.5 MHz	-	-62	dB
d <sub>2</sub>	second order distortion	note 1	-	-73	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	67	-	dBmV
F	noise figure	f = 450 MHz	-	7	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	_	625	mA

### **Notes**

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 391.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 446.5$  MHz.
- 2. Measured according to DIN45004B:

 $f_p = 440.25 \text{ MHz}; V_p = V_o;$   $f_q = 447.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$   $f_r = 449.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$ measured at  $f_p + f_q - f_r = 438.25 \text{ MHz}.$ 

3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

### **BGD601**

#### **FEATURES**

- · Excellent linearity
- Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

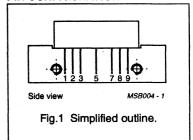
### **DESCRIPTION**

Hybrid high dynamic range amplifier module for CATV systems operating over a frequency range of 40 to 600 MHz at a voltage supply of +24 V (DC).

### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output

#### PIN CONFIGURATION



#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	12	13	dB
		f = 600 MHz	12.7	-	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V	-	435	mA

### **LIMITING VALUES**

In accordance with the Absolute Maximum System (IEC 134).

	SYMBOL	PARAMETER	MIN.	MAX.	UNIT
I	V <sub>i</sub>	RF input voltage	_	60	dBmV
Ì	T <sub>stg</sub>	storage temperature range	-40	+100	°C
-	T <sub>mb</sub>	mounting base operating temperature range	-20	+100	င္

**BGD601** 

#### **CHARACTERISTICS**

Bandwidth 40 to 600 MHz;  $T_{case} = 35$  °C;  $Z_S = Z_L = 75 \Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	12	13	dB
		f = 600 MHz	12.7	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.2	2.2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	_	± 0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz;	20	-	dB
		f = 80 to 160 MHz;	19	_	dB
		f = 160 to 600 MHz	18		dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz;	20	-	dB
		f = 80 to 160 MHz;	19	_	dB
		f = 160 to 600 MHz	18	-	dB
СТВ	composite triple beat	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 595.25 MHz	_	-62	dB
X <sub>mod</sub>	cross modulation	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	_	-66	dB
CSO	composite second order distortion	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 596.5 MHz	_	-60	dB
d <sub>2</sub>	second order distortion	note 1	_	-70	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2	63	-	dBmV
F	noise figure	f = 600 MHz	_	9.5	dB
l <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3	_	435	mA

- 1.  $f_p = 55.25 \text{ MHz}; V_p = 44 \text{ dBmV};$   $f_q = 541.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at  $f_p + f_q = 596.5 \text{ MHz}$
- 2.  $f_p = 590.25 \text{ MHz}$ ;  $V_p = V_o$ ;  $f_q = 597.25 \text{ MHz}$ ;  $V_q = V_o -6 \text{ dB}$ ;  $f_r = 599.25 \text{ MHz}$ ;  $V_r = V_o -6 \text{ dB}$ ; measured at  $f_p + f_q f_r = 588.25 \text{ MHz}$ .
- 3. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

**BGD601** 

#### **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $T_{case} = 35$  °C;  $Z_{S} = Z_{L} = 75 \Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	12	13	dB
		f = 550 MHz	12.5	14.5	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	± 0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz;	20	_	dB
		f = 80 to 160 MHz;	19	-	dB
		f = 160 to 550 MHz	18	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz;	20	-	dB
		f = 80 to 160 MHz;	19	_	dB
		f = 160 to 550 MHz	18	_	dB
СТВ	composite triple beat	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz	_	-65	dB
X <sub>mod</sub>	cross modulation	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz		-68	dB
CSO	composite second order distortion	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz	_	-64	dB
d <sub>2</sub>	second order distortion	note 1	-	-72	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2	64	-	dBmV
F	noise figure	f = 550 MHz	-	9	dB
l <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3	-	435	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 493.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 548.5$  MHz
- $\begin{array}{lll} \text{2.} & f_{p} = 540.25 \text{ MHz; } V_{p} = V_{o}; \\ f_{q} = 547.25 \text{ MHz; } V_{q} = V_{o} 6 \text{ dB;} \\ f_{r} = 549.25 \text{ MHz; } V_{r} = V_{o} 6 \text{ dB;} \\ \text{measured at } f_{p} + f_{q} f_{r} = 538.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

**BGD601** 

#### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $T_{case} = 35$  °C;  $Z_S = Z_L = 75 \Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	12	13	dB
		f = 450 MHz	12.5	-	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.2	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	± 0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz;	20	-	dB
		f = 80 to 160 MHz;	19	-	dB
		f = 160 to 450 MHz	18		dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz;	20	-	dB
		f = 80 to 160 MHz;	19	-	dB
		f = 160 to 450 MHz	18	-	dB
СТВ	composite triple beat	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	-	-67	dB
X <sub>mod</sub>	cross modulation	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	-	-67	dB
CSO	composite second order distortion	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 446.5 MHz	-	-65	dB
d <sub>2</sub>	second order distortion	note 1	. –	<b>-75</b>	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2	67	-	dBmV
F	noise figure	f = 450 MHz	-	8	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3	-	435	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 391.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 446.5$  MHz
- $\begin{array}{lll} \text{2.} & f_p = 440.25 \text{ MHz; } V_p = V_o; \\ f_q = 447.25 \text{ MHz; } V_q = V_o -6 \text{ dB;} \\ f_r = 449.25 \text{ MHz; } V_r = V_o -6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 438.25 \text{ MHz.} \\ \end{array}$
- 3. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

### **BGD602**

#### **FEATURES**

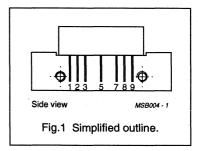
- Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

### **DESCRIPTION**

Hybrid high dynamic range amplifier module designed for applications in CATV systems with a bandwidth of 40 to 600 MHz operating with a voltage supply of 24 V (DC).

#### **PINNING - SOT115C**

PIN	DESCRIPTION					
1.	input					
2	common					
3	common					
5	+V <sub>B</sub>					
7	common					
8	common					
9	output					



### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	18	19	dB
		f = 600 MHz	19	-	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V		435	mA

#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER		MAX.	UNIT
Vi	RF input voltage	= 1000	60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

**BGD602** 

### **CHARACTERISTICS**

Bandwidth 40 to 600 MHz;  $V_B = 24$  V;  $T_{mb} = 35$  °C;  $Z_S = Z_L = 75$   $\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	18	19	dB
		f = 600 MHz	19	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.2	2.2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	Ī-,	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	]-	dB
		f = 80 to 160 MHz	19	1-	dB
		f = 160 to 600 MHz	18	1-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	1-	dB
		f = 80 to 160 MHz	19	1-	dB
	<ul> <li>A section of the sectio</li></ul>	f = 160 to 600 MHz	18	1-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 595.25 MHz	- 1 1 1	-62	dB
X <sub>mod</sub>	cross modulation	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz		-66	dB
CSO	composite second order distortion	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 596.5 MHz		-60	dB
d <sub>2</sub>	second order distortion	note 1	- 4	-70	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	63	-	dBmV
F	noise figure	f = 600 MHz		8	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	-	435	mA

#### Notes

- $\begin{array}{ll} \text{1.} & \text{f}_p = 55.25 \text{ MHz; V}_p = 44 \text{ dBmV;} \\ & \text{f}_q = 541.25 \text{ MHz; V}_q = 44 \text{ dBmV;} \\ & \text{measured at f}_p + \text{f}_q = 596.5 \text{ MHz.} \end{array}$
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 590.25 \text{ MHz; } V_p = V_o; \\ f_q &= 597.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 599.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 588.25 \text{ MHz.} \end{split}$$

3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

**BGD602** 

#### **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $V_B = 24$  V;  $T_{mb} = 35$  °C;  $Z_S = Z_L = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	18	19	dB
		f = 550 MHz	18.8	1-	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	2.2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	]=	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 550 MHz	18	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	T-	dB
		f = 160 to 550 MHz	18	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz	<b>-</b> ** . * * .	-66	dB
X <sub>mod</sub>	cross modulation	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	_	-68	dB
CSO	composite second order distortion	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz	- :	-62	dB
d <sub>2</sub>	second order distortion	note 1	- "	-72	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	64	-	dBmV
F	noise figure	f = 550 MHz	- 1	7.5	dB
I <sub>tot</sub>	total current consumption (DC)	note 3		435	mA

#### **Notes**

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 493.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 548.5$  MHz.
- 2. Measured according to DIN45004B:

 $f_p = 540.25 \text{ MHz}; V_p = V_o;$ 

 $f_q = 547.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$ 

 $f_r = 549.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$ 

measured at  $f_p + f_q - f_r = 538.25$  MHz.

3. The module normally operates at V<sub>B</sub> = 24 V, but is able to withstand supply transients up to 30 V.

**BGD602** 

#### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $V_B = 24 \text{ V}$ ;  $T_{mb} = 35 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 450 MHz	18.6	<u>-</u>	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.2	1.8	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	1-	dB
		f = 80 to 160 MHz	19	1-	dB
		f = 160 to 450 MHz	18	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	dB
V		f = 80 to 160 MHz	19	1-	dB
		f = 160 to 450 MHz	18	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	-	-67	dB
X <sub>mod</sub>	cross modulation	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	-	-66	dB
CSO	composite second order distortion	60 channels flat; V <sub>o</sub> = 46 dBmV measured at 446.5 MHz	-	-60	dB
d <sub>2</sub>	second order distortion	note 1		-75	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	67	-	dBmV
F	noise figure	f = 450 MHz	-	7	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	- 1	435	mA

#### **Notes**

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 391.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 446.5$  MHz.
- 2. Measured according to DIN45004B:

 $\begin{array}{l} f_p = 440.25 \text{ MHz; } V_p = V_o; \\ f_q = 447.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r = 449.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 438.25 \text{ MHz.} \end{array}$ 

3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

BGD602D

#### **FEATURES**

- Excellent linearity
- Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

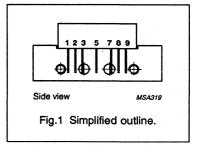
#### **DESCRIPTION**

Hybrid high dynamic range cascode amplifier module with darlington configuration for CATV systems operating over a frequency range of 40 to 600 MHz at a voltage supply of +24 V (DC).

#### **PINNING - SOT115J2**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output

### **PIN CONFIGURATION**



### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	17.5	18.5	dB
	*	f = 600 MHz	18.5	-	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V		440	mA.

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage	_	60	dBmV
T <sub>stg</sub>	storage temperature	<del>-4</del> 0	+100	°C
T <sub>mb</sub>	mounting base operating temperature	-20	+100	°C

BGD602D

### **CHARACTERISTICS**

Bandwidth 40 to 600 MHz;  $T_{case}$  = 35 °C;  $Z_{S}$  =  $Z_{L}$  = 75  $\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	17.5	18.5	dB
		f = 600 MHz	18.5	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.2	2.2	dB
FL	flatness of frequency response	f = 40 to 600 MHz		± 0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz;	20	. <del>-</del> **	dB
		f = 80 to 160 MHz;	19	_	dB
		f = 160 to 600 MHz	18	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz;	20	-	dB
		f = 80 to 160 MHz;	19	_	dB
		f = 160 to 600 MHz	18	_	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 595.25 MHz		-68	dB
X <sub>mod</sub>	cross modulation	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz		-61	dB
CSO	composite second order distortion	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 596.5 MHz	<del>-</del>	-64	dB
d <sub>2</sub>	second order distortion	note 1	-	-76	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	66	-	dBmV
F	noise figure	f = 600 MHz	-	7	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V note 3	-	440	mA

- $\begin{array}{ll} \text{1.} & f_{p} = 55.25 \text{ MHz; V}_{p} = 44 \text{ dBmV;} \\ f_{q} = 541.25 \text{ MHz; V}_{q} = 44 \text{ dBmV;} \\ \text{measured at } f_{p} + f_{q} = 596.5 \text{ MHz.} \end{array}$
- 2.  $f_p = 590.25 \text{ MHz}$ ;  $V_p = V_o$ ;  $f_q = 597.25 \text{ MHz}$ ;  $V_q = V_o 6 \text{ dB}$ ;  $f_r = 599.25 \text{ MHz}$ ;  $V_r = V_o 6 \text{ dB}$ ; measured at  $f_p + f_q f_r = 588.25 \text{ MHz}$ .
- 3. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

BGD602D

#### **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $T_{case} = 35$  °C;  $Z_S = Z_L = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	17.5	18.5	dB
		f = 550 MHz	18.3	-	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	2.2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	± 0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz;	20	_	dB
		f = 80 to 160 MHz;	19	_	dB
		f = 160 to 550 MHz	18	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz;	20	-	dB
		f = 80 to 160 MHz;	19	-	dB
		f = 160 to 550 MHz	18		dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz	-	-69	dB
X <sub>mod</sub>	cross modulation	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-62	dB
CSO	composite second order distortion	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz	-	-66	dB
d <sub>2</sub>	second order distortion	note 1	-	-78	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	67	-	dBmV
F	noise figure	f = 550 MHz	-	7	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V note 3	-	440	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 493.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 548.5$  MHz.
- 2.  $f_p = 540.25 \text{ MHz}; V_p = V_o;$   $f_q = 547.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$   $f_r = 549.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$ measured at  $f_p + f_q - f_r = 538.25 \text{ MHz}.$
- 3. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

BGD602D

#### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $T_{case}$  = 35 °C;  $Z_{S}$  =  $Z_{L}$  = 75  $\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	17.5	18.5	dB
		f = 450 MHz	18.1	-	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.2	1.8	dB
FL	flatness of frequency response	f = 40 to 450 MHz		± 0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz;	20	_	dB
		f = 80 to 160 MHz;	19	- '	dB
		f = 160 to 450 MHz	18	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz;	20	-	dB
		f = 80 to 160 MHz;	19	-	dB
		f = 160 to 450 MHz	18	_	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	-	-68	dB
X <sub>mod</sub>	cross modulation	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	_	-59	dB
CSO	composite second order distortion	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 446.5 MHz	-	-66	dB
d <sub>2</sub>	second order distortion	note 1	-	-80	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	67	-	dBmV
F	noise figure	f = 450 MHz	-	6.5	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V; note 3	_	440	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 391.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 446.5$  MHz.
- $\begin{array}{ll} \text{2.} & \text{f}_{\text{p}} = 440.25 \text{ MHz; V}_{\text{p}} = \text{V}_{\text{o}}; \\ \text{f}_{\text{q}} = 447.25 \text{ MHz; V}_{\text{q}} = \text{V}_{\text{o}} 6 \text{ dB;} \\ \text{f}_{\text{r}} = 449.25 \text{ MHz; V}_{\text{r}} = \text{V}_{\text{o}} 6 \text{ dB;} \\ \text{measured at f}_{\text{p}} + \text{f}_{\text{q}} \text{f}_{\text{r}} = 438.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

### **BGD702**

#### **FEATURES**

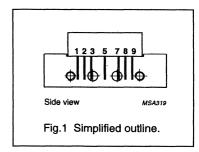
- Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

### **DESCRIPTION**

Hybrid amplifier module designed for CATV systems operating over a frequency range of 40 to 750 MHz at a voltage supply of 24 V (DC).

#### PINNING - SOT115J2

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output



### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	18	19	dB
		f = 750 MHz	18.5	-	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	-	435	mA

#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

**BGD702** 

#### **CHARACTERISTICS**

Bandwidth 40 to 750 MHz;  $V_B$  = 24 V;  $T_{mb}$  = 35 °C;  $Z_S$  =  $Z_L$  =75 $\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 750 MHz	18.5	<b> </b> -	dB
SL	slope cable equivalent	f = 40 to 750 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 750 MHz	-	±0.5	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	<b> </b> -	dB
		f = 80 to 160 MHz	18.5	1-	dB
		f = 160 to 320 MHz	17	T-	dB
		f = 320 to 640 MHz	15.5	T-	dB
		f = 640 to 750 MHz	14	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	T-	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	<b>-</b>	dB
		f = 640 to 750 MHz	14	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	110 channels flat; V <sub>o</sub> = 44 dBmV; measured at 745.25 MHz		-58	dB
X <sub>mod</sub>	cross modulation	110 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-62	dB
CSO	composite second order distortion	110 channels flat; $V_0 = 44 \text{ dBmV}$ ; measured at 746.5 MHz		-58	dB
d <sub>2</sub>	second order distortion	note 1	-	-68	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	61	-	dBmV
F	noise figure	f = 50 MHz	-	5.5	dB
		f = 750 MHz	_	9	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	_	435	mA

### Notes

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 691.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 746.5$  MHz.
- 2. Measured according to DIN45004B:

$$f_p = 740.25 \text{ MHz}; V_p = V_o;$$
  
 $f_q = 747.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$   
 $f_r = 749.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$   
measured at  $f_p + f_q - f_r = 738.25 \text{ MHz}.$ 

3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

**BGD702** 

#### **CHARACTERISTICS**

Bandwidth 40 to 600 MHz;  $V_B = 24 \text{ V}$ ;  $T_{mb} = 35 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 600 MHz	18.5	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	-	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 600 MHz	16	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	_	dB
·		f = 320 to 600 MHz	16	1-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 595.25 MHz	-	-65	dB
X <sub>mod</sub>	cross modulation	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	_	-65	dB
CSO	composite second order distortion	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 596.5 MHz	_	-60	dB
d <sub>2</sub>	second order distortion	note 1	_	-70	dB
Vo	output voltage	$d_{im} = -60 \text{ dB}$ ; note 2	64	[-	dBmV
F	noise figure	f = 50 MHz	-	5.5	dB
		f = 600 MHz	1-	8	dB
I <sub>tot</sub>	total current consumption (DC)	note 3		435	mA

- 1.  $f_p = 55.25 \text{ MHz}$ ;  $V_p = 44 \text{ dBmV}$ ;  $f_q = 541.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at  $f_p + f_q = 596.5$  MHz.
- 2. Measured according to DIN45004B:
  - $$\begin{split} f_p &= 590.25 \text{ MHz; } V_p = V_o; \\ f_q &= 597.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \end{split}$$

  - $f_r = 599.25 \text{ MHz}; V_r = V_o 6 \text{ dB};$
  - measured at  $f_p + f_q f_r = 588.25$  MHz.
- 3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

**BGD702** 

#### **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $V_B = 24 \text{ V}$ ;  $T_{mb} = 35 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 550 MHz	18.5	-	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 550 MHz	16	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	dB
4 4		f = 80 to 160 MHz	18.5	_	dB
-		f = 160 to 320 MHz	17	-	dB
		f = 320 to 550 MHz	16	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz		-67	dB
X <sub>mod</sub>	cross modulation	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-67	dB
cso	composite second order distortion	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz	-	<del>-</del> 62	dB
d <sub>2</sub>	second order distortion	note 1	T-	-72	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	64.5	]-	dBmV
F	noise figure	f = 50 MHz	-	5.5	dB
		f = 550 MHz	_	7.5	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	1-	435	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 493.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 548.5$  MHz.
- 2. Measured according to DIN45004B:
  - $f_p = 540.25 \text{ MHz}; V_p = V_o;$
  - $f_q = 547.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$
  - $f_r = 549.25 \text{ MHz}; V_r = V_o 6 \text{ dB};$
  - measured at  $f_p + f_q f_r = 538.25$  MHz.
- 3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

**BGD702** 

#### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $V_B = 24 \text{ V}$ ;  $T_{mb} = 35 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	18	19	dB
		f = 450 MHz	18.5	-	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.2	2	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	<b> </b> -	dB
		f = 80 to 160 MHz	18.5		dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 450 MHz	16	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	1-	dB
		f = 320 to 450 MHz	16	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	_	-68	dB
X <sub>mod</sub>	cross modulation	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	-	-65	dB
cso	composite second order distortion	60 channels flat; V <sub>o</sub> = 46 dBmV measured at 446.5 MHz	-	-65	dB
$d_2$	second order distortion	note 1	_	-75	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	67	-	dBmV
F	noise figure	f = 50 MHz		5.5	dB
		f = 450 MHz	-	7	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	<b>-</b> -	435	mA

#### **Notes**

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 391.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 446.5$  MHz.
- 2. Measured according to DIN45004B:

 $f_p = 440.25 \text{ MHz}; V_p = V_o;$ 

 $f_q = 447.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$ 

 $f_r = 449.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$ 

measured at  $f_p + f_q - f_r = 438.25$  MHz.

3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

**BGD704** 

#### **FEATURES**

- Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

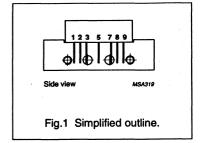
#### **DESCRIPTION**

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 750 MHz at a voltage supply of +24 V (DC).

#### **PINNING - SOT115J2**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output

#### **PIN CONFIGURATION**



#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	19.5	20.5	dB
		f = 750 MHz	20	_	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V	-	435	mA

#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage	_	60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	mounting base operating temperature	-20	+100	°C

**BGD704** 

#### **CHARACTERISTICS**

Bandwidth 40 to 750 MHz;  $T_{\text{case}}$  = 35 °C;  $Z_{\text{S}}$  =  $Z_{\text{L}}$  = 75  $\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	19.5	20.5	dB
		f = 750 MHz	20	-	dB
SL	slope cable equivalent	f = 40 to 750 MHz	0	2	dB
FL	flatness of frequency response	f = 40 to 750 MHz	-	±0.5	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	_	dB
		f = 640 to 750 MHz	14	- L	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5		dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	1-	dB
		f = 640 to 750 MHz	14	_	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	110 chs flat; V <sub>o</sub> = 44 dBmV; measured at 745.25 MHz	-	-57	dB
X <sub>mod</sub>	cross modulation	110 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	_	-61	dB
CSO	composite second order distortion	110 chs flat; V <sub>o</sub> = 44 dBmV; measured at 746.5 MHz	-	-56	dB
d <sub>2</sub>	second order distortion	note 1	_	-66	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	60.5	1-	dBmV
F	noise figure	f = 50 MHz	<b>-</b>	5.5	dB
		f = 750 MHz	-	9	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V; note 3	-	435	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 691.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 746.5$  MHz.
- $\begin{array}{ll} \text{2.} & f_{p} = 740.25 \text{ MHz; } V_{p} = V_{o}; \\ f_{q} = 747.25 \text{ MHz; } V_{q} = V_{o} 6 \text{ dB;} \\ f_{r} = 749.25 \text{ MHz; } V_{r} = V_{o} 6 \text{ dB;} \\ \text{measured at } f_{p} + f_{q} f_{r} = 738.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at  $V_B = +24 \text{ V}$  but is able to withstand supply transients up to 30 V.

**BGD704** 

#### **CHARACTERISTICS**

Bandwidth 40 to 600 MHz;  $T_{case} = 35 \,^{\circ}\text{C}$ ;  $Z_{s} = Z_{L} = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	19.5	20.5	dB
,		f = 600 MHz	20	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0	2	dB
FL	flatness of frequency response	f = 40 to 600 MHz		±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	1-	dB
		f = 320 to 600 MHz	16	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	- : ;	dB
		f = 80 to 160 MHz	18.5		dB
		f = 160 to 600 MHz	17	-	dB
		f = 320 to 600 MHz	16	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 595.25 MHz	-	-64	dB
X <sub>mod</sub>	cross modulation	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-64	dB
CSO	composite second order distortion	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 596.5 MHz	-	-58	dB
d <sub>2</sub>	second order distortion	note 1	-	-68	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	63		dBmV
F	noise figure	f = 50 MHz	-	5.5	dB
		f = 600 MHz	_	8	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V; note 3	-	435	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 541.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 596.5$  MHz.
- 2.  $f_p = 590.25 \text{ MHz}$ ;  $V_p = V_o$ ;  $f_q = 597.25 \text{ MHz}$ ;  $V_q = V_o 6 \text{ dB}$ ;  $f_r = 599.25 \text{ MHz}$ ;  $V_r = V_o 6 \text{ dB}$ ; measured at  $f_p + f_q f_r = 588.25 \text{ MHz}$ .
- 3. The module normally operates at  $V_B = +24 \text{ V}$  but is able to withstand supply transients up to 30 V.

**BGD704** 

#### **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $T_{case} = 35$  °C;  $Z_S = Z_L = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	19.5	20.5	dB
		f = 550 MHz	20	_	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 550 MHz	16	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 550 MHz	16	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz	_	-66	dB
X <sub>mod</sub>	cross modulation	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	_	-66	dB
CSO	composite second order distortion	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz		-60	dB
d <sub>2</sub>	second order distortion	note 1	-	-70	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	63.5		dBmV
F	noise figure	f = 50 MHz	<b>-</b>	5.5	dB
		f = 550 MHz	_	7.5	dB
l <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V; note 3	_	435	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 493.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 548.5$  MHz.
- 2.  $f_p = 540.25$  MHz;  $V_p = V_o$ ;  $f_q = 547.25$  MHz;  $V_q = V_o 6$  dB;  $f_r = 549.25$  MHz;  $V_r = V_o 6$  dB; measured at  $f_p + f_q f_r = 538.25$  MHz.
- 3. The module normally operates at  $V_B = +24 \text{ V}$  but is able to withstand supply transients up to 30 V.

**BGD704** 

#### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $T_{case} = 35$  °C;  $Z_{s} = Z_{L} = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	19.5	20.5	dB
		f = 450 MHz	20	_	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0	2	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_ ''	dB
		f = 160 to 320 MHz	17	- A	dB
		f = 320 to 450 MHz	16	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	<b>-</b> , , , , , .	dB
		f = 160 to 320 MHz	17	<b>-</b>	dB
		f = 320 to 450 MHz	16	_	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	_	-67	dB
X <sub>mod</sub>	cross modulation	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	-	-64	dB
CSO	composite second order distortion	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 446.5 MHz	_	-63	dB
d <sub>2</sub>	second order distortion	note 1	<b>-</b>	-73	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	66	_	dBmV
F	noise figure	f = 50 MHz	-	5.5	dB
		f = 450 MHz	_	7	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V; note 3	-	435	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 391.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 446.5$  MHz.
- 2.  $f_p = 440.25$  MHz;  $V_p = V_o$ ;  $f_q = 447.25$  MHz;  $V_q = V_o 6$  dB;  $f_r = 449.25$  MHz;  $V_r = V_o 6$  dB; measured at  $f_p + f_q f_r = 438.25$  MHz.
- 3. The module normally operates at  $V_B = +24 \text{ V}$  but is able to withstand supply transients up to 30 V.

## **BGD885**

### **FEATURES**

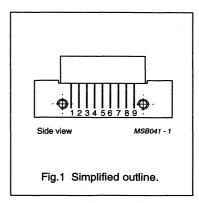
- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

### **DESCRIPTION**

Hybrid amplifier module for CATV/MATV systems operating over a frequency range of 40 to 860 MHz at a voltage supply of 24 V (DC).

#### **PINNING - SOT115D**

PIN	DESCRIPTION
1	input
2	common
3	common
4	10 V, 200 mA supply terminal
5	common
6	common
7	common
8	+V <sub>B</sub>
9	output



#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	16.5	17.5	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	_	450	mA ·

#### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>B</sub>	DC supply voltage	]-	26	V
Vi	RF input voltage		60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

**BGD885** 

### **CHARACTERISTICS**

Bandwidth 40 to 860 MHz;  $V_B = 24 \text{ V}$ ;  $T_{mb} = 35 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	16.5	17.5	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.2	1.6	dB
FL	flatness of frequency response	f = 40 to 860 MHz	-	±0.5	dB
S <sub>11</sub>	input return losses	f = 40 MHz; note 1	20	-	dB
	Approximately and the second s	f = 800 to 860 MHz	10	-	dB
S <sub>22</sub>	output return losses	f = 40 MHz; note 1	20	-	dB
		f = 800 to 860 MHz	10	-	dB
d <sub>2</sub>	second order distortion	note 2	-	-53	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 3	64	-	dBmV
		$d_{im} = -60 \text{ dB}$ ; note 4	63	-	dBmV
F	noise figure	f = 860 MHz	-	8	dB
I <sub>tot</sub>	total current consumption (DC)	note 5	_	450	mA

#### **Notes**

- 1. Decrease per octave of 1.5 dB.
- 2.  $V_p = 59 \text{ dBmV at } f_p = 349.25 \text{ MHz};$   $V_q = 59 \text{ dBmV at } f_q = 403.25 \text{ MHz};$ measured at  $f_p + f_q = 752.5 \text{ MHz}.$
- 3. Measured according to DIN45004B:

$$\begin{split} f_p &= 341.25 \text{ MHz; } V_p = V_o; \\ f_q &= 348.25 \text{ MHz; } V_q = V_o -6 \text{ dB;} \\ f_r &= 350.25 \text{ MHz; } V_r = V_o -6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 339.25 \text{ MHz.} \end{split}$$

4. Measured according to DIN45004B:

```
f_p = 851.25 \text{ MHz}; V_p = V_o;

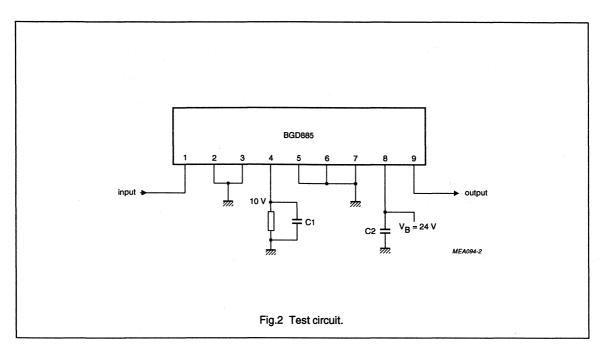
f_q = 858.25 \text{ MHz}; V_q = V_o -6 \text{ dB};

f_r = 860.25 \text{ MHz}; V_r = V_o -6 \text{ dB};

measured at f_p + f_q - f_r = 849.25 \text{ MHz}.
```

5. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

**BGD885** 



## List of components (see Fig.2)

COMPONENT	DESCRIPTION	VALUE
C1	ceramic multilayer capacitor	1 nF (max.)
C2	ceramic multilayer capacitor	1 nF
R	resistor	56 Ω, 2 W

## **BGE85A**

#### **FEATURES**

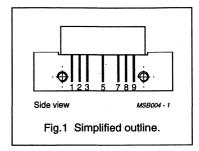
- Excellent linearity
- Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

#### **DESCRIPTION**

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of (DC). It is intended for use as an 18.5 dB output amplifier module.

### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
. 2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output



#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	17.4	_	19.4	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	_	200	230	mA

#### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	ç
T <sub>mb</sub>	operating mounting base temperature	20	+100	ပ <del>ွ</del>

BGE85A

#### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $V_B = 24$  V;  $T_{mb} = 30$  °C;  $Z_S = Z_L = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	17.4	1-	19.4	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.3	-	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-	_	±0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	_	-	dB
		f = 80 to 160 MHz	18.5	_	-	dB
		f = 160 to 320 MHz	17	_	-	dB
		f = 320 to 450 MHz	15.5	-	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	1-	dB
		f = 80 to 160 MHz	18.5	-	-	dB
		f = 160 to 320 MHz	17	-	-	dB
		f = 320 to 450 MHz	15.5	1-	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	-	+45	deg
d <sub>2</sub>	second order distortion	V <sub>o</sub> = -46 dB; note 1	-	-	-72	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	60.5	1-	-	dBmV
F	noise figure	f = 40 to 450 MHz	1-	-	7	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	-	200	230	mA

## Notes

- 1.  $f_p = 55.25$  MHz;  $V_o = 46$  dBmV;  $f_q = 391.25$  MHz;  $V_o = 46$  dBmV; measured at  $f_p + f_q = 446.5$  MHz.
- 2. Measured according to DIN45004B:

$$\begin{aligned} f_p &= 440.25 \text{ MHz; } V_p = V_o; \\ f_q &= 447.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 449.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 438.25 \text{ MHz.} \end{aligned}$$

3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

## **BGE88;BGE88/01**

### **FEATURES**

- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Optimal reliability ensured by TiPtAu metallized crystals.

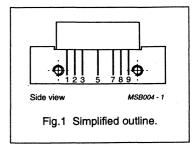
### **DESCRIPTION**

Low cost hybrid amplifier modules for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of +24 V (DC).

### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
- 5	+V <sub>B</sub>
7	common
8	common
9	output

#### **PIN CONFIGURATION**



### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	33	_	36	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V				
	BGE88		-	290	330	mA
	BGE88/01		-	250	260	mA

## LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	60	dBmV
T <sub>stg</sub>	storage temperature range	-40	+100	°C
T <sub>case</sub>	operating case temperature range	-20	+100	ô

BGE88;BGE88/01

### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $T_{case} = 30 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	33	-	36	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	-	2.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-	_	0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20		-	dB
		f = 80 to 160 MHz	18.5	-	_	dB
		f = 160 to 320 MHz	17			dB
		f = 320 to 450 MHz	15.5	-	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	1-	-	dB
		f = 80 to 160 MHz	18.5	-	_	dB
		f = 160 to 320 MHz	17	-	_	dB
		f = 320 to 450 MHz	15.5	_	_	dB
d <sub>2</sub>	second order distortion	note 1	_	-	-70	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2	-			
	BGE88		60	_	_	dBmV
	BGE88/01		59		_	dBmV
F	noise figure	f = 450 MHz		1-	6	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3				
	BGE88		·	290	330	mA
	BGE88/01		_	250	260	mA

#### Notes

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 343.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 398.5$  MHz
- 2.  $f_p = 440.25 \text{ MHz}$ ;  $V_p = V_o$ ;  $f_q = 447.25 \text{ MHz}$ ;  $V_q = V_o 6 \text{ dB}$ ;  $f_r = 449.25 \text{ MHz}$ ;  $V_r = V_o 6 \text{ dB}$ ; measured at  $f_p + f_q f_r = 438.25 \text{ MHz}$ .
- 3. The modules normally operate at  $V_B = +24 \text{ V}$ , but are able to withstand supply transients up to 30 V.

## **BGE884**

#### **FEATURES**

- · Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

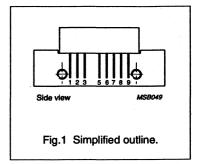
## **DESCRIPTION**

Hybrid amplifier module for CATV/MATV systems operating over a frequency range of 40 to 860 MHz at a voltage supply of +24 V (DC).

#### PINNING - SOT115G2

PIN	DESCRIPTION
1	input
2	common
3	common
5	common
6	common
7	common
- 8	+V <sub>B</sub>
9	output

#### **PIN CONFIGURATION**



### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	16.5	17.5	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V	-	150	mA

#### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage	-	60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	<b>℃</b>
T <sub>mb</sub>	mounting base operating temperature	-20	+100	°C
V <sub>B</sub>	DC supply voltage	-	26	٧

**BGE884** 

### **CHARACTERISTICS**

Bandwidth 40 to 860 MHz;  $T_{mb} = 30$  °C;  $Z_S = Z_L = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	16.5	17.5	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.2	1.4	dB
FL	flatness of frequency response	f = 40 to 860 MHz	-	± 0.3	dB
S <sub>11</sub>	input return losses	f = 40 MHz; note 1	20	-	dB
		f = 800 to 860 MHz	10		dB
S <sub>22</sub>	output return losses	f = 40 to 860 MHz	15	<b> -</b>	dB
d <sub>2</sub>	second order distortion	note 2	-	-60	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; notes 3 and 4	55	-	dBmV
F	noise figure	f = 350 MHz	-	7.5	dB
		f = 860 MHz	·	8	dB
l <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V; note 5	-	150	mA

#### Notes

- 1. Decreases by 1.5 dB per octave.
- 2.  $f_p = 349.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 403.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 752.5$  MHz.
- 3.  $f_p = 341.25 \text{ MHz; } V_p = V_o;$   $f_q = 348.25 \text{ MHz; } V_q = V_o -6 \text{ dB;}$   $f_r = 350.25 \text{ MHz; } V_r = V_o -6 \text{ dB;}$ measured at  $f_p + f_q - f_r = 339.25 \text{ MHz.}$
- $\begin{array}{ll} \text{4.} & \text{f}_{\text{p}} = 851.25 \text{ MHz; } \text{V}_{\text{p}} = \text{V}_{\text{o}}; \\ & \text{f}_{\text{q}} = 858.25 \text{ MHz; } \text{V}_{\text{q}} = \text{V}_{\text{o}} 6 \text{ dB;} \\ & \text{f}_{\text{r}} = 860.25 \text{ MHz; } \text{V}_{\text{r}} = \text{V}_{\text{o}} 6 \text{ dB;} \\ & \text{measured at f}_{\text{p}} + \text{f}_{\text{q}} \text{f}_{\text{r}} = 849.25 \text{ MHz.} \end{array}$
- 5. The module normally operates at  $V_B = 24 \text{ V}$  but is able to withstand supply transients up to 30 V.

**BGE885** 

#### **FEATURES**

- · Excellent linearity
- · Extremely low noise
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

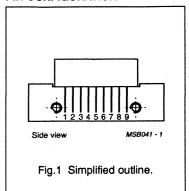
#### **DESCRIPTION**

Hybrid amplifier module intended for use in CATV systems operating over a frequency range of 40 to 860 MHz at a voltage supply of +24 V (DC).

#### **PINNING - SOT115D**

PIN	DESCRIPTION
1	input (note 1)
2	common
3	common
4	12 V - 60 mA supply terminal
5	common
6	common
7	common
8	+V <sub>B</sub>
9	output (note 1)

#### PIN CONFIGURATION



#### Note

1. Pins 1 and 9 carry DC voltages.

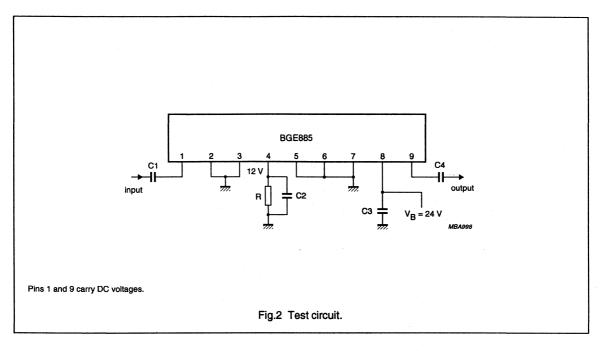
#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	16.5	17.5	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V	-	240	mA

#### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage	-	60	dBmV
T <sub>stg</sub>	storage temperature range	<del>-4</del> 0	+100	°C
T <sub>mb</sub>	mounting base operating temperature range	-20	+100	°C
V <sub>B</sub>	DC supply voltage	_	+28	V

**BGE885** 



## List of components (see Fig.2)

COMPONENT	DESCRIPTION	VALUE
C1, C3, C4	ceramic multilayer capacitor	1 nF
C2	ceramic multilayer capacitor	1 nF (max.)
R	resistor	200 Ω, 1 W

**BGE885** 

#### **CHARACTERISTICS**

 $T_{mb}$  = 30 °C;  $Z_{S}$  =  $Z_{L}$  = 75  $\Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	16.5	17.5	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.2	1.2	dB
FL	flatness of frequency response	f = 40 to 860 MHz	-	± 0.5	dB
S <sub>11</sub>	input return losses	f = 40 to 450 MHz	_	14	dB
		f = 450 to 860 MHz	_	10	dB
S <sub>22</sub>	output return losses	f = 40 to 450 MHz	_	14	dB
		f = 450 to 860 MHz	_	10	dB
d <sub>2</sub>	second order distortion	note 1	-	-53	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2		59	dBmV
F	noise figure	f = 350 MHz; f = 860 MHz	_	7.5 8	dB dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3	_	240	mA

#### **Notes**

- 1.  $V_p = 59 \text{ dBmV}$  at  $f_p = 349.25 \text{ MHz}$ ;  $V_p = 59 \text{ dBmV}$  at  $f_p = 403.25 \text{ MHz}$ ; measured at  $f_p + f_q = 752.25 \text{ MHz}$ .
- 2. Measured according to DIN45004B;  $\begin{array}{l} f_p = 851.25 \text{ MHz; } V_p = V_o = 59.0 \text{ dBmV;} \\ f_q = 858.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ f_r = 860.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 849.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

**BGE887** 

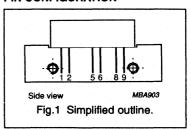
#### **FEATURES**

- Excellent linearity
- Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

#### **PINNING - SOT115H**

PIN	DESCRIPTION		
1	input		
2	common		
5	+V <sub>B</sub>		
6	common		
8	common		
9	output		

#### PIN CONFIGURATION



#### DESCRIPTION

Hybrid amplifier module intended for use in the UHF part of VHF/UHF split-band CATV systems over a frequency range of 470 to 860 MHz with a voltage supply of +24 V (DC).

### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 470 MHz;	22.5	25	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 1	-	280	mA

#### Note

1. The module normally operates at  $V_B = +24$  V, but is able to withstand supply transients up to +30 V.

#### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage	_	60	dBmV
T <sub>stg</sub>	storage temperature range	-40	+100	°C
T <sub>mb</sub>	mounting base operating temperature range	-20	+100	°C
V <sub>B</sub>	DC supply voltage	_	+28	V

**BGE887** 

#### **CHARACTERISTICS**

 $T_{case} = 30 \,^{\circ}C; Z_{S} = Z_{L} = 75 \,\Omega;$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 470 MHz;	22.5	25	dB
SL	slope cable equivalent	f = 470 to 860 MHz	-0.2	+1	dB
FL	flatness of frequency response	f = 470 to 860 MHz	-	±0.3	dB
S <sub>11</sub>	input return losses	f = 470 to 860 MHz;	12	-	dB
S <sub>22</sub>	output return losses	f = 470 to 860 MHz;	17	_	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 1	60.5	_	dBmV
		d <sub>im</sub> = -60 dB note 2	60.5		dBmV
F	noise figure	f = 470 MHz; f = 860 MHz	_	8 8.5	dB dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3		280	mA

#### Notes

- 1.  $f_p = 483.25 \text{ MHz}$ ;  $V_p = V_o$   $f_q = 490.25 \text{ MHz}$ ;  $V_q = V_o -6 \text{ dB}$   $f_r = 492.25 \text{ MHz}$ ;  $V_r = V_o -6 \text{ dB}$ measured at  $f_p + f_q - f_r = 481.25 \text{ MHz}$
- $\begin{array}{lll} 2. & f_p = 851.25 \text{ MHz; V}_p = \text{ V}_o; \\ f_q = 858.25 \text{ MHz; V}_q = \text{ V}_o 6 \text{ dB;} \\ f_r = 860.25 \text{ MHz; V}_r = \text{ V}_o 6 \text{ dB;} \\ \text{measured at f}_p + f_q f_r = 849.25 \text{ MHz.} \\ \end{array}$
- 3. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

**BGX881** 

### **FEATURES**

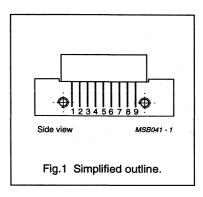
- Excellent linearity
- Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

#### **DESCRIPTION**

Hybrid amplifier module for CATV/MATV systems operating over a frequency range of 40 to 860 MHz at a voltage supply of 24 V (DC).

#### **PINNING - SOT115D**

PIN	DESCRIPTION
1	input; note1
2	common
3	common
4	12 V, 60 mA supply terminal
5	common
6	common
7	common
8	+V <sub>B</sub>
9	output; note1



#### Note

1. Pins 1 and 9 carry DC voltages.

#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	12	13	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	_	240	mA

## **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>B</sub>	DC supply voltage		26	٧
Vi	RF input voltage	-	60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

**BGX881** 

#### **CHARACTERISTICS**

Bandwidth 40 to 860 MHz;  $V_B = 24 \text{ V}$ ;  $T_{mb} = 30 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	12	13	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.2	1.4	dB
FL	flatness of frequency response	f = 40 to 860 MHz		±0.3	dB
S <sub>11</sub>	input return losses	f = 40 MHz; note 1	20	_	dB
	The second secon	f = 800 to 860 MHz	10	-	dB
S <sub>22</sub>	output return losses	f = 40 MHz; note 1	20	-	dB
		f = 640 to 860 MHz	15	-	dB
d <sub>2</sub>	second order distortion	note 2		-53	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 3	60.5	-	dBmV
	*	$d_{im} = -60 \text{ dB}$ ; note 4	59.5	-	dBmV
F	noise figure	f = 350 MHz	_	8.5	dB
		f = 860 MHz	_	9	dB
I <sub>tot</sub>	total current consumption (DC)	note 5	_	240	mA

#### **Notes**

- 1. Decreases 1.5 dB per octave.
- 2.  $f_p = 349.25$  MHz;  $V_p = 59$  dBmV;  $f_q = 403.25$  MHz;  $V_q = 59$  dBmV; measured at  $f_p + f_q = 752.5$  MHz.
- 3. Measured according to DIN45004B:

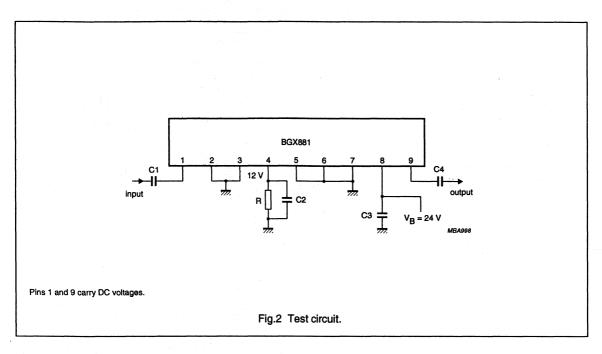
```
\begin{array}{l} f_p = 341.25 \text{ MHz; } V_p = V_o; \\ f_q = 348.25 \text{ MHz; } V_q = V_o -6 \text{ dB;} \\ f_r = 350.25 \text{ MHz; } V_r = V_o -6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 339.25 \text{ MHz.} \end{array}
```

4. Measured according to DIN45004B:

```
\begin{array}{lll} f_p = 851.25 \text{ MHz; } V_p = V_o; \\ f_q = 858.25 \text{ MHz; } V_q = V_o -6 \text{ dB;} \\ f_r = 860.25 \text{ MHz; } V_r = V_o -6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 849.25 \text{ MHz.} \end{array}
```

5. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

**BGX881** 



## List of components (see Fig.2)

COMPONENT	DESCRIPTION	VALUE
C1, C3, C4	ceramic multilayer capacitor	1 nF
C2	ceramic multilayer capacitor	1 nF (max.)
R	resistor	200 Ω, 1 W

## **BGX885N**

### **FEATURES**

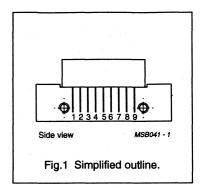
- Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

#### DESCRIPTION

Hybrid amplifier module for CATV/MATV systems operating over a frequency range of 40 to 860 MHz at a voltage supply of 24 V (DC).

### **PINNING - SOT115D**

PIN	DESCRIPTION		
1	input; note 1		
2	common		
3	common		
4	60 mA supply terminal		
5	common		
6	common		
7	common		
8	+V <sub>B</sub>		
9	output; note 1		



#### Note

1. Pins 1 and 9 carry DC voltages.

### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	16.5	17.5	dB
		f = 750 MHz	17.3	-	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	-	240	mA

### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>B</sub>	DC supply voltage	-	26	٧
Vi	RF input voltage	-	60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

BGX885N

#### **CHARACTERISTICS**

Bandwidth 40 to 860 MHz;  $V_B = 24 \text{ V}$ ;  $T_{mb} = 30 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	16.5	17.5	dB
		f = 750 MHz	17.3	<u>-</u>	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.2	1.4	dB
FL	flatness of frequency response	f = 40 to 860 MHz	-	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 MHz; note 1	20	-	dB
		f = 800 to 860 MHz	10	_	dB
S <sub>22</sub>	output return losses	f = 40 MHz; note 1	20	_	dB
e e e		f = 640 to 860 MHz	15	_	dB
d <sub>2</sub>	second order distortion	note 2		-53	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 3	61	_	dBmV
		d <sub>im</sub> = -60 dB; note 4	60	_	dBmV
F	noise figure	f = 350 MHz	-	7.5	dB
		f = 860 MHz		8	dB
I <sub>tot</sub>	total current consumption (DC)	note 5	_	240	mA

#### Notes

- 1. Decreases by 1.5 dB per octave.
- 2.  $f_p = 349.25 \text{ MHz}$ ;  $V_p = V_o = 59 \text{ dBmV}$ ;

 $f_q = 403.25 \text{ MHz}; V_q = V_o;$ measured at  $f_p + f_q = 752.5 \text{ MHz}$ .

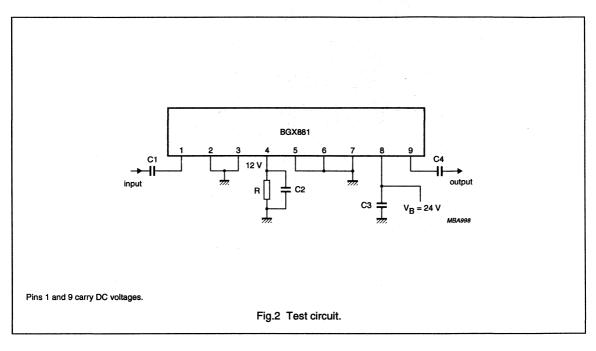
- 3. Measured according to DIN45004B:
  - $\begin{array}{l} f_p \ = \ 341.25 \ \text{MHz}; \ V_p \ = \ V_o; \\ f_q \ = \ 348.25 \ \text{MHz}; \ V_q \ = \ V_o \ -6 \ \text{dB}; \end{array}$

  - $f_r = 350.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$

measured at  $f_p + f_q - f_r = 339.25$  MHz.

- 4. Measured according to DIN45004B:
  - $f_p = 851.25 \text{ MHz}; V_p = V_o;$
  - $f_q = 858.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$
  - $f_r = 860.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$
  - measured at  $f_p + f_q f_r = 849.25$  MHz.
- 5. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

**BGX885N** 



## List of components (see Fig.2)

COMPONENT	DESCRIPTION	VALUE
C1, C3, C4	ceramic multilayer capacitor	1 nF
C2	ceramic multilayer capacitor	1 nF (max.)
R	resistor	200 Ω; 1 W

**BGY61** 

#### **FEATURES**

- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

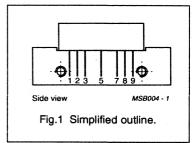
#### DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 5 to 200 MHz at a voltage supply of +24 V (DC). The device is intended as a reverse amplifier for use in two way systems.

#### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output

#### PIN CONFIGURATION



#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 10 MHz;	12.5	-	13.5	dB
l <sub>tot</sub>		DC value; V <sub>B</sub> = +24 V		215	230	mA

#### LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage	<del></del>	67	dBmV
T <sub>stg</sub>	storage temperature range	-40	+100	°C
T <sub>mb</sub>	mounting base operating temperature range	-20	+90	°C

**BGY61** 

#### **CHARACTERISTICS**

Bandwidth 5 to 200 MHz;  $T_{mb} = 30$  °C;  $Z_S = Z_L = 75 \Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 10 MHz;	12.5	-	13.5	dB
SL	slope cable equivalent	f = 5 to 200 MHz	-0.2	_	+0.5	dB
FL	flatness of frequency response	f = 5 to 200 MHz	_	_	± 0.2	dB
S <sub>11</sub>	input return losses	f = 5 to 200 MHz;	20	-	-	dB
S <sub>22</sub>	output return losses	f = 5 to 200 MHz;	20	<b> </b> -	-	dB
СТВ	composite triple beat	22 chs flat; V <sub>o</sub> = 50 dBmV; measured at 175.25 MHz	_	-	-68	dB
X <sub>mod</sub>	cross modulation	22 chs flat; V <sub>o</sub> = 50 dBmV; measured at 55.25 MHz	_	-	-61	dB
d <sub>2</sub>	second order distortion	V <sub>o</sub> = 50 dBmV; note 1	_	-	-72	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2	67	-	-	dBmV
		d <sub>im</sub> = -60 dB note 3	64	-	-	dBmV
F	noise figure	f = 200 MHz	-	T-	7	dB
l <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 4	_	215	230	mA

#### Notes

- $\begin{array}{ll} \text{1.} & f_p = 83.25 \text{ MHz; V}_p = 50 \text{ dBmV;} \\ & f_q = 109.25 \text{ MHz; V}_q = 50 \text{ dBmV;} \\ & \text{measured at f}_p + f_q = 192.5 \text{ MHz} \end{array}$
- 2. Measured according to DIN45004B;

 $f_p = 35.25 \text{ MHz}; V_o = V_p;$ 

 $f_a = 42.25 \text{ MHz}; V_a = V_o -6 \text{ dB};$ 

 $f_r = 44.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$ 

measured at  $f_p + f_q - f_r = 33.25 \text{ MHz}$ 

3. Measured according to DIN45004B;

 $f_p = 187.25 \text{ MHz}; V_o = V_p;$ 

 $f_q = 194.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$ 

 $f_r = 196.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$ 

measured at  $f_p + f_q - f_r = 185.25 \text{ MHz}$ 

4. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

**BGY65** 

#### **FEATURES**

- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

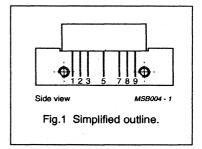
#### **DESCRIPTION**

Hybrid amplifier module for CATV systems operating over a frequency range of 5 to 200 MHz at a voltage supply of +24 V (DC). The device is intended as a reverse amplifier for use in two way systems.

#### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output

#### **PIN CONFIGURATION**



## **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$G_p$	power gain	f = 10 MHz;	18	-	19	dB
I <sub>tot</sub>	I	DC value; V <sub>B</sub> = +24 V	-	215	230	mA

#### LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	65	dBmV
T <sub>stg</sub>	storage temperature range	<del>-4</del> 0	+100	°C
T <sub>mb</sub>	mounting base operating temperature range	-20	+90	°C

**BGY65** 

### **CHARACTERISTICS**

Bandwidth 5 to 200 MHz;  $T_{mb}$  = 30 °C;  $Z_S$  =  $Z_L$  = 75  $\Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 10 MHz;	18	-	19	dB
SL	slope cable equivalent	f = 5 to 200 MHz	-0.2		+0.5	dB
FL	flatness of frequency response	f = 5 to 200 MHz	-		± 0.2	dB
S <sub>11</sub>	input return losses	f = 5 to 200 MHz;	20	<b>-</b>	_	dB
S <sub>22</sub>	output return losses	f = 5 to 200 MHz;	20	-	<b> -</b>	dB
СТВ	composite triple beat	22 chs flat; V <sub>o</sub> = 50 dBmV; measured at 175.25 MHz	-	-	-68	dB
X <sub>mod</sub>	cross modulation	22 chs flat; V <sub>o</sub> = 50 dBmV; measured at 55.25 MHz	_	_	-61	dB
d <sub>2</sub>	second order distortion	V <sub>o</sub> = 50 dBmV; note 1	-	-	-72	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2	67	-	-	dBmV
		d <sub>im</sub> = -60 dB note 3	64	-	_	dBmV
F	noise figure	f = 200 MHz	-	-	5.5	dB
l <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 4	_	215	230	mA

#### **Notes**

- 1.  $f_p = 83.25$  MHz;  $V_p = 50$  dBmV;  $f_q = 109.25$  MHz;  $V_q = 50$  dBmV; measured at  $f_p + f_q = 192.5$  MHz
- 2. Measured according to DIN45004B;

 $f_p = 35.25 \text{ MHz}; V_o = V_p;$   $f_q = 42.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$  $f_r = 44.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$ 

measured at  $f_p + f_q - f_r = 33.25$  MHz 3. Measured according to DIN45004B;

Measured according to DIN45004B;  $f_p = 187.25 \text{ MHz}$ ;  $V_o = V_p$ ;  $f_q = 194.25 \text{ MHz}$ ;  $V_q = V_o -6 \text{ dB}$ ;  $f_r = 196.25 \text{ MHz}$ ;  $V_r = V_o -6 \text{ dB}$ ; measured at  $f_p + f_q - f_r = 185.25 \text{ MHz}$ 

4. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

## **BGY66B**

#### **FEATURES**

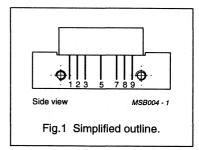
- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

### **APPLICATIONS**

 Intended as a reverse amplifier for use in two-way systems.

## **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output



## **DESCRIPTION**

Hybrid high dynamic range amplifier module designed for applications in CATV systems with a bandwidth of 5 to 120 MHz operating with a voltage supply of 24 V (DC).

#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 10 MHz	24.5	25.5	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	115	135	mA

#### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

BGY66B

#### **CHARACTERISTICS**

Bandwidth 5 to 120 MHz;  $V_B = 24 \text{ V}$ ;  $T_{mb} = 30 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 10 MHz	24.5	25.5	dB
SL	slope cable equivalent		-0.2	+0.5	dB
FL	flatness of frequency response		-	±0.2	dB
S <sub>11</sub>	input return losses		20	T-	dB
S <sub>22</sub>	output return losses		20	_	dB
СТВ	composite triple beat	14 channels flat; V <sub>o</sub> = 48 dBmV; measured at 67.25 MHz	-	-66	dB
X <sub>mod</sub>	cross modulation	14 channels flat; V <sub>o</sub> = 48 dBmV; measured at 67.25 MHz	_	-54	dB
d <sub>2</sub>	second order distortion	note 1		-70	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	60	_	dBmV
F	noise figure	f = 120 MHz	-	5	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	115	135	mA

#### **Notes**

- 1.  $f_p = 55.25$  MHz;  $V_p = 48$  dBmV;  $f_q = 61.25$  MHz;  $V_q = 48$  dBmV; measured at  $f_p + f_q = 116.5$  MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 111.25 \text{ MHz; } V_p = V_o; \\ f_q &= 118.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 120.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 109.25 \text{ MHz.} \end{split}$$

3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

BGY67

### **FEATURES**

- Excellent linearity
- Extremely low noise
- Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

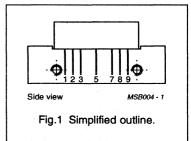
### **DESCRIPTION**

Hybrid amplifier module for CATV systems operating over a frequency range of 5 to 200 MHz at a voltage supply of +24 V (DC). The device is intended as a reverse amplifier for use in two way systems.

#### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output

#### PIN CONFIGURATION



### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 10 MHz;	21.5	-	22.5	dB
I <sub>tot</sub>		DC value; V <sub>B</sub> = +24 V	-	215	230	mA

### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage	-	65	dBmV
T <sub>stg</sub>	storage temperature range	-40	+100	°C
T <sub>mb</sub>	mounting base operating temperature range	-20	+90	°C

BGY67

#### **CHARACTERISTICS**

Bandwidth 5 to 200 MHz;  $T_{mb}$  = 30 °C;  $Z_{S}$  =  $Z_{L}$  = 75  $\Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 10 MHz;	21.5	-	22.5	dB
SL	slope cable equivalent	f = 5 to 200 MHz	-0.2	-	+0.5	dB
FL	flatness of frequency response	f = 5 to 200 MHz	_	-	± 0.2	dB
S <sub>11</sub>	input return losses	f = 5 to 200 MHz;	20	-	-	dB
S <sub>22</sub>	output return losses	f = 5 to 200 MHz;	20	-	-	dB
СТВ	composite triple beat	22 chs flat; V <sub>o</sub> = 50 dBmV; measured at 175.25 MHz	-	-	<b>–67</b>	dB
X <sub>mod</sub>	cross modulation	22 chs flat; V <sub>o</sub> = 50 dBmV; measured at 55.25 MHz	<del>-</del>	_	-60	dB
d <sub>2</sub>	second order distortion	V <sub>o</sub> = 50 dBmV; note 1	_	-	-67	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2	67	-	-	dBmV
		d <sub>im</sub> = -60 dB note 3	64	-	-	dBmV
F	noise figure	f = 200 MHz	-	-	5.5	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 4	-	215	230	mA

## **Notes**

- 1.  $f_p = 83.25 \text{ MHz}$ ;  $V_p = 50 \text{ dBmV}$ ;  $f_{q} = 109.25 \text{ MHz}; V_{q} = 50 \text{ dBmV};$ measured at  $f_p + f_q = 192.5 \text{ MHz}$
- 2. Measured according to DIN45004B;

 $\begin{aligned} &f_p = 35.25 \text{ MHz; } V_o = V_p; \\ &f_q = 42.25 \text{ MHz; } V_q = V_o \text{ } -6 \text{ dB;} \end{aligned}$ 

 $f_r = 44.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$ 

measured at  $f_p + f_q - f_r = 33.25 \text{ MHz}$ 

3. Measured according to DIN45004B;

 $f_p = 187.25 \text{ MHz}; V_o = V_p;$ 

 $f_{q} = 194.25 \text{ MHz}; V_{q} = V_{o} -6 \text{ dB};$ 

 $f_r = 196.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$ 

measured at  $f_p + f_q - f_r = 185.25 \text{ MHz}$ 

4. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

BGY67A

#### **FEATURES**

- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

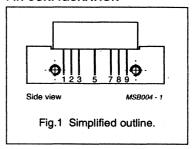
#### DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 5 to 200 MHz at a voltage supply of +24 V (DC). The device is intended as a reverse amplifier for use in two way systems.

#### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output

#### PIN CONFIGURATION



### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 10 MHz;	23.5	-	24.5	dB
Itot	l .	DC value; V <sub>B</sub> = +24 V	-	215	230	mA

#### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage	_	63	dBmV
T <sub>stg</sub>	storage temperature range	<b>-40</b>	+100	°C
T <sub>mb</sub>	mounting base operating temperature range	-20	+90	°C

BGY67A

#### **CHARACTERISTICS**

Bandwidth 5 to 200 MHz;  $T_{mb}$  = 30 °C;  $Z_{S}$  =  $Z_{L}$  = 75  $\Omega$ 

SYMBOL	PARAMETER	CONDITIONS	Maria de	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 10 MHz;	- 17	23.5	-	24.5	dB
SL	slope cable equivalent	f = 5 to 200 MHz		-0.2	-	+0.5	dB
FL	flatness of frequency response	f = 5 to 200 MHz		_	-	± 0.2	dB
S <sub>11</sub>	input return losses	f = 5 to 200 MHz;		20	_	-	dB
S <sub>22</sub>	output return losses	f = 5 to 200 MHz;		20	_	<u>-</u> 1 , 1 , 1 , 1 , 1	dB
СТВ	composite triple beat	22 chs flat; $V_o = 50 \text{ dBmV}$ ; measured at 175.25 MHz		_	_	-67	dB
X <sub>mod</sub>	cross modulation	22 chs flat; V <sub>o</sub> = 50 dBmV; measured at 55.25 MHz		_	_	-59	dB
d <sub>2</sub>	second order distortion	V <sub>o</sub> = 50 dBmV; note 1		_	-	-67	dB
<b>V</b> o , , , , , , , , , , , , , , , , , , ,	output voltage	d <sub>im</sub> = -60 dB note 2		67	-	-	dBmV
		d <sub>im</sub> = -60 dB note 3		64	-	-	dBmV
F	noise figure	f = 200 MHz			_	5.5	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 4			215	230	mA

#### **Notes**

- 1.  $f_p = 83.25 \text{ MHz}; V_p = 50 \text{ dBmV}; \\ f_q = 109.25 \text{ MHz}; V_q = 50 \text{ dBmV}; \\ \text{measured at } f_p + f_q = 192.5 \text{ MHz}$
- 2. Measured according to DIN45004B;  $\begin{aligned} f_p &= 35.25 \text{ MHz; } V_o = V_p; \\ f_q &= 42.25 \text{ MHz; } V_q = V_o & -6 \text{ dB;} \\ f_r &= 44.25 \text{ MHz; } V_r = V_o & -6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 33.25 \text{ MHz} \end{aligned}$
- 3. Measured according to DIN45004B;
  - $f_p = 187.25 \text{ MHz}; V_o = V_p;$   $f_q = 194.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$   $f_r = 196.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$ measured at  $f_p + f_q - f_r = 185.25 \text{ MHz}$
- 4. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

## **BGY80; BGY81**

#### **FEATURES**

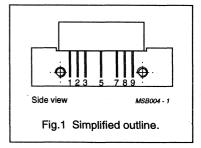
- Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

### **DESCRIPTION**

Hybrid amplifier modules for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of (DC). The BGY80 is intended for use as a 12.5 dB pre-amplifier and the BGY81 as a 12.5 dB final amplifier.

#### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output



### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	12	Ī-	13	dB
		f = 450 MHz	12.5	-	14	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V				
	BGY80		-	180	200	mA
	BGY81		-	220	240	mA

### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage		60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

**BGY80; BGY81** 

### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $V_B = 24$  V;  $T_{mb} = 30$  °C;  $Z_S = Z_L = 75$   $\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	12	-	13	dB
		f = 450 MHz	12.5	T	14	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.2	T	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	<b>-</b>	<b>-</b>	±0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	19	T-	I	dB
		f = 160 to 450 MHz	18	- 1 1	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	19	<b>I</b> -	-	dB
		f = 160 to 450 MHz	18	-	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	-	+45	deg
СТВ	composite triple beat BGY80 BGY81	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	_	_	-54 -58	dB dB
<b>v</b> .	cross modulation	60 channels flat;	<del> </del>	<del>                                     </del>	-36	UB
X <sub>mod</sub>	BGY80 BGY81	V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	-		-59 -62	dB dB
CSO	composite second order distortion BGY80 BGY81	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 446.5 MHz	_	-	-58 -61	dB dB
d <sub>2</sub>	second order distortion BGY80 BGY81	note 1	_	-	-72 -74	dB dB
Vo	output voltage BGY80 BGY81	$d_{im} = -60 \text{ dB}$ ; note 2	61.5 64	_		dBmV dBmV
F	noise figure BGY80 BGY81	f = 450 MHz	_	_	7.5 8	dB dB
I <sub>tot</sub>	total current consumption (DC) BGY80 BGY81	note 3		180 220	200 240	mA mA

#### **Notes**

- 1.  $f_p = 55.25 \text{ MHz}$ ;  $V_p = 46 \text{ dBmV}$ ;  $f_q = 391.25 \text{ MHz}$ ;  $V_q = 46 \text{ dBmV}$ ; measured at  $f_p + f_q = 446.5 \text{ MHz}$ .
- 2. Measured according to DIN45004B:  $f_p$  = 440.25 MHz;  $V_p$  =  $V_o$ ;  $f_q$  = 447.25 MHz;  $V_q$  =  $V_o$  -6 dB;  $f_r$  = 449.25 MHz;  $V_r$  =  $V_o$  -6 dB; measured at  $f_p$  +  $f_q$   $f_r$  = 438.25 MHz.
- 3. The modules normally operate at  $V_B = 24 \text{ V}$ , but are able to withstand supply transients up to 30 V.

**BGY82;BGY83** 

### **FEATURES**

- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Optimal reliability ensured by TiPtAu metallized crystals.

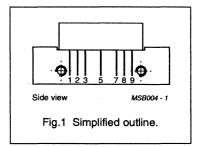
### DESCRIPTION

Hybrid amplifier modules for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of +24 V (DC).

#### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7 200	common
8	common
9	output

### **PIN CONFIGURATION**



## QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	13.5	-	14.5	dB
		f = 450 MHz	14.5	-	_	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V				N
	BGY82		-	180	200	mA
	BGY83		-	220	240	mA

#### LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage	-	60	dBmV
T <sub>stg</sub>	storage temperature range	-40	+100	°C
T <sub>case</sub>	operating case temperature range	-20	+100	°C

BGY82;BGY83

### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $T_{case} = 30$  °C;  $Z_{S} = Z_{L} = 75 \Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	13.5	<b> -</b>	14.5	dB
		f = 450 MHz	14.5	-	-	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.2	-	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-	-	± 0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	1-	_	dB
		f = 80 to 160 MHz	19	-	_	dB
		f = 160 to 450 MHz	18		_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	1-	_	dB
		f = 80 to 160 MHz	19	_	_	dB
		f = 160 to 450 MHz	18	_	_	dB
СТВ	composite triple beat	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz				
	BGY82		-	-	-55	dB
	BGY83		-	-	-59	dB
X <sub>mod</sub>	cross modulation	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz				
	BGY82		_	-	-56	dB
•	BGY83		-	-	<i>–</i> 59	dB
CSO	composite second order distortion	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 446.5 MHz				
	BGY82	,	-	_	-55	dB
	BGY83		_	_	-59	dB
d <sub>2</sub>	second order distortion	note 1				
	BGY82		-	-	-72	dB
	BGY83			_	-74	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2				
	BGY82		61.5	-	-	dBmV
	BGY83		64	-	_	dBmV
F	noise figure	f = 450 MHz				
	BGY82		_	-	7	dB
	BGY83		_	-	8	dB

**BGY82;BGY83** 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3				
	BGY82		<u>-</u>	180	200	mA
1-	BGY83		-	220	240	mA .

#### **Notes**

- 1.  $f_p = 55.25 \text{ MHz}; V_p = 46 \text{ dBmV};$   $f_q = 391.25 \text{ MHz}; V_q = 46 \text{ dBmV};$ measured at  $f_p + f_q = 446.5 \text{ MHz}$
- 2. Measured according to DIN45004B;

```
\begin{split} f_p &= 440.25 \text{ MHz; } V_p = V_o; \\ f_q &= 447.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 449.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 438.25 \text{ MHz.} \end{split}
```

3. The modules normally operate at  $V_B = +24 \text{ V}$ , but are able to withstand supply transients up to 30 V.

**BGY84;BGY85** 

### **FEATURES**

- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- Optimal reliability ensured by TiPtAu metallized crystals.

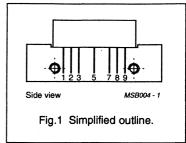
#### DESCRIPTION

Hybrid amplifier modules for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of +24 V (DC). BGY84 intended for use as an input amplifier module and BGY85 as an output amplifier module.

#### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output

#### PIN CONFIGURATION



#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	16.5	-	17.5	dB
		f = 450 MHz	17.3	-	18.8	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V				
	BGY84		_	180	200	mA
	BGY85		_	220	240	mA .

### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage	_	65	dBmV
T <sub>stg</sub>	storage temperature range	-40	+100	°C
T <sub>mb</sub>	mounting base operating temperature range	-20	+100	°C

BGY84;BGY85

## **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $T_{mb} = 30$  °C;  $Z_{S} = Z_{L} = 75 \Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	16.5	-	17.5	dB
		f = 450 MHz	17.3	_ '	18.8	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	-	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-	-	± 0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	_	-	dB
		f = 80 to 160 MHz	19		_	dB
		f = 160 to 450 MHz	18	_	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	_	dB
		f = 80 to 160 MHz	19	-	-	dB
		f = 160 to 450 MHz	18	_	-	dB
СТВ	composite triple beat	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz				
	BGY84		-	-	-55	dB
	BGY85		-	-	-58	dB
X <sub>mod</sub>	cross modulation	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz				
	BGY84		_	_	-57	dB
	BGY85		_	-	-60	dB
d <sub>2</sub>	second order distortion	note 1	_	-	-70	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2				
	BGY84		60	-	-	dBmV
	BGY85		62.5	-	-	dBmV
F	noise figure	f = 40 to 450 MHz				
	BGY84		-	_	6.5	dB
	BGY85		_	-	7	dB
I <sub>tot</sub> .	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3				
	BGY84		_	180	200	mA
	BGY85		_	220	240	mA

BGY84;BGY85

- 1.  $f_p$  = 55.25 MHz;  $V_p$  = 46 dBmV;  $f_q$  = 343.25 MHz;  $V_q$  = 46 dBmV; measured at  $f_p$  +  $f_q$  = 398.5 MHz
- 2. Measured according to DIN45004B;  $f_p = 440.25 \text{ MHz}; V_p = V_o; f_q = 447.25 \text{ MHz}; V_q = V_o -6 \text{ dB}; f_r = 449.25 \text{ MHz}; V_r = V_o -6 \text{ dB}; measured at <math>f_p + f_q f_r = 438.25 \text{ MHz}.$
- 3. The modules normally operate at  $V_B = +24 \text{ V}$ , but are able to withstand supply transients up to 30 V.

## BGY84A;BGY85A

#### **FEATURES**

- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Optimal reliability ensured by TiPtAu metallized crystals.

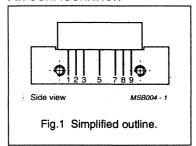
#### DESCRIPTION

Hybrid amplifier modules for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of +24 V (DC). The BGY84A is intended for use as an input amplifier module and BGY85A as an output amplifier module.

#### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output

#### PIN CONFIGURATION



#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	18	-	18.8	dB
		f = 450 MHz	18.7	_	20.2	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V				
	BGY84A		_	180	200	mA
	BGY85A		_	220	240	mA

#### LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage	_	65	dBmV
T <sub>stg</sub>	storage temperature range	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature range	-20	+100	°C

# BGY84A;BGY85A

### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $T_{mb} = 30$  °C;  $Z_S = Z_L = 75 \Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	18	-	18.8	dB
•		f = 450 MHz	18.7	_	20.2	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.3	-	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-	- 1	± 0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	1-	_	dB
		f = 80 to 160 MHz	19	-	-	dB
	'	f = 160 to 450 MHz	18	-	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	19	_	_	dB
* .	w	f = 160 to 450 MHz	18	-		dB
СТВ	composite triple beat	60 chs flat; $V_o = 46 \text{ dBmV}$ ; measured at 445.25 MHz				
	BGY84A			-	-55	dB
	BGY85A		_	-	-59	dB
X <sub>mod</sub>	cross modulation	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz				
	BGY84A	_	_	-	-58	dB
	BGY85A		_	_	-61	dB
d <sub>2</sub>	second order distortion	note 1	-	-	-72	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2				
	BGY84A		60	-	_	dBmV
	BGY85A		62.5	_ ,	- '	dBmV
F	noise figure	f = 40 to 450 MHz				
	BGY84A		_	-	6.5	dB
	BGY85A		_	-	7	dB
l <sub>tot</sub> .	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3				
	BGY84A		_	180	200	mA
	BGY85A		_	220	240	mA

## BGY84A;BGY85A

- 1.  $f_p = 55.25 \text{ MHz}; V_p = 46 \text{ dBmV}; \\ f_q = 343.25 \text{ MHz}; V_q = 46 \text{ dBmV}; \\ \text{measured at } f_p + f_q = 398.5 \text{ MHz}$
- 2. Measured according to DIN45004B;  $f_p = 440.25 \text{ MHz}; V_p = V_o;$   $f_q = 447.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$   $f_r = 449.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$  measured at  $f_p + f_q f_r = 438.25 \text{ MHz}.$
- 3. The modules normally operate at  $V_B = +24 \text{ V}$ , but are able to withstand supply transients up to 30 V.

## **BGY85H/01**

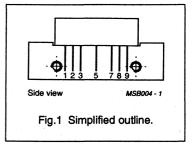
#### **FEATURES**

- Excellent linearity
- High slope of 5.1 dB so that total cable slope can be equalised by the slope of the module
- · Silicon nitride passivation
- Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

#### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7 .	common
8	common
9	output

### **PIN CONFIGURATION**



### **DESCRIPTION**

High slope, pre-emphasis, hybrid amplifier module intended for use as a 20.7 dB trunk amplifier in CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of +24 V (DC).

#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	14.8	-	16.4	dB
		f = 450 MHz	20.2	_	21.2	dB
l <sub>tot</sub>	1	DC value; V <sub>B</sub> = +24 V	_ ,	215	230	mA

#### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage	-	65	dBmV
T <sub>stg</sub>	storage temperature range	-40	+100	°C
T <sub>mb</sub>	mounting base operating temperature range	-20	+100	°C
V <sub>B</sub>	DC supply voltage	-	+28	V

BGY85H/01

#### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $T_{case}$  = 30 °C;  $Z_{S}$  =  $Z_{L}$  = 75  $\Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	14.8	-	16.4	dB
		f = 450 MHz	20.2	-	21.2	dB
ΔG	delta gain	f = 40 to 450 MHz	4.7	-	5.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz; note 1	-	- :::::	± 0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz;	20	_		dB
		f = 80 to 160 MHz;	19	-		dB
		f = 160 to 450 MHz	18	-	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz;	20	-	-	dB
		f = 80 to 160 MHz;	19	-	_	dB
		f = 160 to 450 MHz	18	_		dB
СТВ	composite triple beat	36 chs flat; V <sub>o</sub> = 46 dBmV; measured at 433.25 MHz		-	<b>–65</b>	dB
		60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	-	-59	_	dB
X <sub>mod</sub>	cross modulation	36 chs flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	-	-	-65	dB
		60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz		-61	-	dB
d <sub>2</sub>	second order distortion	note 2	_		-72	dB
V <sub>o</sub>	output voltage	$d_{im} = -60 \text{ dB}$				
		note 3	65	-	-	dBmV
		note 4	64	_	_	dBmV
		note 5	62.5		-	dBmV
F	noise figure	f = 450 MHz	-	- ,	6.8	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 6	-	215	230	mA

#### Notes

1. Flatness calculation is based on the following formula which describes the 'ideal' gain versus frequency curve,  $G_f = G_{50} + \Delta G$  [a (f – 50) + b (f – 50)² + c (f –50)³], in which :

G<sub>50</sub> = measured gain at 50 MHz;

 $\Delta G$  = measured difference in gain between 450 and 50 MHz;

 $a = 3.132 \times 10^{-3}$ 

 $b = 1.993 \times 10^{-6}$ 

 $c = -8.934 \times 10^{-9}$ 

BGY85H/01

```
2. f_p = 55.25 MHz; V_p = 46 dBmV; f_q = 343.25 MHz; V_q = 46 dBmV; measured at f_p + f_q = 398.5 MHz
```

3. Measured according to DIN45004B;  $f_p = 287.25$  MHz;  $V_p = V_o$ ;  $f_q = 294.25$  MHz;  $V_q = V_o$  -6 dB;  $f_r = 296.25$  MHz;  $V_r = V_o$  -6 dB;

4. Measured according to DIN45004B;

```
\begin{array}{l} f_p = 387.25 \text{ MHz; } V_p = V_o; \\ f_q = 394.25 \text{ MHz; } V_q = V_o \ -6 \text{ dB;} \\ f_r = 396.25 \text{ MHz; } V_r = V_o \ -6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 385.25 \text{ MHz} \end{array}
```

measured at  $f_p + f_q - f_r = 285.25 \text{ MHz}$ 

5. Measured according to DIN45004B;  $f_p = 440.25 \text{ MHz}; V_p = V_o;$   $f_q = 447.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$   $f_r = 449.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$  measured at  $f_o + f_g - f_r = 438.25 \text{ MHz}$ 

6. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

**BGY86; BGY87** 

#### **FEATURES**

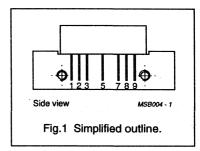
- Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

#### **DESCRIPTION**

Hybrid amplifier modules for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of 24 V (DC). The BGY86 is intended for use as a pre-amplifier and BGY87 as a final amplifier.

#### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output



#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	21.5	-	22.5	dB
		f = 450 MHz	21.7	<b> </b> -	23.5	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V				
	BGY86		_	180	200	mA
	BGY87		-	220	240	mA

### LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	60	dBmV
T <sub>stg</sub>	storage temperature	<del>-4</del> 0	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

**BGY86**; **BGY87** 

#### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $V_B = 24 \text{ V}$ ;  $T_{mb} = 30 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	21.5	-	22.5	dB
		f = 450 MHz	21.7	-	23.5	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0	-	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	-	±0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	_	dB
		f = 80 to 160 MHz	19	-	_	dB
		f = 160 to 450 MHz	18	-	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	_	dB
		f = 80 to 160 MHz	19	_		dB
		f = 160 to 450 MHz	18	-	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	+135	_	+225	deg
СТВ	composite triple beat BGY86 BGY87	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	_	- 1	-54 -58	dB dB
V	cross modulation	60 channels flat;		<del> -</del>	-36	ub
X <sub>mod</sub>	BGY86 BGY87	V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	- 1	_	-51 -55	dB dB
CSO	composite second order distortion BGY86 BGY87	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 446.5 MHz		_	-53 -57	dB dB
d <sub>2</sub>	second order distortion BGY86 BGY87	note 1		_	-68 -72	dB dB
Vo	output voltage BGY86 BGY87	d <sub>im</sub> = -60 dB; note 2	61.5 64	_	: -	dBmV dBmV
F	noise figure BGY86	f = 450 MHz	_	_	6	dB
	BGY87		-	-	6.5	dB
l <sub>tot</sub>	total current consumption (DC) BGY86 BGY87	note 3	-	180 220	200 240	mA mA

- 1.  $f_p = 55.25 \text{ MHz}$ ;  $V_p = 46 \text{ dBmV}$ ;  $f_q = 391.25 \text{ MHz}$ ;  $V_q = 46 \text{ dBmV}$ ; measured at  $f_p + f_q = 446.5 \text{ MHz}$ .
- 2. Measured according to DIN45004B:  $f_p$  = 440.25 MHz;  $V_p$  =  $V_o$ ;  $f_q$  = 447.25 MHz;  $V_q$  =  $V_o$  -6 dB;  $f_r$  = 449.25 MHz;  $V_r$  =  $V_o$  -6 dB; measured at  $f_p$  +  $f_q$   $f_r$  = 438.25 MHz.
- 3. The modules normally operate at  $V_B = 24 \text{ V}$ , but are able to withstand supply transients up to 30 V.

BGY87B

#### **FEATURES**

- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimum reliability.

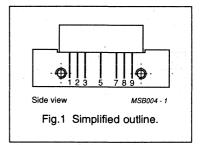
#### DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of +24 V.

#### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output

#### PIN CONFIGURATION



## **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	26.2	27.8	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V	_	340	mA
		(note 1)			

#### Note

1. The module normally operates at  $V_B = +24$  V, but is able to withstand supply transients up to +30 V.

### LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage	-	55	dBmV
T <sub>stg</sub>	storage temperature range	-40	+100	°C
T <sub>mb</sub>	mounting base operating temperature range	-20	+100	°C

BGY87B

## **CHARACTERISTICS**

 $T_{case} = 35 \,^{\circ}C; Z_{S} = Z_{L} = 75 \,\Omega.$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	26.2	27.8	dB
•		f = 450 MHz	27.5	-	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	2.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-	± 0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz;	-	20	dB
		f = 80 to 160 MHz;	-	19	dB
		f = 160 to 450 MHz	_	18	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz;	-	20	dB
		f = 80 to 160 MHz;	_	19	dB
		f = 160 to 450 MHz	-	18	dB
СТВ	composite triple beat	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	-	-58	dB
X <sub>mod</sub>	cross modulation	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	-	-58	dB
CSO	composite second order distortion	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 446.5 MHz	-	-60	dB
d <sub>2</sub>	second order beat	V <sub>o</sub> = 46 dBmV note 1	-	70	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2	64	-	dBmV
F	noise figure	f = 450 MHz	-	6	dB
l <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V	-	340	mA

### Notes

1.  $f_p = 55.25 \text{ MHz}; V_p = 46 \text{ dBmV};$  $f_q = 391.25 \text{ MHz}; V_q = 46 \text{ dBmV};$ measured at  $f_p + f_q = 446.5$  MHz.

2. Measured according to DIN 45004B;

 $f_p = 440.25 \text{ MHz}; V_p = V_o;$   $f_q = 447.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$   $f_r = 449.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$ measured at  $f_p + f_q - f_r = 438.25$  MHz.

BGY88

#### **FEATURES**

- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

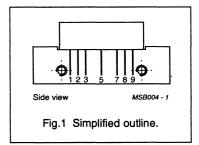
### **DESCRIPTION**

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of +24 V (DC) and intended for use as a line-extender.

#### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output

#### PIN CONFIGURATION



### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	33.5	-	35.5	dB
		f = 450 MHz	35	-	37	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V	-	320	340	mA

#### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	55	dBmV
T <sub>stg</sub>	storage temperature range	-40	+100	°C
T <sub>mb</sub>	mounting base operating temperature range	-20	+100	°C

**BGY88** 

#### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $T_{mb}$  = 35 °C;  $Z_S$  =  $Z_L$  = 75  $\Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	33.5	-	35.5	dB
·		f = 450 MHz	35	_	37	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	_	2.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-	-	± 0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz;	20	1-		dB
		f = 80 to 160 MHz;	19	_1		dB
		f = 160 to 450 MHz	18	-	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz;	20	-	-	dB
		f = 80 to 160 MHz;	19	-		dB
4		f = 160 to 450 MHz	18	-	-	dB
СТВ	composite triple beat	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	-	-	-58	dB
X <sub>mod</sub>	cross modulation	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	÷. %	-	-59	dB
d <sub>2</sub>	second order distortion	note 1	-	<b>-</b>	-70	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	62	-	-	dBmV
F	noise figure	f = 450 MHz	-	-	6	dB
l <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3	<del>-</del>	320	340	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 343.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 398.5$  MHz
- 2. Measured according to DIN45004B;  $\begin{aligned} f_p &= 440.25 \text{ MHz; } V_p = V_o = 62 \text{ dBmV;} \\ f_q &= 447.25 \text{ MHz; } V_q = V_o & -6 \text{ dB;} \\ f_r &= 449.25 \text{ MHz; } V_r = V_o & -6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 438.25 \text{ MHz} \end{aligned}$
- 3. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

**BGY89** 

#### **FEATURES**

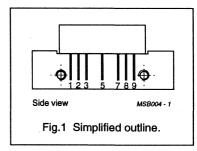
- Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

#### **DESCRIPTION**

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of 24 V (DC). The module is intended for use as a line-extender.

#### **PINNING - SOT115C**

PIN	DESCRIPTION		
. 1	input		
2	common		
3	common		
5	+V <sub>B</sub>		
7	common		
8	common		
9	output		



### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	37	_	39	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	-	320	340	mA .

### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	55	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

BGY89

#### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $V_B = 24 \text{ V}$ ;  $T_{mb} = 35 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	37	-	39	dB
		f = 450 MHz	37	-	_	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0		2.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-		±0.4	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	_	-	dB
		f = 80 to 160 MHz	19	T-	-	dB
		f = 160 to 450 MHz	18	_	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19	_	_	dB
		f = 160 to 450 MHz	18	-	_	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	-	+45	deg
СТВ	composite triple beat	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	_	-	-58	dB
X <sub>mod</sub>	cross modulation	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	-	-	-58	dB
CSO	composite second order distortion	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 446.5 MHz	-	_	-58	dB
d <sub>2</sub>	second order distortion	note 1	_	-	-70	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	63	-	_	dBmV
F	noise figure	f = 450 MHz	_	-	5.5	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	-	320	340	mA

#### **Notes**

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 343.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 398.5$  MHz.
- 2. Measured according to DIN45004B:

```
f_p = 440.25 \text{ MHz}; V_p = V_o = 63 \text{ dBmV}; \\ f_q = 447.25 \text{ MHz}; V_q = V_o -6 \text{ dB}; \\ f_r = 449.25 \text{ MHz}; V_r = V_o -6 \text{ dB}; \\ \text{measured at } f_p + f_q - f_r = 438.25 \text{ MHz}.
```

3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

## **BGY580;BGY581**

#### **FEATURES**

- Excellent linearity
- Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Optimal reliability ensured by TiPtAu metallized crystals.

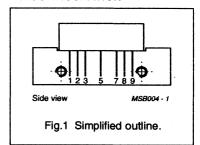
### **DESCRIPTION**

Hybrid amplifier modules for CATV systems operating over a frequency range of 40 to 550 MHz at a voltage supply of +24 V (DC). The BGY580 is intended for use as a pre-amplifier and BGY581 as a final amplifier.

#### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output

#### PIN CONFIGURATION



## **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	12	-	13	dB
		f = 550 MHz	12.5	-	14.5	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V			:	
	BGY580		_	180	200	mA
	BGY581		-	220	240	mA

#### LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	60	dBmV
T <sub>stg</sub>	storage temperature range	-40	+100	°C
T <sub>case</sub>	operating case temperature range	-20	+100	°C

BGY580;BGY581

### **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $T_{case} = 30 \,^{\circ}\text{C}$ ;  $Z_{s} = Z_{L} = 75 \,\Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	12	T-	13	dB
		f = 550 MHz	12.5	-	14.5	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.5	-	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	-	± 0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	1-	dB
		f = 80 to 160 MHz	19	-	_	dB
		f = 160 to 550 MHz	18	_	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	1-	dB
		f = 80 to 160 MHz	19		_	dB
		f = 160 to 550 MHz	18	_		dB
СТВ	composite triple beat	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz		:		
	BGY580		-	-	-52	dB
	BGY581		-	-	-56	dB
X <sub>mod</sub>	cross modulation	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz				
	BGY580		_		-59	dB
	BGY581		-		-62	dB
CSO	composite second order distortion	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz				
	BGY580			-	-56	dB
	BGY581		_	-	-59	dB
d <sub>2</sub>	second order distortion	note 1				
	BGY580		_	-	-70	dB
	BGY581			-	-72	dB
V <sub>o</sub> .	output voltage	d <sub>im</sub> = -60 dB note 2				
	BGY580		59	-	-	dBmV
	BGY581		61.5	-	_	dBmV
F	noise figure	f = 550 MHz				
	BGY580		-	_	8.5	dB
	BGY581		_	_	9	dB

## BGY580;BGY581

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
l <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3				
	BGY580		-	180	200	mA
	BGY581		-	220	240	mA

- 1.  $\begin{aligned} f_p &= 55.25 \text{ MHz; V}_p = 44 \text{ dBmV;} \\ f_q &= 493.25 \text{ MHz; V}_q = 44 \text{ dBmV;} \end{aligned}$ measured at  $f_p + f_q = 548.5 \text{ MHz}$
- 2. Measured according to DIN45004B;

  - $$\begin{split} &f_p = 540.25 \text{ MHz; } V_p = V_o; \\ &f_q = 547.25 \text{ MHz; } V_q = V_p 6 \text{ dB;} \\ &f_r = 549.25 \text{ MHz; } V_r = V_p 6 \text{ dB;} \end{split}$$
  - measured at  $f_p + f_q f_r = 538.25$  MHz.
- 3. The modules normally operate at  $V_B = +24 \text{ V}$ , but are able to withstand supply transients up to 30 V.

## **BGY582;BGY583**

### **FEATURES**

- · Excellent linearity
- Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- Optimal reliability ensured by TiPtAu metallized crystals.

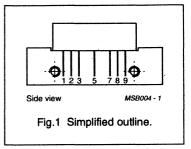
#### **DESCRIPTION**

Hybrid amplifier modules for CATV systems operating over a frequency range of 40 to 550 MHz at a voltage supply of +24 V (DC).

#### **PINNING - SOT115C**

PIN	DESCRIPTION		
1	input		
2	common		
3	common		
5	+V <sub>B</sub>		
7	common		
8	common		
9	output		

#### PIN CONFIGURATION



### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	13.5	-	14.5	dB
		f = 550 MHz	14.5	-	_	dB
l <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V				
	BGY582		-	180	200	mA
	BGY583		_	220	240	mA

#### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage	-	60	dBmV
T <sub>stg</sub>	storage temperature range	<del>-4</del> 0	+100	°C
T <sub>mb</sub>	mounting base operating temperature range	-20	+100	°C

BGY582;BGY583

## **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $T_{case} = 30$  °C;  $Z_{S} = Z_{L} = 75 \Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	13.5	-	14.5	dB
		f = 550 MHz	14.5	_	-	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	-	1.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	-	± 0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	19	-	-	dB
		f = 160 to 550 MHz	18		-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	19		_	dB
		f = 160 to 550 MHz	18	-	_	dB
СТВ	composite triple beat	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz				
	BGY582		-	_	-55	dB
	BGY583		_	_	-59	dB
X <sub>mod</sub>	cross modulation	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz				
	BGY582		_	_	-58	dB
	BGY583		_	-	<b>–61</b>	dB
CSO	composite second order distortion	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz				
	BGY582		-   -	_	-55	dB
	BGY583		_	1-	-59	dB
d <sub>2</sub>	second order distortion	note 1				
	BGY582		_		-70	dB
	BGY583		_	-	-72	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2				
	BGY582		59	-	-	dBmV
	BGY583		61.5	-	_	dBmV
F	noise figure	f = 550 MHz		1		
	BGY582		-	_	7.5	dB
	BGY583		_	_	8.5	dB

## BGY582;BGY583

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3				
	BGY582 BGY583		<u>-</u>	180 220	200 240	mA mA

### Notes

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 493.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 548.5$  MHz
- 2. Measured according to DIN45004B;

3. The modules normally operate at  $V_B = +24 \text{ V}$ , but are able to withstand supply transients up to 30 V.

**BGY584; BGY585** 

### **FEATURES**

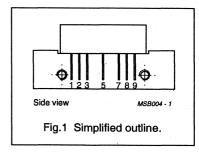
- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

#### **DESCRIPTION**

Hybrid amplifier modules for CATV systems operating over a frequency range of 40 to 550 MHz at a voltage supply of 24 V (DC). The BGY584 is intended for use as a pre-amplifier and BGY585 as a final amplifier.

### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output



#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	16.5	-	17.5	dB
		f = 550 MHz	17.6	_	19	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V				
	BGY584		_	180	200	mA
	BGY585		_	220	240	mA

#### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

Philips Semiconductors Product specification

## **CATV** amplifier modules

BGY584; BGY585

#### **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $V_B = 24 \text{ V}$ ;  $T_{mb} = 30 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	16.5	-	17.5	dB
		f = 550 MHz	17.6	-	19	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.5	-	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz		-	±0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	19	_	_	dB
		f = 160 to 550 MHz	18	-	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	_	-	dB
		f = 80 to 160 MHz	19	_	-	dB
		f = 160 to 550 MHz	18	-	_	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	-	+45	deg
СТВ	composite triple beat BGY584 BGY585	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz	_	_	-56 -59	dB dB
V	cross modulation	77 channels flat;	<del> -</del>	<del> </del>	-39	I UD
X <sub>mod</sub>	BGY584 BGY585	V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	_	_ _	-59 -62	dB dB
CSO	composite second order distortion BGY584 BGY585	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz	-	 	-56 -59	dB dB
d <sub>2</sub>	second order distortion BGY584 BGY585	note 1	-	- 'i'	-68 -70	dB dB
Vo	output voltage BGY584 BGY585	d <sub>im</sub> = -60 dB; note 2	58.5 61	-		dBmV dBmV
F	noise figure BGY584 BGY585	f = 550 MHz	-	-	7	dB dB
I <sub>tot</sub>	total current consumption (DC) BGY584 BGY585	note 3	  -  -	180 220	200 240	mA mA

- 1.  $f_p = 55.25 \text{ MHz}$ ;  $V_p = 44 \text{ dBmV}$ ;  $f_q = 493.25 \text{ MHz}$ ;  $V_q = 44 \text{ dBmV}$ ; measured at  $f_p + f_q = 548.5 \text{ MHz}$ .
- 2. Measured according to DIN45004B:  $f_p = 540.25$  MHz;  $V_p = V_o$ ;  $f_q = 547.25$  MHz;  $V_q = V_o$  -6 dB;  $f_r = 549.25$  MHz;  $V_r = V_o$  -6 dB; measured at  $f_p + f_q f_r = 538.25$  MHz.
- 3. The modules normally operate at  $V_B = 24 \text{ V}$ , but are able to withstand supply transients up to 30 V.

BGY584; BGY585

#### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $V_B = 24 \text{ V}$ ;  $T_{mb} = 30 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	16.5	_	17.5	dB
		f = 450 MHz	17.4	_	18.8	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	_	1.8	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-	-	±0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	_	-	dB
-1		f = 80 to 160 MHz	19	_	-	dB
		f = 160 to 450 MHz	18	-		dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19	_	-	dB
		f = 160 to 450 MHz	18	-	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	-	+45	deg
СТВ	composite triple beat BGY584 BGY585	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz		-	-58 -61	dB dB
<b>-</b>	cross modulation	60 channels flat;	<del> -</del>	<del> -</del>	-01	UD
X <sub>mod</sub>	BGY584 BGY585	V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	-		-57 -60	dB dB
CSO	composite second order distortion BGY584 BGY585	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 446.5 MHz	_		-58 -61	dB dB
d <sub>2</sub>	second order distortion BGY584 BGY585	note 1	_	- -	-73 -75	dB dB
Vo	output voltage BGY584 BGY585	d <sub>im</sub> = -60 dB; note 2	61.5 64	-	_	dBmV dBmV
F	noise figure BGY584 BGY585	f = 450 MHz		_	6	dB dB
I <sub>tot</sub>	total current consumption (DC) BGY584 BGY585	note 3	_ 	180 220	200 240	mA mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 391.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 446.5$  MHz.
- 2. Measured according to DIN45004B:  $f_p$  = 440.25 MHz;  $V_p$  =  $V_o$ ;  $f_q$  = 447.25 MHz;  $V_q$  =  $V_o$  -6 dB;  $f_r$  = 449.25 MHz;  $V_r$  =  $V_o$  -6 dB; measured at  $f_p$  +  $f_q$   $f_r$  = 438.25 MHz.
- 3. The modules normally operate at  $V_B = 24 \text{ V}$ , but are able to withstand supply transients up to 30 V.

## BGY584A;BGY585A

### **FEATURES**

- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- Optimal reliability ensured by TiPtAu metallized crystals.

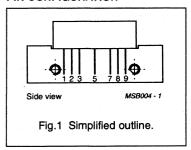
#### **DESCRIPTION**

Hybrid amplifier modules for CATV systems operating over a frequency range of 40 to 550 MHz at a voltage supply of +24 V (DC). The BGY584A is intended for use as a pre-amplifier and BGY585A as a final amplifier.

#### **PINNING - SOT115C**

PIN DESCRIPTION	
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output

#### PIN CONFIGURATION



#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	17.7	-	18.7	dB
-		f = 550 MHz	18.8	-	20	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V				-
	BGY584A		_	180	200	mA
	BGY585A		_	220	240	mA

### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	60	dBmV
T <sub>stg</sub>	storage temperature range	<b>-40</b>	+100	°C
T <sub>case</sub>	operating case temperature range	-20	+100	°C

# BGY584A;BGY585A

### **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $T_{case} = 30$  °C;  $Z_{S} = Z_{L} = 75 \Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	17.7		18.7	dB
		f = 550 MHz	18.8		20	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.5	-	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	_	-	± 0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20		_	dB
		f = 80 to 160 MHz	19			dB
		f = 160 to 550 MHz	18	200 000	_ ~ ~	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	<b>1</b>	_	dB
		f = 80 to 160 MHz	19	: : :		dB
		f = 160 to 550 MHz	18	L_ **	_	dB
СТВ	composite triple beat	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz	-			
	BGY584A		_	-	-56	dB
	BGY585A		_	-	-59	dB
X <sub>mod</sub>	cross modulation	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz				
	BGY584A		_	_	-59	dB
	BGY585A		_	_	-62	dB
CSO	composite second order distortion	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz				H
	BGY584A		_	_	-55	dB
	BGY585A		_	_	-59	dB
d <sub>2</sub>	second order distortion	note 1				
	BGY584A		-	-	-70	dB
	BGY585A		-	_	-72	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2				
	BGY584A		59	-	-	dBmV
	BGY585A		61.5	-	-	dBmV
F	noise figure	f = 550 MHz				
	BGY584A		_	_	7	dB
	BGY585A		_	_	8	dB

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## BGY584A;BGY585A

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3				
	BGY584A			180	200	mA
	BGY585A		_	220	240	mA .

#### **Notes**

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 493.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 548.5$  MHz
- 2. Measured according to DIN45004B;

$$f_p = 540.25 \text{ MHz}; V_p = V_o;$$
  
 $f_q = 547.25 \text{ MHz}; V_q = V_p - 6 \text{ dB};$   
 $f_r = 549.25 \text{ MHz}; V_r = V_p - 6 \text{ dB};$   
measured at  $f_p + f_q - f_r = 538.25 \text{ MHz}.$ 

3. The modules normally operate at  $V_B = +24 \text{ V}$ , but are able to withstand supply transients up to 30 V.

# BGY584A;BGY585A

## **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $T_{case} = 30 \, ^{\circ}\text{C}; Z_{S} = Z_{L} = 75 \, \Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	17.7	1-	18.7	dB
		f = 450 MHz	18.6	-	19.8	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	-	1.8	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-	_	± 0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20			dB
		f = 80 to 160 MHz	19			dB
		f = 160 to 450 MHz	18	1 -	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	<b>-</b>	1-	dB
		f = 80 to 160 MHz	19	_	_	dB
		f = 160 to 450 MHz	18		l	dB
СТВ	composite triple beat	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz			-	
	BGY584A		-	-	-57	dB
	BGY585A		-	-	-61	dB
X <sub>mod</sub>	cross modulation	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz		~		
	BGY584A		_	-	-58	dB
	BGY585A		_	-	-61	dB
CSO	composite second order distortion	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 446.5 MHz				
	BGY584A		_	_	-58	dB
	BGY585A		_	_	<b>–61</b>	dB
d <sub>2</sub>	second order distortion	note 1				
	BGY584A		_	-	-73	dB
	BGY585A		_	_	-75	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2				
	BGY584A		61.5	-	-	dBmV
	BGY585A		64	_	-	dBmV
F	noise figure	f = 450 MHz				
	BGY584A		_	-	6	dB
	BGY585A				7	dB

## BGY584A;BGY585A

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3				
	BGY584A		<del>-</del> ' .	180	200	mA
	BGY585A		_	220	240	mA

#### Notes

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 391.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 446.5$  MHz
- 2. Measured according to DIN45004B;

```
f_p = 440.25 \text{ MHz}; V_p = V_o;

f_q = 447.25 \text{ MHz}; V_q = V_p - 6 \text{ dB};

f_r = 449.25 \text{ MHz}; V_r = V_p - 6 \text{ dB};

measured at f_p + f_q - f_r = 438.25 \text{ MHz}.
```

3. The modules normally operate at  $V_B = +24 \text{ V}$ , but are able to withstand supply transients up to 30 V.

## **BGY586; BGY587**

### **FEATURES**

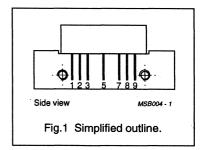
- Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

#### DESCRIPTION

Hybrid amplifier modules for CATV systems operating over a frequency range of 40 to 550 MHz at a voltage supply of 24 V (DC). The BGY586 is intended for use as a pre-amplifier and BGY587 as a final amplifier.

### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output



#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	21.5	-	22.5	dB
		f = 550 MHz	22	_	-	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V				
	BGY586		_	180	200	mA
	BGY587		_	220	240	mA

#### **LIMITING VALUES**

SYMBOL	PARAMETER		MAX.	UNIT
Vi	RF input voltage	_	60	dBmV
T <sub>stg</sub>	storage temperature	<del>-4</del> 0	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

BGY586; BGY587

### **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $V_B$  = 24 V;  $T_{mb}$  = 30 °C;  $Z_S$  =  $Z_L$  = 75  $\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	21.5	_	22.5	dB
		f = 550 MHz	22	-	-	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	1-	1.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz		_ :	±0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	1-	]-	dB
		f = 80 to 160 MHz	19	-	-	dB
		f = 160 to 550 MHz	18	<b>1</b> -	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	1-	-	dB
	·	f = 80 to 160 MHz	19	]-	-	dB
		f = 160 to 550 MHz	18	1-	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	+135	-	+225	deg
СТВ	composite triple beat BGY586 BGY587	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz	_		-53 -57	dB dB
X <sub>mod</sub>	cross modulation	77 channels flat;				
	BGY586	$V_0 = 44 \text{ dBmV};$		_	-55	dB
	BGY587	measured at 55.25 MHz	_	_	-58	dB
CSO	composite second order distortion	77 channels flat;				
	BGY586	V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz	-	-	<b>–50</b>	dB
	BGY587	measured at 546.5 Minz		<u> </u>	-54	dB
d <sub>2</sub>	second order distortion BGY586 BGY587	note 1	_ _	- -	-62 -66	dB dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2				
	BGY586		58.5	-	_	dBmV
	BGY587		61		_	dBmV
F	noise figure	f = 550 MHz				
	BGY586		_	_	6.5	dB
	BGY587		_	_	7	dB
I <sub>tot</sub>	total current consumption (DC)	note 3				
	BGY586		_	180	200	mA
	BGY587		_	220	240	mA

- 1.  $f_p = 55.25 \text{ MHz}$ ;  $V_p = 44 \text{ dBmV}$ ;  $f_q = 493.25 \text{ MHz}$ ;  $V_q = 44 \text{ dBmV}$ ; measured at  $f_p + f_q = 548.5 \text{ MHz}$ .
- 2. Measured according to DIN45004B:  $f_p$  = 540.25 MHz;  $V_p$  =  $V_o$ ;  $f_q$  = 547.25 MHz;  $V_q$  =  $V_o$  –6 dB;  $f_r$  = 549.25 MHz;  $V_r$  =  $V_o$  –6 dB; measured at  $f_p$  +  $f_q$   $f_r$  = 538.25 MHz.
- 3. The modules normally operate at  $V_B = 24 \text{ V}$ , but are able to withstand supply transients up to 30 V.

## **BGY587B**

#### **FEATURES**

- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

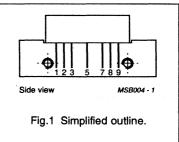
#### DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 550 MHz at a voltage supply of +24 V (DC).

#### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output

## PIN CONFIGURATION



## **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	26.2	27.8	dB
	1	f = 550 MHz	27.5	-	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V	-	340	mA

### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage	-	55	dBmV
T <sub>stg</sub>	storage temperature range	-40	+100	°C
T <sub>mb</sub>	mounting base operating temperature range	-20	+100	င
V <sub>B</sub>	DC supply voltage	-	+28	V

**BGY587B** 

## **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $T_{case}$  = 35 °C;  $Z_{S}$  =  $Z_{L}$  = 75  $\Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	26.2	27.8	dB
		f = 550 MHz	27.5	_	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.5	2.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	± 0.4	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz;	20	-	dB
		f = 80 to 160 MHz;	19		dB
		f = 160 to 550 MHz	18	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz;	20	_	dB
		f = 80 to 160 MHz;	19	_	dB
		f = 160 to 550 MHz	18	1-	dB
СТВ	composite triple beat	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz	_	<b>-57</b>	dB
X <sub>mod</sub>	cross modulation	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	_	-60	dB
CSO	composite second order distortion	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz	-	-57	dB
d <sub>2</sub>	second order distortion	note 1	-	-68	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2	61	_	dBmV
F	noise figure	f = 550 MHz		6.5	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3	-	340	mA

- 1.  $f_p = 55.25 \text{ MHz}; V_p = 44 \text{ dBmV};$   $f_q = 493.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at  $f_p + f_q = 548.5 \text{ MHz}$
- 2. Measured according to DIN45004B;  $f_p = 540.25 \text{ MHz}; V_p = V_o = 66.5 \text{ dBmV}; \\ f_q = 547.25 \text{ MHz}; V_q = V_o -6 \text{ dB}; \\ f_r = 549.25 \text{ MHz}; V_r = V_o -6 \text{ dB}; \\ \text{measured at } f_p + f_q f_r = 538.25 \text{ MHz}$
- 3. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

**BGY588** 

#### **FEATURES**

- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

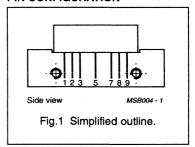
#### **DESCRIPTION**

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 550 MHz at a voltage supply of +24 V (DC) and intended for use as a line-extender.

### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output

#### **PIN CONFIGURATION**



#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	33.5	-	35.5	dB
		f = 550 MHz	35	- '	37	dB
I <sub>tot</sub>	1	DC value; V <sub>B</sub> = +24 V	_	320	340	mA

### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage		60	dBmV
T <sub>stg</sub>	storage temperature range	-40	+100	ů
T <sub>mb</sub>	mounting base operating temperature range	-20	+100	°C

**BGY588** 

#### **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $\rm T_{case}$  = 30 °C;  $\rm Z_{S}$  =  $\rm Z_{L}$  = 75  $\Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	33.5	-	35.5	dB
		f = 550 MHz	35	-	37	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0	-	2.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	-	± 0.4	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz;	20	-	_	dB
		f = 80 to 160 MHz;	19	_	-	dB
		f = 160 to 550 MHz	18	_	<u>-</u>	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz;	20	_	-	dB
		f = 80 to 160 MHz;	19	_	_	dB
		f = 160 to 550 MHz	18	-	-	dB
СТВ	composite triple beat	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz	-	-	-57	dB
X <sub>mod</sub>	cross modulation	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-	-59	dB
CSO	composite second order distortion	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz		_	-57	dB
d <sub>2</sub>	second order distortion	note 1	_	_	-68	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2	61	-	-	dBmV
F	noise figure	f = 550 MHz	-	-	6.5	dB
l <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3	_	320	340	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 493.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 548.5$  MHz
- 2. Measured according to DIN45004B;  $f_p = 540.25 \text{ MHz}; V_p = V_o = 66.5 \text{ dBmV}; f_q = 547.25 \text{ MHz}; V_q = V_o -6 \text{ dB}; f_r = 549.25 \text{ MHz}; V_r = V_o -6 \text{ dB}; measured at <math>f_p + f_q f_r = 538.25 \text{ MHz}$
- 3. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

**BGY588** 

## **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $T_{case}$  = 35 °C;  $Z_{S}$  =  $Z_{L}$  = 75  $\Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	33.5	-	35.5	dB
		f = 450 MHz	35	-	37	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	-	2.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-	-	± 0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz;	20			dB
		f = 80 to 160 MHz;	19	_ ,		dB
		f = 160 to 450 MHz	18	-	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz;	20	-	-	dB
		f = 80 to 160 MHz;	19	-	-	dB
		f = 160 to 450 MHz	18	-	-	dB
CTB	composite triple beat	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	-	-	<b>-61</b>	dB
X <sub>mod</sub>	cross modulation	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	_	_	-59	dB
CSO	composite second order distortion	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 446.5 MHz	-	-	-59	dB
d <sub>2</sub>	second order distortion	note 1	-	-	-72	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2	64	-	=	dBmV
F	noise figure	f = 450 MHz	- 4	-	6	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3	_	320	340	mA

### Notes

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 391.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 446.5$  MHz
- 2. Measured according to DIN45004B;

 $f_p = 440.25 \text{ MHz}; V_p = V_o = 66.5 \text{ dBmV};$ 

 $f_q = 447.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$ 

 $f_r = 449.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$ 

measured at  $f_p + f_q - f_r = 438.25 \text{ MHz}$ 

**BGY681** 

## **FEATURES**

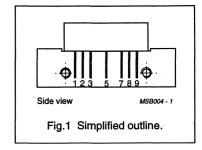
- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

### DESCRIPTION

Hybrid high dynamic range amplifier module designed for CATV systems operating over a frequency range of 40 to 600 MHz operating with a voltage supply of 24 V (DC).

## **PINNING - SOT115C**

PIN	DESCRIPTION			
1	input			
2	common			
3	common			
5	+V <sub>B</sub>			
7	common			
8	common			
9	output			



## **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	12	13	dB
		f = 600 MHz	12.7	_	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	-	240	mA

### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

**BGY681** 

#### **CHARACTERISTICS**

Bandwidth 40 to 600 MHz;  $V_B = 24$  V;  $T_{mb} = 30$  °C;  $Z_S = Z_L = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	12	-	13	dB
		f = 600 MHz	12.7	-	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.7	-	2.2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	<b>—</b>	_	±0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20		-	dB
		f = 80 to 160 MHz	19	_	_	dB
		f = 160 to 600 MHz	18	-		dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	19	-	_	dB
		f = 160 to 600 MHz	18	-	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	-	+45	deg
СТВ	composite triple beat	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 595.25 MHz	-	-	-52	dB
X <sub>mod</sub>	cross modulation	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-	-58	dB
CSO	composite second order distortion	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 596.5 MHz	-	-	-57	dB
d <sub>2</sub>	second order distortion	note 1	<b>—</b>	<b> </b>	-70	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	59.5	-	-	dBmV
F	noise figure	f = 600 MHz	-	-	9.5	dB
I <sub>tot</sub>	total current consumption (DC)	note 3		220	240	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 541.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 596.5$  MHz.
- 2. Measured according to DIN45004B:
  - $$\begin{split} f_p &= 590.25 \text{ MHz; } V_p = V_o; \\ f_q &= 597.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ f_r &= 599.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 588.25 \text{ MHz.} \end{split}$$
- 3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

**BGY681** 

#### **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $V_B = 24 \text{ V}$ ;  $T_{mb} = 30 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	12	-	13	dB
		f = 550 MHz	12.5	-	14.5	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.5	-	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz		_	±0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	19	-	_	dB
		f = 160 to 550 MHz	18	-	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	_	-	dB
		f = 80 to 160 MHz	19	-	_	dB
		f = 160 to 550 MHz	18	-	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	-	+45	deg
СТВ	composite triple beat	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz	_	_	-56	dB
X <sub>mod</sub>	cross modulation	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	_	-	-62	dB
CSO	composite second order distortion	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz	_	-	-59	dB
d <sub>2</sub>	second order distortion	note 1		-	-72	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	61.5	-	-	dBmV
F	noise figure	f = 550 MHz	_	_	9	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	-	220	240	mA

## **Notes**

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 493.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 548.5$  MHz.
- 2. Measured according to DIN45004B:

$$f_p = 540.25 \text{ MHz}; V_p = V_o;$$
  
 $f_q = 547.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$   
 $f_r = 549.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$   
measured at  $f_p + f_q - f_r = 538.25 \text{ MHz}.$ 

**BGY681** 

#### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $V_B = 24$  V;  $T_{mb} = 30$  °C;  $Z_S = Z_L = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	12	_	13	dB
		f = 450 MHz	12.5	-	14	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	-	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-·	-	±0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	19	_		dB
		f = 160 to 450 MHz	18	_	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	_	dB
		f = 80 to 160 MHz	19	_	_	dB
		f = 160 to 450 MHz	18	_	_	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	_	+45	deg
СТВ	composite triple beat	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	-	-	-58	dB
X <sub>mod</sub>	cross modulation	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	_	-	-62	dB
CSO	composite second order distortion	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 446.5 MHz	-	-	-61	dB
d <sub>2</sub>	second order distortion	note 1	-	-	-74	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	64	-	_	dBmV
F	noise figure	f = 450 MHz	-	-	8	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	_	220	240	mA

#### **Notes**

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 391.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 446.5$  MHz.
- 2. Measured according to DIN45004B:

 $f_p = 440.25 \text{ MHz; } V_p = V_o; \\ f_q = 447.25 \text{ MHz; } V_q = V_o -6 \text{ dB; } \\ f_r = 449.25 \text{ MHz; } V_r = V_o -6 \text{ dB; } \\ \text{measured at } f_p + f_q - f_r = 438.25 \text{ MHz.} \\$ 

**BGY683** 

## **FEATURES**

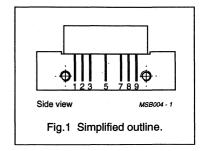
- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

#### **DESCRIPTION**

Hybrid high dynamic range amplifier module for CATV systems operating over a frequency range of 40 to 600 MHz at a voltage supply of +24 V (DC).

#### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output



#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	13.5	14.5	dB
		f = 600 MHz	14.5	-	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	_	240	mA

## **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	ů
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

**BGY683** 

#### **CHARACTERISTICS**

Bandwidth 40 to 600 MHz;  $V_B = 24 \text{ V}$ ;  $T_{case} = 30 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	13.5	14.5	dB
		f = 600 MHz	14.5		dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.2	1.7	dB
FL	flatness of frequency response	f = 40 to 600 MHz	_	±0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 600 MHz	18		dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	1-	dB
		f = 160 to 600 MHz	18	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 595.25 MHz		-55	dB
X <sub>mod</sub>	cross modulation	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-59	dB
CSO	composite second order distortion	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 596.5 MHz	-	-57	dB
d <sub>2</sub>	second order distortion	note 1		-68	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	58	-	dBmV
F	noise figure	f = 600 MHz	-	9	dB
I <sub>tot</sub>	total current consumption (DC)	note 3		240	mA

#### **Notes**

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 541.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 596.5$  MHz.
- 2. Measured according to DIN45004B:

 $\begin{array}{l} f_p = 590.25 \text{ MHz; } V_p = V_o; \\ f_q = 597.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r = 599.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 588.25 \text{ MHz.} \end{array}$ 

**BGY683** 

#### **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $V_B = 24 \text{ V}$ ;  $T_{case} = 30 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	13.5	-	14.5	dB
		f = 550 MHz	14.5	1-	-	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.2	_	1.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	_	±0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	_	dB
		f = 80 to 160 MHz	19	-	<b>I</b> -	dB
		f = 160 to 550 MHz	18	-		dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	_	dB
		f = 80 to 160 MHz	19	-	_	dB
		f = 160 to 550 MHz	18	_	_	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	-	+45	deg
СТВ	composite triple beat	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz	_	-	-59	dB
X <sub>mod</sub>	cross modulation	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	_	-	-61	dB
CSO	composite second order distortion	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz	_	_	-59	dB
d <sub>2</sub>	second order distortion	note 1	_	]-	-72	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	61.5	1-	_	dBmV
F	noise figure	f = 550 MHz	-	_	8.5	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	-	200	240	mA

#### Notes

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 493.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 548.5$  MHz.
- 2. Measured according to DIN45004B:

 $\begin{array}{l} f_p = 440.25 \text{ MHz; } V_p = V_o; \\ f_q = 447.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r = 449.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 438.25 \text{ MHz.} \end{array}$ 

**BGY683** 

#### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $V_B = 24 \text{ V}$ ;  $T_{case} = 30 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	16.5	_	17.5	dB
		f = 450 MHz	17.4	_	18.8	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	_	1.8	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-	-	±0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	_	_	dB
,		f = 80 to 160 MHz	19	_	- "	dB
		f = 160 to 450 MHz	18	- , ,	- "	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	_	dB
		f = 80 to 160 MHz	19	-	-	dB
		f = 160 to 450 MHz	18	-	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	-	+45	deg
СТВ	composite triple beat	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	_	_	-61	dB
X <sub>mod</sub>	cross modulation	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	-	_	-60	dB
CSO	composite second order distortion	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 446.5 MHz	_		-61	dB
d <sub>2</sub>	second order distortion	note 1	-		-75	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	64	-		dBmV
F	noise figure	f = 450 MHz	-	-	7	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	-	200	240	mA

### Notes

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 391.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 446.5$  MHz.
- 2. Measured according to DIN45004B:

$$\begin{array}{l} f_p = 440.25 \text{ MHz; } V_p = V_o; \\ f_q = 447.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r = 449.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 438.25 \text{ MHz.} \end{array}$$

**BGY685** 

## **FEATURES**

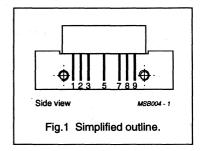
- Excellent linearity
- Extremely low noise
- Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

## **DESCRIPTION**

Hybrid high dynamic range amplifier module designed for applications in CATV systems operating over a frequency range of 40 to 600 MHz operating with a voltage supply of 24 V (DC).

#### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output



## **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	16.5	17.5	dB
		f = 600 MHz	17.8	-	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	-	240	mA

#### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

**BGY685** 

#### **CHARACTERISTICS**

Bandwidth 40 to 600 MHz;  $V_B = 24 \text{ V}$ ;  $T_{mb} = 30 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	16.5	17.5	dB
		f = 600 MHz	17.8	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.5	2.2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	_	±0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	<b>1</b> -	dB
		f = 160 to 600 MHz	18	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	T-	dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 600 MHz	18	_	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 595.25 MHz	-	-55	dB
X <sub>mod</sub>	cross modulation	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	_	-60	dB
CSO	composite second order distortion	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 596.5 MHz	_	-56	dB
d <sub>2</sub>	second order distortion	note 1	-	-68	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	60	T-	dBmV
F	noise figure	f = 600 MHz	-	8.5	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	_	240	mA

#### **Notes**

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 541.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 596.5$  MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 590.25 \text{ MHz; } V_p = V_o; \\ f_q &= 597.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 599.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 588.25 \text{ MHz.} \end{split}$$

**BGY685** 

#### **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $V_B = 24 \text{ V}$ ;  $T_{mb} = 30 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	16.5	-	17.5	dB
		f = 550 MHz	17.6	T-	19	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.5		2	dB
FL	flatness of frequency response	f = 40 to 550 MHz		Ī-	±0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	19	<b> </b> -	-	dB
		f = 160 to 550 MHz	18	-	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	_	dB
		f = 80 to 160 MHz	19	1-	-	dB
		f = 160 to 550 MHz	18	_	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	-	+45	deg
СТВ	composite triple beat	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz	_	_	-59	dB
X <sub>mod</sub>	cross modulation	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-	-62	dB
CSO	composite second order distortion	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz	-	-	-59	dB
d <sub>2</sub>	second order distortion	note 1	_	_	-70	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	61	-	1-	dBmV
F	noise figure	f = 550 MHz	<b>-</b>	-	8	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	-	220	240	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 493.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 548.5$  MHz.
- 2. Measured according to DIN45004B:
  - $\begin{array}{l} f_p = 540.25 \text{ MHz; } V_p = V_o; \\ f_q = 547.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ f_r = 549.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 538.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at  $V_B$  = 24 V, but is able to withstand supply transients up to 30 V.

**BGY685** 

## **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $V_B = 24$  V;  $T_{mb} = 30$  °C;  $Z_S = Z_L = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	16.5	_	17.5	dB
		f = 450 MHz	17.4	-	18.8	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	-	1.8	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	_	±0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	_	_	dB
		f = 80 to 160 MHz	19	-	_	dB
		f = 160 to 450 MHz	18	_	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	19	_	_	dB
		f = 160 to 450 MHz	18	-	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	-	+45	deg
СТВ	composite triple beat	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	·	-	_61 °	dB
X <sub>mod</sub>	cross modulation	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	-	-	-60	dB
CSO	composite second order distortion	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 446.5 MHz	-	-	-61	dB
d <sub>2</sub>	second order distortion	note 1	-	-	-75	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	64	-	-	dBmV
F	noise figure	f = 450 MHz	-		7	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	<b>-</b>	220	240	mA

### Notes

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 391.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 446.5$  MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 440.25 \text{ MHz; } V_p = V_o; \\ f_q &= 447.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 449.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 438.25 \text{ MHz.} \end{split}$$

# BGY685A/04

#### **FEATURES**

- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

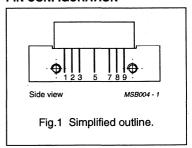
#### **DESCRIPTION**

Special super-high dynamic range amplifier module designed for applications in CATV systems with a bandwidth of 40 to 600 MHz operating with a voltage supply of +24 V (DC).

#### **PINNING - SOT115C**

PIN	DESCRIPTION			
1	input			
2	common			
3	common			
5	+V <sub>B</sub>			
7	common			
8	common			
9	output			

#### PIN CONFIGURATION



## **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$G_p$	power gain	f = 50 MHz;	17.7	-	18.7	dB
,		f = 600 MHz	19	_	-	dB
I <sub>tot</sub>	total current	DC value;		220	240	mA
	consumption	$V_{B} = 24 \text{ V}$			l	1

#### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	ů
T <sub>mb</sub>	mounting base operating temperature	-20	+100	°C

BGY685A/04

#### **CHARACTERISTICS**

Bandwidth 40 to 600 MHz;  $\rm T_{case}$  = 30 °C;  $\rm Z_{S}$  =  $\rm Z_{L}$  = 75  $\Omega.$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	17.7	18.7	dB
		f = 600 MHz	19	- 1	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.5	2.2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	_	±0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	<del>-</del>	dB
		f = 80 to 160 MHz	19		dB
		f = 160 to 600 MHz	18	<b> -</b>	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	19	-	dB
		f = 160 to 600 MHz	18	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	<b>-45</b>	+45	deg
СТВ	composite triple beat	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 595.25 MHz	_	-55	dB
X <sub>mod</sub>	cross modulation	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-60	dB
CSO	composite second order distortion	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 596.5 MHz	_	-56	dB
d <sub>2</sub>	second order distortion	note 1	_	-70	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	60	-	dBmV
F	noise figure	f = 600 MHz	-  -  -  -  -  -  -  -  -  -  -  -  -	8.5	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3	<del>-</del>	240	mA

- $\begin{array}{ll} \text{1.} & \text{f}_{\text{p}} = 55.25 \text{ MHz; V}_{\text{p}} = 44 \text{ dBmV;} \\ & \text{f}_{\text{q}} = 541.25 \text{ MHz; V}_{\text{q}} = 44 \text{ dBmV;} \\ & \text{measured at f}_{\text{p}} + \text{f}_{\text{q}} = 596.5 \text{ MHz.} \end{array}$
- 2.  $f_p = 590.25 \text{ MHz}; V_p = V_o;$   $f_q = 597.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$   $f_r = 599.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$ measured at  $f_p + f_q - f_r = 588.25 \text{ MHz}.$
- 3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

BGY685A/04

## **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $T_{case} = 30 \, ^{\circ}\text{C}$ ;  $Z_{s} = Z_{L} = 75 \, \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	17.7		18.7	dB
		f = 550 MHz	18.8	-	20	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.5	-	2	dB
FL	flatness of frequency response	f = 40 to 550 MHz	_	_	±0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	19	-	-	dB
		f = 160 to 550 MHz	18	-	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	_	-	dB
		f = 80 to 160 MHz	19	-	-	dB
		f = 160 to 550 MHz	18	-	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	-	+45	deg
СТВ	composite triple beat	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz	-		-59	dB
X <sub>mod</sub>	cross modulation	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	_	-62	dB
CSO	composite second order distortion	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz	_	-	-59	dB
d <sub>2</sub>	second order distortion	note 1	_	_	-72	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	61.5	_	_	dBmV
F	noise figure	f = 550 MHz	_	-	8	dB
I <sub>tot</sub>	total current consumption	DC value; $V_B = +24 \text{ V}$ ; note 3	_	220	240	mA

- 1.  $f_p$  = 55.25 MHz;  $V_p$  = 44 dBmV;  $f_q$  = 493.25 MHz;  $V_q$  = 44 dBmV; measured at  $f_p$  +  $f_q$  = 548.5 MHz.
- $\begin{array}{ll} \text{2.} & \text{f}_{\text{p}} = 540.25 \text{ MHz; V}_{\text{p}} = \text{V}_{\text{o}}; \\ \text{f}_{\text{q}} = 547.25 \text{ MHz; V}_{\text{q}} = \text{V}_{\text{o}} 6 \text{ dB;} \\ \text{f}_{\text{r}} = 549.25 \text{ MHz; V}_{\text{r}} = \text{V}_{\text{o}} 6 \text{ dB;} \\ \text{measured at f}_{\text{p}} + \text{f}_{\text{q}} \text{f}_{\text{r}} = 538.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

BGY685A/04

#### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $T_{case} = 30 \,^{\circ}\text{C}$ ;  $Z_{S} = Z_{L} = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	17.7		18.7	dB
		f = 450 MHz	18.6	-	19.8	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	_	1.8	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-		±0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	_ ,	-	dB
11		f = 80 to 160 MHz	19	<b> </b> -	_	dB
		f = 160 to 450 MHz	18		_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	-	dB
		f = 80 to 160 MHz	19	_ , , ,		dB
		f = 160 to 450 MHz	18		_	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	-	+45	deg
СТВ	composite triple beat	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	-	_	-61	dB
X <sub>mod</sub>	cross modulation	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	-	-	-61	dB
CSO	composite second order distortion	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 446.5 MHz	-	-	-61	dB
d <sub>2</sub>	second order distortion	note 1	-	-	-75	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	64	-	_	dBmV
F	noise figure	f = 450 MHz			7.	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3	-	220	240	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 391.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 446.5$  MHz.
- 2.  $f_p = 440.25 \text{ MHz}$ ;  $V_p = V_o$ ;  $f_q = 447.25 \text{ MHz}$ ;  $V_q = V_o 6 \text{ dB}$ ;  $f_r = 449.25 \text{ MHz}$ ;  $V_r = V_o 6 \text{ dB}$ ; measured at  $f_p + f_q f_r = 438.25 \text{ MHz}$ .
- 3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

# **BGY685AD**

## **FEATURES**

- · Excellent linearity
- Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

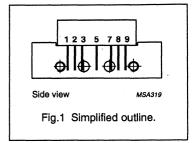
## **DESCRIPTION**

Hybrid high dynamic range cascode amplifier module with Darlington pre-stage crystals for CATV systems operating over a frequency range of 40 to 600 MHz at a voltage supply of +24 V (DC).

#### **PINNING - SOT115J2**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
. 8	common
9	output

### PIN CONFIGURATION



#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	18	19	dB
		f = 600 MHz	18.75	-	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V	-	250	mA

#### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage	-	60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	mounting base operating temperature	-20	+100	°C

# BGY685AD

## **CHARACTERISTICS**

Bandwidth 40 to 600 MHz;  $T_{case} = 30$  °C;  $Z_S = Z_L = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	18	19	dB
		f = 600 MHz	18.75	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.2	2.2	dB ·
FL	flatness of frequency response	f = 40 to 600 MHz	-	± 0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz;	20	_	dB
		f = 80 to 160 MHz;	19	_	dB
		f = 160 to 600 MHz	18	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz;	20	-	dB
		f = 80 to 160 MHz;	19	_	dB
		f = 160 to 600 MHz	18	_	dB
СТВ	composite triple beat	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 595.25 MHz	-	-62	dB
X <sub>mod</sub>	cross modulation	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-58	dB
CSO	composite second order distortion	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 596.5 MHz	_	-60	dB
d <sub>2</sub>	second order distortion	note 1	<b>—</b>	-70	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	62	-	dBmV
F	noise figure	f = 600 MHz	<b>-</b>	8	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V; note 3	-	250	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 541.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 596.5$  MHz.
- 2.  $f_p = 590.25 \text{ MHz}$ ;  $V_p = V_o$ ;  $f_q = 597.25 \text{ MHz}$ ;  $V_q = V_o 6 \text{ dB}$ ;  $f_r = 599.25 \text{ MHz}$ ;  $V_r = V_o 6 \text{ dB}$ ; measured at  $f_p + f_q f_r = 588.25 \text{ MHz}$ .
- 3. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

# BGY685AL

#### **FEATURES**

- Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

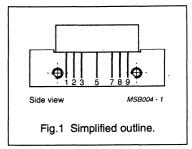
#### **DESCRIPTION**

Hybrid high dynamic range amplifier module designed for applications in CATV systems operating over a frequency range of 40 MHz to 600 MHz operating with a voltage supply of +24 V (DC).

#### **PINNING - SOT115C**

PIN	DESCRIPTION		
1	input		
2	common		
3	common		
5	+V <sub>B</sub>		
7	common		
8	common		
9	output		

## PIN CONFIGURATION



# **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	18	19	dB
		f = 600 MHz	18.5	-	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V	-	250	mA

## **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage	-	60	dBmV
T <sub>stg</sub>	storage temperature range	<del>-4</del> 0	+100	°C
T <sub>mb</sub>	mounting base operating temperature range	-20	+100	°C

Printips Semiconductors Product specification

# Hybrid CATV amplifier module

BGY685AL

#### **CHARACTERISTICS**

Bandwidth 40 to 600 MHz;  $T_{case} = 30 \, ^{\circ}\text{C}$ ;  $Z_{S} = Z_{L} = 75 \, \Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	18	19	dB
		f = 600 MHz	18.5	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.5	2.0	dB
FL	flatness of frequency response	f = 40 to 600 MHz	_	± 0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz;	20	-	dB
		f = 80 to 160 MHz;	19	_	dB
		f = 160 to 600 MHz	18	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz;	20	-	dB
		f = 80 to 160 MHz;	19	_	dB
		f = 160 to 600 MHz	18	-	dB
СТВ	composite triple beat	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 595.25 MHz	-	-56	dB
X <sub>mod</sub>	cross modulation	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	55	dB
CSO	composite second order distortion	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 596.5 MHz	_	-56	dB
d <sub>2</sub>	second order distortion	note 1	_	-70	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2	60	_	dBmV
F	noise figure	f = 600 MHz	_	5.0	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3	_	250	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 541.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 596.5$  MHz
- 2.  $f_p = 590.25$  MHz;  $V_p = V_o$ ;  $f_q = 597.25$  MHz;  $V_q = V_o$  -6 dB;  $f_r = 599.25$  MHz;  $V_r = V_o$  -6 dB; measured at  $f_p + f_q f_r = 588.25$  MHz.
- 3. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

BGY685AL

#### **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $T_{case} = 30$  °C;  $Z_{S} = Z_{L} = 75 \Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	18	19	dB
		f = 550 MHz	18.5	_	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.5	2.0	dB
FL	flatness of frequency response	f = 40 to 550 MHz		± 0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz;	20		dB
		f = 80 to 160 MHz;	19	-	dB
		f = 160 to 550 MHz	18	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz;	20	-	dB
		f = 80 to 160 MHz;	19	_	dB
		f = 160 to 550 MHz	18	_	dB
СТВ	composite triple beat	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz	`	-58	dB
X <sub>mod</sub>	cross modulation	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	_	-56	dB
CSO	composite second order distortion	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz	_	-58	dB
d <sub>2</sub>	second order distortion	note 1	-	-72	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2	61.5	_	dBmV
F	noise figure	f = 550 MHz	_	4.5	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3	-	250	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 493.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 548.5$  MHz
- $\begin{array}{lll} 2. & f_p = 540.25 \text{ MHz; } V_p = V_o; \\ & f_q = 547.25 \text{ MHz; } V_q = V_o -6 \text{ dB;} \\ & f_r = 549.25 \text{ MHz; } V_r = V_o -6 \text{ dB;} \\ & \text{measured at } f_p + f_q f_r = 538.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

BGY685AL

# **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $T_{case} = 30 \, ^{\circ}\text{C}$ ;  $Z_{S} = Z_{L} = 75 \, \Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	18	19	dB
		f = 450 MHz	18.3	-	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.3	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-	± 0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz;	20	_	dB
		f = 80 to 160 MHz;	19	_	dB
		f = 160 to 450 MHz	18	<b>1</b> -	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz;	20	- 1	dB
		f = 80 to 160 MHz;	19	<b>-</b> ,	dB
		f = 160 to 450 MHz	18	_ '	dB
СТВ	composite triple beat	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	_	-58	dB
X <sub>mod</sub>	cross modulation	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	_	-54	dB
CSO	composite second order distortion	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 446.5 MHz	_	-58	dB
d <sub>2</sub>	second order distortion	note 1	-	-70	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2	62.5	-	dBmV
F	noise figure	f = 450 MHz	_	4.5	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3	_	250	mA

- 1.  $f_p = 55.25 \text{ MHz}; V_p = 46 \text{ dBmV};$   $f_q = 391.25 \text{ MHz}; V_q = 46 \text{ dBmV};$ measured at  $f_p + f_q = 446.5 \text{ MHz}$
- 2.  $f_p = 440.25 \text{ MHz}$ ;  $V_p = V_o$ ;  $f_q = 447.25 \text{ MHz}$ ;  $V_q = V_o -6 \text{ dB}$ ;  $f_r = 449.25 \text{ MHz}$ ;  $V_r = V_o -6 \text{ dB}$ ; measured at  $f_p + f_q f_r = 438.25 \text{ MHz}$ .
- 3. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

**BGY687** 

#### **FEATURES**

- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

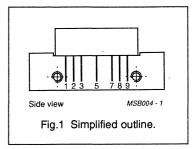
#### **DESCRIPTION**

Hybrid high dynamic range amplifier module designed for CATV systems operating over a frequency range of 40 to 600 MHz at a voltage supply of +24 V (DC).

#### **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output

#### PIN CONFIGURATION



#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	21	22	dB
		f = 600 MHz	22	-	dB
I <sub>tot</sub>	total current consumption		_	240	mA
		$V_B = +24 V$			

## **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage -		60	dBmV
T <sub>stg</sub>	storage temperature range	-40	+100	°C
T <sub>mb</sub>	mounting base operating temperature range	-20	+100	°C

**BGY687** 

## **CHARACTERISTICS**

 $T_{case}$  = 30 °C;  $Z_{S}$  =  $Z_{L}$  = 75  $\Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	21	22	dB
,		f = 600 MHz	22	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.8	2.2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	-	0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz; f = 80 to 160 MHz; f = 160 to 600 MHz	20 19 18	-	dB dB dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz;	20		dB
		f = 80 to 160 MHz;	19	-	dB
		f = 160 to 550 MHz;	18	_	dB
		f = 550 to 600 MHz	16	_	dB
СТВ	composite triple beat	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 595.25 MHz	-	-54	dB
X <sub>mod</sub>	cross modulation	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	_	-54	dB
CSO	composite second order distortion	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 596.25 MHz	=	-52	dB
d <sub>2</sub>	second order distortion	note 1	<b>-</b>	-66	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2	58		dBmV
F	noise figure	f = 600 MHz	-	6.5	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = +24 V; note 3	_	240	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 541.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 596.5$  MHz
- 2.  $f_p = 590.25$  MHz;  $V_p = V_o$ ;  $f_q = 597.25$  MHz;  $V_q = V_o 6$  dB;  $f_r = 599.25$  MHz;  $V_r = V_o 6$  dB; measured at  $f_p + f_q f_r = 588.25$  MHz.
- 3. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

# **BGY687B**

#### **FEATURES**

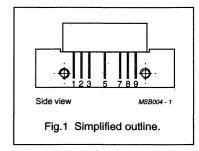
- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

#### **DESCRIPTION**

Hybrid high dynamic range amplifier module designed for CATV systems operating over a frequency range of 40 to 600 MHz at a voltage supply of 24 V (DC).

### **PINNING - SOT115C**

PIN	DESCRIPTION			
1	input			
2	common			
3	common			
5	+V <sub>B</sub>			
7	common			
8	common			
9	output			



## **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	26.2	27.8	dB
		f = 600 MHz	27.8	-	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	-	340	mA

#### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

**BGY687B** 

#### **CHARACTERISTICS**

Bandwidth 40 to 600 MHz;  $V_B = 24 \text{ V}$ ;  $T_{mb} = 35 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	26.2	27.8	dB
		f = 600 MHz	27.8	T-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0.8	2.8	dB
FL	flatness of frequency response	f = 40 to 600 MHz	-	±0.4	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 600 MHz	18	- "	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 600 MHz	18	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 595.25 MHz	-	-53	dB
X <sub>mod</sub>	cross modulation	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-58	dB
CSO	composite second order distortion	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 596.5 MHz	_	-54	dB
d <sub>2</sub>	second order distortion	note 1	-	-66	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	60	-	dBmV
F	noise figure	f = 600 MHz	_	7	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	-	340	mA

### **Notes**

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 541.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 596.5$  MHz.
- 2. Measured according to DIN45004B:

 $\begin{array}{l} f_p = 590.25 \text{ MHz; } V_p = V_o; \\ f_q = 597.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r = 599.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 588.25 \text{ MHz.} \end{array}$ 

BGY687B

## **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $V_B = 24 \text{ V}$ ;  $T_{mb} = 35 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	26.2	27.8	dB
No. of the second		f = 550 MHz	27.5	-	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0.5	2.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	±0.4	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	1-	dB
		f = 80 to 160 MHz	19	1-	dB
		f = 160 to 550 MHz	18	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	1-	dB
		f = 160 to 550 MHz	18		dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz	-	-57	dB
X <sub>mod</sub>	cross modulation	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	_	-60	dB
CSO	composite second order distortion	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz	-	-57	dB
d <sub>2</sub>	second order distortion	note 1	_	-68	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	61	-	dBmV
F	noise figure	f = 550 MHz	_	6.5	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	1-	340	mA.

#### Notes

- 1.  $f_p = 55.25 \text{ MHz}; V_p = 44 \text{ dBmV};$   $f_q = 493.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at  $f_p + f_q = 548.5 \text{ MHz}.$
- 2. Measured according to DIN45004B:

 $f_p = 540.25 \text{ MHz}; V_p = V_o;$   $f_q = 547.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$   $f_r = 549.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$ measured at  $f_p + f_q - f_r = 538.25 \text{ MHz}.$ 

**BGY687B** 

#### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $V_B = 24$  V;  $T_{mb} = 35$  °C;  $Z_S = Z_L = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	26.2	27.8	dB
		f = 450 MHz	27.5	-	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.5	2.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-	±0.2	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 450 MHz	18	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	19	_	dB
		f = 160 to 450 MHz	18	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	$V_0 = 46 \text{ dBmV};$ measured at 445.25 MHz	_	-58	dB
X <sub>mod</sub>	cross modulation	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	_	-58	dB
CSO	composite second order distortion	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 446.5 MHz	_	-60	dB
d <sub>2</sub>	second order distortion	note 1	_	-70	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	64	-	dBmV
F	noise figure	f = 450 MHz	_	6	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	_	340	mA

## Notes

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 391.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 446.5$  MHz.
- 2. Measured according to DIN45004B:

 $f_p = 440.25 \text{ MHz}; V_p = V_o;$   $f_q = 447.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$  $f_r = 449.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$ 

measured at  $f_p + f_q - f_r = 438.25$  MHz.

# **BGY785A**

## **FEATURES**

- · Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

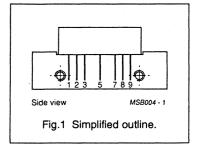
#### DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 750 MHz at a voltage supply of +24 V (DC).

## **PINNING - SOT115C**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output

#### PIN CONFIGURATION



## **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	18	19	dB
		f = 750 MHz	18.5	_	dB
I <sub>tot</sub>	total current consumption	DC value;	-	240	mA
		$V_B = +24 \text{ V}$	-		

## **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
$V_{i}$	RF input voltage	_	60	dBmV
T <sub>stg</sub>	storage temperature range	-40	+100	°C
T <sub>mb</sub>	mounting base operating temperature range	-20	+100	°C

Philips Semiconductors Product specification

# CATV amplifier module

BGY785A

#### **CHARACTERISTICS**

 $T_{case} = 30 \, ^{\circ}C; Z_{S} = Z_{L} = 75 \, \Omega;$  Bandwidth 40 to 750 MHz;

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$G_p$	power gain	f = 50 MHz;	18	19	dB
		f = 750 MHz	18.5	-	dB
SL	slope cable equivalent	f = 40 to 750 MHz	0	2.0	dB
FL	flatness of frequency response	f = 40 to 750 MHz	_	± 0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz;	20	-	dB
		f = 80  to  160  MHz;	18.5	-	dB
		f = 160 to 320 MHz	17	- "	dB
		f = 320 to 640 MHz;	15.5	-	dB
		f = 640 to 750 MHz	14	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz;	20	-	dB
		f = 80 to 160 MHz;	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz;	15.5	- ,	dB
		f = 640 to 750 MHz	14	_	dB
СТВ	composite triple beat	110 chs flat;	_	-53	dB
		$V_{\circ} = 44 \text{ dBmV};$			
		measured at 745.25 MHz			
X <sub>mod</sub>	cross modulation	110 chs flat;	-	<i>–</i> 56	dB
		V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz			
CSO	composite second order	110 chs flat:	_	-53	dB
	distortion	$V_o = 44 \text{ dBmV};$			
		measured at 746.5 MHz			
d <sub>2</sub>	second order distortion	note 1	_	-65	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB note 2	59	<del>-</del> , , , , , , , , , , , , , , , , , , ,	dBmV
F	noise figure	f = 750 MHz	T-	8	dB
I <sub>tot</sub>	total current consumption	DC value; $V_B = +24 \text{ V}$ ; note 3	-	240	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 691.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 746.5$  MHz
- 2.  $f_p = 740.25 \text{ MHz}$ ;  $V_p = V_o$ ;  $f_q = 747.25 \text{ MHz}$ ;  $V_q = V_o -6 \text{ dB}$ ;  $f_r = 749.25 \text{ MHz}$ ;  $V_r = V_o -6 \text{ dB}$ ; measured at  $f_p + f_q f_r = 738.25 \text{ MHz}$ .
- 3. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

BGY785A

#### **CHARACTERISTICS**

Bandwidth 40 to 600 MHz;  $T_{case} = 30$  °C;  $Z_S = Z_L = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>P</sub>	power gain	f = 50 MHz	18	19	dB
		f = 600 MHz	18.5	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 600 MHz	_	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 600 MHz	16	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	T-	dB
		f = 80 to 160 MHz	18.5		dB
		f = 160 to 320 MHz	17		dB
		f = 320 to 600 MHz	16	_	dB
СТВ	composite triple beat	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 595.25 MHz	-	-57	dB
X <sub>mod</sub>	cross modulation	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-59	dB
CSO	composite second order distortion	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 596.5 MHz	-	-58	dB
d <sub>2</sub>	second order distortion	note 1	_	-70	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	61	-	dBmV
F	noise figure	f = 50 MHz	T-	5.5	dB
-		f = 600 MHz	-	7.5	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V; note 3	-	235	mA

#### Notes

- 1.  $f_p = 55.25 \text{ MHz}; V_p = 44 \text{ dBmV};$   $f_q = 541.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at  $f_p + f_q = 596.5 \text{ MHz}.$
- $\begin{array}{ll} 2. & f_p = 590.25 \text{ MHz; } V_p = V_o; \\ f_q = 597.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ f_r = 599.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 588.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

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BGY785A

#### **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $T_{case} = 30$  °C;  $Z_S = Z_L = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>P</sub>	power gain	f = 50 MHz	18	19	dB
		f = 550 MHz	18.5	_	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz		±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	1-	dB
		f = 80 to 160 MHz	18.5	-	dB
:		f = 160 to 320 MHz	17	-	dB
		f = 320 to 550 MHz	16	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	_	dB
÷ 1		f = 160 to 320 MHz	17	-	dB
		f = 320 to 550 MHz	16	_	dB
СТВ	composite triple beat	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz	-	-60	dB
X <sub>mod</sub>	cross modulation	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-60	dB
CSO	composite second order distortion	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz	-	-60	dB
d <sub>2</sub>	second order distortion	note 1		-72	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	62	-	dBmV
F	noise figure	f = 50 MHz	-	5.5	dB
		f = 550 MHz	_	7	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V; note 3		235	mA

- $\begin{array}{ll} \text{1.} & f_p = 55.25 \text{ MHz; } V_p = 44 \text{ dBmV;} \\ & f_q = 493.25 \text{ MHz; } V_q = 44 \text{ dBmV;} \\ & \text{measured at } f_p + f_q = 548.5 \text{ MHz.} \end{array}$
- $\begin{array}{ll} \text{2.} & f_p = 540.25 \text{ MHz; } V_p = V_o; \\ & f_q = 547.25 \text{ MHz; } V_q = V_o 6\text{dB;} \\ & f_r = 549.25 \text{ MHz; } V_r = V_o 6\text{ dB;} \\ & \text{measured at } f_p + f_q f_r = 538.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to +30 V.

**BGY785A** 

## **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $T_{case} = 30$  °C;  $Z_S = Z_L = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>P</sub>	power gain	f = 50 MHz	18	19	dB
		f = 450 MHz	18.5	_	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0.0	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	1-	dB
		f= 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 450 MHz	16	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	dB
	·	f= 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 450 MHz	16	-	dB
СТВ	composite triple beat	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	-	-61	dB
X <sub>mod</sub>	cross modulation	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	-	-60	dB
CSO	composite second order distortion	60 chs flat; V <sub>o</sub> = 44 dBmV; measured at 446.5 MHz	-	-61	dB
d <sub>2</sub>	second order distortion	note 1	-	-75	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	64	1-	dBmV
F	noise figure	f = 50 MHz	-	5.5	dB
		f = 450 MHz		6.5	₫B
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V; note 3	-	235	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 391.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 446.5$  MHz.
- $\begin{array}{ll} \text{2.} & f_p = 440.25 \text{ MHz; } V_p = V_o; \\ f_q = 447.25 \text{ MHz ; } V_q = V_o 6 \text{ dB;} \\ f_r = 449.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 438.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at  $V_B$  = +24 V, but is able to withstand supply transients up to +30 V.

# **BGY785AD**

#### **FEATURES**

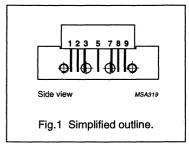
- · Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

## **DESCRIPTION**

Hybrid high dynamic range cascode amplifier module with darlington pre-stage crystals designed for CATV systems operating over a frequency range of 40 to 750 MHz at a voltage supply of 24 V (DC).

#### **PINNING - SOT115J2**

PIN	DESCRIPTION		
1	input		
2	common		
3	common		
5	+V <sub>B</sub>		
7	common		
8	common		
9	output		



## **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 750 MHz	18.5	_	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	_	265	mA

#### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

BGY785AD

#### **CHARACTERISTICS**

Bandwidth 40 to 750 MHz;  $V_B = 24$  V;  $T_{case} = 30$  °C;  $Z_S = Z_L = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 750 MHz	18.5	_	dB
SL	slope cable equivalent	f = 40 to 750 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 750 MHz	-	±0.5	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	1- 1	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	1-	dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 750 MHz	14	1-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	1-	dB
		f = 80 to 160 MHz	18.5	1-	dB
-		f = 160 to 320 MHz	17	-	dB
*		f = 320 to 640 MHz	15.5	_	dB
4		f = 640 to 750 MHz	14	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	135	225	deg
СТВ	composite triple beat	110 channels flat; V <sub>o</sub> = 44 dBmV; measured at 745.25 MHz		-58	dB
X <sub>mod</sub>	cross modulation	110 channels flat; V <sub>g</sub> ≈ 44 dBmV; measured at 55.25 MHz	-	-56	dB
CSO	composite second order distortion	110 channels flat; V <sub>o</sub> = 44 dBmV; measured at 746.25 MHz	-	-58	dB
d <sub>2</sub>	second order distortion	note 1	-	-68	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	61	_	dBmV
F	noise figure	f = 50 MHz	-	5.5	dB
1.0		f = 750 MHz	-	7	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	-	265	mA

#### **Notes**

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 691.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 746.5$  MHz.
- 2. Measured according to DIN45004B:

 $f_p = 740.25 \text{ MHz}; V_p = V_o;$ 

 $f_q = 747.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$ 

 $f_r = 749.25 \text{ MHz} = ; V_r = V_o - 6 \text{ dB};$ 

measured at  $f_p + f_q - f_r = 738.25$  MHz.

## BGY785AD

#### **CHARACTERISTICS**

Bandwidth 40 to 600 MHz;  $V_B = 24 \text{ V}$ ;  $T_{case} = 30 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 600 MHz	18.5	_	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 600 MHz	-	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
i i		f = 160 to 320 MHz	17	1-	dB
		f = 320 to 600 MHz	16	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	1-	dB
-		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	1-	dB
1		f = 320 to 600 MHz	16	_	dB
S <sub>21</sub>	phase response	f = 50 MHz	135	225	deg
СТВ	composite triple beat	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 595.25 MHz	- - -	-64	dB
X <sub>mod</sub>	cross modulation	85 channels flat; $V_0 = 44 \text{ dBmV}$ ; measured at 55.25 MHz	-	-59	dB
CSO	composite second order distortion	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 596.5 MHz	-	-60	dB
d <sub>2</sub>	second order distortion	note 1	-	-70	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	64	_	dBmV
F	noise figure	f = 50 MHz	_	5.5	dB
		f = 600 MHz	-	6	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	_	265	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 541.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 596.5$  MHz.
- 2. Measured according to DIN45004B:
  - $$\begin{split} f_p &= 590.25 \text{ MHz; } V_p = V_o; \\ f_q &= 597.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ f_r &= 599.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 588.25 \text{ MHz.} \end{split}$$
- 3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

BGY785AD

#### **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $V_B = 24 \text{ V}$ ;  $T_{case} = 30 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 550 MHz	18.5	-	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 550 MHz	16	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 550 MHz	16	_	dB
S <sub>21</sub>	phase response	f = 50 MHz	135	225	deg
СТВ	composite triple beat	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz	-	-66	dB
X <sub>mod</sub>	cross modulation	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-61	dB
cso	composite second order distortion	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz	-	-62	dB
d <sub>2</sub>	second order distortion	note 1	-	-72	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	64.5		dBmV
F	noise figure	f = 50 MHz	_	5.5	dB
		f = 550 MHz	-	5.5	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	-	265	mA

- 1.  $f_p = 55.25 \text{ MHz}$ ;  $V_p = 44 \text{ dBmV}$ ;  $f_q = 493.25 \text{ MHz}$ ;  $V_q = 44 \text{ dBmV}$ ; measured at  $f_p + f_q = 548.5 \text{ MHz}$ .
- 2. Measured according to DIN45004B:
  - $f_p = 540.25 \text{ MHz}; V_p = V_o;$   $f_q = 547.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$   $f_r = 549.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$ measured at  $f_p + f_q - f_r = 538.25 \text{ MHz}.$
- 3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

BGY785AD

#### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $V_B = 24$  V;  $T_{case} = 30$  °C;  $Z_S = Z_L = 75$   $\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 450 MHz	18.5	_	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	dB
*		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 450 MHz	16	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	1-	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	1-	dB
		f = 320 to 450 MHz	16	_	dB
S <sub>21</sub>	phase response	f = 50 MHz	135	225	deg
СТВ	composite triple beat	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	_	-66	dB
X <sub>mod</sub>	cross modulation	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	-	-59	dB
CSO	composite second order distortion	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 446.5 MHz	-	-65	dB
d <sub>2</sub>	second order distortion	note 1		-75	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	66	1-	dBmV
F	noise figure	f = 50 MHz	_	5.5	dB
		f = 450 MHz	_	5.5	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	]-	265	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 391.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 446.5$  MHz.
- 2. Measured according to DIN45004B:
  - $\begin{array}{l} f_p = 440.25 \text{ MHz; } V_p = V_o; \\ f_q = 447.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ f_r = 449.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 438.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

**BGY787** 

#### **FEATURES**

- Excellent linearity
- · Extremely low noise
- Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

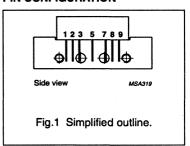
#### **DESCRIPTION**

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 750 MHz at a voltage supply of +24 V (DC).

### **PINNING - SOT115J2**

PIN	DESCRIPTION	
1	input	
2	common	
3	common	
5	+V <sub>B</sub>	
7	common	
8	common	
9	output	

#### **PIN CONFIGURATION**



### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz;	21	22	dB
		f = 750 MHz	21.5		dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V	-	240	mA

#### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	60	dBmV
T <sub>stg</sub>	storage temperature	-40	100	°C
T <sub>mb</sub>	mounting base operating temperature	-20	100	°C

**BGY787** 

#### **CHARACTERISTICS**

Bandwidth 40 to 750 MHz;  $T_{case} = 30$  °C;  $Z_{S} = Z_{L} = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	21	22	dB
		f = 750 MHz	21.5	-	dB
SL	slope cable equivalent	f = 40 to 750 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 750 MHz	-	±0.5	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	1-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	_	dB
		f = 640 to 750 MHz	14	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	_	dB
		f = 640 to 750 MHz	14	_	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	110 chs flat; V <sub>o</sub> = 44 dBmV; measured at 745.25 MHz	-	-51	dB
X <sub>mod</sub>	cross modulation	110 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-51	dB
CSO	composite second order distortion	110 chs flat; V <sub>o</sub> = 44 dBmV; measured at 746.5 MHz	-	-50	dB
d <sub>2</sub>	second order distortion	note 1	_	-63	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	59	-	dBmV
F	noise figure	f = 50 MHz	_	5	dB
		f = 750 MHz	-	8	dB
l <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V; note 3	_	240	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 691.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 746.5$  MHz.
- $\begin{array}{ll} 2. & f_p = 740.25 \text{ MHz; } V_p = V_o; \\ f_q = 747.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ f_r = 749.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 738.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at  $V_B = +24 \text{ V}$  but is able to withstand supply transients up to 30 V.

**BGY787** 

# CATV amplifier module

### CHARACTERISTICS

Bandwidth 40 to 600 MHz;  $T_{case} = 30$  °C;  $Z_{s} = Z_{L} = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	21	22	dB
		f = 600 MHz	21.5	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 600 MHz		±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	dB
	•	f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 600 MHz	16	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
1		f = 320 to 600 MHz	16	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	<b>-45</b>	+45	deg
СТВ	composite triple beat	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 595.25 MHz	_	-56	dB
X <sub>mod</sub>	cross modulation	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz		-53	dB
CSO	composite second order distortion	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 596.5 MHz	_	-53	dB
d <sub>2</sub>	second order distortion	note 1	-	-66	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	59.5	-	dBmV
F	noise figure	f = 50 MHz	-	5	dB
	17	f = 600 MHz	_	7	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V; note 3	-	240	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 541.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 596.5$  MHz.
- 2.  $f_p = 590.25$  MHz;  $V_p = V_o$ ;  $f_q = 597.25$  MHz;  $V_q = V_o 6$  dB;  $f_r = 599.25$  MHz;  $V_r = V_o 6$  dB; measured at  $f_p + f_q f_r = 588.25$  MHz.
- 3. The module normally operates at  $V_B = +24 \text{ V}$  but is able to withstand supply transients up to 30 V.

**BGY787** 

#### **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $T_{\text{case}}$  = 30 °C;  $Z_{\text{S}}$  =  $Z_{\text{L}}$  = 75  $\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	21	22	dB
		f = 550 MHz	21.5	-	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz	_	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 550 MHz	16	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	_	dB
	,	f = 80 to 160 MHz	18.5	- 1	dB
		f = 160 to 320 MHz	17	_	dB
1		f = 320 to 550 MHz	16	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz	-	-59	dB
X <sub>mod</sub>	cross modulation	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	_	-55	dB
CSO	composite second order distortion	77 chs flat; V <sub>o</sub> = 44 dBmV; measured at 548.5 MHz	_	-55	dB
d <sub>2</sub>	second order distortion	note 1	_	-66	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	61.5	-	dBmV
F	noise figure	f = 50 MHz	_	5	dB
		f = 550 MHz	_	6.5	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V; note 3	-	240	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 493.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 548.5$  MHz.
- $\begin{array}{ll} \text{2.} & f_p = 540.25 \text{ MHz; } V_p = V_o; \\ & f_q = 547.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ & f_r = 549.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ & \text{measured at } f_p + f_q f_r = 538.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at  $V_B = +24 \text{ V}$  but is able to withstand supply transients up to 30 V.

**BGY787** 

### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $T_{case}$  = 30 °C;  $Z_{S}$  =  $Z_{L}$  = 75  $\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	21	22	dB
		f = 450 MHz	21.5	_	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	_	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	- "	dB
		f = 160 to 320 MHz	17	<b> -</b>	dB
		f = 320 to 450 MHz	16	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 450 MHz	16	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	<b>-45</b>	+45	deg
СТВ	composite triple beat	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	_	-59	dB
X <sub>mod</sub>	cross modulation	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz		-53	dB
CSO	composite second order distortion	60 chs flat; V <sub>o</sub> = 46 dBmV; measured at 446.5 MHz	-	-60	dB
d <sub>2</sub>	second order distortion	note 1	-	-72	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	64	-	dBmV
F	noise figure	f = 50 MHz	_	5	dB
	the state of the s	f = 450 MHz	_	6	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V; note 3	_	240	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 391.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 446.5$  MHz.
- 2.  $f_p = 440.25$  MHz;  $V_p = V_o$ ;  $f_q = 447.25$  MHz;  $V_q = V_o - 6$  dB;  $f_r = 449.25$  MHz;  $V_r = V_o - 6$  dB; measured at  $f_p + f_q - f_r = 438.25$  MHz.
- 3. The module normally operates at  $V_B = +24 \text{ V}$  but is able to withstand supply transients up to 30 V.

**BGY883** 

### **FEATURES**

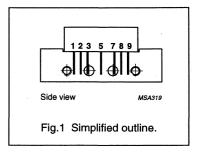
- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

#### **DESCRIPTION**

Hybrid amplifier module designed for CATV systems operating over a frequency range of 40 to 860 MHz at a voltage supply of 24 V (DC).

### **PINNING - SOT115J2**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output



### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	14.5	15.5	dB
		f = 860 MHz	15	_	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	<b> </b> -	235	mA

### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	65	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

**BGY883** 

#### **CHARACTERISTICS**

Bandwidth 40 to 860 MHz;  $V_B = 24$  V;  $T_{case} = 30$  °C;  $Z_S = Z_L = 75$   $\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	ГҮР.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	14.5	_	15.5	dB
		f = 860 MHz	15	_		dB
SL	slope cable equivalent	f = 40 to 860 MHz	0	_	2	dB
FL	flatness of frequency response	f = 40 to 860 MHz	-	-	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	_	_ :	dB
		f = 80 to 160 MHz	18.5	-	-	dB
		f = 160 to 320 MHz	17	-	-	dB
		f = 320 to 640 MHz	15.5		-	dB
		f = 640 to 860 MHz	14	1-	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	1-	-	dB
		f = 80 to 160 MHz	18.5	-	-	dB
		f = 160 to 320 MHz	17	-	-	dB
		f = 320 to 640 MHz	15.5	-	_	dB
		f = 640 to 860 MHz	14	1-	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	_	+45	deg
СТВ	composite triple beat	49 channels flat; V <sub>o</sub> = 44 dBmV; measured at 859.25 MHz		-	-61	dB
X <sub>mod</sub>	cross modulation	49 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	_	-61	dB
CSO	composite second order distortion	49 channels flat; V <sub>o</sub> = 44 dBmV; measured at 860.5 MHz	_	-	-61	dB
d <sub>2</sub>	second order distortion	note 1	_	- 1	68	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	58.5	60	-	dBmV
F	noise figure	f = 50 MHz	1-	1-	6	dB
		f = 860 MHz	_	_	8.5	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	_	_	235	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 805.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 860.5$  MHz.
- 2. Measured according to DIN45004B:
  - $$\begin{split} f_p &= 851.25 \text{ MHz; } V_p = V_o; \\ f_q &= 858.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ f_r &= 860.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 849.25 \text{ MHz.} \end{split}$$
- 3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

## **BGY885A**

#### **FEATURES**

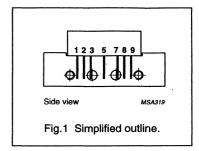
- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

#### DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 860 MHz at a voltage supply of 24 V (DC).

### **PINNING - SOT115J2**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output



#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 860 MHz	18.5	-	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	_	240	mA

#### **LIMITING VALUES**

SYMBOL	PARAMETER		MAX.	UNIT
Vi	RF input voltage	_	60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

## BGY885A

#### **CHARACTERISTICS**

Bandwidth 40 to 860 MHz;  $V_B = 24$  V;  $T_{mb} = 30$  °C;  $Z_S = Z_L = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	-	19	dB
		f = 860 MHz	18.5	_	<u>-</u>	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0	_	2	dB
FL	flatness of frequency response	f = 40 to 860 MHz	_	_	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	<u>.</u>	dB
		f = 80 to 160 MHz	18.5	-	_	dB
		f = 160 to 320 MHz	17	-	_	dB
		f = 320 to 640 MHz	15.5	-	-	dB
		f = 640 to 860 MHz	14	-	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	_	dB
		f = 80 to 160 MHz	18.5	_	-	dB
		f = 160 to 320 MHz	17	_ *	_	dB
		f = 320 to 640 MHz	15.5	-	_	dB
		f = 640 to 860 MHz	14	-	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	_ '	+45	deg
СТВ	composite triple beat	49 channels flat; V <sub>o</sub> = 44 dBmV; measured at 859.25 MHz	_	_	<del>-</del> 61	dB
X <sub>mod</sub>	cross modulation	49 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	_ * * * * * * * * * * * * * * * * * * *	_	61	dB
CSO	composite second order distortion	49 channels flat; V <sub>o</sub> = 44 dBmV; measured at 860.5 MHz	-	_	<del>-</del> 61	dB
d <sub>2</sub>	second order distortion	note 1	-	-	-70	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	58	60	-	dBmV
F	noise figure	f = 860 MHz	_	-	8	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	_	<u> </u>	240	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 805.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 860.5$  MHz.
- 2. Measured according to DIN45004B:
  - $\begin{array}{l} f_p = 851.25 \text{ MHz; } V_p = V_o; \\ f_q = 858.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ f_r = 860.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 849.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

BGY885A

#### **CHARACTERISTICS**

Bandwidth 40 to 750 MHz;  $V_B = 24$  V;  $T_{mb} = 30$  °C;  $Z_S = Z_L = 75$   $\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 750 MHz	18.5	÷	dB
SL	slope cable equivalent	f = 40 to 750 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 750 MHz	_	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 750 MHz	14	1-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	<b> </b> -	dB
-		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 750 MHz	14	T-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	110 channels flat; V <sub>o</sub> = 44 dBmV; measured at 745.25 MHz	-	-53	dB
X <sub>mod</sub>	cross modulation	110 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-57	dB
CSO	composite second order distortion	110 channels flat; V <sub>o</sub> = 44 dBmV; measured at 746.5 MHz		-53	dB
$d_2$	second order distortion	note 1	<b>1</b> -	-65	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	59	_	dBmV
F	noise figure	f = 50 MHz	-	5.5	dB
		f = 750 MHz	-	9	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	<b>-</b>	235	mA

#### Notes

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 691.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 746.5$  MHz.
- 2. Measured according to DIN45004B:

```
\begin{split} f_p &= 740.25 \text{ MHz; } V_p = V_o; \\ f_q &= 747.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 749.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 738.25 \text{ MHz.} \end{split}
```

BGY885A

#### **CHARACTERISTICS**

Bandwidth 40 to 600 MHz;  $V_B = 24 \text{ V}$ ;  $T_{mb} = 30 \text{ °C}$ ;  $Z_S = Z_L = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 600 MHz	18.5	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 600 MHz	<b> </b> -	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 600 MHz	16	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	_	dB
-		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 600 MHz	16	_	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 595.25 MHz	_	-57	dB
X <sub>mod</sub>	cross modulation	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	59	dB
CSO	composite second order distortion	85 channels flat; $V_0 = 44 \text{ dBmV}$ ; measured at 596.5 MHz	_	-58	dB
d <sub>2</sub>	second order distortion	note 1		-70	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	61	-	dBmV
F	noise figure	f = 50 MHz		5.5	dB
		f = 600 MHz	_	7.5	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	-	235	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 541.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 596.5$  MHz.
- 2. Measured according to DIN45004B:
  - $\begin{array}{l} f_p = 590.25 \text{ MHz; } V_p = V_o; \\ f_q = 597.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ f_r = 599.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 588.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

BGY885A

### **CHARACTERISTICS**

Bandwidth 40 to 550 MHz;  $V_B = 24$  V;  $T_{mb} = 30$  °C;  $Z_S = Z_L = 75$   $\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	18	19	dB
		f = 550 MHz	18.5	-	dB
SL	slope cable equivalent	f = 40 to 550 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 550 MHz	-	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	<b> </b> -	dB
		f = 320 to 550 MHz	16	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	-	dB
4.4		f = 320 to 550 MHz	16	_	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 547.25 MHz	_	-60	dB
X <sub>mod</sub>	cross modulation	77 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	_	-60	dB
CSO	composite second order distortion	77 channels flat; $V_0 = 44 \text{ dBmV}$ ; measured at 548.5 MHz	-	-60	dB
d <sub>2</sub>	second order distortion	note 1	ļ-	-72	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	62	_	dBmV
F	noise figure	f = 50 MHz	_	5.5	dB
		f = 550 MHz	1-	7	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	_	235	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 493.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 548.5$  MHz.
- 2. Measured according to DIN45004B:
  - $\begin{array}{l} f_p = 540.25 \text{ MHz; } V_p = V_o; \\ f_q = 547.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ f_r = 549.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 538.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

BGY885A

### **CHARACTERISTICS**

Bandwidth 40 to 450 MHz;  $V_B = 24$  V;  $T_{mb} = 30$  °C;  $Z_S = Z_L = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	18	19	dB
		f = 450 MHz	18.5	-	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0	1.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	-	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5		dB
		f = 160 to 320 MHz	17	- , ,	dB
		f = 320 to 450 MHz	16	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 450 MHz	16	1-	dB
S <sub>21</sub>	phase response	f = 50 MHz	-45	+45	deg
СТВ	composite triple beat	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 445.25 MHz	_	-61	dB
X <sub>mod</sub>	cross modulation	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 55.25 MHz	-	-60	dB
CSO	composite second order distortion	60 channels flat; V <sub>o</sub> = 46 dBmV; measured at 446.5 MHz	_	-61	dB
$d_2$	second order distortion	note 1		-75	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	64	- 2 2 2	dBmV
F	noise figure	f = 50 MHz	-	5.5	dB
		f = 450 MHz	-	6.5	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	1-	235	mA

### Notes

- 1.  $f_p = 55.25$  MHz;  $V_p = 46$  dBmV;  $f_q = 391.25$  MHz;  $V_q = 46$  dBmV; measured at  $f_p + f_q = 446.5$  MHz.
- 2. Measured according to DIN45004B:

 $f_p = 440.25 \text{ MHz}; V_p = V_o;$ 

 $f_q = 447.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$ 

 $f_r = 449.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$ 

measured at  $f_p + f_q - f_r = 438.25$  MHz.

**BGY885B** 

### **FEATURES**

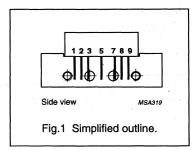
- Excellent linearity
- · Extremely low noise
- · Silicon nitride passivation
- · Rugged construction
- Gold metallization ensures excellent reliability.

### **DESCRIPTION**

The BGY885B is a hybrid amplifier module designed for CATV systems operating over a frequency range of 40 to 860 MHz at a voltage supply of 24 V (DC).

#### **PINNING - SOT115J2**

PIN	DESCRIPTION		
1	input		
2	common		
3	common		
5	+V <sub>B</sub>		
7	common		
8	common		
9	output		



#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	19.5	20.5	dB
		f = 860 MHz	20	-	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	_	235	mA

### LIMITING VALUES

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

BGY885B

### **CHARACTERISTICS**

Bandwidth 40 to 860 MHz;  $V_B = 24$  V;  $T_{mb} = 35$  °C;  $Z_S = Z_L = 75 \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	19.5	20.5	dB
		f = 860 MHz	20	-	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0	2	dB
FL	flatness of frequency response	f = 40 to 860 MHz	_	±0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	<del>-</del>	dB
		f = 80 to 160 MHz	18.5		dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 860 MHz	14	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	-	₫B
		f = 640 to 860 MHz	14	-	dB
СТВ	composite triple beat	49 channels flat; V <sub>o</sub> = 44 dBmV; measured at 859.25 MHz	-	-60	dB
CSO	composite second order distortion	49 channels flat; V <sub>o</sub> = 44 dBmV; measured at 860.5 MHz	_	-60	dB
d <sub>2</sub>	second order distortion	note 1	_	-68	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	59	_	dBmV
F	noise figure	f = 860 MHz	_	7.5	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	-	235	mA

#### **Notes**

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 805.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 860.5$  MHz.
- 2. Measured according to DIN45004B:

 $f_p = 851.25 \text{ MHz}; V_p = V_o;$   $f_q = 858.25 \text{ MHz}; V_q = V_o -6 \text{ dB};$   $f_r = 860.25 \text{ MHz}; V_r = V_o -6 \text{ dB};$ measured at  $f_p + f_q - f_r = 849.25 \text{ MHz}.$ 

**BGY887B** 

#### **FEATURES**

- Excellent linearity
- · Extremely low noise
- · High gain
- · Excellent return loss properties.

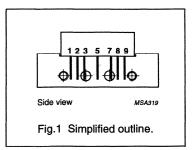
### **DESCRIPTION**

The BGY887B is a hybrid amplifier module designed for CATV systems operating over a frequency range of 40 to 860 MHz at a voltage supply of 24 V (DC).

This high gain module consists of two cascaded stages, both in cascode configuration. It is intended for use as a single-module line extender.

### **PINNING - SOT115J2**

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output



#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	28.5	29.5	dB
		f = 860 MHz	29	_	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	-	340	mA

#### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	_	60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

BGY887B

#### **CHARACTERISTICS**

Bandwidth 40 to 860 MHz;  $V_B = 24 \text{ V}$ ;  $T_{mb} = 30 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	28.5	29.5	dB
		f = 860 MHz	29		dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.5	2.5	dB
FL	flatness of frequency response	f = 40 to 860 MHz	_	±0.5	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20		dB
		f = 80 to 160 MHz	18.5	1-	dB
		f = 160 to 320 MHz	17	-	dB
~		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 860 MHz	14	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	1-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	<b>-</b>	dB
		f = 640 to 860 MHz	14		dB
СТВ	composite triple beat	49 channels flat; V <sub>o</sub> = 44 dBmV; measured at 859.25 MHz	-	-60	dB
X <sub>mod</sub>	cross modulation	49 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	_	-60	dB
CSO	composite second order distortion	49 channels flat; V <sub>o</sub> = 44 dBmV; measured at 860.5 MHz		-60	dB
d <sub>2</sub>	second order distortion	note 1	<u> </u>	-70	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	58.5	_	dBmV
F	noise figure	f = 860 MHz	. <del>-</del> :	7.5	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	- 10,0	340	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 805.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 860.5$  MHz.
- 2. Measured according to DIN45004B:
  - $\begin{array}{l} f_p = 851.25 \text{ MHz}; \ V_p = V_o; \\ f_q = 858.25 \text{ MHz}; \ V_q = V_o 6 \text{ dB}; \\ f_r = 860.25 \text{ MHz}; \ V_r = V_o 6 \text{ dB}; \\ \text{measured at } f_p + f_q f_r = 849.25 \text{ MHz}. \end{array}$
- 3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

## **BGY887B**

#### **CHARACTERISTICS**

Bandwidth 40 to 860 MHz;  $V_B = 24$  V;  $T_{mb} = 30$  °C;  $Z_S = Z_L = 75$   $\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	28.5	29.5	dB
		f = 860 MHz	29	<b> </b>	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.5	2.5	dB
FL	flatness of frequency response	f = 40 to 860 MHz	T-	±0.5	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	_	dB
		f = 640 to 860 MHz	14	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	T-	dB
		f = 640 to 860 MHz	14	-	dB
СТВ	composite triple beat	129 channels flat; V <sub>o</sub> = 44 dBmV; measured at 859.25 MHz	-	-46	dB
X <sub>mod</sub>	cross modulation	129 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	1-	-52	dB
CSO	composite second order distortion	129 channels flat; V <sub>o</sub> = 44 dBmV; measured at 860.5 MHz	-	-53	dB
d <sub>2</sub>	second order distortion	note 1		70	dB
Vo	output voltage	$d_{im} = -60 \text{ dB}$ ; note 2	58.5	-	dBmV
F	noise figure	f = 860 MHz		7.5	dB
I <sub>tot</sub>	total current consumption (DC)	note 3		340	mA

### **Notes**

1.  $f_p = 55.25 \text{ MHz}$ ;  $V_p = 44 \text{ dBmV}$ ;  $f_q = 805.25 \text{ MHz}; V_q = 44 \text{ dBmV};$ measured at  $f_p + f_q = 860.5 \text{ MHz}.$ 

2. Measured according to DIN45004B:

 $f_p = 851.25 \text{ MHz}; V_p = V_o;$  $f_a = 858.25 \text{ MHz}; V_a = V_o - 6 \text{ dB};$ 

 $f_r = 860.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$ 

measured at  $f_p + f_q - f_r = 849.25$  MHz.

**BGY887B** 

#### **CHARACTERISTICS**

Bandwidth 40 to 750 MHz;  $V_B$  = 24 V;  $T_{mb}$  = 30 °C;  $Z_S$  =  $Z_L$  = 75  $\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	28.5	29.5	dB
		f = 750 MHz	29	_	dB
SL	slope cable equivalent	f = 40 to 750 MHz	0.2	2.2	dB
FL	flatness of frequency response	f = 40 to 750 MHz	_	±0.45	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 750 MHz	14	1-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	1-	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	<b>1</b> -	dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 750 MHz	14	-	dB
СТВ	composite triple beat	110 channels flat; V <sub>o</sub> = 44 dBmV; measured at 745.25 MHz	-	-50	dB
X <sub>mod</sub>	cross modulation	110 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-54	dB
CSO	composite second order distortion	110 channels flat; V <sub>o</sub> = 44 dBmV; measured at 746.5 MHz	_ '	-56	dB
d <sub>2</sub>	second order distortion	note 1	-	-70	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	59	_	dBmV
F	noise figure	f = 750 MHz	-	7	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	_	340	mA

#### **Notes**

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 691.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 746.5$  MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 740.25 \text{ MHz; } V_p = V_o; \\ f_q &= 747.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 749.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 738.25 \text{ MHz.} \end{split}$$

BGY887B

#### **CHARACTERISTICS**

Bandwidth 40 to 600 MHz;  $V_B = 24 \text{ V}$ ;  $T_{mb} = 30 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	28.5	29.5	dB
		f = 600 MHz	29	-	dB
SL	slope cable equivalent	f = 40 to 600 MHz	-	2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	-	±0.35	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 600 MHz	16	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	- "	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 600 MHz	16	-	dB
СТВ	composite triple beat	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 595.25 MHz	-	-55	dB
X <sub>mod</sub>	cross modulation	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	_	-56	dB
CSO	composite second order distortion	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 596.5 MHz	-	-60	dB
d <sub>2</sub>	second order distortion	note 1	-	-72	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	61	_	dBmV
F	noise figure	f = 600 MHz	-	6.5	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	-	340	mA

### Notes

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 541.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 596.5$  MHz.
- 2. Measured according to DIN45004B:

```
f_p = 590.25 \text{ MHz}; V_p = V_o;

f_q = 597.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};

f_r = 599.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};

measured at f_p + f_q - f_r = 588.25 \text{ MHz}.
```

# Optical receiver module

## **BGY887BO**

#### **FEATURES**

- Excellent linearity
- · Extremely low noise
- Excellent flatness
- Standard CATV outline
- · Rugged construction
- Gold metallization ensures excellent reliability.

#### DESCRIPTION

Hybrid high dynamic range optical receiver module for CATV systems operating over a frequency range of 40 to 860 MHz at a voltage supply of +24 V (DC). The module contains a monomode optical input suitable for wavelengths from 1290 to 1600 nm, a terminal to monitor the pin diode current and an electrical output with an impedance of 75  $\Omega$ .

#### PINNING - SOT115M2

PIN	DESCRIPTION
1	monitor current
2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output

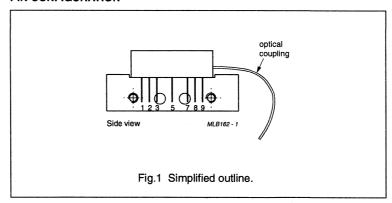
#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
f	frequency range		40	860	MHz
S <sub>22</sub>	output return losses	f = 40 to 860 MHz	12	_	dB
	optical input return losses		40	_	dB
d <sub>2</sub>	second order distortion		-	-70	dBc
F	equivalent noise input		_	7	p <b>A</b> /√Hz
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V	-	250	mA

#### CAUTION

The device is supplied in an antistatic package. The gate-source input must be protected against static charge during transport and handling.

#### PIN CONFIGURATION



#### LIMITING VALUES

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
f	frequency range		40	860	MHz
T <sub>stg</sub>	storage temperature		-40	+85	°C
T <sub>mb</sub>	mounting base operating temperature		-20	+85	°C
P <sub>IN</sub>	optical input power	continuous	_	2	mW
ESD	ESD sensitivity	human body model; R = 1.5 kΩ; C = 100 pF	500	_	V

# Optical receiver module

**BGY887BO** 

### **HANDLING**

Fibreglass optical coupling: maximum tensile strength = 5 N; minimum bending radius = 35 mm.

#### **CHARACTERISTICS**

Bandwidth 40 to 860 MHz;  $T_{mb}$  = 30 °C;  $Z_S$  =  $Z_L$  = 75  $\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
S	responsivity	$\lambda = 1300 \text{ nm}$	1000	-	V/W
FL	flatness of frequency response		<b> </b> -	±0.5	dB
S <sub>22</sub>	output return losses	f = 40 to 860 MHz	11	-	dB
	optical input return losses		40	_	dB
d <sub>2</sub>	second order distortion	note 1	1-	-70	dBc
$d_3$	third order distortion	note 2	1-	-80	dBc
F	equivalent noise input	f <sub>1</sub> = 40 MHz	1-	7	pA/√Hz
$s_{\lambda}$	spectral sensitivity	<sub>λ</sub> = 1310 ±20 nm	0.85	T-	A/W
		$_{\lambda}$ = 1550 ±20 nm	0.9	- '	A/W
λ	optical wavelength		1290	1600	nm
L	length of pigtail	fibre: SM type; 9/125 μm	1	1-	m
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	- 1	250	mA

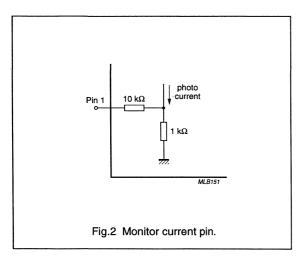
#### Notes

Two laser test, each laser with a 40% modulation index;

$$f_p = 135 \text{ MHz}; P_p = 0.5 \text{ mW};$$
  
 $f_q = 189.25 \text{ MHz}; P_q = 0.5 \text{ mW};$   
measured at  $f_p + f_q = 324.25 \text{ MHz}.$ 

2. Three laser test, each laser with a 40% modulation index;

$$f_p$$
 = 326.25 MHz;  $P_p$  = 0.33 mW;  $f_q$  = 333.25 MHz;  $P_q$  = 0.33 mW;  $f_r$  = 335.25 MHz;  $P_q$  = 0.33 mW; measured at  $f_p$ +  $f_q$  -  $f_r$  = 324.25 MHz.



**BGY888** 

#### **FEATURES**

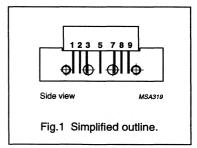
- Excellent linearity
- · Extremely low noise
- · High gain
- · Excellent return loss properties.

#### **APPLICATIONS**

 Intended for use as a single module line extender.

#### **PINNING - SOT115J2**

PIN	DESCRIPTION
1	input
, 2	common
3	common
5	+V <sub>B</sub>
7	common
8	common
9	output



### **DESCRIPTION**

Hybrid high dynamic range amplifier module designed for CATV systems operating over a frequency range of 40 to 860 MHz at a voltage supply of 24 V (DC).

This high gain module consists of two cascaded stages, both in cascode configuration.

#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	33.5	34.5	dB
		f = 860 MHz	34	-	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	-	340	mA

### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
Vi	RF input voltage	-	55	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

**BGY888** 

### **CHARACTERISTICS**

Bandwidth 40 to 860 MHz;  $V_B = 24$  V;  $T_{case} = 30$  °C;  $Z_S = Z_L = 75$   $\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	33.5	34.5	dB
		f = 860 MHz	34	1-	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.5	2.5	dB
FL	flatness of frequency response	f = 40 to 860 MHz	T-	±0.5	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	<b> </b> -	dB
		f = 80 to 160 MHz	18.5	-	dB
	·	f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	_	dB
		f = 640 to 860 MHz	14	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	1-	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17		dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 860 MHz	14	_	dB
S <sub>21</sub>	phase response	f = 50 MHz	135	225	deg
СТВ	composite triple beat	49 channels flat; V <sub>o</sub> = 44 dBmV; measured at 859.25 MHz	-	-60	dB
X <sub>mod</sub>	cross modulation	49 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-59	dB
CSO	composite second order distortion	49 channels flat; V <sub>o</sub> = 44 dBmV; measured at 860.5 MHz	-	-55	dB
d <sub>2</sub>	second order distortion	note 1	-	65	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	58	1-	dBmV
F	noise figure	f = 50 MHz	-	5	dB
		f = 860 MHz	_	7.5	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	_	340	mA

#### Notes

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 805.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 860.5$  MHz.
- 2. Measured according to DIN45004B:

 $f_p = 851.25 \text{ MHz}; V_p = V_o;$ 

 $f_q = 858.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};$ 

 $f_r = 860.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};$ 

measured at  $f_p + f_q - f_r = 849.25$  MHz.

**BGY888** 

### **CHARACTERISTICS**

Bandwidth 40 to 860 MHz;  $V_B = 24 \text{ V}$ ;  $T_{case} = 30 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	33.5	34.5	dB
		f = 860 MHz	34	-	dB
SL	slope cable equivalent	f = 40 to 860 MHz	0.5	2.5	dB
FL	flatness of frequency response	f = 40 to 860 MHz	-	±0.5	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 860 MHz	14	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	1-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 640 MHz	15.5	-	dB
	0	f = 640 to 860 MHz	14	<b> </b> -	dB
S <sub>21</sub>	phase response	f = 50 MHz	135	225	deg
СТВ	composite triple beat	129 channels flat; V <sub>o</sub> = 44 dBmV; measured at 859.25 MHz	_	-46	dB
X <sub>mod</sub>	cross modulation	129 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	_	-50	dB
CSO	composite second order distortion	129 channels flat; V <sub>o</sub> = 44 dBmV; measured at 860.5 MHz		-48	dB
d <sub>2</sub>	second order distortion	note 1	_	-65	dB
V <sub>o</sub>	output voltage	d <sub>im</sub> = -60 dB; note 2	58	-	dBmV
F	noise figure	f = 860 MHz	_	7.5	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	_	340	mA

#### Notes

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 805.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 860.5$  MHz.
- 2. Measured according to DIN45004B:

```
f_p = 851.25 \text{ MHz}; V_p = V_o;

f_q = 858.25 \text{ MHz}; V_q = V_o - 6 \text{ dB};

f_r = 860.25 \text{ MHz}; V_r = V_o - 6 \text{ dB};

measured at f_p + f_q - f_r = 849.25 \text{ MHz}.
```

**BGY888** 

#### **CHARACTERISTICS**

Bandwidth 40 to 750 MHz;  $V_B = 24 \text{ V}$ ;  $T_{case} = 30 \,^{\circ}\text{C}$ ;  $Z_S = Z_L = 75 \,\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	33.5	34.5	dB
•		f = 750 MHz	34	]- ·	dB
SL	slope cable equivalent	f = 40 to 750 MHz	0.2	2.2	dB
FL	flatness of frequency response	f = 40 to 750 MHz	-	±0.45	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	_	dB
·		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	T-	dB
		f = 320 to 640 MHz	15.5	-	dB
		f = 640 to 750 MHz	14	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	_	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 640 MHz	15.5	_	dB
		f = 640 to 750 MHz	14	T-	dB
S <sub>21</sub>	phase response	f = 50 MHz	135	225	deg
СТВ	composite triple beat	110 channels flat; V <sub>o</sub> = 44 dBmV; measured at 745.25 MHz	-	<b>-50</b>	dB
X <sub>mod</sub>	cross modulation	110 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	<b>-51</b>	dB
CSO	composite second order distortion	110 channels flat; V <sub>o</sub> = 44 dBmV; measured at 746.5 MHz	_	-53	dB
d <sub>2</sub>	second order distortion	note 1	_	-65	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	59	_	dBmV
F	noise figure	f = 750 MHz	_	7	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	-	340	mA

#### **Notes**

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 691.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 746.5$  MHz.
- 2. Measured according to DIN45004B:

$$\begin{split} f_p &= 740.25 \text{ MHz; } V_p = V_o; \\ f_q &= 747.25 \text{ MHz; } V_q = V_o - 6 \text{ dB;} \\ f_r &= 749.25 \text{ MHz; } V_r = V_o - 6 \text{ dB;} \\ \text{measured at } f_p + f_q - f_r = 738.25 \text{ MHz.} \end{split}$$

**BGY888** 

### **CHARACTERISTICS**

Bandwidth 40 to 600 MHz;  $V_B$  = 24 V;  $T_{case}$  = 30 °C;  $Z_S$  =  $Z_L$  = 75  $\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 50 MHz	33.5	34.5	dB
		f = 600 MHz	34		dB
SL	slope cable equivalent	f = 40 to 600 MHz	0	2	dB
FL	flatness of frequency response	f = 40 to 600 MHz	-	±0.35	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	<b>—</b>	dB
-11		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	-	dB
		f = 320 to 600 MHz	16	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	_	dB
		f = 80 to 160 MHz	18.5	-	dB
		f = 160 to 320 MHz	17	_	dB
		f = 320 to 600 MHz	16	-	dB
S <sub>21</sub>	phase response	f = 50 MHz	135	225	deg
СТВ	composite triple beat	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 595.25 MHz	-	-55	dB
X <sub>mod</sub>	cross modulation	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	_	-54	dB
CSO	composite second order distortion	85 channels flat; V <sub>o</sub> = 44 dBmV; measured at 596.5 MHz	-	-56	dB
d <sub>2</sub>	second order distortion	note 1	-	-68	dB
Vo	output voltage	d <sub>im</sub> = -60 dB; note 2	61	_	dBmV
F	noise figure	f = 600 MHz	-	6.5	dB
I <sub>tot</sub>	total current consumption (DC)	note 3	_	340	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 541.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 596.5$  MHz.
- 2. Measured according to DIN45004B:
  - $\begin{array}{l} f_p = 590.25 \text{ MHz; } V_p = V_o; \\ f_q = 597.25 \text{ MHz; } V_q = V_o 6 \text{ dB;} \\ f_r = 599.25 \text{ MHz; } V_r = V_o 6 \text{ dB;} \\ \text{measured at } f_p + f_q f_r = 588.25 \text{ MHz.} \end{array}$
- 3. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

## **BGY1085A**

### **FEATURES**

- Excellent linearity
- Extremely low noise
- · Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

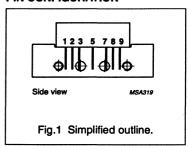
#### DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 1000 MHz at a voltage supply of +24 V (DC).

### **PINNING - SOT115J2**

PIN	DESCRIPTION		
1	input		
2	common		
3	common		
5	+V <sub>B</sub>		
7	common		
8	common		
9	output		

### **PIN CONFIGURATION**



### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	18	19	dB
		f = 1000 MHz	18.5	l- "	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V	-	240	mA

#### **LIMITING VALUES**

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage	-	60	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	mounting base operating temperature	-20	+100	°C

**BGY1085A** 

**CHARACTERISTICS** 

Bandwidth 40 to 1000 MHz;  $T_{case} = 30$  °C;  $Z_{S} = Z_{L} = 75~\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 50 MHz	18	-	19	dB
		f = 1000 MHz	18.5	-	-	dB
SL	slope cable equivalent	f = 40 to 1000 MHz	0	-	2	dB
FL ·	flatness of frequency response	f = 40 to 1000 MHz	T-	<b>-</b>	± 0.3	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	20	-	1-	dB
		f = 80 to 160 MHz	18.5	-	-	dB
		f = 160 to 320 MHz	17	-	-	dB
		f = 320 to 640 MHz	15.5	-	1	dB
		f = 640 to 1000 MHz	14	1-	_	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	20	]-	-	dB
		f = 80 to 160 MHz	18.5	-	-	dB
		f = 160 to 320 MHz	17	-	-	dB
		f = 320 to 640 MHz	15.5	-"	-	dB
		f = 640 to 1000 MHz	14		_	dB
СТВ	composite triple beat	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 595.25 MHz	-	_	-58	dB
		110 chs flat; V <sub>o</sub> = 44 dBmV; measured at 745.25 MHz	-	-	-53	dB
		150 chs flat; V <sub>o</sub> = 40 dBmV; measured at 985.25 MHz	-	-53	-	dB
X <sub>mod</sub>	cross modulation	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	_	-58	dB
		110 chs flat; V <sub>o</sub> = 44 dBmV; measured at 55.25 MHz	-	-	-54	dB
		150 chs flat; V <sub>o</sub> = 40 dBmV; measured at 55.25 MHz	-	-54	-	dB
CSO	composite second order distortion	85 chs flat; V <sub>o</sub> = 44 dBmV; measured at 596.5 MHz	-	-	-60	dB
		110 chs flat; V <sub>o</sub> = 44 dBmV; measured at 746.5 MHz	-	_	-56	dB
		150 chs flat; V <sub>o</sub> = 40 dBmV; measured at 986.5 MHz	-	-56	_	dB
d <sub>2</sub>	second order distortion	note 1	-	-	-72	dB
		note 2	-	l –	-65	dB
		note 3	-	-68	-	dB
V <sub>o</sub>	output voltage	$d_{im} = -60 \text{ dB}$				
		note 4	61	-	_	dBmV
		note 5	60	-	-	dBmV
		note 6	_	59	-	dBmV

**BGY1085A** 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
F	noise figure	f = 50 MHz	-	-	6	dB
		f = 600 MHz	<b> </b> -	<b>-</b> ,	6.5	dB
		f = 750 MHz	-	_	7	dB
		f = 1000 MHz	-	7.5	-	dB
I <sub>tot</sub>	total current consumption	DC value; V <sub>B</sub> = 24 V; note 7	_	_	240	mA

- 1.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 541.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_q = 596.5$  MHz.
- 2.  $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  $f_q = 691.25$  MHz;  $V_q = 44$  dBmV; measured at  $f_p + f_n = 746.5$  MHz.
- 3.  $f_p = 55.25$  MHz;  $V_p = 40$  dBmV;  $f_q = 931.25$  MHz;  $V_q = 40$  dBmV; measured at  $f_p + f_q = 986.5$  MHz.
- 4.  $f_p = 590.25$  MHz;  $V_p = V_o$ ;  $f_q = 597.25$  MHz;  $V_q = V_o 6$  dB;  $f_r = 599.25$  MHz;  $V_r = V_o 6$  dB; measured at  $f_p + f_q f_r = 588.25$  MHz.
- 5.  $f_p = 740.25 \text{ MHz}$ ;  $V_p = V_o$ ;  $f_q = 747.25 \text{ MHz}$ ;  $V_q = V_o 6 \text{ dB}$ ;  $f_r = 749.25 \text{ MHz}$ ;  $V_r = V_o 6 \text{ dB}$ ; measured at  $f_p + f_q f_r = 738.25 \text{ MHz}$ .
- 6.  $f_p = 980.25 \text{ MHz}$ ;  $V_p = V_o$ ;  $f_q = 987.25 \text{ MHz}$ ;  $V_q = V_o 6 \text{ dB}$ ;  $f_r = 989.25 \text{ MHz}$ ;  $V_r = V_o 6 \text{ dB}$ ; measured at  $f_o + f_o f_r = 978.25 \text{ MHz}$ .
- 7. The module normally operates at  $V_B = +24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

# **PACKAGE OUTLINES**

**CATV** amplifier modules

# **Wideband Hybrid IC Modules**

# **Package Outlines**

### **MOUNTING and SOLDERING RECOMMENDATIONS**

#### Mounting

The heatsink surface must be flat, free of burrs, oxidation and parallel to the mounting surface.

The heatsink, mounting base and ground leads should be properly RF grounded.

Heatsink compound should be applied sparingly and evenly on the mounting base. Suitable heatsink compounds are Dow Corning 340, Eccotherm TC-5 (E&C) and Wakefield 120.

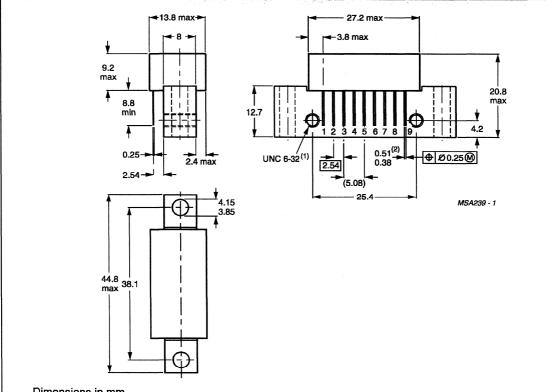
When mounting CATV hybrid components, the UNC screws must first be turned finger-tight. The screws should then be tightened to within the tolerance 0.5 Nm minimum and 0.7 Nm maximum.

### **Soldering**

Devices may be soldered directly into a circuit using a soldering iron with a maximum temperature of 260 °C for not more than 3 s when the soldered joints are a minimum of 3 mm from the module.

#### **SOT115 PACKAGE OUTLINES - SUMMARY**

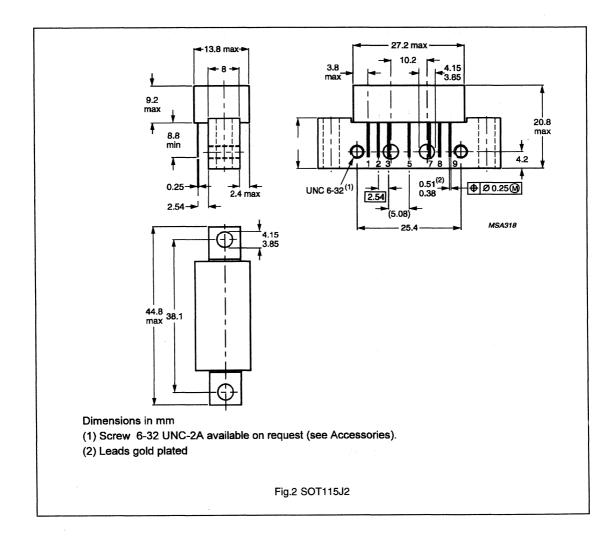
VARIANT	NUMBER OF PINS	USED PINS	FIGURE REFERENCE
С	7	1,2,3,5,7,8,9	Fig.1
D	9. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1.	ALL	Fig.1
F *	2002 1934 <b>7</b> 932 2932	1,2,5,6,8,9	Fig.1
G	8	1,2,3,5,6,7,8,9	Fig.1
Н	6	1,2,5,6,8,9	Fig.1
J2	7	1,2,3,5,7,8,9	Fig.2
L	7	1,2,3,5,7,8,9	Fig.3



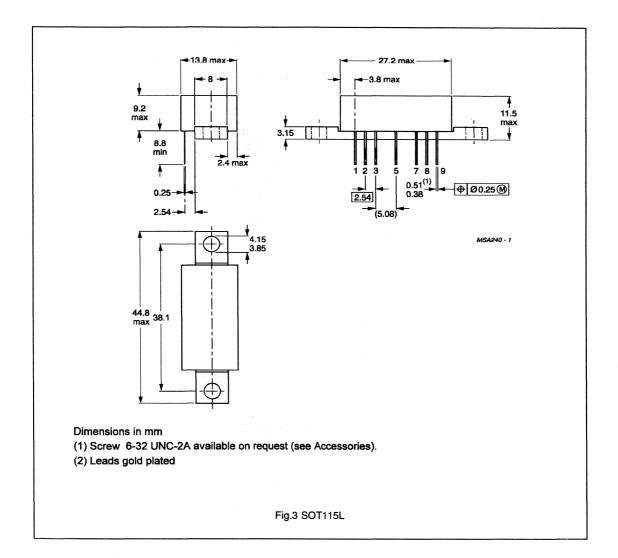
Dimensions in mm

- (1) Screw 6-32 UNC-2A available on request (see Accessories).
- (2) Leads gold plated

Fig.1 SOT115



# **Package Outlines**



# **ACCESSORIES**

**CATV** amplifier modules



CATV test jig Accessories

SPECIFICATION FOR CATV TEST JIG

Devices

: suitable only for BGX885 and

**BGD885** 

Impedance

(range 40 - 860 MHz)

75 Ω

Ordering information

CATV test fixture 860 MHz, 12NC: 7322 142 89060.

Return loss

< -40 dB at 40 MHz. Decreases 1.5 dB/octave up to 860 MHz. < -32 dB at 860 MHz. (Measured with thru-line system and other port terminated with a very good 75  $\Omega$ 

load)

Cross talk

<-80 dB

Insertion loss

< 0.1 dB (Measured with thru-line

system)

#### Note

The above parameters are in the frequency range from 40-860 MHz

DC current

max. 1 A.

Voltage

max. 50 V. (The DC is automatically switched to the device, by means of a micro-switch, after closing the

pressing system.)

Temperature

range

-25 to +75 °C.

RF connectors :

N-type female (75  $\Omega$ )

DC connectors :

Banana plug

Dimensions

110 x 60 x 55 mm (l x b x h, dimensions without pressing system, RF connectors and cooling

connections).

Distance between the centre contact of the RF connectors is

35.2 mm.

Cooling

possibility for water cooling available

on the fixture.

### CATV test jig Accessories

#### SPECIFICATION FOR CATV TEST JIG

(range 5 - 600 MHz)

Impedance

 $75 \Omega$ 

Return loss

< -40 dB (Measured with thru-line system and other port terminated with a very good 75 Ω load)

Cross talk

 $< -80 \, dB$ 

Insertion loss

< 0.1 dB (Measured with thru-line

system)

#### Note

The above parameters are in the frequency range from 5 - 600 MHz.

DC current

max. 1 A.

Voltage

range

max. 50 V. (The DC is automatically switched to the device, by means of a micro-switch, after closing the pressing system.)

Temperature

-25 to +75 °C.

RF connectors

N-type female (75  $\Omega$ )

DC connectors :

Banana plug

Dimensions

110 x 60 x 55 mm (l x b x h, dimensions without pressing system, RF connectors and cooling

connections).

Distance between the centre contact of the RF connectors is

35.2 mm.

Cooling

possibility for water cooling available

on the fixture.

Devices

suitable only for devices with positive and negative power requirement, (by means of switch).

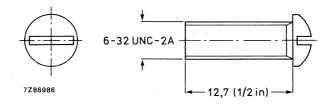
Ordering information

CATV test fixture 600 MHz, 12NC: 7322 142 54250.

February 1995

### **ROUND HEAD SCREW 6-32 UNC-2A**

Available, upon request, under type number 56396 or 12 NC code number 9390 298 10xx0.



# **HYBRID WIDEBAND AMPLIFIERS**

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Product capability overview	222
Replaced types	224
Device data (in alphanumeric sequence)	

### PRODUCT CAPABILITY OVERVIEW

### **TECHNOLOGIES**

CERAMICS	RESISTIVE	CONDUCTIVE	DIE BONDING AND
	TECHNOLOGY	TECHNOLOGY	WIRE BONDING
Al <sub>2</sub> 0 <sub>3</sub> AlN	Nickel Chromium Tantalum Nitride	Gold Copper Track widths down to 25 microns	All technologies available for silicon and GaAs

### **RF MODULES**

### **Products**

**CATV MODULES** 

Substrates
Wideband amplifiers (cable and satellite)
Resistive circuits
Video amplifiers
Customized circuits
Inductive proximity sensors.

# TYPICAL TIME TO MARKET (custom made circuits)

Between two and seven months (depending on product style/complexity).

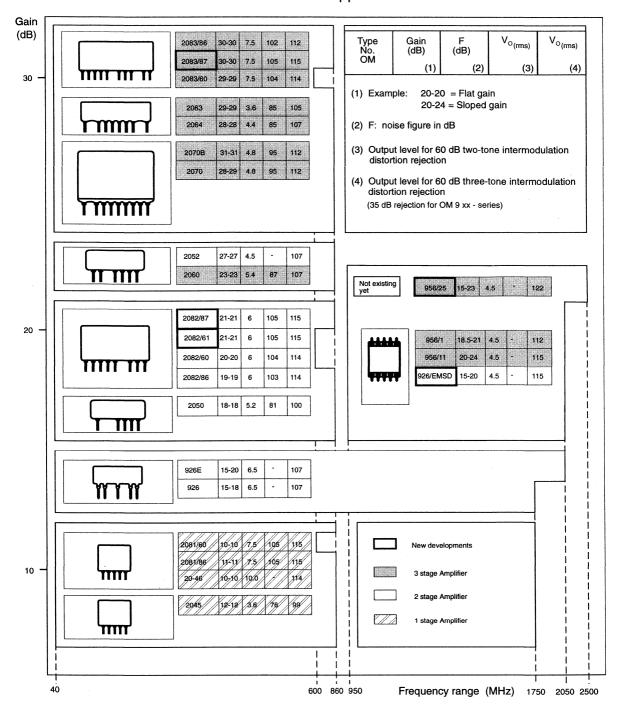
### **FINISHINGS**

Substrates
Plate
SIL lacquered
DIL lacquered
Hermetic
SMD
Plastic cover

### **DESIGN LANGUAGES**

IGDS (Intergraph, Microstation) GDSII (CALMA), DXF (AutoCad), IGES, also HPGL, GERBER.

# Hybrid Wideband Amplifiers for 12 V Antenna Systems and Industrial Applications



### **REPLACED TYPES**

WITHDRAWN TYPE	REPLACEMENT
OM345	OM2045
OM350	OM2050
OM361	OM2064
ОМ370	OM2070

OM926

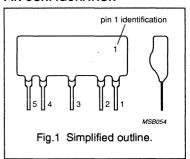
#### DESCRIPTION

A two-stage wideband amplifier in hybrid integrated circuit form on a thin-film substrate. The device is intended for use as an IF amplifier for satellite television and as a general purpose amplifier in the range 10 to 2000 MHz.

#### **PINNING**

PIN	DESCRIPTION
1	input
2	common
- 3	common
4	common
5	output/supply (+)

#### PIN CONFIGURATION



### **QUICK REFERENCE DATA**

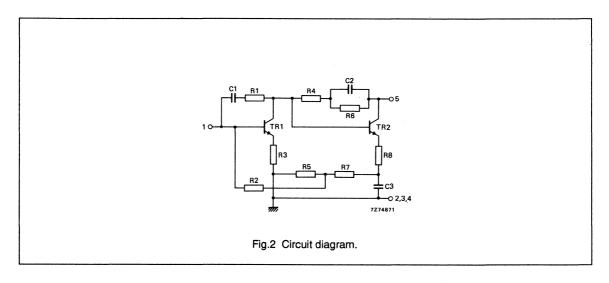
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
f	frequency range		10		2000	MHz
G <sub>tr</sub>	transducer gain	f = 1750  MHz; $G_{tr} =  s_t ^2$	-	18	- 2. 7.	dB
V <sub>o(RMS)</sub>	output voltage	d <sub>im</sub> = -60 dB (DIN 45004, paragraph 6.3: 3-tone)	101	-	-	dΒμV
F	noise figure		-	6.5	_	dB
V <sub>B</sub>	supply voltage	DC value	[-	12	-	V
T <sub>amb</sub>	ambient operating temperature range		-20	-	70	°C

OM926

### **MECHANICAL DATA**

### Encapsulation

The encapsulation comprises a 5-pin, in-line, resin-coated body, see Fig.8.



### Soldering recommendations

HAND SOLDERING

The maximum contact time for a soldering iron temperature of 260 °C up to the seating plane is 5 s.

DIP OR WAVE SOLDERING

The maximum permissible temperature for the solder is 250 °C. It must not be in contact with the joint for more than 5 s.

The total contact time of successive solder waves must not exceed 5 s.

The device may be mounted against the printed-circuit board, but the temperature of the device must not exceed 125 °C.

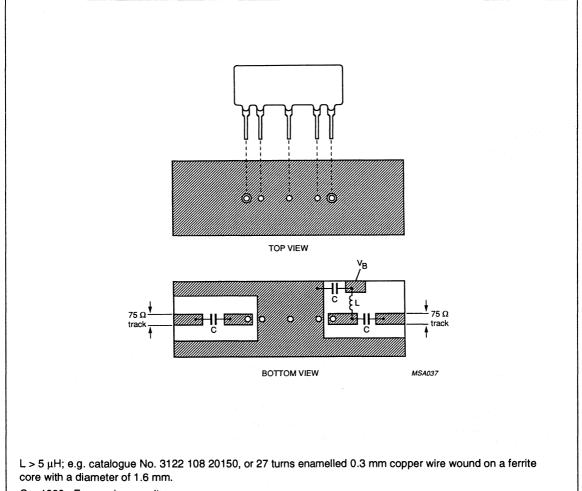
If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature below the allowable limit.

### Mounting recommendations

The module should preferably be mounted on a double-sided printed-circuit board, see Fig.3. Input and output should be connected to 75  $\Omega$  tracks. The connection to the common pins should be as close to the seating plane as possible.

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C > 1000 pF ceramic capacitor.

Fig.3 Printed-circuit board holes and tracks.

### **LIMITING VALUES**

In accordance with the Absolute Maximum System (IEC 134).

SYMBOL	SYMBOL PARAMETER		MAX.	UNIT
T <sub>amb</sub>	ambient operating temperature range	-20	70	°C
T <sub>stg</sub>	storage temperature range		125	°C
V <sub>B</sub>	DC supply voltage		15	٧
P <sub>I1M</sub> , P <sub>I5M</sub>	peak incident powers on pins 1 and 5		100	mW

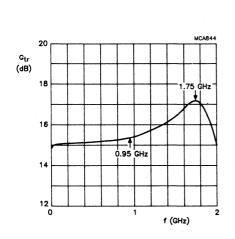
OM926

### **CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Measuring	conditions		<del></del>	<del></del>		
T <sub>amb</sub>	ambient operating temperature		T-	25	T	°C
V <sub>B</sub>	supply voltage	DC value		12	_	٧
Z <sub>s</sub>	source impedance		-	75	-	Ω
Z <sub>L</sub>	load impedance		_	75	-	Ω
Performan	ce					
l <sub>B</sub>	supply current		T-	28	T-	mA
G <sub>tr</sub>	transducer gain	$G_{tr} =  s_t ^2;$	1			
		f = 10 to 1000 MHz	-	15	_	dB
		f = 1750 MHz	-	18	_	dB
		f = 2000 MHz	-	16	_	dB
S <sub>11</sub>	input return loss					
		f = 10 to 1000 MHz	-	14	_	dB
		f = 1000 to 1750 MHz	-	12	_	dB
S <sub>22</sub>	output return loss					
		f = 10 to 1000 MHz	-	14	- "	dB
		f = 1000 to 1750 MHz	-	12	_	dB
IS <sub>r</sub> I <sup>2</sup>	feedback attenuation		-	25	-	dB
V <sub>o(RMS)</sub>	output voltage	d <sub>im</sub> = -60 dB (DIN 45004, paragraph 6.3, 3-tone)	101	103	<u>-</u>	dΒμV
F	noise figure		-	6.5	-	dB
Operating of	conditions	· .				:
T <sub>amb</sub>	ambient operating temperature range		-20	_	70	°C
V <sub>B</sub>	supply voltage	DC value	10.8	_	13.2	٧
f	frequency range		10	<b> </b> -	2000	MHz
Z <sub>s</sub>	source impedance	The second secon	-	75	-	Ω
ZL	load impedance		1_	75	_	Ω

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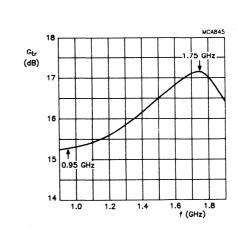
OM926



Gain over the entire frequency range.

 $Z_o = 75 \Omega$ .

Fig.4 Transducer gain as a function of frequency.



Expanded view of the satellite first IF frequency range.

 $Z_o = 75 \Omega$ .

Fig.5 Transducer gain as a function of frequency.

OM926

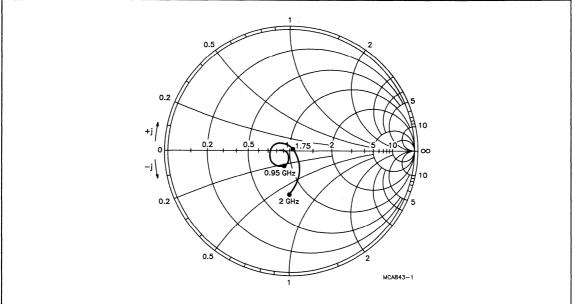
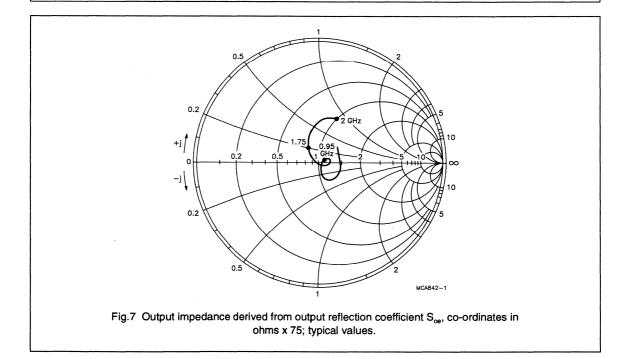


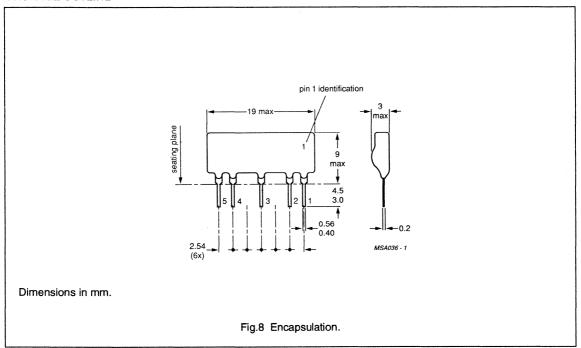
Fig.6 Input impedance derived from input reflection coefficient  $S_{ie}$ , co-ordinates in ohms x 75; typical values.



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### **PACKAGE OUTLINE**



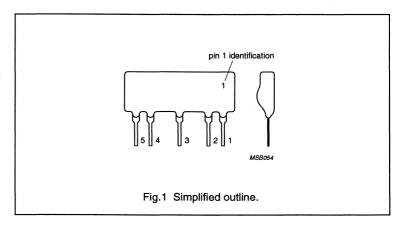
**OM926E** 

#### **DESCRIPTION**

A two-stage wideband amplifier in hybrid integrated circuit form on a thin-film substrate. The device is intended for use as an IF amplifier for satellite television and as a general purpose amplifier in the range 10 to 2050 MHz.

### **PINNING**

PIN	DESCRIPTION
1	input
2	common
3	common
4	common
5	output/supply (+)



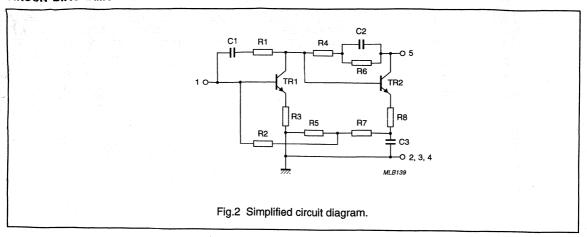
#### **QUICK REFERENCE DATA**

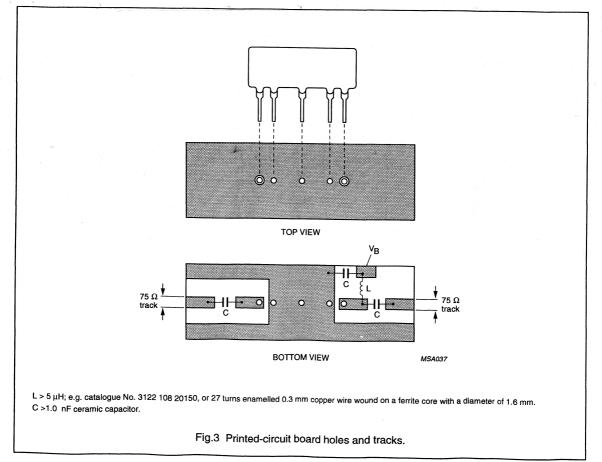
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
f	frequency range		10	_	2050	MHz
G <sub>T</sub>	transducer gain = IS <sub>21</sub> I <sup>2</sup>	f = 2050 MHz	_	20	-	dB
V <sub>o(rms)</sub>	output voltage (RMS value)	d <sub>im</sub> = -60 dB; (DIN 45004, paragraph 6.3: 3-tone)	104	105	_	dBμV
		d <sub>im</sub> = -35 dB; 2-tone	112	113	-	dΒμV
F	noise figure		Ī-	6.5	-	dB
$V_B$	DC supply voltage			12	-	٧
T <sub>amb</sub>	operating ambient temperature		-20	-	+70	°C

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### **OM926E**

### CIRCUIT DIAGRAM AND PRINTED-CIRCUIT BOARD





**OM926E** 

### **LIMITING VALUES**

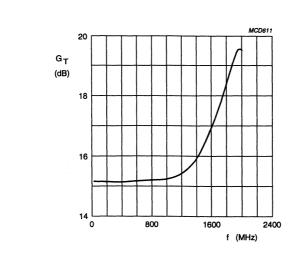
In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL PARAMETER		М	IN.	MAX.	UNIT
T <sub>amb</sub>	operating ambient temperature	-20	À	+70	<sup>o</sup> C
T <sub>stg</sub>	storage temperature	-40	- 14	+125	°C
V <sub>B</sub>	DC supply voltage	T-		15	V
P <sub>IM</sub>	peak incident powers on pins 1 and 5	-		100	mW

### **CHARACTERISTICS**

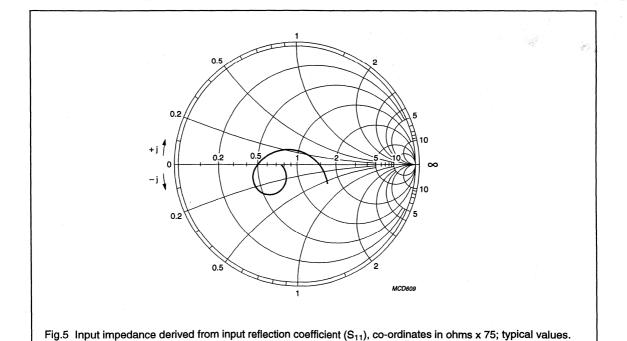
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Measuring	conditions		·	4	<u> </u>	
T <sub>amb</sub>	ambient operating temperature		<b>-</b>	25	<b>-</b>	°C
V <sub>B</sub>	DC supply voltage		-	12	_	V
Zs	source impedance		_	75	_	Ω
Z <sub>L</sub>	load impedance		_	75	- ,	Ω
Performano	;e		1			
I <sub>B</sub>	supply current		35	37.5	40	mA
GT	transducer gain = IS <sub>21</sub> I <sup>2</sup>	f = 10 to 1000 MHz	14	15	16	dB
		f = 2050 MHz	19	20	22	dB
S <sub>11</sub>	input return loss		7	8	_	dB
S <sub>22</sub>	output return loss		7.5	10	-	dB
IS <sub>12</sub> I <sup>2</sup>	feedback attenuation		-	25	-	dB
V <sub>o(rms)</sub>	output voltage (RMS value)	d <sub>im</sub> = -60 dB; (DIN 45004, paragraph 6.3: 3-tone)	104	105	_	dΒμV
		d <sub>im</sub> = -35 dB; 2-tone	112	113	_	dΒμV
F	noise figure		_	6.5	-	dB
Operating of	conditions					
T <sub>amb</sub>	ambient operating temperature		-20	-	+70	°C
V <sub>B</sub>	DC supply voltage		10.8	<b> </b> -	13.2	V
f	frequency range		10	-	2050	MHz
Z <sub>S</sub>	source impedance		-	75	_	Ω
$Z_{L}$	load impedance		_	75	_	Ω

**OM926E** 



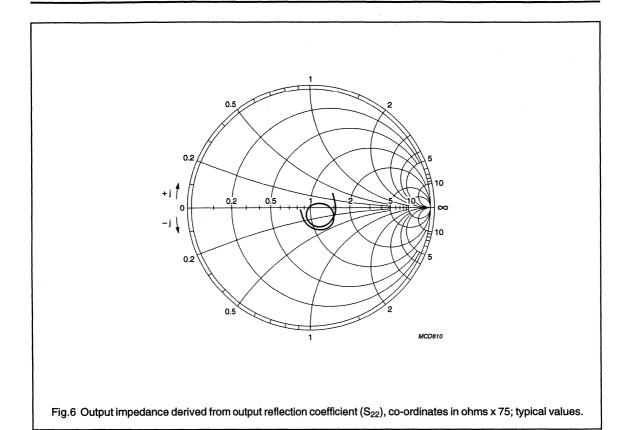
Gain over entire frequency range.  $Z_o = 75~\Omega. \label{eq:Zo}$ 

Fig.4 Transducer gain as a function of frequency.



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OM926E



### OM926E

#### MOUNTING

The module should preferably be mounted on a double-sided printed-circuit board, see Fig.3. Input and output should be connected to 75  $\Omega$  tracks. The connection to the common pins should be as close to the seating plane as possible.

#### SOLDERING

### Hand soldering

The maximum contact time for a soldering iron temperature of 260 °C up to the seating plane is 5 s.

### Dip or wave soldering

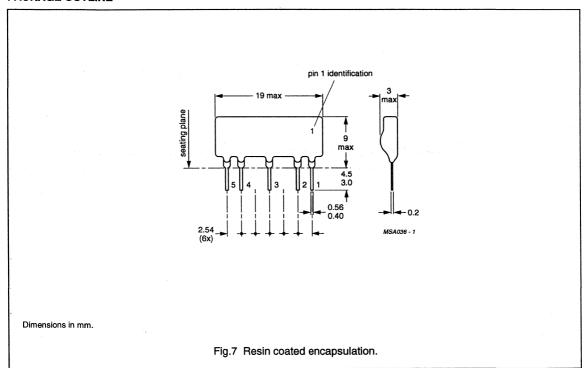
The maximum permissible temperature for the solder is 260 °C. It must not be in contact with the joint for more than 5 s.

The total contact time of successive solder waves must not exceed 5 s.

The device may be mounted against the printed-circuit board, but the temperature of the device must not exceed 125 °C.

If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature below the allowable limit.

#### **PACKAGE OUTLINE**



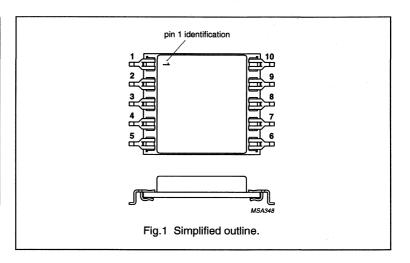
OM956/1

### **DESCRIPTION**

A three-stage wideband amplifier in hybrid integrated circuit form on a thin-film substrate. The device is intended for use as an IF amplifier for satellite television and as a general purpose amplifier in the range 950 to 2050 MHz.

### **PINNING**

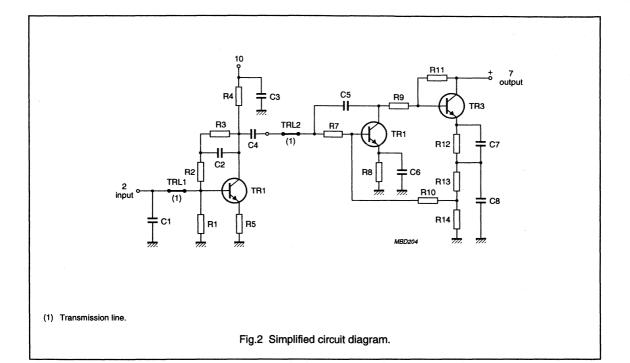
PIN	DESCRIPTION
1	common
2	input
3	common
4	common
5	common
6	common
7	output/supply (+)
8	common
9	common
10	supply (+)

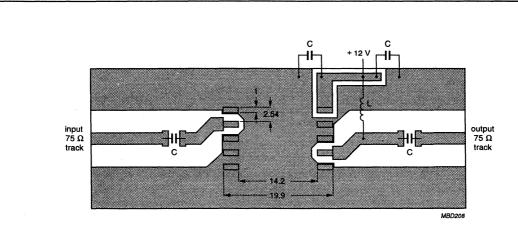


### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
f	frequency range		950	-	2050	MHz
G <sub>T</sub>	transducer gain = IS <sub>21</sub> I <sup>2</sup>	f = 950 MHz	_	18.5	-	dB
		f = 2050 MHz	-	21.0	-	dB
V <sub>o(rms)</sub>	output voltage (RMS value)	d <sub>im</sub> = -35dB; third order, 2-tone	112	_		dΒμV
F	noise figure		_	4.5	-	dB
V <sub>B</sub>	DC supply voltage		-	12	_	V
T <sub>amb</sub>	operating ambient temperature		-20	-	+70	°C

### OM956/1





L > 5 μH; e.g. catalogue No. 3122 108 20150, or 27 turns enamelled 0.3 mm copper wire wound on a ferrite core with a diameter of 1.6 mm. C > 1.0 nF ceramic capacitor.

Fig.3 Printed-circuit board holes and tracks.

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### **LIMITING VALUES**

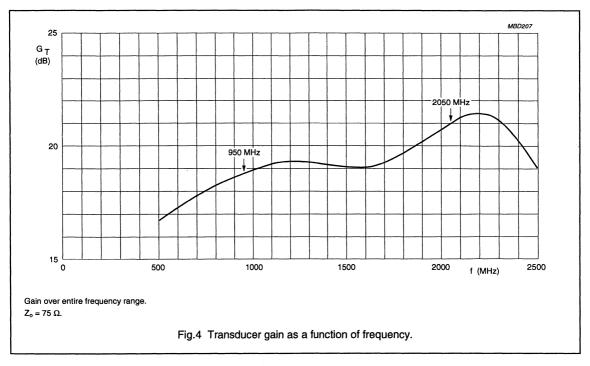
In accordance with the Absolute Maximum Rating System (IEC 134).

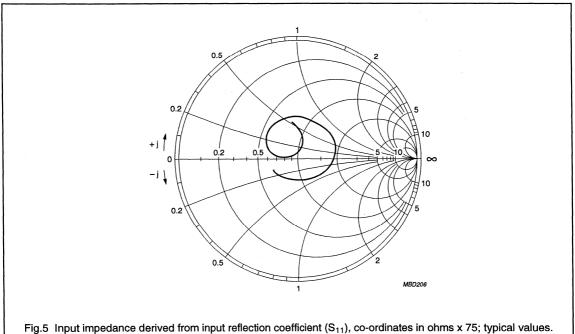
SYMBOL	PARAMETER	MIN.	MAX.	UNIT
T <sub>amb</sub>	operating ambient temperature	-20	+70	°C
T <sub>stg</sub>	storage temperature	<b>–40</b>	+125	°C
V <sub>B</sub>	DC supply voltage		15	V
P <sub>IM</sub>	peak incident powers on pins 2 and 7		100	mW

### **CHARACTERISTICS**

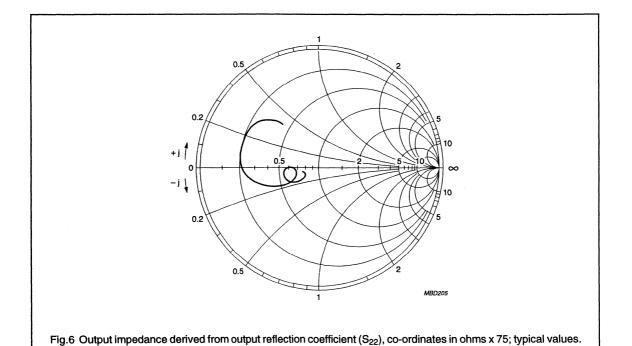
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Measuring	conditions					
T <sub>amb</sub>	ambient operating temperature		_	25	<b> </b> -	°C
V <sub>B</sub>	DC supply voltage		_	12	_	٧
Zs	source impedance		_	75		Ω
Z <sub>L</sub>	load impedance		-	75	_	Ω
Performano	ce					
I <sub>B</sub>	supply current		-	57.5	_	mA
G <sub>T</sub>	transducer gain = IS <sub>21</sub> I <sup>2</sup>	f = 950 MHz	_	18.5	_	dB
		f = 2050 MHz	-	21.0	-	dB
	slope		_	2.5	-	dB
S <sub>11</sub>	input return loss	f = 950 to 2050 MHz	_	10.0	_	dB
S <sub>22</sub>	output return loss	f = 950 to 2050 MHz	-	8.0	_	dB
IS <sub>12</sub>  2	feedback attenuation		_		_	dB
V <sub>o(rms)</sub>	output voltage (RMS value)	d <sub>im</sub> = -35 dB; third order, 2-tone		112.0	_	dBμV
F	noise figure		-	4.5	-	dB
Operating of	conditions					
T <sub>amb</sub>	ambient operating temperature		-20	<b>-</b>	+70	°C
V <sub>B</sub>	DC supply voltage		10.8	_	13.2	٧
f	frequency range		950	_	2050	MHz
Z <sub>S</sub>	source impedance		1-	75	_	Ω
$Z_L$	load impedance		<b>-</b>	75	_	Ω

OM956/1





OM956/1



### OM956/1

#### MOUNTING

The module should preferably be mounted on a double-sided printed-circuit board, see Fig.3. Input and output should be connected to 75  $\Omega$  tracks. The connection to the common pins should be as close to the seating plane as possible.

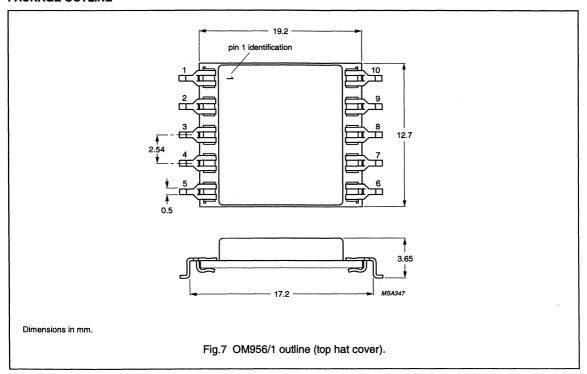
#### SOLDERING

### **Hand soldering**

The maximum contact time for a soldering iron temperature of 260 °C up to the seating plane is 5 s.

If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature below the allowable limit.

### **PACKAGE OUTLINE**





# HYBRID INTEGRATED CIRCUIT VHF/UHF WIDE-BAND AMPLIFIER

One-stage wide-band amplifier in hybrid integrated circuit technique on a thin-film substrate, intended for aerial amplifiers in car radios, caravans or RATV and MATV applications.

### QUICK REFERENCE DATA

D.C. supply voltage	V <sub>B</sub>	, <b>=</b> , <sup>1</sup>	12 V ± 10%		
Frequency range	f	4	0 to 860 MHz		
Source and load (characteristic) impedance	$R_S = R_{\ell} = Z_0$	=	75 Ω		
Transducer gain	$G_{tr} =  s_f ^2$	typ.	12 dB		
Flatness of frequency response	$\pm \Delta  s_f ^2$	typ.	1 dB		
Output voltage at -60 dB intermodulation distortion (DIN 45004, 3-tone)	Vo(rms)	typ.	99 dΒμV		
Noise figure	F	typ.	3,6 dB		
Operating ambient temperature	T <sub>amb</sub>	-20	-20 to + 70 °C		

ENCAPSULATION 5-pin, in-line, resin-coated body, see MECHANICAL DATA (Fig. 2)

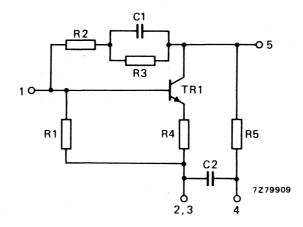


Fig. 1 Circuit diagram.

### **RATINGS**

NATINGS				
Limiting values in accordance with the Absolute M	Maximum System (IEC 13	34)		
Operating ambient temperature	T <sub>amb</sub>	-20	to +70	oC
Storage temperature	$T_{stg}$	-40 to +125		oC .
D.C. supply voltage	V <sub>B</sub>	max.	15	٧
Peak incident powers on pins 1 and 5	P11M,P15M	max.	100	mW
CHARACTERISTICS				
Measuring conditions				
Ambient temperature	$T_{amb}$	=	25	oC
D.C. supply voltage	$v_B$	=	12	V
Source impedance and load impedance	R <sub>s,</sub> Rℓ	=	75	Ω
Characteristic impedance of h.f. connections	$Z_{0}$	=	75	Ω
Frequency range	f	= 40	to 860	MHz
Performance				
Supply current	ΙΒ	typ.	11,5	mΑ
Transducer gain	$G_{tr} =  s_f ^2$	typ.	12	dB
Flatness of frequency response	$\pm \Delta  s_f ^2$	typ.	1	dB
Individual maximum v.s.w.r.				
input	VSWR <sub>(i)</sub>	typ.	2,0	*
output	VSWR <sub>(o)</sub>	typ.	1,4	*
Back attenuation				
f = 100 MHz	s <sub>r</sub>   <sup>2</sup>	typ.	22	dB
f = 860 MHz	s <sub>r</sub>   <sup>2</sup>	typ.	19	dB
Output voltage at -60 dB intermodulation distortion				
(DIN 45004, par. 6.3: 3-tone)	$V_{o(rms)}$	typ.	99	dΒμV
Noise figure	F	typ.	3,6	dB

s-parameters: 
$$\begin{aligned} s_f = s_{21} & s_i = s_{11} \\ s_r = s_{12} & s_o = s_{22} \end{aligned}$$

<sup>\*</sup> Highest value, for a sample, occuring in the frequency range.

#### **OPERATING CONDITIONS**

Ambient temperature range	T <sub>amb</sub>		-20 to + 70	°C
D.C. supply voltage	$V_{B}$	=	12	V ±10%
Frequency range	f		40 to 860	MHz
Source impedance and load impedance	$R_{s}$ , $R_{\ell}$	=	75	Ω

#### **MECHANICAL DATA**

Dimensions in mm

The device is resin coated.

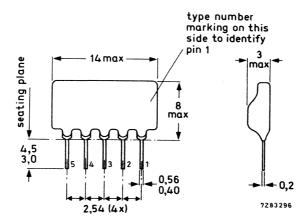


Fig. 2 Encapsulation.

#### **Terminal connections**

1 = input 2,3 = common 4 = supply (+) 5 = output

#### Soldering recommendations

#### Hand soldering

Maximum contact time for a soldering-iron temperature of 260 °C up to the seating plane is 5 s.

#### Dip or wave soldering

260 °C is the maximum permissible temperature of the solder; it must not be in contact with the joint for more than 5 seconds. The total contact time of successive solder waves must not exceed 5 seconds. The device may be mounted against the printed-circuit board, but the temperature of the device must not exceed 125 °C. If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature below the allowable limit.

#### Mounting recommendations

The module should preferably be mounted on double-sided printed-circuit board, see the example shown below.

Input and output should be connected to 75  $\Omega$  tracks.

The connections to the 'common' pins should be as close to the seating plane as possible.

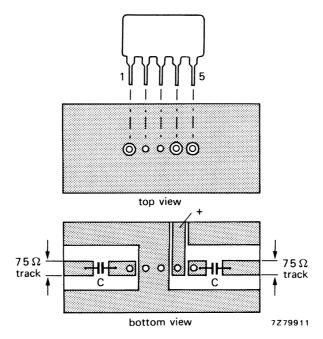


Fig. 3 Printed-circuit board holes and tracks. C > 220 pF ceramic capacitor.

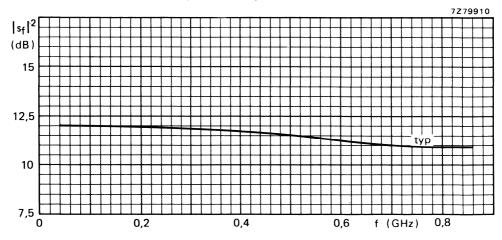


Fig. 4 Transducer gain as a function of frequency;  $Z_0 = 75 \Omega$ .

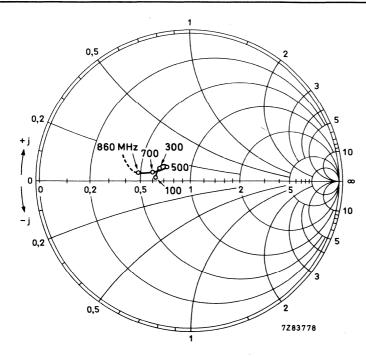


Fig. 5 Input impedance derived from input reflection coefficient  $s_i$ , co-ordinates in ohm x 75; typical values.

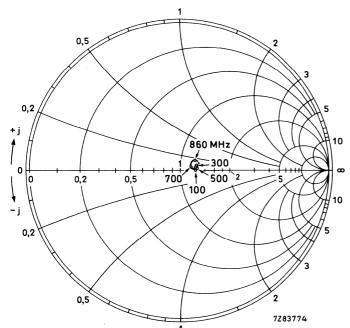


Fig. 6 Output impedance derived from output reflection coefficient  $s_0$ , co-ordinates in ohm x 75; typical values.

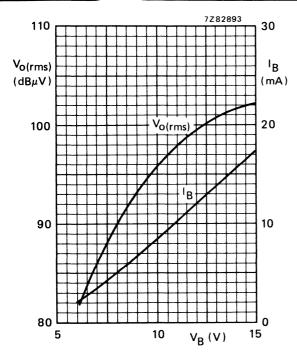


Fig. 7 Output voltage and supply current as a function of the supply voltage; typical values.

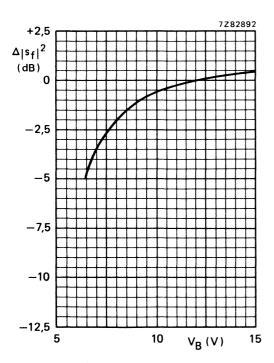


Fig. 8 Variation of transducer gain with supply voltage; reference 0 dB at 12 V; f = 100 to 860 MHz; typical values.

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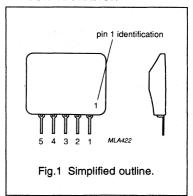
#### DESCRIPTION

A one-stage wideband amplifier in hybrid integrated circuit technology on a thin-film substrate, intended for use in mast-head booster-amplifiers, as an amplifier in MATV and CATV systems, and as a general purpose amplifier for VHF and UHF applications.

#### **PINNING**

PIN	DESCRIPTION
1	input
2	common (–)
3	common (–)
4	common (–)
5	output/supply (+)

#### **PIN CONFIGURATION**



#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
f	frequency range		40	_	860	MHz
R <sub>s</sub> , R <sub>L</sub>	source and load resistance		-	75	<b>-</b>	Ω
z <sub>o</sub>	characteristic impedance of HF connections		-	75	-	Ω
$G_{tr} =  s_f ^2$	transducer gain		-	10	_	dB
±∆ls <sub>f</sub> l²	flatness of frequency response		_	1	_	dB
V <sub>o(RMS)</sub>	output voltage	at -60 dB intermodulation distortion (DIN 45004, 3-tone)				
	VHF		_	116	_ , ,	dΒμV
	UHF		_	114	<b> </b>	dΒμV
F	noise figure		-	10	_	dB
V <sub>B</sub>	DC supply voltage		10.8	12	13.2	V
T <sub>amb</sub>	ambient operating temperature range		-20	-	70	°C

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#### **MECHANICAL DATA**

## Encapsulation

The encapsulation comprises a 5-pin, in-line, resin-coated body, see Fig.5.

#### Soldering recommendations

HAND SOLDERING

The maximum contact time for a soldering iron temperature of 260 °C up to the seating plane is 5 s.

DIP OR WAVE SOLDERING

The maximum permissible temperature for the solder is 260 °C. It must not be in contact with the joint for more than 5 s.

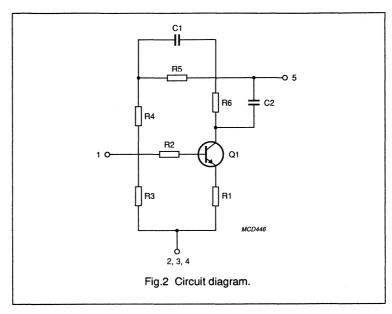
The total contact time of successive solder waves must not exceed 5 s.

The device may be mounted against the printed-circuit board, but the temperature of the device must not exceed 125 °C.

If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature below the allowable limit.

#### Mounting recommendations

The module should preferably be mounted on a double-sided printed-circuit board, see Fig.3. Input and output pins should be connected to 75  $\Omega$  tracks. The connection to the common pins should be as close to the seating plane as possible.



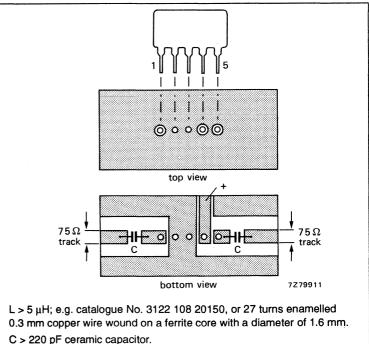


Fig.3 Printed-circuit board holes and tracks.

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#### **LIMITING VALUES**

In accordance with the Absolute Maximum System (IEC 134).

SYMBOL PARAMETER		MIN.	MAX.	UNIT
T <sub>amb</sub>	ambient operating temperature range	-20	70	°C
T <sub>stg</sub>	storage temperature range	-40	125	°C
V <sub>B</sub>	DC supply voltage		13.5	٧
P <sub>I1M</sub> , P <sub>I8M</sub>	peak incident powers on pins 1 and 8	-	100	mW

#### **CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Measuring c	onditions				<u></u>	
T <sub>amb</sub>	ambient temperature		[-	25	<u> </u>	°C
V <sub>B</sub>	DC supply voltage		-	12	-	V
R <sub>s</sub> , R <sub>L</sub>	source and load resistance		-	75	<b>1</b> -	Ω
Z <sub>o</sub>	characteristic impedance of HF connections		-	75	-	Ω
f	frequency range		40	-	860	MHz
Performance	e					
l <sub>B</sub>	supply current		-	82	-	mA
$G_{tr} =  s_f ^2$	transducer gain		9	10	11	dB
±∆ls₁l²	flatness of frequency response		_	1	<b> </b> -	dB
VSWR <sub>(i)</sub>	individual maximum VSWR	input	-	1.5 (note 1)	-	
VSWR <sub>(o)</sub>	individual maximum VSWR	output	-	1.4 (note 1)	-	
ls,l²	back attenuation	f = 100 MHz	_	16	-	dB
		f = 860 MHz	-	15	_	dB
V <sub>o(RMS)</sub>	output voltage	at -60 dB intermodulation distortion (DIN 45004, par. 6.3, 3-tone)				
	VHF		115	116	-	dΒμV
	UHF		113	114	-	dΒμV
F	noise figure		_	10	-	dB

#### **Notes**

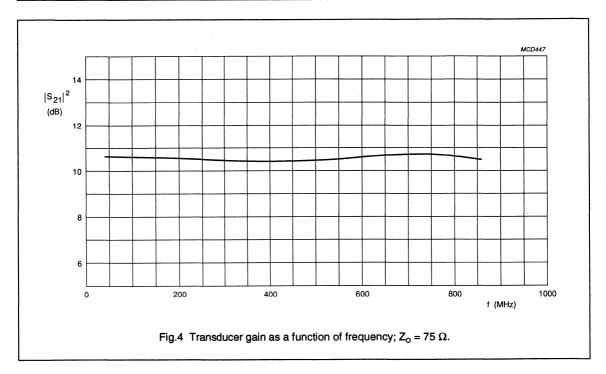
Scattering parameters:  $s_f = s_{21}$ ;  $s_r = s_{12}$ .

<sup>1.</sup> Highest value (for a sample) occurring in the frequency range.

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## **OPERATING CONDITIONS**

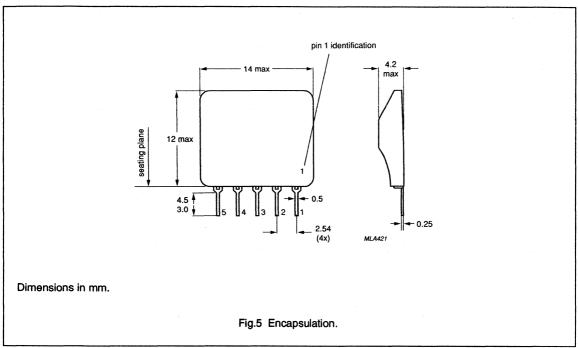
SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNIT
T <sub>amb</sub>	ambient operating temperature range	-20	_	70	°C
V <sub>B</sub>	DC supply voltage	10.8	12	13.2	V
f	frequency range	40		860	MHz
R <sub>s</sub> , R <sub>L</sub>	source and load resistance		75	_	Ω



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## **PACKAGE OUTLINE**



## HYBRID INTEGRATED CIRCUIT VHF/UHF WIDE-BAND AMPLIFIER

Two-stage wide-band amplifier in hybrid integrated circuit technique on a thin-film substrate, intended for RATV and MATV applications.

#### **QUICK REFERENCE DATA**

D.C. supply voltage	V <sub>B</sub>	=	12 V ± 10%
Frequency range	f	40	to 860 MHz
Source and load (characteristic) impedance	$R_s = R_{\ell} = Z_o$	=	75 Ω
Transducer gain	$G_{tr} =  s_f ^2$	typ.	18 dB
Flatness of frequency response	$\pm \Delta  s_f ^2$	typ.	1 dB
Output voltage at -60 dB intermodulation distortion (DIN 45004, 3-tone)	V	tum	100 dBμV
	V <sub>o(rms)</sub>	typ.	•
Noise figure	F	typ.	5,2 dB
Operating ambient temperature	T <sub>amb</sub>	-20 t	o +70 °C

ENCAPSULATION 5-pin, in-line, resin-coated body, see MECHANICAL DATA (Fig. 2)

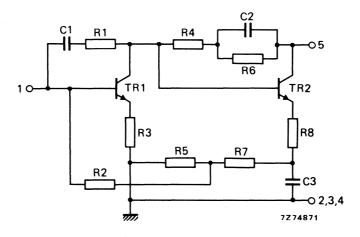


Fig. 1 Circuit diagram.

## **RATINGS**

Limiting values in accordance with the Absolute Maximum System (IEC 134)

Elimiting values in accordance with the Absolute Maxi	mum bystem (ILC i	J <del>T</del> /		
Operating ambient temperature	T <sub>amb</sub>	-20 to	+ 70	оС
Storage temperature	T <sub>stg</sub>	-40 to	+ 125	oC .
D.C. supply voltage	VB	max.	15	V
Peak incident powers on pins 1 and 5	P <sub>11M</sub> , P <sub>15M</sub>	max.	100	mW
CHARACTERISTICS				
Measuring conditions				
Ambient temperature	T <sub>amb</sub>	=	25	oC
D.C. supply voltage	V <sub>B</sub>	=	12	٧
Source impedance and load impedance	$R_s$ , $R_\ell$	=	75	Ω
Characteristic impedance of h.f. connections	Zo	= " "	75	Ω
Frequency range	f	= 40 t	o 860	MHz
Performance				
Supply current	ΙΒ	typ.	18	mΑ
Transducer gain	$G_{tr} =  s_f ^2$	typ.	18	dB
Flatness of frequency response	$\pm \Delta \mid s_{f} \mid^{2}$	typ.	1	dB
Individual maximum v.s.w.r.				
input	VSWR <sub>(i)</sub>	typ.	1,5	
output Back attenuation	VSWR <sub>(o)</sub>	typ.	1,9	
f = 100 MHz	s <sub>r</sub>   <sup>2</sup>	typ.	29	dB
f = 860 MHz	Sr   2	typ.		dB
Output voltage at –60 dB intermodulation distortion				
(DIN 45004, par. 6.3: 3-tone)	Vo(rms)	typ.	100	dΒμV
Noise figure	F	typ.	5,2	•

s-parameters: 
$$\begin{aligned} s_f &= s_{21} \\ s_r &= s_{12} \end{aligned} \quad \begin{aligned} s_i &= s_{11} \\ s_o &= s_{22} \end{aligned}$$

<sup>\*</sup> Highest value, for a sample, occuring in the frequency range.

#### OPERATING CONDITIONS

Ambient temperature range

D.C. supply voltage

Frequency range

Source impedance and load impedance

T<sub>amb</sub> -20 to +70 °C  $V_{R}$ 

12 V ± 10%

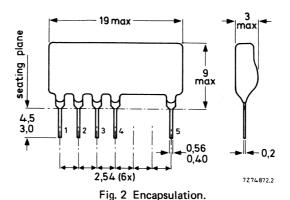
40 to 860 MHz

Dimensions in mm

75 Ω R<sub>s</sub>, Rℓ

#### **MECHANICAL DATA**

The device is resin coated.



#### Terminal connections

= input

2,3,4 = common

= output/supply(+)

#### Soldering recommendations

#### Hand soldering

Maximum contact time for a soldering-iron temperature of 260 °C up to the seating plane is 5 s.

#### Dip or wave soldering

260 °C is the maximum permissible temperature of the solder; it must not be in contact with the joint for more than 5 seconds. The total contact time of successive solder waves must not exceed 5 seconds. The device may be mounted against the printed-circuit board, but the temperature of the device must not exceed 125 °C. If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature below the allowable limit.

## Mounting recommendations

The module should preferably be mounted on double-sided printed-circuit board, see the example shown below.

Input and output should be connected to 75  $\boldsymbol{\Omega}$  tracks.

The connections to the 'common' pins should be as close to the seating plane as possible.

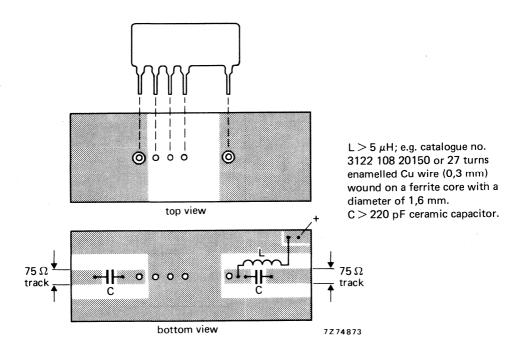


Fig. 3 Printed-circuit board holes and tracks.

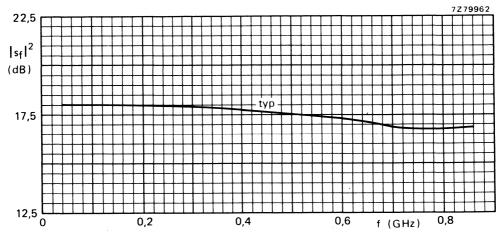


Fig. 4 Transducer gain as a function of frequency;  $Z_0 = 75 \Omega$ .

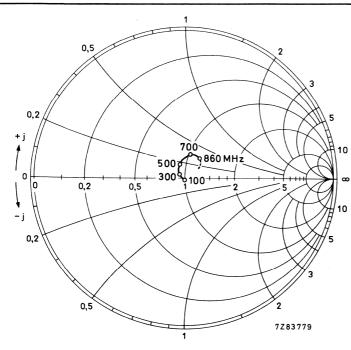


Fig. 5 Input impedance derived from input reflection coefficient  $s_i$ , co-ordinates in ohm x 75; typical values.

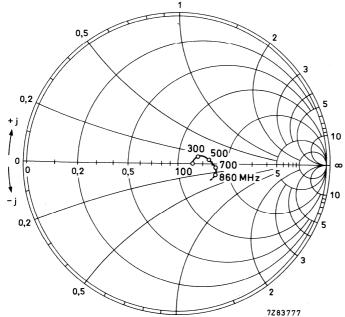


Fig. 6 Output impedance derived from output reflection coefficient  $s_0$ , co-ordinates in ohm x 75; typical values.

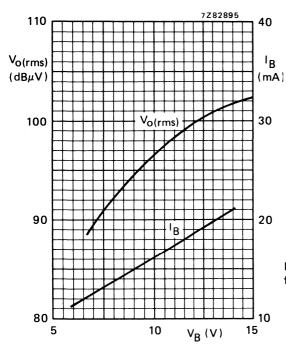


Fig. 7 Output voltage and supply current as a function of the supply voltage; typical values.

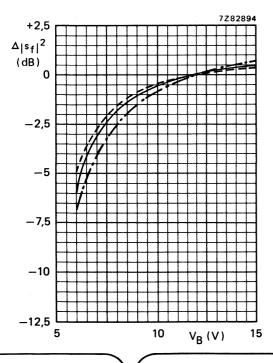


Fig. 8 Variation of transducer gain with supply voltage; reference 0 dB at 12 V:

---- f = 500 MHz;

---- f = 100 MHz;

----- f = 860 MHz;

typical values.

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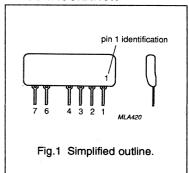
## **DESCRIPTION**

A two-stage wideband amplifier in hybrid integrated circuit technology on a thin-film substrate, intended CATV and MATV applications.

#### **PINNING**

PIN	DESCRIPTION		
1	input		
2	common (-)		
3	common (–)		
4	common ()		
5	n.c.		
6	common (–)		
7	output/supply (+)		

#### PIN CONFIGURATION



#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
f	frequency range		40	_	860	MHz
R <sub>s</sub> , R <sub>L</sub>	source and load resistance		-	75	-	Ω
Z <sub>o</sub>	characteristic impedance of HF connections		-	75	-	Ω
$G_{tr} =  s_t ^2$	transducer gain		-	28	-	dB
±ΔlS <sub>f</sub> l <sup>2</sup>	flatness of frequency response		Ī-	1	-	dB
V <sub>o(RMS)</sub>	output voltage	at -60 dB intermodulation distortion (DIN 45004, 3-tone)	-	107	-	dΒμV
F	noise figure		-	4.5	-	dB
$V_B$	DC supply voltage		10.8	12	13.2	V
T <sub>amb</sub>	ambient operating temperature range		-20	_	70	°C

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#### **MECHANICAL DATA**

#### Encapsulation

The encapsulation comprises an 8-pin, in-line, resin-coated body, see Fig.7.

#### Soldering recommendations

HAND SOLDERING

The maximum contact time for a soldering iron temperature of 260 °C up to the seating plane is 5 s.

DIP OR WAVE SOLDERING

The maximum permissible temperature for the solder is 260 °C. It must not be in contact with the joint for more than 5 s.

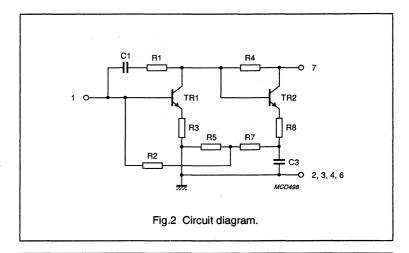
The total contact time of successive solder waves must not exceed 5 s.

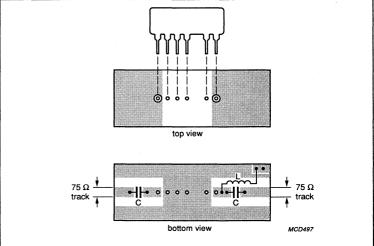
The device may be mounted against the printed-circuit board, but the temperature of the device must not exceed 125 °C.

If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature below the allowable limit.

#### Mounting recommendations

The module should preferably be mounted on a double-sided printed-circuit board, see Fig.3. Input and output pins should be connected to 75  $\Omega$  tracks. The connection to the common pins should be as close to the seating plane as possible.





L > 5  $\mu$ H; e.g. catalogue No. 3122 108 20150, or 27 turns enamelled 0.3 mm copper wire wound on a ferrite core with a diameter of 1.6 mm. C > 220 pF ceramic capacitor.

Fig.3 Printed-circuit board holes and tracks.

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## **LIMITING VALUES**

In accordance with the Absolute Maximum System (IEC 134).

SYMBOL PARAMETER		MIN.	MAX.	UNIT
T <sub>amb</sub>	ambient operating temperature range	-20	70	°C
T <sub>stg</sub>	storage temperature range	-40	125	°C
$V_{B}$	DC supply voltage		15	٧
P <sub>I1M</sub> , P <sub>I8M</sub>	peak incident powers on pins 1 and 8		100	mW

#### **CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Measuring o	conditions		***************************************			
T <sub>amb</sub>	ambient temperature		T-	25	T-	°C
$V_B$	DC supply voltage		11.9	12	12.1	٧
R <sub>s</sub> , R <sub>L</sub>	source and load resistance		-	75	-	Ω
Z <sub>o</sub>	characteristic impedance of HF connections		_	75	-	Ω
f	frequency range		40	-	860	MHz
Performance	e					
l <sub>B</sub>	supply current		38	42	44	mA
$G_{tr} =  s_f ^2$	transducer gain		26	28	29	dB
±∆ls <sub>t</sub> l²	flatness of frequency response		-	1	_	dB
VSWR <sub>(i)</sub>	individual maximum VSWR	input		2.2 (note 1)	-	
VSWR <sub>(o)</sub>	individual maximum VSWR	output	-	2.1 (note 1)	-	
ls <sub>r</sub> l²	back attenuation	f = 100 MHz	1-	36	-	dB
		f = 860 MHz	-	29	-	dB
V <sub>o(RMS)</sub>	output voltage	at -60 dB intermodulation distortion (DIN 45004, par. 6.3, 3-tone)		107	-	dΒμV
F	noise figure		1-	4.5	<b>—</b>	dB

#### **Notes**

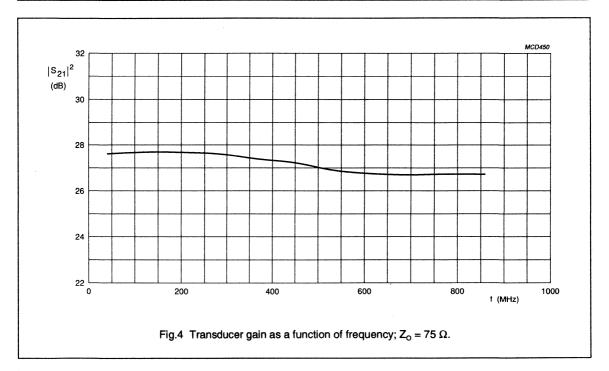
Scattering parameters:  $s_i = s_{21}$ ;  $s_r = s_{12}$ ;  $s_i = s_{11}$ ;  $s_o = s_{22}$ .

1. Highest value (for a sample) occurring in the frequency range.

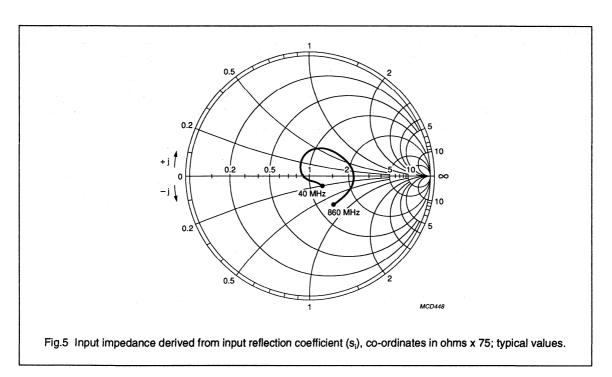
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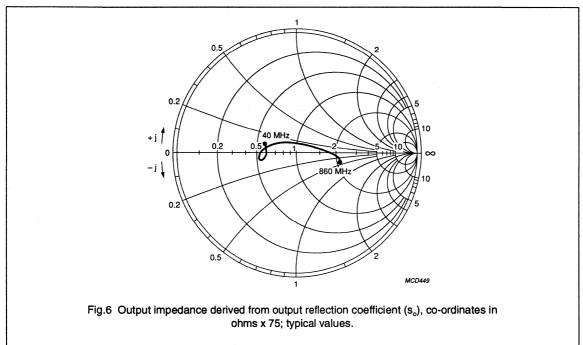
#### **OPERATING CONDITIONS**

SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNIT
T <sub>amb</sub>	ambient operating temperature range	-20	1-	70	°C
V <sub>B</sub>	DC supply voltage	10.8	12	13.2	V
f	frequency range	40	_	860	MHz
R <sub>s</sub> , R <sub>L</sub>	source and load resistance	-	75	-	Ω



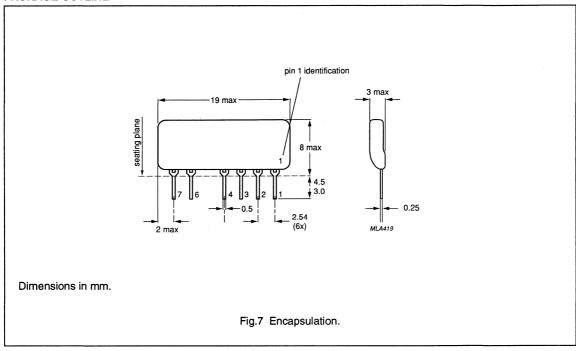
November 1991





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## **PACKAGE OUTLINE**



## HYBRID INTEGRATED CIRCUIT VHF/UHF WIDE-BAND AMPLIFIER

Three-stage wide-band amplifier in hybrid integrated circuit technique on a thin-film substrate, intended for use in mast-head booster-amplifiers, as preamplifier in MATV systems, and as general-purpose amplifier for v.h.f. and u.h.f. applications.

#### **QUICK REFERENCE DATA**

Frequency range	f	40	to 860 MHz
Source and load (characteristic) impedance	$R_s = R_{\ell} = Z_o$	=	<b>75</b> Ω
Transducer gain	$G_{tr} =  s_f ^2$	typ.	23 dB
Flatness of frequency response	$\pm \Delta  s_{f} ^2$	typ.	1.0 dB
Output voltage at -60 dB intermodulation distortion (DIN 45004, 3-tone)	Vo(rms)	>	105 dBμV
Noise figure	F	typ.	5,4 dB
D.C. supply voltage	$V_{B}$	=	12 V ± 10%
Operating ambient temperature	T <sub>amb</sub>	-20	to +70 °C

ENCAPSULATION 8-pin, in-line, resin-coated body, see MECHANICAL DATA (Fig. 2)

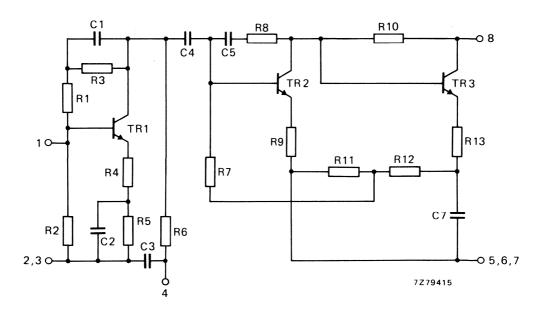


Fig. 1 Circuit diagram.

## **RATINGS**

Limiting values in accordance with the Absolute Maxin	mum System (IEC 134)			
Operating ambient temperature	T <sub>amb</sub>	-20	to +70	оС
Storage temperature	T <sub>stg</sub>	-40 to	+125	оС
D.C. supply voltage	V <sub>B</sub>	max.	15	٧
Peak incident powers on pins 1 and 7	P <sub>I1M</sub> , P <sub>I7M</sub>	max.	100	mW
CHARACTERISTICS				
Measuring conditions				
Ambient temperature	T <sub>amb</sub>	= " "	25	оС
D.C. supply voltage	$V_{B}$	-	12	٧
Source impedance and load impedance	$R_s$ , $R_\ell$	=	75	Ω
Characteristic impedance of h.f. connections	$z_{o}$	=	75	Ω
Frequency range	f	= 40	to 860	MHz
Performance				
Supply current	ΙΒ	typ.	56	mA
Transducer gain	$G_{tr} =  s_{f} ^2$	typ. 21	23 to 25	dB dB
Flatness of frequency response	$\pm \Delta  s_f ^2$	typ.	1.0	dB
Individual maximum v.s.w.r.				
input	VSWR <sub>(i)</sub>	typ.	1.4 1.6	
output	VSWR <sub>(o)</sub>	typ.	1.0	•
Back attenuation f = 100 MHz	s <sub>r</sub>   <sup>2</sup>	typ.	42	dB
f = 860 MHz	s <sub>r</sub>   <sup>2</sup>	typ.		dB .
Output voltage				
at -60 dB intermodulation distortion	V <sub>o(rms)</sub>	>		dBμV
(DIN 45004, par. 6.3: 3-tone)		typ.		dBμV
Noise figure	F	typ.	5,4	qB
s-parameters. sr = so4	C: = C4.4			

s-parameters:	s <sub>f</sub> = s <sub>21</sub>	$s_i = s_{11}$
	$s_r = s_{12}$	$s_0 = s_{22}$

<sup>\*</sup> Highest value, for a sample, occurring in the frequency range.

#### **OPERATING CONDITIONS**

Ambient temperature range	T <sub>amb</sub>	-20 to +70	OC
D.C. supply voltage	V <sub>B</sub>	= 12	V ± 10%
Frequency range	f	40 to 860	) MHz
Source impedance and load impedance	$R_s$ , $R_{\ell}$	= 75	Ω

#### **MECHANICAL DATA**

Dimensions in mm

The device is resin coated.

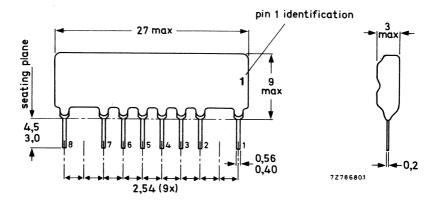


Fig. 2 Encapsulation.

#### Terminal connections

```
1 = input
2, 3, 5, 6, 7 = common
4 = supply (+)
8 = output/supply (+)
```

#### Soldering recommendations

#### Hand soldering

Maximum contact time for a soldering-iron temperature of 260 °C up to the seating plane is 5 s.

## Dip or wave soldering

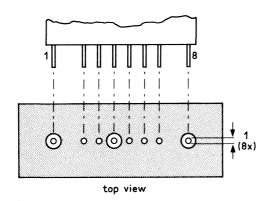
260 °C is the maximum permissible temperature of the solder; it must not be in contact with the joint for more than 5 seconds. The total contact time of successive solder waves must not exceed 5 seconds. The device may be mounted against the printed-circuit board, but the temperature of the device must not exceed 125 °C. If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature below the allowable limit.

#### Mounting recommendations

The module should preferably be mounted on double-sided printed-circuit board, see the example shown below.

Input and output should be connected to 75  $\Omega$  tracks.

The connections to the 'common' pins should be as close to the seating plane as possible.



75 Ω track bottom view 7279416

 $L > 5 \mu H$ ; e.g. catalogue no. 3122 108 20150 or 27 turns enamelled Cu wire (0,3 mm) wound on a ferrite core with a diameter of 1,6 mm. C > 220 pF ceramic capacitor.

Fig. 3 Printed-circuit board holes and tracks.

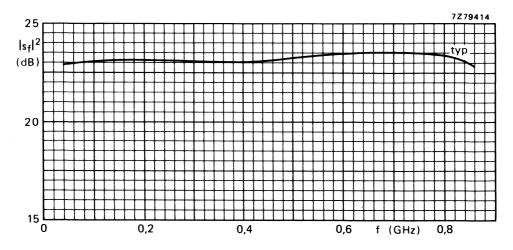


Fig. 4 Transducer gain as a function of frequency;  $Z_0 = 75 \Omega$ .

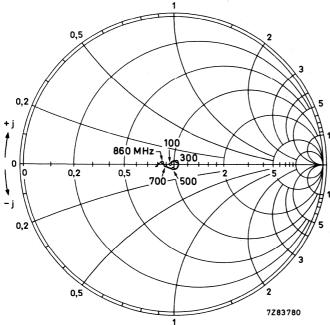


Fig. 5 Input impedance derived from input reflection coefficient s<sub>i</sub>, co-ordinates in ohm x 75; typical values.

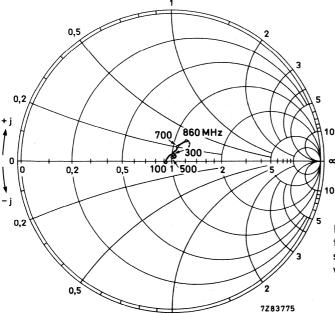


Fig. 6 Output impedance derived from output reflection coefficient s<sub>0</sub>, co-ordinates in ohm x 75; typical values.

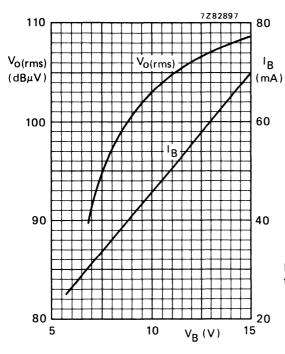


Fig. 7 Output voltage and supply current as a function of the supply voltage; typical values.

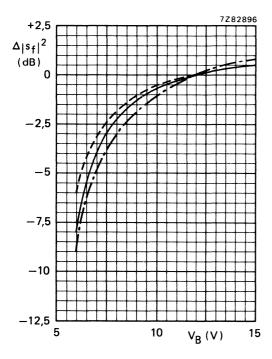


Fig. 8 Variation of transducer gain with supply voltage; reference 0 dB at 12 V;

---- f = 500 MHz;

---- f = 100 MHz;

---- f = 860 MHz;

typical values.

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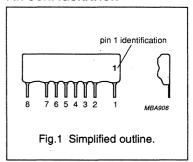
#### DESCRIPTION

A three-stage wideband amplifier in hybrid integrated circuit technology on a thin-film substrate, intended for use in mast-head booster-amplifiers, as an amplifier in MATV systems, and as a general purpose amplifier for VHF and UHF applications.

#### **PINNING**

PIN	DESCRIPTION
1	input
2	common
3	common
4	supply (+)
5	common
6	common
7	common
8	output/supply (+)

#### PIN CONFIGURATION



## **QUICK REFERENCE DATA**

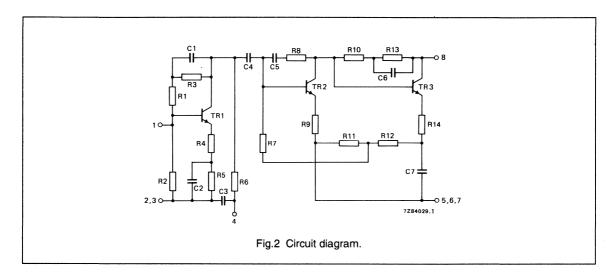
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
f	frequency range		40	-	860	MHz
$R_S = R_L = Z_O$	source and load (characteristic) impedance		-	75	-	Ω
$G_{tr} =  s_f ^2$	transducer gain		_	29	-	dB
±ΔlS <sub>f</sub> l <sup>2</sup>	flatness of frequency response		_	1	_	dB
V <sub>o(RMS)</sub>	output voltage	at -60 dB intermodulation distortion (DIN 45004, 3-tone)				
	VHF		_	103	-	dΒμV
	UHF		_	105	-	dΒμV
F	noise figure		-	3.6	_	dB
V <sub>B</sub>	DC supply voltage		10.8	12	13.4	V
T <sub>amb</sub>	ambient operating temperature range		-20	_	70	°C

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#### **MECHANICAL DATA**

#### Encapsulation

The encapsulation comprises an 8-pin, in-line, resin-coated body, see Fig.8.



#### Soldering recommendations

HAND SOLDERING

The maximum contact time for a soldering iron temperature of 260 °C up to the seating plane is 5 s.

DIP OR WAVE SOLDERING

The maximum permissible temperature for the solder is 260 °C. It must not be in contact with the joint for more than 5 s.

The total contact time of successive solder waves must not exceed 5 s.

The device may be mounted against the printed-circuit board, but the temperature of the device must not exceed 125 °C.

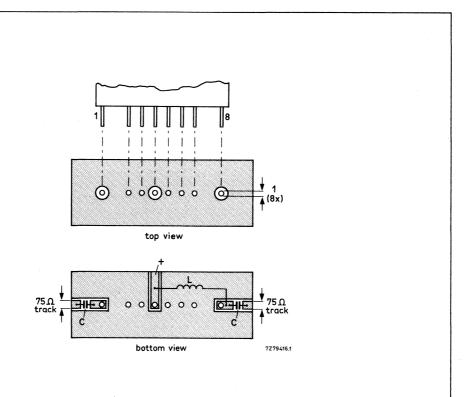
If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature below the allowable limit.

#### Mounting recommendations

The module should preferably be mounted on a double-sided printed-circuit board, see Fig.3. Input and output pins should be connected to 75  $\Omega$  tracks. The connection to the common pins should be as close to the seating plane as possible.

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 $L > 5~\mu H$ ; e.g. catalogue No. 3122 108 20150, or 27 turns enamelled 0.3 mm copper wire wound on a ferrite core (material 4B1; catalogue No. 3122 104 91110) with a diameter of 1.6 mm. C > 220~pF ceramic capacitor.

Fig.3 Printed-circuit board holes and tracks.

#### **LIMITING VALUES**

In accordance with the Absolute Maximum System (IEC 134).

SYMBOL	SYMBOL PARAMETER		MAX.	UNIT
T <sub>amb</sub>	ambient operating temperature range	-20	70	°C
T <sub>stg</sub> storage temperature range		-40	125	°C
V <sub>B</sub> DC supply voltage		_	15	٧
P <sub>I1M</sub> , P <sub>I8M</sub>	peak incident powers on pins 1 and 8	-	100	mW

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## **CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Measuring o	onditions					
T <sub>amb</sub>	ambient temperature		-	25	·-	°C
V <sub>B</sub>	DC supply voltage		_	12	-	V
R <sub>S</sub> , R <sub>L</sub>	source impedance and load impedance		-	75	-	Ω
Z <sub>o</sub>	characteristic impedance of HF connections		-	75	-	Ω
f	frequency range		40	-	860	MHz
Performance	е					
l <sub>B</sub>	supply current		-	52	-	mA
$G_{tr} =  s_t ^2$	transducer gain		-	29	-	dB
±∆ls <sub>f</sub> l²	flatness of frequency response		-	1	1.5	dB
VSWR <sub>(i)</sub>	individual maximum VSWR	input	-	2.3 (note 1)	_	
VSWR <sub>(o)</sub>	individual maximum VSWR	output	-	1.4 (note 1)	_	
ls <sub>r</sub> l <sup>2</sup>	back attenuation	f = 100 MHz	-	46	T-	dB
		f = 860 MHz	_	41	-	dB
V <sub>o(RMS)</sub>	output voltage	at –60 dB intermodulation distortion (DIN 45004, par. 6.3, 3-tone)				
	VHF		-	103	-	dΒμV
	UHF		-	105	_	dΒμV
F	noise figure		-	3.6	-	dB

#### Notes

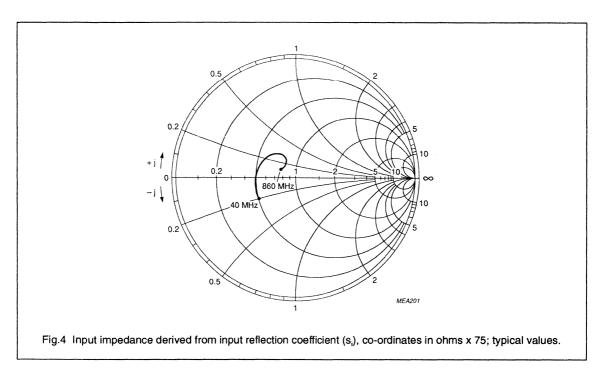
Scattering parameters:  $s_f = s_{21}$ ;  $s_r = s_{12}$ .

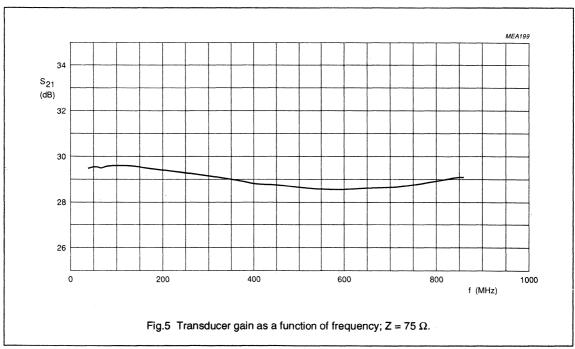
1. Highest value (for a sample) occurring in the frequency range.

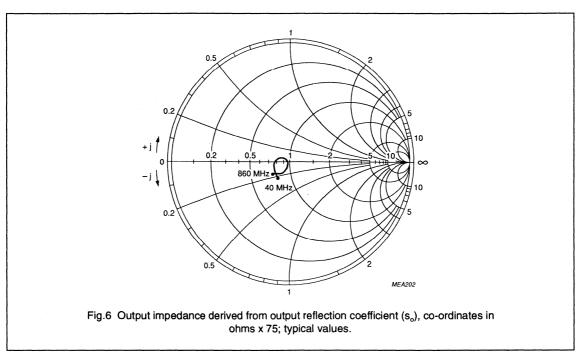
## **OPERATING CONDITIONS**

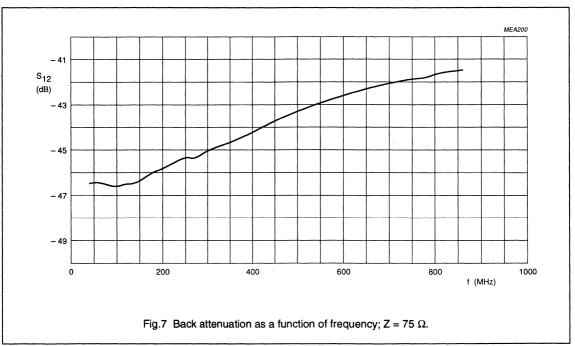
SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNIT
T <sub>amb</sub>	ambient operating temperature range	-20	_	70	°C
N <sup>B</sup>	DC supply voltage	10.8	12	13.4	V
f	frequency range	40	_	860	MHz
R <sub>s</sub> , R <sub>L</sub>	source impedance and load impedance	Ī-	75	_	Ω

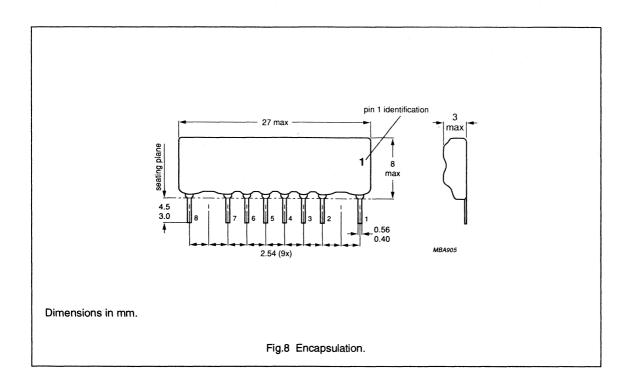
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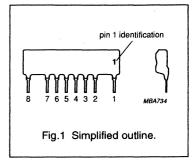
#### DESCRIPTION

A three-stage wideband amplifier in hybrid integrated circuit technology on a thin-film substrate, intended for use in mast-head booster-amplifiers, as an amplifier in MATV systems, and as a general purpose amplifier for VHF and UHF applications.

#### **PINNING**

PIN	DESCRIPTION
1	input
2	common
3	common
4	supply (+)
5	common
6	common
7	common
8	output/supply (+)

#### PIN CONFIGURATION



#### QUICK REFERENCE DATA

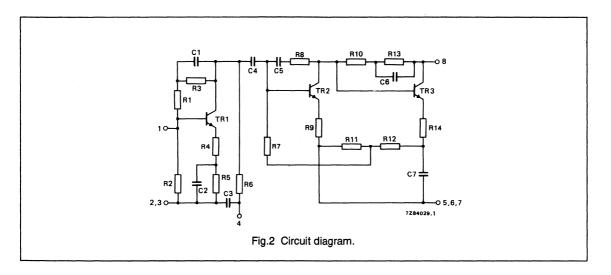
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
f	frequency range		40	_	860	MHz
$R_S = R_L = Z_O$	source and load (characteristic) impedance		-	75	-	Ω
$G_{tr} =  s_f ^2$	transducer gain		1-	28	-	dB
±Δls <sub>f</sub> l <sup>2</sup>	flatness of frequency response		<b> </b> -	1	<b> </b> -	dB
V <sub>o(RMS)</sub>	output voltage	at -60 dB intermodulation distortion (DIN 45004, 3-tone)	105	107	_	dΒμV
F	noise figure		1-	4.4	_	dB
V <sub>B</sub>	DC supply voltage		10.8	12	13.4	٧
T <sub>amb</sub>	ambient operating temperature range		-20	-	70	°C

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### **MECHANICAL DATA**

### Encapsulation

The encapsulation comprises an 8-pin, in-line, resin-coated body, see Fig.7.



## Soldering recommendations

HAND SOLDERING

The maximum contact time for a soldering iron temperature of 260 °C up to the seating plane is 5 s.

DIP OR WAVE SOLDERING

The maximum permissible temperature for the solder is 260 °C. It must not be in contact with the joint for more than 5 s.

The total contact time of successive solder waves must not exceed 5 s.

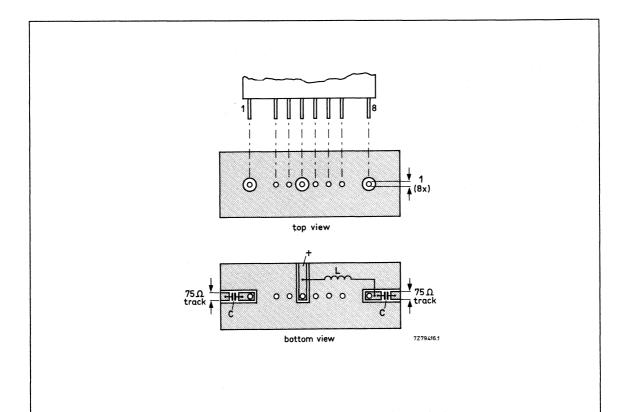
The device may be mounted against the printed-circuit board, but the temperature of the device must not exceed 125 °C.

If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature below the allowable limit.

## Mounting recommendations

The module should preferably be mounted on a double-sided printed-circuit board, see Fig.3. Input and output should be connected to 75  $\Omega$  tracks. The connection to the common pins should be as close to the seating plane as possible.

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 $L>5~\mu H;$  e.g. catalogue No. 3122 108 20150, or 27 turns enamelled 0.3 mm copper wire wound on a ferrite core (material 4B1; catalogue No. 3122 104 91110) with a diameter of 1.6 mm.

C > 220 pF ceramic capacitor.

Fig.3 Printed-circuit board holes and tracks.

## **LIMITING VALUES**

In accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
T <sub>amb</sub>	ambient operating temperature range	-20	70	°C
T <sub>stg</sub>	storage temperature range	-40	125	°C
V <sub>B</sub>	DC supply voltage	-	15	٧
P <sub>I1M</sub> , P <sub>I8M</sub>	peak incident powers on pins 1 and 8	_	100	mW

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## **CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT		
Measuring	Measuring conditions							
T <sub>amb</sub>	ambient temperature		-	25	_	°C		
V <sub>B</sub>	DC supply voltage		-	12	-	V		
R <sub>s</sub> , R <sub>L</sub>	source impedance and load impedance		-	75	-	Ω		
Z <sub>o</sub>	characteristic impedance of HF connections		_	75	-	Ω		
f	frequency range		40	- ,	860	MHz		
Performan	се							
I <sub>B</sub>	supply current		48	51	54	mA		
$G_{tr} =  s_t ^2$	transducer gain		26	28	31	dB		
±∆ls <sub>f</sub> l²	flatness of frequency response		-	1	1.5	dB		
VSWR <sub>(i)</sub>	individual maximum VSWR	input	_	1.3 (note 1)	1.5			
VSWR <sub>(o)</sub>	individual maximum VSWR	output	_	1.5 (note 1)	1.6			
ls <sub>r</sub> l <sup>2</sup>	back attenuation	f = 100 MHz	42	44	-	dB		
		f = 860 MHz	37	39	-	dB		
V <sub>o(RMS)</sub>	output voltage	at –60 dB intermodulation distortion (DIN 45004, par. 6.3, 3-tone)	105	107	-	dΒμV		
F	noise figure		_	4.4	-	dB		

## Notes

Scattering parameters:  $s_f = s_{21}$ ;  $s_r = s_{12}$ .

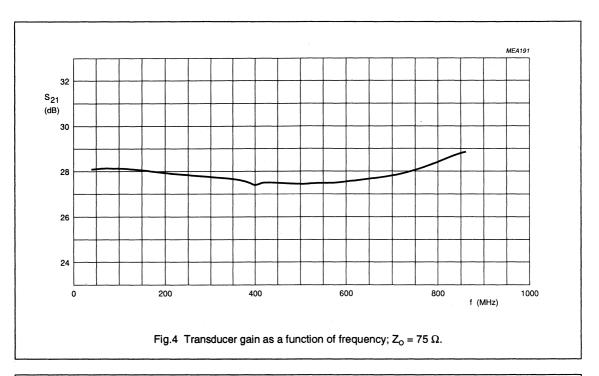
1. Highest value (for a sample) occurring in the frequency range.

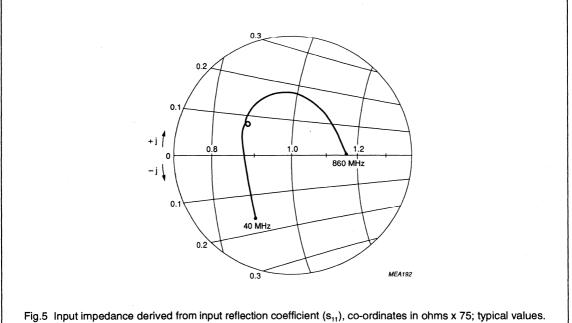
### **OPERATING CONDITIONS**

SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNIT
T <sub>amb</sub>	ambient temperature range	-20	<b> </b> -	70	°C
V <sub>B</sub>	DC supply voltage	10.8	12	13.4	V
f	frequency range	40	_	860	MHz
R <sub>s</sub> , R <sub>L</sub>	source impedance and load impedance	-	75		Ω

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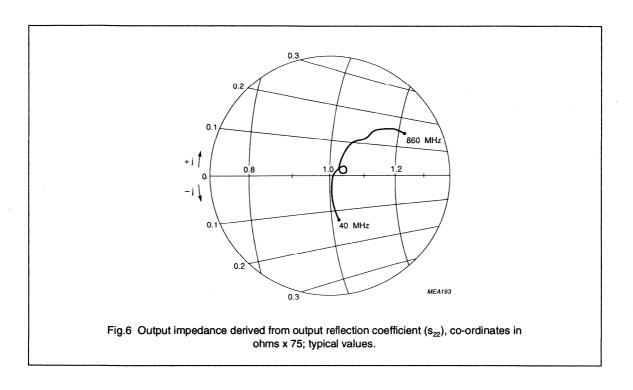
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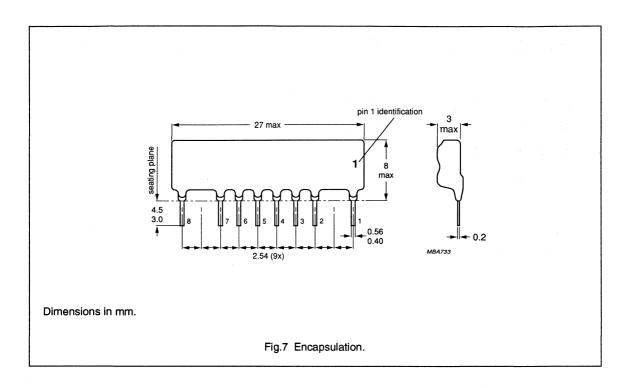


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## HYBRID INTEGRATED CIRCUIT VHF/UHF WIDE-BAND AMPLIFIER

Three-stage wide-band amplifier in hybrid integrated circuit technique on a thin-film substrate, intended for use in mast-head booster-amplifiers, as an amplifier in MATV and CATV systems, and as general-purpose amplifier for v.h.f. and u.h.f. applications.

## QUICK REFERENCE DATA

Frequency range	f	-	40 to 860	MHz
Source and load (characteristic) impedance	$R_s = R_{\ell} = Z_0$	=	75	Ω
Transducer gain	$G_{tr} =  s_f ^2$	typ.	28	dB
Flatness of frequency response	$\pm \Delta  s_f ^2$	typ.	1	dB
Output voltage at -60 dB intermodulation distortion (DIN 45004, 3-tone) VHF UHF	Vo(rms) Vo(rms)	typ. typ.		dBμV dBμV
Noise figure	F	typ.	4,8	dB
D.C. supply voltage	$v_B$	=	12	V ± 10%
Operating ambient temperature	T <sub>amb</sub>		-20 to +70	°С

ENCAPSULATION 9-pin, in-line, resin-coated body, see MECHANICAL DATA (Fig.2)

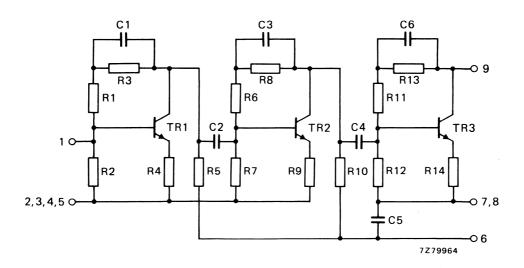


Fig. 1 Circuit diagram.

## **RATINGS**

Limiting values in acco	ordance with the Absolu	te Maximum	System (IEC 13	4)		
Operating ambient tem			T <sub>amb</sub>		-20 to +70	οС
Storage temperature			T <sub>stg</sub>		40 to +125	οС
D.C. supply voltage			V <sub>B</sub>	max.	15	V
Peak incident powers of	on pins 1 and 8		P <sub>I1M</sub> , P <sub>I8M</sub>	max.	100	mW
CHARACTERISTICS						
Measuring conditions						
Ambient temperature			T <sub>amb</sub>	=	25	оС
D.C. supply voltage			$V_{B}$	=	12	V
Source impedance and	load impedance		$R_{s}$ , $R_{\ell}$	=	75	$\Omega$
Characteristic impedan	ce of h.f. connections		Zo	=	75	Ω
Frequency range			f	=	40 to 860	MHz
Performance						
Supply current			I <sub>B</sub>	typ.	100	mΑ
Transducer gain			$G_{tr} =  s_f ^2$	typ.	28 26 to 31	dB dB
Flatness of frequency i	response		$\pm \Delta  \mathbf{s_f} ^2$	typ.	1	dB
Individual maximum v	.s.w.r.		•			
input			VSWR <sub>(i)</sub>	typ.	2,3	*
output			VSWR <sub>(o)</sub>	typ.	1,9	*
Back attenuation			•			
f = 100 MHz f = 860 MHz			s <sub>r</sub>   <sup>2</sup>	typ.		dB dB
Output voltage			$ s_r ^2$	typ.	30	uБ
at -60 dB intermod	ulation distortion					
(DIN 45004, par. 6,	3; 3-tone)					
VHF			V <sub>o(rms)</sub>	>		dBμV
			- 0(1118)	typ.		dBμV
UHF			Vo(rms)	> typ.		dBμV dBμV
Noise figure			F	typ.	4,8	-
	s-parameters:	of = \$21	s <sub>i</sub> = s <sub>11</sub>	7		
		or = \$12	$s_0 = s_{22}$			
		1 14	0 22	_ا		

<sup>\*</sup> Highest value, for a sample, occurring in the frequency range.

Dimensions in mm

### **OPERATING CONDITIONS**

Ambient temperature range	Tamb		-20 to +70	°C
D.C. supply voltage	V <sub>B</sub>	=	12	V ± 10%
Frequency range	f		40 to 860	MHz
Source impedance and load impedance	$R_{s}$ , $R_{\ell}$	=	75	Ω

#### **MECHANICAL DATA**

The device is resin coated.

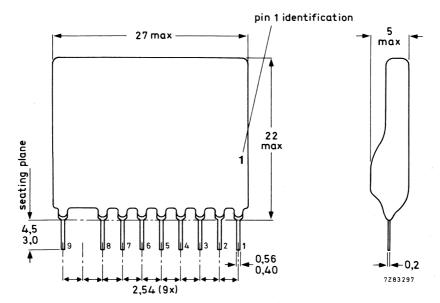


Fig. 2 Encapsulation.

### Terminal connections

```
1 = input
2,3,4,5 and 7,8 = common
6 = supply (+)
9 = output/supply (+)
```

## Soldering recommendations

### Hand soldering

Maximum contact time for a soldering-iron temperature of 260 °C up to the seating plane is 5 s.

## Dip or wave soldering

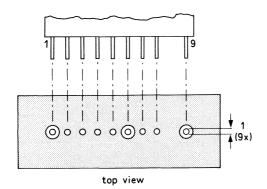
260 °C is the maximum permissible temperature of the solder; it must not be in contact with the joint for more than 5 seconds. The total contact time of successive solder waves must not exceed 5 seconds. The device may be mounted against the printed-circuit board, but the temperature of the device must not exceed 125 °C. If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature below the allowable limit.

## Mounting recommendations

The module should preferably be mounted on double-sided printed-circuit board, see the example shown below.

Input and output should be connected to 75  $\Omega$  tracks.

The connections to the 'common' pins should be as close to the seating plane as possible.



75Ω track c c 75Ω track

L > 5  $\mu$ H; e.g. catalogue no. 3122 108 20150 or 27 turns enamelled Cu wire (0,3 mm) wound on a ferrite core (material 4B1; catalogue no. 3122 104 91110) with a diameter of 1,6 mm. C > 220 pF ceramic capacitor.

Fig. 3 Printed-circuit board holes and tracks.

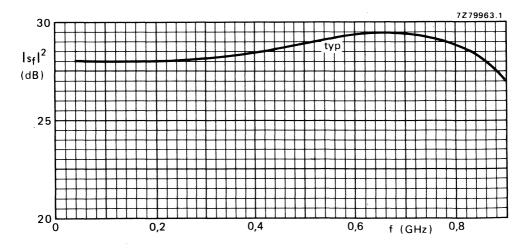


Fig. 4 Transducer gain as a function of frequency;  $Z_{\Omega} = 75 \Omega$ .

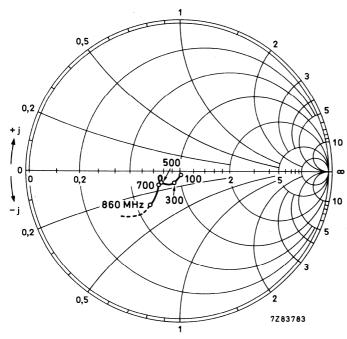


Fig. 5 Input impedance derived from input reflection coefficient  $s_i$ , co-ordinates in ohm x 75; typical values.

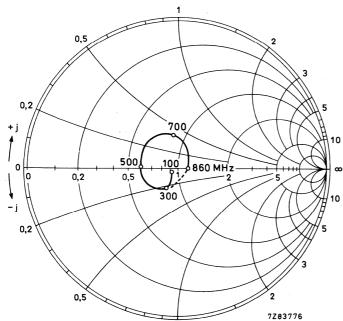


Fig. 6 Output impedance derived from output reflection coefficient  $s_0$ , co-ordinates in ohm x 75; typical values.

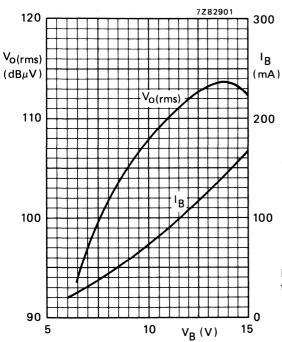


Fig. 7 Output voltage and supply current as a function of the supply voltage; typical values.

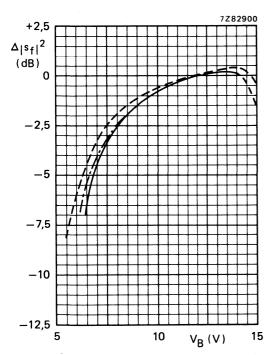


Fig. 8 Variation of transducer gain with supply voltage; reference 0 dB at 12 V;

---- f = 500 MHz;

---- f = 100 MHz;

----- f = 860 MHz;

typical values.

## **OM2070B**

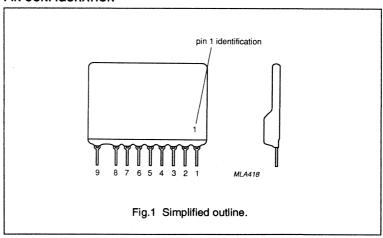
## **DESCRIPTION**

A three-stage wideband amplifier in hybrid integrated circuit technology on a thin-film substrate, intended for use in mast-head booster-amplifiers, as an amplifier in CATV and MATV systems, and as a general purpose amplifier for VHF and UHF applications.

## **PINNING**

PIN	DESCRIPTION
1	input
2	common ()
3	common (–)
4	common (–)
5	common (-)
6	supply (+)
7	common (-)
8	common (–)
9	output/supply (+)
9	, ,

### **PIN CONFIGURATION**



## **QUICK REFERENCE DATA**

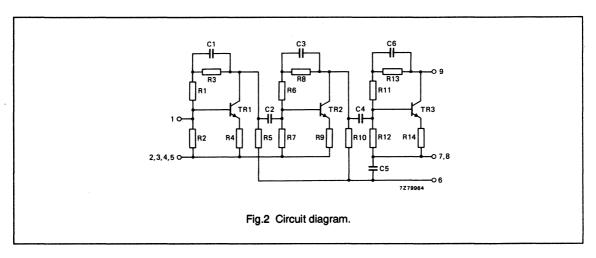
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
f	frequency range		40	_	860	MHz
R <sub>s</sub> , R <sub>L</sub>	source and load resistance		-	75	_	Ω
Z <sub>o</sub>	characteristic impedance of HF connections		-	75	-	Ω
$G_{tr} =  s_f ^2$	transducer gain		_	30	_	dB
±∆ls <sub>f</sub> l²	flatness of frequency response		-	1	-	dB
V <sub>o(RMS)</sub>	output voltage VHF UHF	at -60 dB intermodulation distortion (DIN 45004, 3-tone)	_	113 112		dΒμV dΒμV
F	noise figure		- ,	4.8	1-	dB
V <sub>B</sub>	DC supply voltage		10.8	12	13.2	V
T <sub>amb</sub>	ambient operating temperature range		-20	-	70	°C

OM2070B

### **MECHANICAL DATA**

## **Encapsulation**

The encapsulation comprises a 9-pin, in-line, resin-coated body, see Fig.6.



### Soldering recommendations

HAND SOLDERING

The maximum contact time for a soldering iron temperature of 260 °C up to the seating plane is 5 s.

DIP OR WAVE SOLDERING

The maximum permissible temperature for the solder is 260 °C. It must not be in contact with the joint for more than 5 s.

The total contact time of successive solder waves must not exceed 5 s.

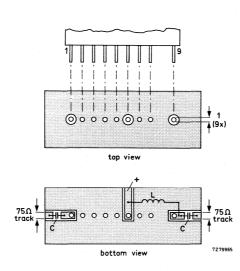
The device may be mounted against the printed-circuit board, but the temperature of the device must not exceed 125 °C.

If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature below the allowable limit.

## **Mounting recommendations**

The module should preferably be mounted on a double-sided printed-circuit board, see Fig.3. Input and output pins should be connected to 75  $\Omega$  tracks. The connection to the common pins should be as close to the seating plane as possible.

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 $L > 5 \mu H$ ; e.g. catalogue No. 3122 108 20150, or 27 turns enamelled 0.3 mm copper wire wound on a ferrite core with a diameter of 1.6 mm.

C > 220 pF ceramic capacitor.

Fig.3 Printed-circuit board holes and tracks.

## **LIMITING VALUES**

In accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
T <sub>amb</sub>	ambient operating temperature range	-20	70	°C
T <sub>stg</sub>	storage temperature range	-40	125	°C
V <sub>B</sub>	DC supply voltage	-	15	V
P <sub>11M</sub> , P <sub>18M</sub>	peak incident powers on pins 1 and 8	_	100	mW

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## **CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT		
Measuring c	Measuring conditions							
T <sub>amb</sub>	ambient temperature		-	25	-	°C		
V <sub>B</sub>	DC supply voltage		<b> </b> -	12	-	٧		
R <sub>s</sub> , R <sub>L</sub>	source and load resistance		-	75	-	Ω		
Z <sub>o</sub>	characteristic impedance of HF connections		-	75	-	Ω		
f	frequency range		40	-	860	MHz		
Performance	•							
I <sub>B</sub>	supply current		<b>-</b>	100	_	mA		
$G_{tr} =  S_t ^2$	transducer gain		28	30	33	dB		
±∆ls <sub>t</sub> l²	flatness of frequency response		<b>-</b>	1	_	dB		
VSWR <sub>(i)</sub>	individual maximum VSWR	input	-	2.7 (note 1)	-			
VSWR <sub>(o)</sub>	individual maximum VSWR	output	-	1.9 (note 1)	-			
ls,l <sup>2</sup>	back attenuation	f = 100 MHz	-	45	-	dB		
		f = 860 MHz	-	35	-	dB		
V <sub>o(RMS)</sub>	output voltage	at -60 dB intermodulation						
, ,	VHF	distortion (DIN 45004,	111	113	-	dΒμV		
	UHF	par. 6.3, 3-tone)	110	112	-	dΒμV		
F	noise figure		-	4.8	-	dB		

## Notes

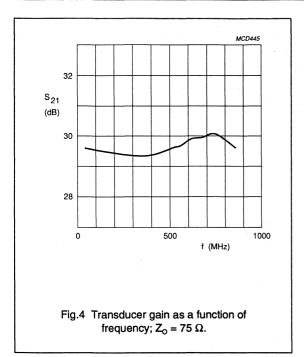
Scattering parameters:  $s_f = s_{21}$ ;  $s_r = s_{12}$ ;  $s_i = s_{11}$ ;  $s_o = s_{22}$ .

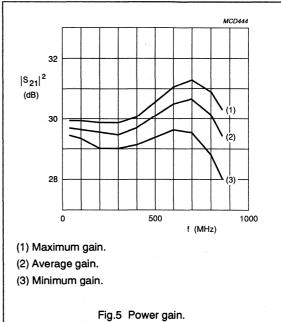
1. Highest value (for a sample) occurring in the frequency range.

## OM2070B

### **OPERATING CONDITIONS**

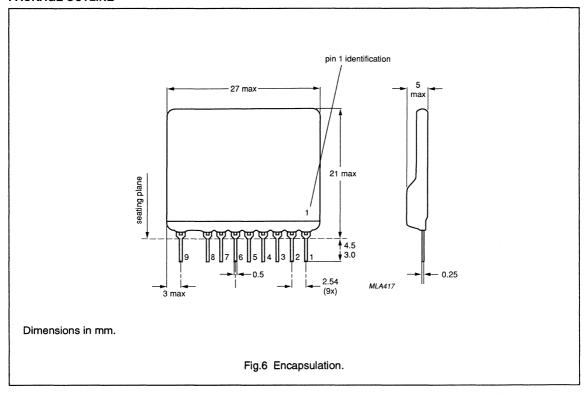
SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNIT
T <sub>amb</sub>	ambient operating temperature range	-20	_	70	°C
V <sub>B</sub>	DC supply voltage	10.8	12	13.2	٧
f	frequency range	40	<b>–</b>	860	MHz
R <sub>s</sub> , R <sub>L</sub>	source and load resistance	-	75	-	Ω





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## **PACKAGE OUTLINE**



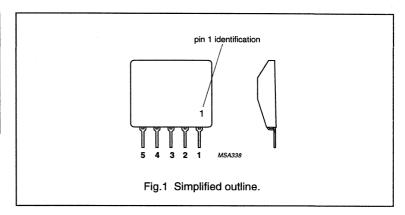
OM2081/60

## **DESCRIPTION**

A one-stage wideband amplifier in hybrid integrated circuit form on a thin-film substrate. The device is intended for use in mast-head booster amplifiers, as an amplifier in MATV and CATV systems and as a general purpose amplifier for VHF and UHF applications.

### **PINNING**

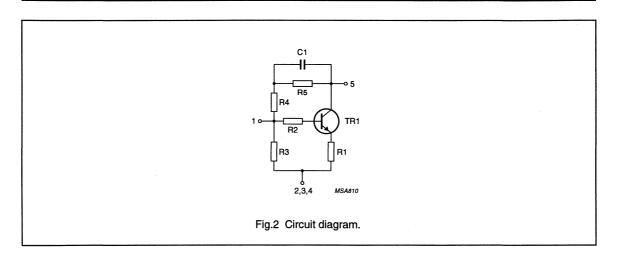
PIN	DESCRIPTION
1	input
2	common
3	common
4	common
5	output/supply (+)

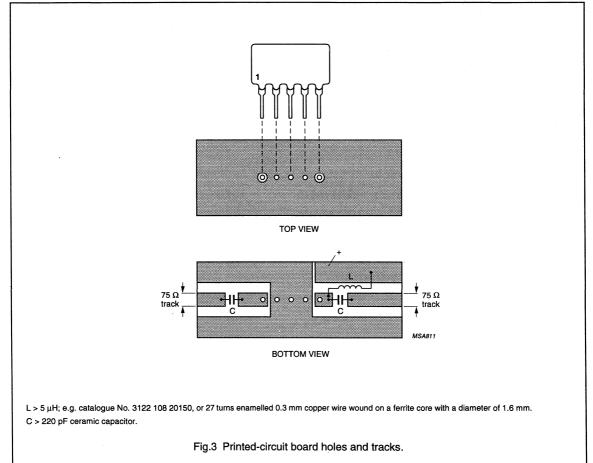


## **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
f	frequency range		40	_	600	MHz
Z <sub>s</sub> , Z <sub>L</sub>	source and load impedance		-	75	_	Ω
G <sub>T</sub>	transducer gain = $ S_{21} ^2$		-	10	11	dB
$\Delta G_T$	flatness of frequency response		_	1	-	dB
V <sub>o(rms)</sub>	output voltage (RMS value)	d <sub>im</sub> = -60 dB				
		2nd order intermodulation (2-tone)	104	105	_	dΒμV
		3rd order intermodulation (3-tone)	114	115	_	dΒμV
F	noise figure		-	7.5	-	dB
V <sub>B</sub>	DC supply voltage		10.8	12	13.2	V
T <sub>amb</sub>	ambient operating temperature		20	_	+70	∘C

## OM2081/60





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## **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
T <sub>amb</sub>	ambient operating temperature	-20	+70	°C
T <sub>stg</sub>	storage temperature	-40	+125	°C
V <sub>B</sub>	DC supply voltage	-	13.5	٧
P <sub>IM</sub>	peak incident powers on pins 1 and 5	_	100	mW

## **CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Measuring	conditions					
T <sub>amb</sub>	ambient operating temperature		<b>1</b>	25	<b>-</b>	°C
V <sub>B</sub>	DC supply voltage		-	12	-	V
Z <sub>s</sub>	source impedance		-	75	-	Ω
Z <sub>L</sub>	load impedance	:	<b>-</b>	75	-	Ω
Zo	characteristic impedance of HF connections	, , , , , , , , , , , , , , , , , , ,	-	75	-	Ω
f	frequency range		40	-	600	MHz
Performance	ce					
l <sub>B</sub>	supply current		T-	85	-	mA
G <sub>T</sub>	transducer gain = IS <sub>21</sub> I <sup>2</sup>	1	10	11	12	dB
ΔG <sub>T</sub>	flatness of frequency response		-	1	-	dB
VSWR <sub>in</sub>	individual maximum VSWR	input; note (1)	-	1.5	1.6	
VSWR <sub>out</sub>	individual maximum VSWR	output; note (1)	_	1.3	1.4	
IS <sub>12</sub> I <sup>2</sup>	back attenuation	f = 100 MHz	15	16	-	dB
		f = 600MHz	13	14	-	dB
V <sub>o(rms)</sub>	output voltage (RMS value)	$d_{im} = -60 \text{ dB}$				
		2nd order intermodulation (2-tone)	104	105	_	dΒμV
		3rd order intermodulation (3-tone)	114	115		dΒμV
F	noise figure		1-	7.5	_	dB

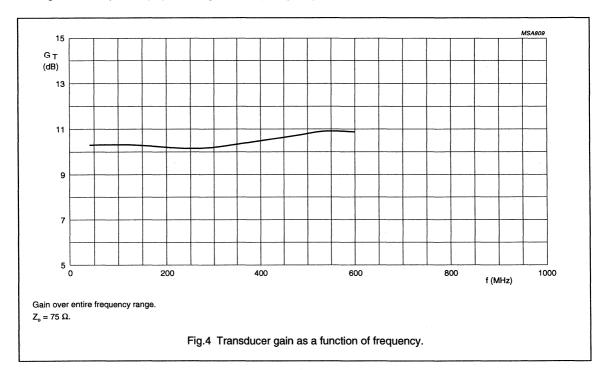
303

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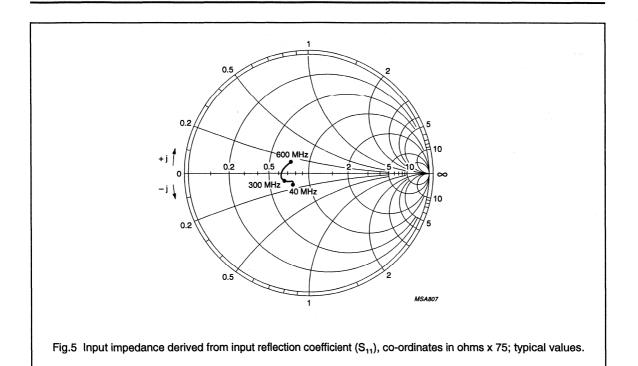
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Operating of	conditions					
T <sub>amb</sub>	ambient operating temperature		-20	-	+70	°C
V <sub>B</sub>	DC supply voltage		10.8	12 -	13.2	٧
f	frequency range		40	-	600	MHz
Z <sub>s</sub>	source impedance		-	75	-	Ω
Z <sub>L</sub>	load impedance		-	75	-	Ω

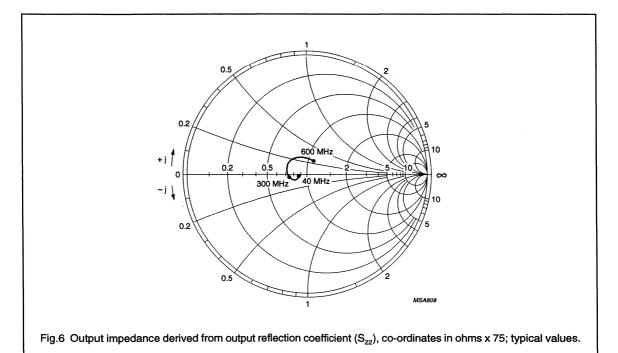
## Note to the characteristics

1. Highest value (for sample) occurring in the frequency range.



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#### MOUNTING

The module should preferably be mounted on a double-sided printed-circuit board, see Fig.3. Input and output should be connected to 75  $\Omega$  tracks. The connection to the common pins should be as close to the seating plane as possible.

### **SOLDERING**

## Hand soldering

The maximum contact time for a soldering iron temperature of 260  $^{\circ}$ C up to the seating plane is 5 s.

## Dip or wave soldering

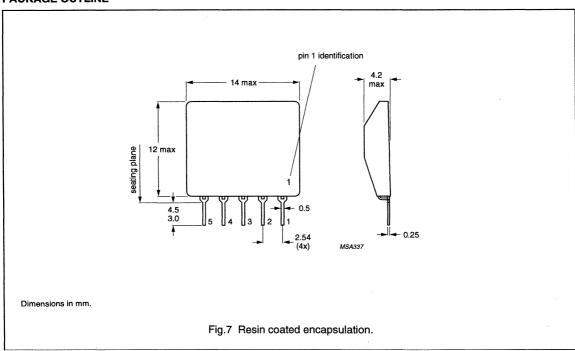
The maximum permissible temperature for the solder is 260 °C. It must not be in contact with the joint for more than 5 s.

The total contact time of successive solder waves must not exceed 5 s.

The device may be mounted against the printed-circuit board, but the temperature of the device must not exceed 125 °C.

If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature below the allowable limit.

## **PACKAGE OUTLINE**



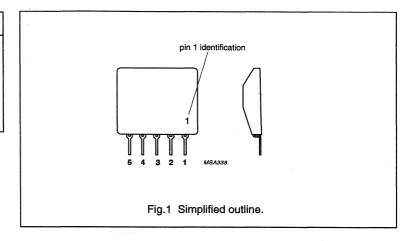
OM2081/86

## **DESCRIPTION**

A one-stage wideband amplifier in hybrid integrated circuit form on a thin-film substrate. The device is intended for use in mast-head booster amplifiers, as an amplifier in MATV and CATV systems and as a general purpose amplifier for VHF and UHF applications.

## **PINNING**

PIN	DESCRIPTION
1	input
2	common
3	common
4	common
5	output/supply (+)

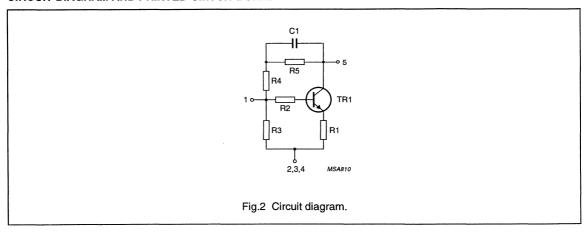


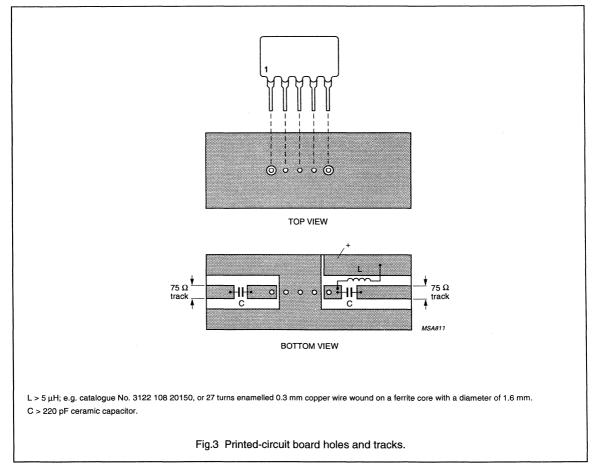
### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
f	frequency range		40	_	860	MHz
$Z_S, Z_L$	source and load impedance		-	75	_	Ω
G <sub>T</sub>	transducer gain = IS <sub>21</sub> I <sup>2</sup>		10.0	10.5	12.0	dB
$\Delta G_T$	flatness of frequency response		_	1	-	dB
$V_{o(rms)}$	output voltage (RMS value)	$d_{im} = -60 \text{ dB}$	-			
		2nd order intermodulation (2-tone)	104	105	-	dΒμV
		3rd order intermodulation (3-tone)	114	115	-	dΒμV
F	noise figure		_	7.5	8.0	dB
$V_B$	DC supply voltage		10.8	12	13.2	V
T <sub>amb</sub>	ambient operating temperature		-20	_	+70	°C

## OM2081/86

### **CIRCUIT DIAGRAM AND PRINTED-CIRCUIT BOARD**





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### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
T <sub>amb</sub>	ambient operating temperature	-20	+70	°C
T <sub>stg</sub>	storage temperature	-40	+125	°C
V <sub>B</sub>	DC supply voltage	-	13.5	٧
P <sub>IM</sub>	peak incident powers on pins 1 and 5	-	100	mW

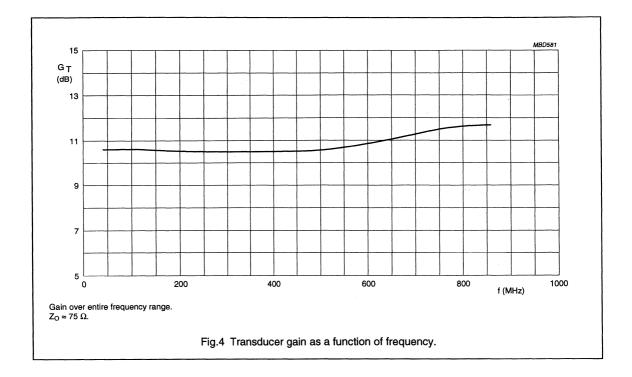
## **CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Measuring co	onditions					
T <sub>amb</sub>	ambient operating temperature		_	25	-	°C
V <sub>B</sub>	DC supply voltage		_	12	-	V
Z <sub>S</sub>	source impedance		_	75	_	Ω
$Z_L$	load impedance		_	75	_	Ω
Z <sub>O</sub>	characteristic impedance of HF connections		_	75	_	Ω
f	frequency range		40	_	860	MHz
Performance						
I <sub>B</sub>	supply current		60	65	70	mA
G <sub>T</sub>	transducer gain = IS <sub>21</sub> I <sup>2</sup>		10	11	12	dB
$\Delta G_T$	flatness of frequency response	·	_	1	-	dB
VSWR <sub>in</sub>	individual maximum VSWR	input; note 1	-	1.5	1.6	
VSWR <sub>out</sub>	individual maximum VSWR	output; note 1	-	1.3	1.4	
IS <sub>12</sub> I <sup>2</sup>	back attenuation	f = 100 MHz	15	16	_	dB
		f = 600MHz	13	14	-	dB
V <sub>o(rms)</sub>	output voltage (RMS value)	$d_{im} = -60 \text{ dB}$				
		2nd order intermodulation (2-tone)	104	105	-	dΒμV
		3rd order intermodulation (3-tone)	114	115	_	dΒμV
F	noise figure		_	7.5	8.0	dB
Operating co	onditions					
T <sub>amb</sub>	ambient operating temperature		-20	_	+70	°C
V <sub>B</sub>	DC supply voltage		10.8	12	13.2	V
f	frequency range		40	_	860	MHz
Z <sub>S</sub>	source impedance		_	75	-	Ω
$Z_{L}$	load impedance		_	75	I-	Ω

## Note

1. Highest value (for sample) occurring in the frequency range.

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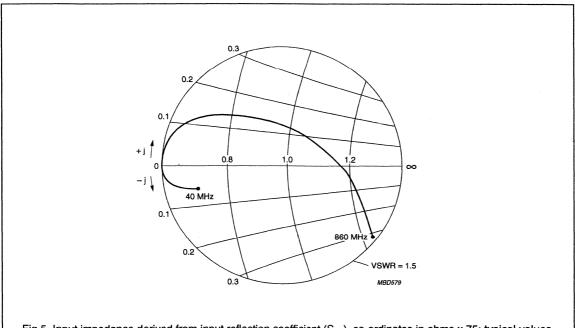


Fig.5 Input impedance derived from input reflection coefficient ( $S_{11}$ ), co-ordinates in ohms x 75; typical values.

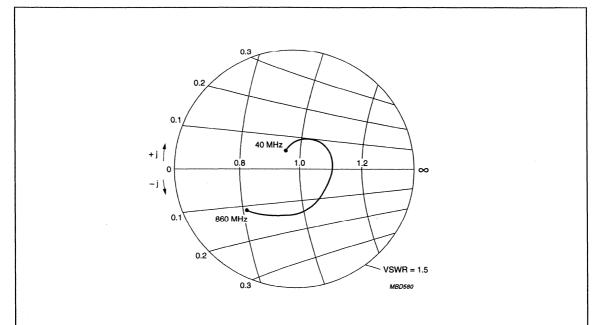


Fig.6 Output impedance derived from output reflection coefficient (S<sub>22</sub>), co-ordinates in ohms x 75; typical values.

## OM2081/86

#### MOUNTING

The module should preferably be mounted on a double-sided printed-circuit board, see Fig.3. Input and output should be connected to 75  $\Omega$  tracks. The connection to the common pins should be as close to the seating plane as possible.

### **SOLDERING**

## Hand soldering

The maximum contact time for a soldering iron temperature of 260 °C up to the seating plane is 5 s.

## Dip or wave soldering

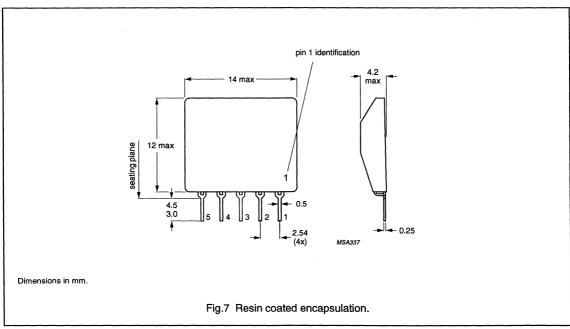
The maximum permissible temperature for the solder is 260 °C. It must not be in contact with the joint for more than 5 s.

The total contact time of successive solder waves must not exceed 5 s.

The device may be mounted against the printed-circuit board, but the temperature of the device must not exceed 125 °C.

If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature below the allowable limit.

## **PACKAGE OUTLINE**



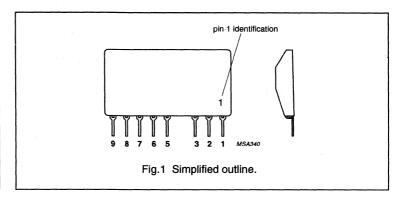
OM2082/60

## **DESCRIPTION**

A two-stage wideband amplifier in hybrid integrated circuit form on a thin-film substrate. The device is intended for use in mast-head booster amplifiers, as an amplifier in MATV and CATV systems and as a general purpose amplifier for VHF and UHF applications.

### **PINNING**

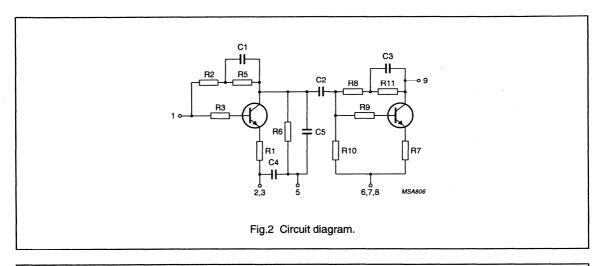
PIN	DESCRIPTION
1	input
2	common
3	common
5	supply (+)
6	common
7	common
8	common
9	output/supply (+)

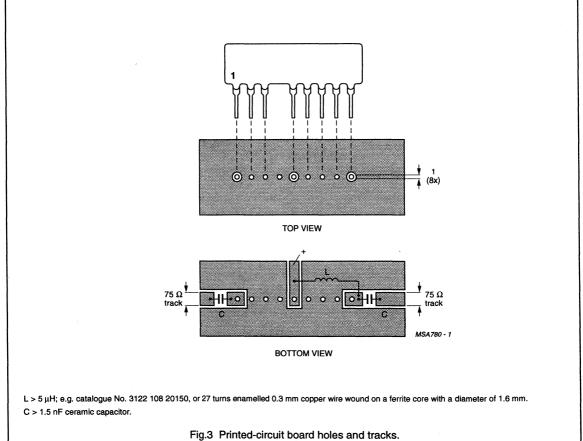


### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
f	frequency range		40	-	600	MHz
Z <sub>s</sub> , Z <sub>L</sub>	source and load impedance		-	75	-	Ω
G <sub>⊤</sub>	transducer gain = IS <sub>21</sub> I <sup>2</sup>		20	21	-	dB
$\Delta G_T$	flatness of frequency response		_	1	_	dB
V <sub>o(rms)</sub>	output voltage (RMS value)	$d_{im} = -60 \text{ dB}$				
		2nd order intermodulation (2-tone)	104	105	-	dΒμV
		3rd order intermodulation (3-tone)	114	115	-	dBμV
F	noise figure		-	7.5	_	dB
V <sub>B</sub>	DC supply voltage		10.8	12	13.2	٧
T <sub>amb</sub>	ambient operating temperature		-20	-	+70	°C

## OM2082/60





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## **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
T <sub>amb</sub>	ambient operating temperature	20	+70	°C
T <sub>stg</sub>	storage temperature	-40	+125	°C
V <sub>B</sub>	DC supply voltage	-	13.5	V
P <sub>IM</sub>	peak incident powers on pins 1 and 9	_	100	mW

## **CHARACTERISTICS**

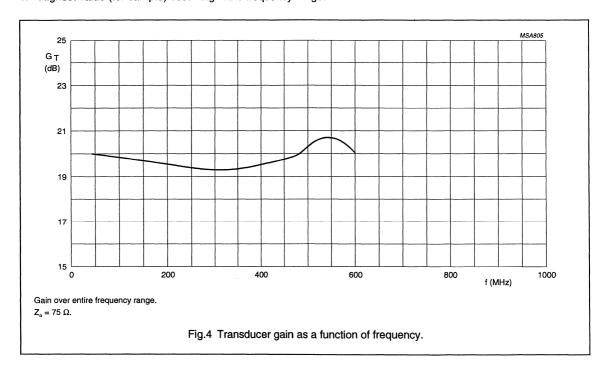
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT			
Measuring	Measuring conditions								
T <sub>amb</sub>	ambient operating temperature		-	25	-	°C			
$V_B$	DC supply voltage		_	12	-	٧			
Z <sub>s</sub>	source impedance		_	75	-	Ω			
Z <sub>L</sub>	load impedance		_	75	-	Ω			
Z <sub>o</sub>	characteristic impedance of HF connections		-	75	_	Ω			
f	frequency range		40	-	600	MHz			
Performand	ce								
I <sub>B</sub>	supply current		-	145	150	mA			
G <sub>T</sub>	transducer gain = IS <sub>21</sub> I <sup>2</sup>		19	20	21	dB			
∆G <sub>T</sub>	flatness of frequency response		-	1	_	dB			
VSWR <sub>in</sub>	individual maximum VSWR	input; note (1)	<b>-</b>	1.5	1.6				
VSWR <sub>out</sub>	individual maximum VSWR	output; note (1)	-	1.6	1.7				
IS <sub>12</sub> I <sup>2</sup>	back attenuation	f = 100 MHz	-	16	-	dB			
		f = 600MHz	-	14	-	dB			
V <sub>o(rms)</sub>	output voltage (RMS value)	$d_{im} = -60 \text{ dB}$							
		2nd order intermodulation (2-tone)	104	105	-	dΒμV			
		3rd order intermodulation (3-tone)	114	115	-	dΒμV			
F	noise figure		-	7.5	-	dB			

## OM2082/60

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Operating conditions						
T <sub>amb</sub>	ambient operating temperature		-20	-	+70	°C
V <sub>B</sub>	DC supply voltage		10.8	12	13.2	V
f	frequency range		40	-	600	MHz
Z <sub>s</sub>	source impedance		-	75	-	Ω
Z <sub>L</sub>	load impedance		-	75	-	Ω

## Note to the characteristics

1. Highest value (for sample) occurring in the frequency range.



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## OM2082/60

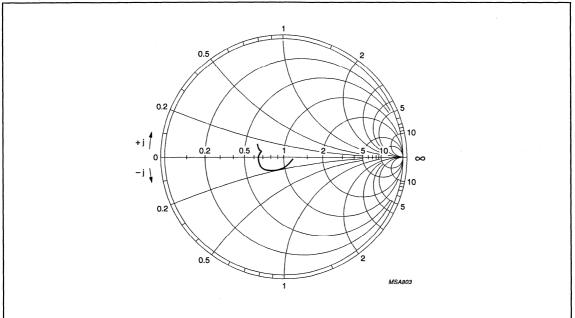


Fig. 5 Input impedance derived from input reflection coefficient ( $S_{11}$ ), co-ordinates in ohms x 75; typical values.

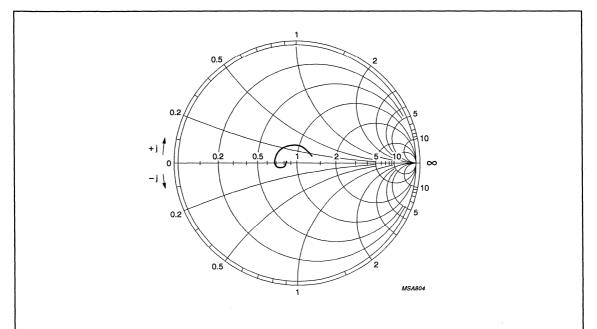


Fig. 6 Output impedance derived from output reflection coefficient ( $S_{22}$ ), co-ordinates in ohms x 75; typical values.

## OM2082/60

#### MOUNTING

The module should preferably be mounted on a double-sided printed-circuit board, see Fig.3. Input and output should be connected to 75  $\Omega$  tracks. The connection to the common pins should be as close to the seating plane as possible.

#### SOLDERING

## Hand soldering

The maximum contact time for a soldering iron temperature of 260 °C up to the seating plane is 5 s.

## Dip or wave soldering

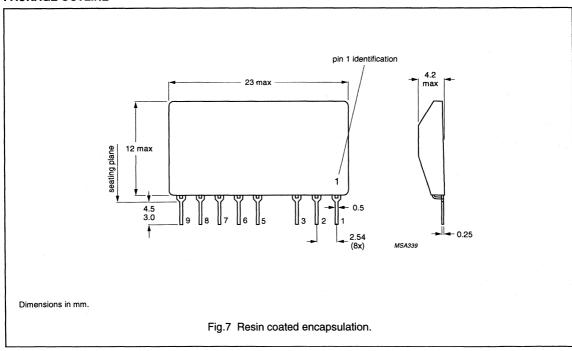
The maximum permissible temperature for the solder is 260 °C. It must not be in contact with the joint for more than 5 s.

The total contact time of successive solder waves must not exceed 5 s.

The device may be mounted against the printed-circuit board, but the temperature of the device must not exceed 125 °C.

If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature below the allowable limit.

## **PACKAGE OUTLINE**



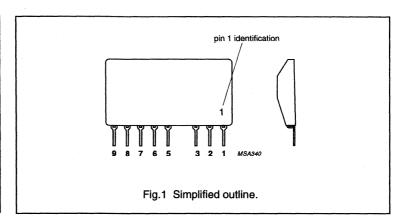
OM2082/86

### **DESCRIPTION**

A two-stage wideband amplifier in hybrid integrated circuit form on a thin-film substrate. The device is intended for use in mast-head booster amplifiers, as an amplifier in MATV and CATV systems and as a general purpose amplifier for VHF and UHF applications.

#### **PINNING**

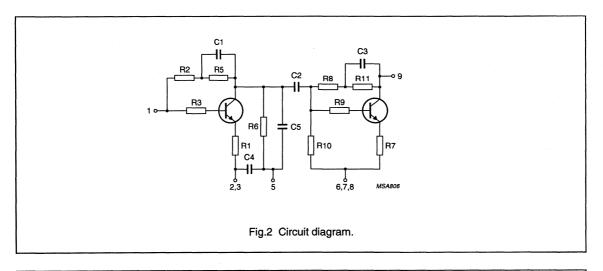
PIN	DESCRIPTION
1	input
2	common
3	common
4	supply (+)
5	common
6	common
7	common
8	common
9	output/supply (+)

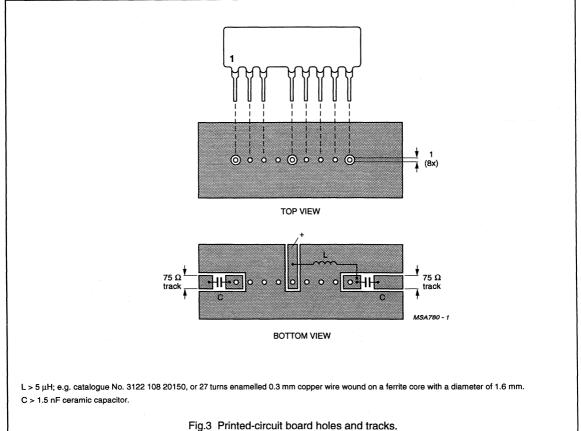


### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
f	frequency range		40	-	860	MHz
Z <sub>S</sub> , Z <sub>L</sub>	source and load impedance		-	75	_	Ω
G <sub>T</sub>	transducer gain = IS <sub>21</sub> I <sup>2</sup>		17	19	21	dB
$\Delta G_T$	flatness of frequency response		-	2	_	dB
V <sub>o(rms)</sub>	output voltage (RMS value)	d <sub>im</sub> =60 dB				
		2nd order intermodulation (2-tone)	103	104	_	dΒμV
		3rd order intermodulation (3-tone)	110	111	-	dΒμV
F	noise figure		-	7.5	_	dB
V <sub>B</sub>	DC supply voltage		10.8	12	13.2	٧
T <sub>amb</sub>	ambient operating temperature		-20	-	+70	°C

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### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
T <sub>amb</sub>	ambient operating temperature	-20	+70	°C
T <sub>stg</sub>	storage temperature	-40	+125	°C
V <sub>B</sub>	DC supply voltage	_	13.5	V
P <sub>IM</sub>	peak incident powers on pins 1 and 5	_	100	mW

### **CHARACTERISTICS**

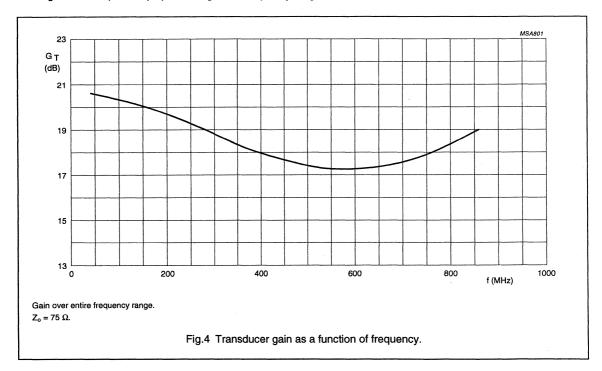
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Measuring	conditions		:			
T <sub>amb</sub>	ambient operating temperature		-	25	-	°C
V <sub>B</sub>	DC supply voltage		-	12	-	٧
Z <sub>S</sub>	source impedance		-	75	_	Ω
Z <sub>L</sub>	load impedance		1-	75	-	Ω
Z <sub>O</sub>	characteristic impedance of HF connections		-	75	-	Ω
f	frequency range	·	40	-	860	MHz
Performan	ce					
l <sub>B</sub>	supply current		-	145	150	mA
G <sub>T</sub>	transducer gain = IS <sub>21</sub> I <sup>2</sup>		17	19	21	dB
$\Delta G_T$	flatness of frequency response		-	2	-	dB
VSWRin	individual maximum VSWR	input; note <sup>(1)</sup>	-	1.7	1.9	
VSWR <sub>out</sub>	individual maximum VSWR	output; note (1)	1-	1.4	1.6	
IS <sub>12</sub>  2	back attenuation	f = 100 MHz	-	30	-	dB
		f = 860 MHz	-	30	<b> </b> -	dB
V <sub>o(rms)</sub>	output voltage (RMS value)	d <sub>im</sub> = -60 dB				
		2nd order intermodulation (2-tone)	103	104	-	dΒμV
		3rd order intermodulation (3-tone)	110	111	-	dΒμV
F	noise figure		1-	7.5	-	dB

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT		
Operating of	Operating conditions							
T <sub>amb</sub>	ambient operating temperature		-20	<u> </u>	+70	°C		
V <sub>B</sub>	DC supply voltage		10.8	12	13.2	٧		
f	frequency range		40	-	860	MHz		
Z <sub>S</sub>	source impedance		-	75	-	Ω		
$Z_{L}$	load impedance		-	75	-	Ω		

### Note to the characteristics

1. Highest value (for sample) occurring in the frequency range.



### OM2082/86

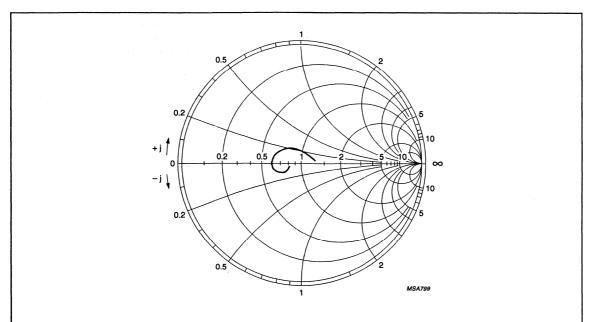


Fig.5 Input impedance derived from input reflection coefficient (S<sub>11</sub>), co-ordinates in ohms x 75; typical values.

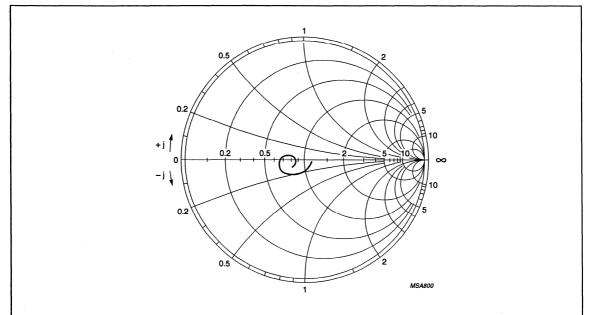


Fig. 6 Output impedance derived from output reflection coefficient (S22), co-ordinates in ohms x 75; typical values.

### OM2082/86

#### MOUNTING

The module should preferably be mounted on a double-sided printed-circuit board, see Fig.3. Input and output should be connected to 75  $\Omega$  tracks. The connection to the common pins should be as close to the seating plane as possible.

#### **SOLDERING**

#### Hand soldering

The maximum contact time for a soldering iron temperature of 260  $^{\circ}$ C up to the seating plane is 5 s.

#### Dip or wave soldering

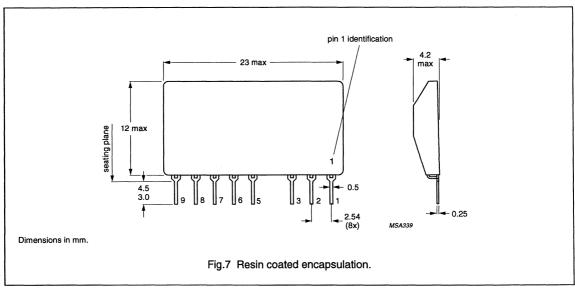
The maximum permissible temperature for the solder is 260 °C. It must not be in contact with the joint for more than 5 s.

The total contact time of successive solder waves must not exceed 5 s.

The device may be mounted against the printed-circuit board, but the temperature of the device must not exceed 125 °C.

If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature below the allowable limit.

#### **PACKAGE OUTLINE**



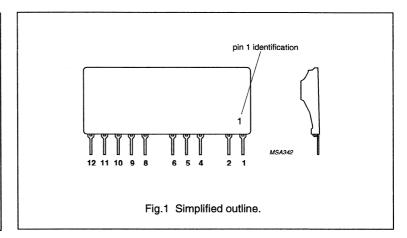
OM2083/60

#### DESCRIPTION

A three-stage wideband amplifier in hybrid integrated circuit form on a thin-film substrate. The device is intended for use in mast-head booster amplifiers, as an amplifier in MATV and CATV systems and as a general purpose amplifier for VHF and UHF applications.

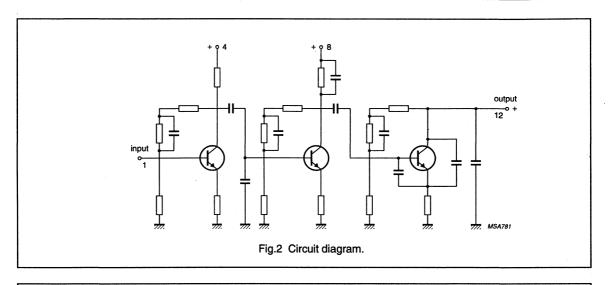
### **PINNING**

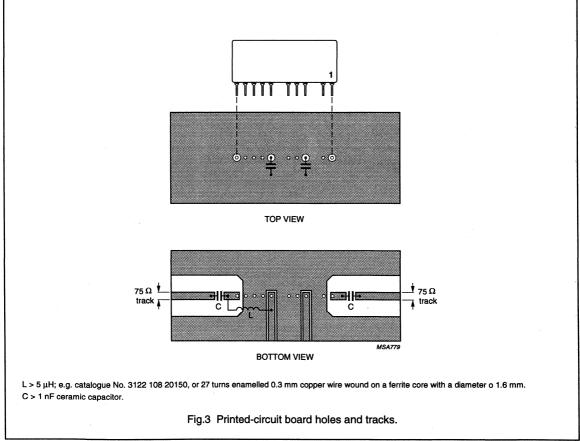
PIN	DESCRIPTION
1	input
2	common
4	supply (+)
5	common
6	common
8	supply (+)
9	common
10	common
11	common
12	output/supply (+)



### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
f	frequency range		40	-	600	MHz
Z <sub>s</sub> , Z <sub>L</sub>	source and load impedance		-	75	-	Ω
G <sub>T</sub>	transducer gain = IS <sub>21</sub> I <sup>2</sup>		28	29	30	dB
$\Delta G_T$	flatness of frequency response		-	1	_	dB
V <sub>o(rms)</sub>	output voltage (RMS value)	$d_{im} = -60 \text{ dB}$				
		2nd order intermodulation (2-tone)	103	104	-	dΒμV
		3rd order intermodulation (3-tone)	113	114	-	dΒμV
F	noise figure	·	-	6.5	-	dB
V <sub>B</sub>	DC supply voltage		10.8	12	13.2	V
T <sub>amb</sub>	ambient operating temperature		-20	-	+70	°C





OM2083/60

### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
T <sub>amb</sub>	ambient operating temperature	-20	+70	°C
T <sub>stg</sub>	storage temperature	-40	+125	°C
V <sub>B</sub>	DC supply voltage	_	13.5	V
P <sub>IM</sub>	peak incident powers on pins 1 and 12	_	100	mW

### **CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Measuring	conditions					
T <sub>amb</sub>	ambient operating temperature		T-	25	<b> </b> -	°C
V <sub>B</sub>	DC supply voltage		1-	12	<b> </b>	٧
Z <sub>s</sub>	source impedance		1-	75	-	Ω
Z <sub>L</sub>	load impedance		-	75	-	Ω
Z <sub>o</sub>	characteristic impedance of HF connections		-	75	-	Ω
f	frequency range		40	-	600	MHz
Performance	ce					
I <sub>B</sub>	supply current		-	175	<u> </u>	mA
G <sub>T</sub>	transducer gain = IS <sub>21</sub> I <sup>2</sup>		28	29	30	dB
∆G <sub>T</sub>	flatness of frequency response		1-	1	-	dB
VSWR <sub>in</sub>	individual maximum VSWR	input; note (1)	-	1.2	1.35	
VSWR <sub>out</sub>	individual maximum VSWR	output; note (1)	-	1.3	1.35	
IS <sub>12</sub> I <sup>2</sup>	back attenuation	f = 100 MHz	_	50	-	dB
		f = 600 MHz	_	40	_	dB
V <sub>o(rms)</sub>	output voltage (RMS value)	$d_{im} = -60 \text{ dB}$				
		2nd order intermodulation (2-tone)	103	104	-	dΒμV
		3rd order intermodulation (3-tone)	113	114	-	dΒμV
F	noise figure		1-	6.5	7.5	dB

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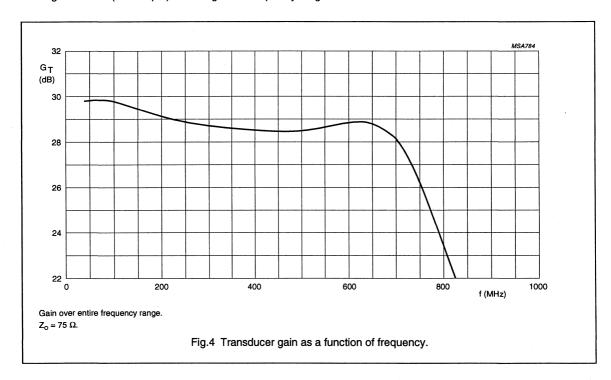
OM2083/60

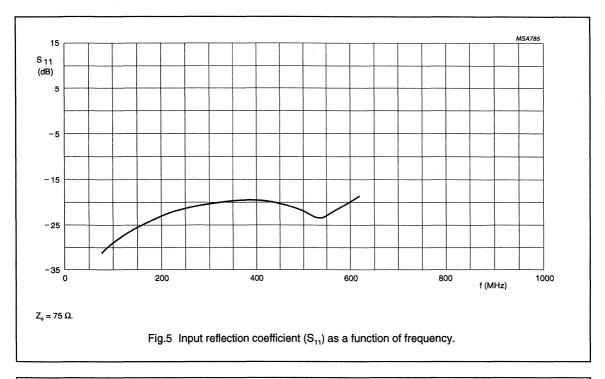
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Operating conditions						
T <sub>amb</sub>	ambient operating temperature		-20	-	+70	°C
V <sub>B</sub>	DC supply voltage		10.8	12	13.2	٧
f	frequency range	-	40	-	600	MHz
Z <sub>s</sub>	source impedance		_	75	-	Ω
Z <sub>L</sub>	load impedance		-	75	-	Ω

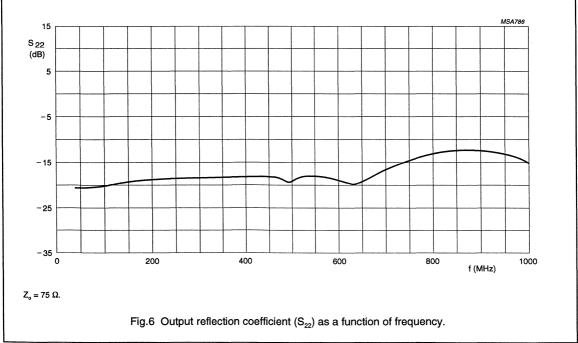
### Note to the characteristics

October 1993

1. Highest value (for sample) occurring in the frequency range.







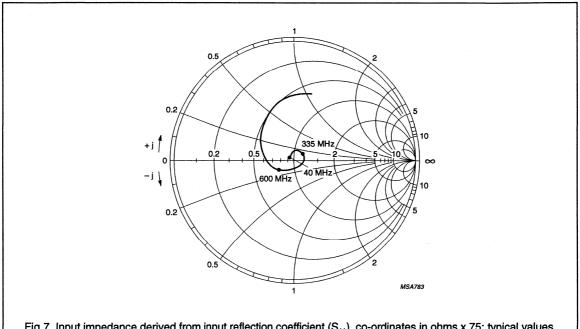


Fig.7 Input impedance derived from input reflection coefficient (S<sub>11</sub>), co-ordinates in ohms x 75; typical values.

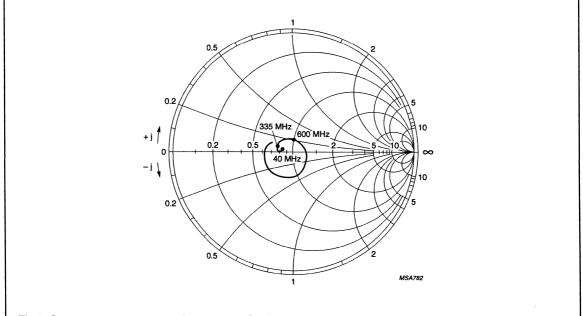


Fig. 8 Output impedance derived from output reflection coefficient ( $S_{22}$ ), co-ordinates in ohms x 75; typical values.

### OM2083/60

#### MOUNTING

The module should preferably be mounted on a double-sided printed-circuit board, see Fig.3.

Input and output should be connected to 75  $\Omega$  tracks. The connection to the common pins should be as close to the seating plane as possible.

#### SOLDERING

#### Hand soldering

The maximum contact time for a soldering iron temperature of 260 °C up to the seating plane is 5 s.

### Dip or wave soldering

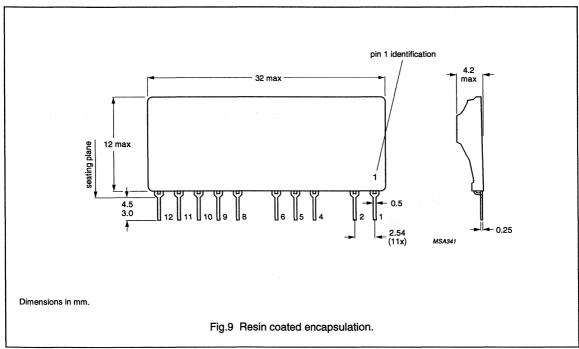
The maximum permissible temperature for the solder is 260 °C. It must not be in contact with the joint for more than 5 s.

The total contact time of successive solder waves must not exceed 5 s.

The device may be mounted against the printed-circuit board, but the temperature of the device must not exceed 125 °C.

If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature below the allowable limit.

### **PACKAGE OUTLINE**



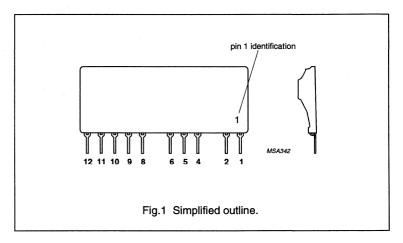
OM2083/86

#### DESCRIPTION

A three-stage wideband amplifier in hybrid integrated circuit form on a thin-film substrate. The device is intended for use in mast-head booster amplifiers, as an amplifier in MATV and CATV systems and as a general purpose amplifier for VHF and UHF applications.

### **PINNING**

PIN	DESCRIPTION
1	input
2	common
4	supply (+)
5	common
6	common
8	supply (+)
9	common
10	common
11	common
12	output/supply (+)

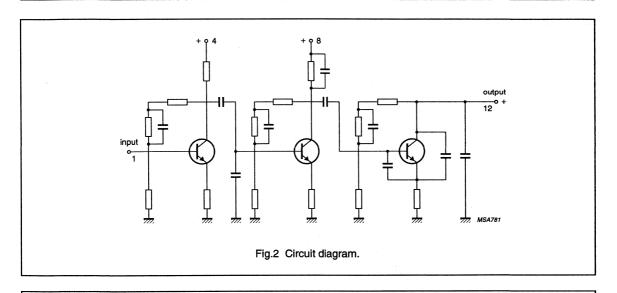


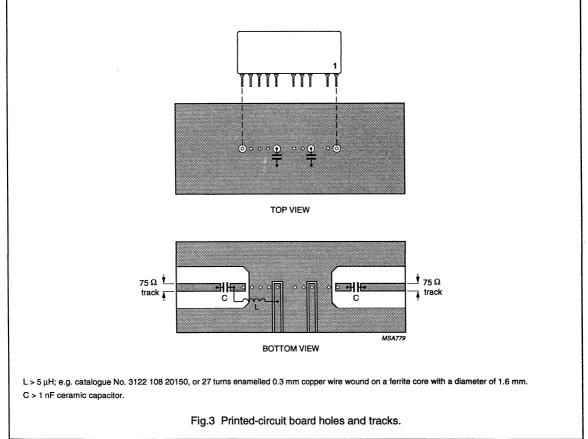
### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
f	frequency range		40	-	860	MHz
$Z_s, Z_L$	source and load impedance		-	75	_	Ω
G <sub>T</sub>	transducer gain = IS <sub>21</sub> I <sup>2</sup>		28.5	30	31.5	dB
ΔG <sub>T</sub>	flatness of frequency response		_	1.5	_	dB
V <sub>o(rms)</sub>	output voltage (RMS value)	d <sub>im</sub> = -60 dB				
		2nd order intermodulation (2-tone)	102(1)	103	_	dBμV
		3rd order intermodulation (3-tone)	112	113	_	dΒμV
F	noise figure			7	7.5	dB
V <sub>B</sub>	DC supply voltage		10.8	12	13.2	٧
T <sub>amb</sub>	ambient operating temperature		-20	_	+70	°C

#### Note

1. 100 dBµV over 750 MHz.





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### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	BOL PARAMETER		MAX.	UNIT	
T <sub>amb</sub>	ambient operating temperature	-20	+70	°C	
T <sub>stg</sub>	storage temperature	-40	+125	°C	
V <sub>B</sub>	DC supply voltage		13.5	٧	
P <sub>IM</sub>	peak incident powers on pins 1 and 12		100	mW	

### **CHARACTERISTICS**

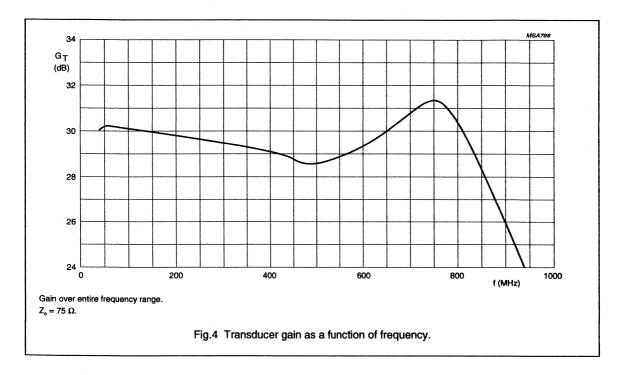
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT		
Measuring conditions								
T <sub>amb</sub>	ambient operating temperature		1-	25	-	°C		
V <sub>B</sub>	DC supply voltage		1-	12	-	٧		
Z <sub>s</sub>	source impedance		1-	75	-	Ω		
Z <sub>L</sub>	load impedance	: :	1-	75	-	Ω		
Z <sub>o</sub>	characteristic impedance of HF connections		_	75	-	Ω		
f	frequency range		40	-	860	MHz		
Performan	ce					<u> </u>		
I <sub>B</sub>	supply current		T-	165	<b>I</b> -	mA		
G <sub>T</sub>	transducer gain = IS <sub>21</sub> I <sup>2</sup>		28	30	32	dB		
ΔG <sub>T</sub>	flatness of frequency response		1-	1.5	-	dB		
VSWR <sub>in</sub>	individual maximum VSWR	input; note (1)	1-	1.9	2.0			
VSWR <sub>out</sub>	individual maximum VSWR	output; note (1)	1-	1.7	1.8			
S <sub>12</sub>   <sup>2</sup>	back attenuation	f = 100 MHz	1-	45		dB		
		f = 860 MHz	1-	40	-	dB		
V <sub>o(rms)</sub>	output voltage (RMS value)	$d_{im} = -60 \text{ dB}$						
		2nd order intermodulation (2-tone)	102(2)	103	_	dΒμV		
		3rd order intermodulation (3-tone)	112	113		dBμV		
F	noise figure		1-	7	7.5	dB		

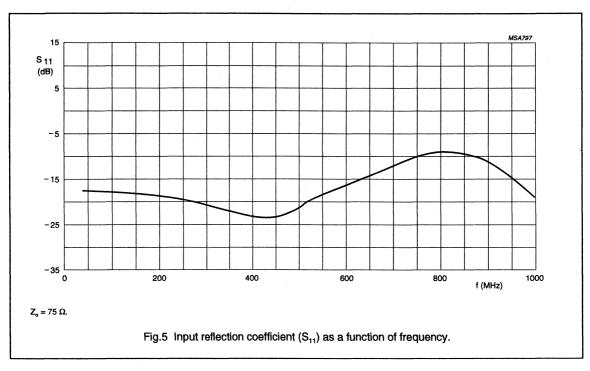
## OM2083/86

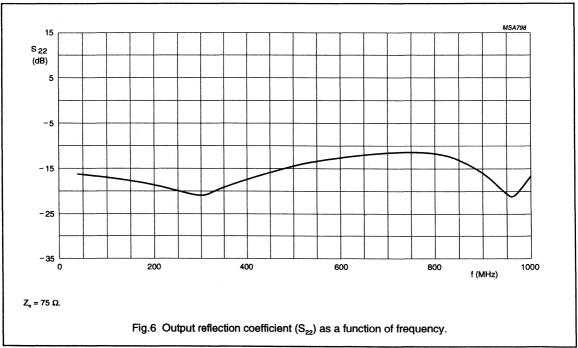
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Operating	conditions				·	•
T <sub>amb</sub>	ambient operating temperature		-20	<u> </u>	+70	°C
V <sub>B</sub>	DC supply voltage		10.8	12	13.2	V
f	frequency range		40	-	860	MHz
Z <sub>s</sub>	source impedance		-	75	-	Ω
Z <sub>L</sub>	load impedance		1-	75	-	Ω

### Notes to the characteristics

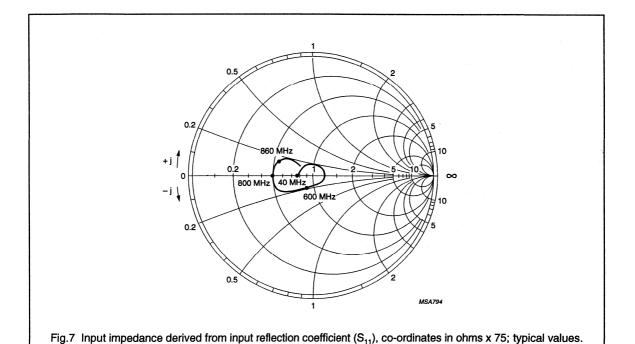
- 1. Highest value (for sample) occurring in the frequency range.
- 2. 100 dBμV over 750 MHz.







OM2083/86



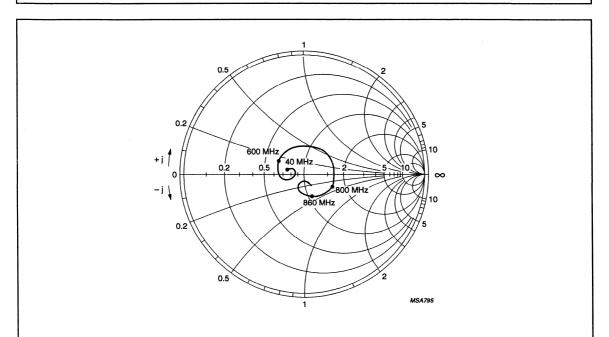


Fig. 8 Output impedance derived from output reflection coefficient ( $S_{22}$ ), co-ordinates in ohms x 75; typical values.

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### OM2083/86

#### MOUNTING

The module should preferably be mounted on a double-sided printed-circuit board, see Fig.3. Input and output should be connected to 75  $\Omega$  tracks. The connection to the

to 75  $\Omega$  tracks. The connection to the common pins should be as close to the seating plane as possible.

#### **SOLDERING**

#### Hand soldering

The maximum contact time for a soldering iron temperature of 260 °C up to the seating plane is 5 s.

### Dip or wave soldering

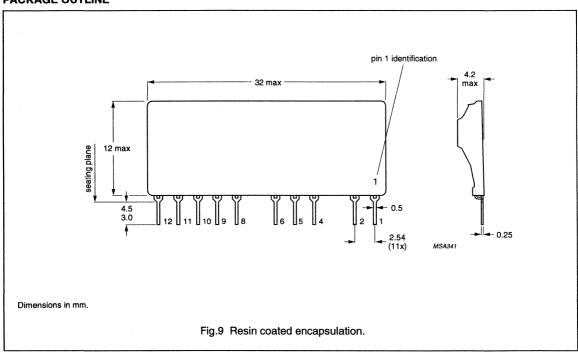
The maximum permissible temperature for the solder is 260 °C. It must not be in contact with the joint for more than 5 s.

The total contact time of successive solder waves must not exceed 5 s.

The device may be mounted against the printed-circuit board, but the temperature of the device must not exceed 125 °C.

If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature below the allowable limit.

#### **PACKAGE OUTLINE**



## **DATA HANDBOOK SYSTEM**

### Data handbook system

#### **DATA HANDBOOK SYSTEM**

Philips Semiconductors data handbooks contain all pertinent data available at the time of publication and each is revised and reissued regularly.

Loose data sheets are sent to subscribers to keep them up-to-date on additions or alterations made during the lifetime of a data handbook.

Catalogues are available for selected product ranges (some catalogues are also on floppy discs).

Our data handbook titles are listed here.

#### Integrated circuits

Book	Title
IC01	Semiconductors for Radio and Audio Systems
IC02	Semiconductors for Television and Video Systems
IC03	Semiconductors for Telecom Systems
IC04	CMOS HE4000B Logic Family
IC06	High-speed CMOS Logic Family
IC11	General-purpose/Linear ICs
IC12	I <sup>2</sup> C Peripherals
IC13	Programmable Logic Devices (PLD)
IC14	8048-based 8-bit Microcontrollers
IC15	FAST TTL Logic Series
IC16	CMOS Integrated Circuits for Clocks and Watches
IC17	RF/Wireless Communications
IC18	Semiconductors for In-car Electronics
IC19	ICs for Data Communications
IC20	80C51-based 8-bit Microcontrollers
IC22	Desktop Video
IC23	QUBiC Advanced BiCMOS Interface Logic ABT MULTIBYTE™
IC24	Low Voltage CMOS & BiCMOS Logic

#### Discrete semiconductors Title

Book

DOOM	THIC
SC01	Diodes
SC02	Power Diodes
SC03	Thyristors and Triacs
SC04	Small-signal Transistors
SC06	High-voltage and Switching
	NPN Power Transistors
SC07	Small-signal Field-effect Transistors
SC08a	RF Power Bipolar Transistors
SC08b	RF Power MOS Transistors
SC09	RF Power Modules
SC10	Surface Mounted Semiconductors
SC13	PowerMOS Transistors
	including TOPFETs and IGBTs
SC14	RF Wideband Transistors,
	Video Transistors and Modules
SC15	Microwave Transistors
SC16	Wideband Hybrid IC Modules
SC17	Semiconductor Sensors

#### **Professional components**

PC01 High-power Klystrons and Accessories PC06 Circulators and Isolators

#### MORE INFORMATION FROM PHILIPS SEMICONDUCTORS?

For more information about Philips Semiconductors data handbooks, catalogues and subscriptions contact your nearest Philips Semiconductors national organization, select from the address list on the back cover of this handbook. Product specialists are at your service and enquiries are answered promptly.

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### Data handbook system

# OVERVIEW OF PHILIPS COMPONENTS DATA HANDBOOKS

Our sister product division, Philips Components, also has a comprehensive data handbook system to support their products. Their data handbook titles are listed here.

#### **Display components**

Book Title

DC01 Colour TV Picture Tubes and Assemblies

Colour Monitor Tubes

DC02 Monochrome Monitor Tubes and Deflection Units

DC03 Television Tuners, Coaxial Aerial Input

Assemblies

DC05 Flyback Transformers, Mains Transformers and

General-purpose FXC Assemblies

#### **Magnetic products**

MA01 Soft Ferrites

MA03 Piezoelectric Ceramics

Specialty Ferrites

MA04 Dry-reed Switches

#### **Passive components**

PA01 Electrolytic Capacitors

PA02 Varistors, Thermistors and Sensors

PA03 Potentiometers

PA04 Variable Capacitors

PA05 Film Capacitors

PA06 Ceramic Capacitors

PA07 Quartz Crystals for Special and Industrial

Applications

PA08 Fixed Resistors

PA10 Quartz Crystals for Automotive and Standard

Applications

PA11 Quartz Oscillators

#### Professional components

PC04 Photo Multipliers

PC05 Plumbicon Camera Tubes and Accessories

PC07 Vidicon and Newvicon Camera Tubes and

**Deflection Units** 

PC08 Image Intensifiers PC12 Electron Multipliers

#### MORE INFORMATION FROM PHILIPS COMPONENTS?

For more information contact your nearest Philips Components national organization shown in the following list.

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Printed in The Netherlands

123057/5000/02/pp341 Document order number: Date of release: March 1995 9397 750 00006



